

38D2 Group

SINGLE-CHIP 8-BIT CMOS MICROCOMPUTER

REJ03B0177-0302

Rev.3.02

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DESCRIPTION

The 38D2 Group is the 8-bit microcomputer based on the 740 Family core technology.

The 38D2 Group is pin-compatible with the 38C2 Group.

The 38D2 Group has an LCD drive control circuit, an A/D converter, a serial interface, and a ROM correction function and on-chip oscillator as additional functions.

The QzROM version and the flash memory version are available.

The flash memory version does not have a selection function for the oscillation start mode. Only the on-chip oscillator starts oscillating.

The various microcomputers include variations of memory size, and packaging. For details, refer to the section on part numbering.

FEATURES

- Basic machine-language instructions 71
- The minimum instruction execution time 0.32 μ s
(at 12.5 MHz oscillation frequency)
- Memory size (QzROM version)
 - ROM 16 K to 60 K bytes
 - RAM 640 to 2048 bytes
- Memory size (Flash memory version)
 - ROM 60 K bytes
 - RAM 2048 bytes
- Programmable input/output ports .. 51 (common to SEG: 24)
- Interrupts 18 sources, 16 vectors
- Timers 8-bit $\times$ 4, 16-bit $\times$ 2
- Serial interface 8-bit $\times$ 2 (UART or Clock-synchronized)
- PWM 10-bit $\times$ 2, 16-bit $\times$ 1 (common to IGBT output)
- A/D converter 10-bit $\times$ 8 channels
(A/D converter can be operated in low-speed mode.)
- Watchdog timer 8-bit $\times$ 1
- ROM correction function 32 bytes $\times$ 2 vectors
- LED direct drive port 8
(average current: 15 mA, peak current: 30 mA, total current: 90 mA)
- LCD drive control circuit
 - Bias 1/2, 1/3
 - Duty 2, 3, 4
 - Common output 4
 - Segment output 24
- Main clock generating circuit 1
(connect to external ceramic resonator or on-chip oscillator)
- Sub-clock generating circuit 1
(connect to external quartz-crystal oscillator)

Power source voltage (QzROM version)

[In frequency/2 mode]

$f(XIN) \leq 12.5$ MHz.....	4.5 to 5.5 V
$f(XIN) \leq 8$ MHz.....	4.0 to 5.5 V
$f(XIN) \leq 4$ MHz.....	2.0 to 5.5 V
$f(XIN) \leq 2$ MHz.....	1.8 to 5.5 V

[In frequency/4 mode]

$f(XIN) \leq 16$ MHz.....	4.5 to 5.5 V
$f(XIN) \leq 8$ MHz.....	2.0 to 5.5 V
$f(XIN) \leq 4$ MHz.....	1.8 to 5.5 V

[In frequency/8 mode]

$f(XIN) \leq 16$ MHz.....	4.5 to 5.5 V
$f(XIN) \leq 8$ MHz.....	2.0 to 5.5 V
$f(XIN) \leq 4$ MHz.....	1.8 to 5.5 V

[In low-speed mode]..... 1.8 to 5.5 V

Note. 12.5 MHz $< f(XIN) \leq 16$ MHz is not available in the frequency/2 mode.

Power source voltage (Flash memory version)

[In frequency/2 mode]

$f(XIN) \leq 12.5$ MHz.....	4.5 to 5.5 V
$f(XIN) \leq 8$ MHz.....	4.0 to 5.5 V
$f(XIN) \leq 4$ MHz.....	2.7 to 5.5 V

[In frequency/4 mode]

$f(XIN) \leq 16$ MHz.....	4.5 to 5.5 V
$f(XIN) \leq 8$ MHz.....	2.7 to 5.5 V

[In frequency/8 mode]

$f(XIN) \leq 16$ MHz.....	4.5 to 5.5 V
$f(XIN) \leq 8$ MHz.....	2.7 to 5.5 V

[In low-speed mode]..... 2.7 to 5.5 V

Note. 12.5 MHz $< f(XIN) \leq 16$ MHz is not available in the frequency/2 mode.

Power dissipation (QzROM version)

- In frequency/2 mode Typ. 32 mW
($V_{CC} = 5$ V, $f(XIN) = 12.5$ MHz, $T_a = 25^\circ\text{C}$)

- In low-speed mode Typ. 18 μ W
($V_{CC} = 2.5$ V, $f(XIN) = \text{stop}$, $f(XCIN) = 32$ kHz, $T_a = 25^\circ\text{C}$)

Power dissipation (Flash memory version)

- In frequency/2 mode Typ. 20 mW
($V_{CC} = 5$ V, $f(XIN) = 12.5$ MHz, $T_a = 25^\circ\text{C}$)

- In low-speed mode Typ. 1.1 mW
($V_{CC} = 2.7$ V, $f(XIN) = \text{stop}$, $f(XCIN) = 32$ kHz, $T_a = 25^\circ\text{C}$)

- Operating temperature range -20 to 85°C

Flash Memory Mode

- Program/Erase voltage $V_{CC} = 2.7$ to 5.5 V
- Program method Programming in unit of byte
- Erase method Block erasing
- Program/Erase control by software command

APPLICATION

Household products, Consumer electronics, etc.

Fig. 1 Pin configuration (LQFP Package)

Table 1 Performance overview

Parameter			Function
Number of basic instructions			71
Instruction execution time			0.32 μs (Minimum instruction, Oscillation frequency 12.5 MHz)
Oscillation frequency			16 MHz (Maximum) ⁽¹⁾
Memory sizes (QzROM version)	ROM	16 K to 60 K bytes	
	RAM	640 to 2048 bytes	
Memory sizes (Flash memory version)	ROM	60 K bytes	
	RAM	2048 bytes	
I/O port	P0-P5, P60-P62		8-bit × 6, 3-bit × 1 (24 pins sharing SEG)
Interrupt			18 sources, 16 vectors (includes key input interrupt)
Timer			8-bit × 4, 16-bit × 2
Serial Interface			8-bit × 2 (UART or Clock-synchronized)
PWM			10-bit × 2, 16-bit × 1 (common to IGBT output)
A/D converter			10-bit × 8 (operated in low-speed mode)
Watchdog timer			8-bit × 1
ROM correction function			32 bytes × 2 vectors
LED direct drive port			8 (average current: 15 mA, peak current: 30 mA, total current: 90 mA)
LCD drive control circuit	Bias	1/2, 1/3	
	Duty	2, 3, 4	
	Common output	4	
	Segment output	24	
Main clock generating circuits			Built-in (connect to external ceramic resonator or on-chip oscillator)
Sub-clock generating circuits			Built-in (connect to external quartz-crystal oscillator)
Power source voltage (QzROM version)	In frequency/2 mode (1)	f(X _{IN}) ≤ 12.5 MHz	4.5 to 5.5 V
		f(X _{IN}) ≤ 8 MHz	4.0 to 5.5 V
		f(X _{IN}) ≤ 4 MHz	2.0 to 5.5 V
		f(X _{IN}) ≤ 2 MHz	1.8 to 5.5 V
	In frequency/4 mode	f(X _{IN}) ≤ 16 MHz	4.5 to 5.5 V
		f(X _{IN}) ≤ 8 MHz	2.0 to 5.5 V
		f(X _{IN}) ≤ 4 MHz	1.8 to 5.5 V
	In frequency/8 mode	f(X _{IN}) ≤ 16 MHz	4.5 to 5.5 V
		f(X _{IN}) ≤ 8 MHz	2.0 to 5.5 V
		f(X _{IN}) ≤ 4 MHz	1.8 to 5.5 V
	In low-speed mode		1.8 to 5.5 V
Power source voltage (Flash memory version)	In frequency/2 mode (1)	f(X _{IN}) ≤ 12.5 MHz	4.5 to 5.5 V
		f(X _{IN}) ≤ 8 MHz	4.0 to 5.5 V
		f(X _{IN}) ≤ 4 MHz	2.7 to 5.5 V
	In frequency/4 mode	f(X _{IN}) ≤ 16 MHz	4.5 to 5.5 V
		f(X _{IN}) ≤ 8 MHz	2.7 to 5.5 V
	In frequency/8 mode	f(X _{IN}) ≤ 16 MHz	4.5 to 5.5 V
		f(X _{IN}) ≤ 8 MHz	2.7 to 5.5 V
	In low-speed mode		2.7 to 5.5 V
Power dissipation (QzROM version)	In frequency/2 mode		Std. 32 mW (V _{CC} = 5 V, f(X _{IN}) = 12.5 MHz, T _a = 25°C)
	In low-speed mode		Std. 18 μW (V _{CC} = 2.5 V, f(X _{IN}) = stop, f(X _{CIN}) = 32 kHz, T _a = 25°C)
Power dissipation (Flash memory version)	In frequency/2 mode		Std. 20 mW (V _{CC} = 5 V, f(X _{IN}) = 12.5 MHz, T _a = 25°C)
	In low-speed mode		Std. 1.1 mW (V _{CC} = 2.7 V, f(X _{IN}) = stop, f(X _{CIN}) = 32 kHz, T _a = 25°C)
Input/Output characteristics	Input/Output withstand voltage		V _{CC}
	Output current		10 mA
Operating temperature range			-20 to 85°C
Device structure			CMOS silicon gate
Package			64-pin plastic molded LQFP

NOTE:

1. 12.5 MHz $< f(X_{IN}) \leq 16$ MHz is not available in the frequency/2 mode.

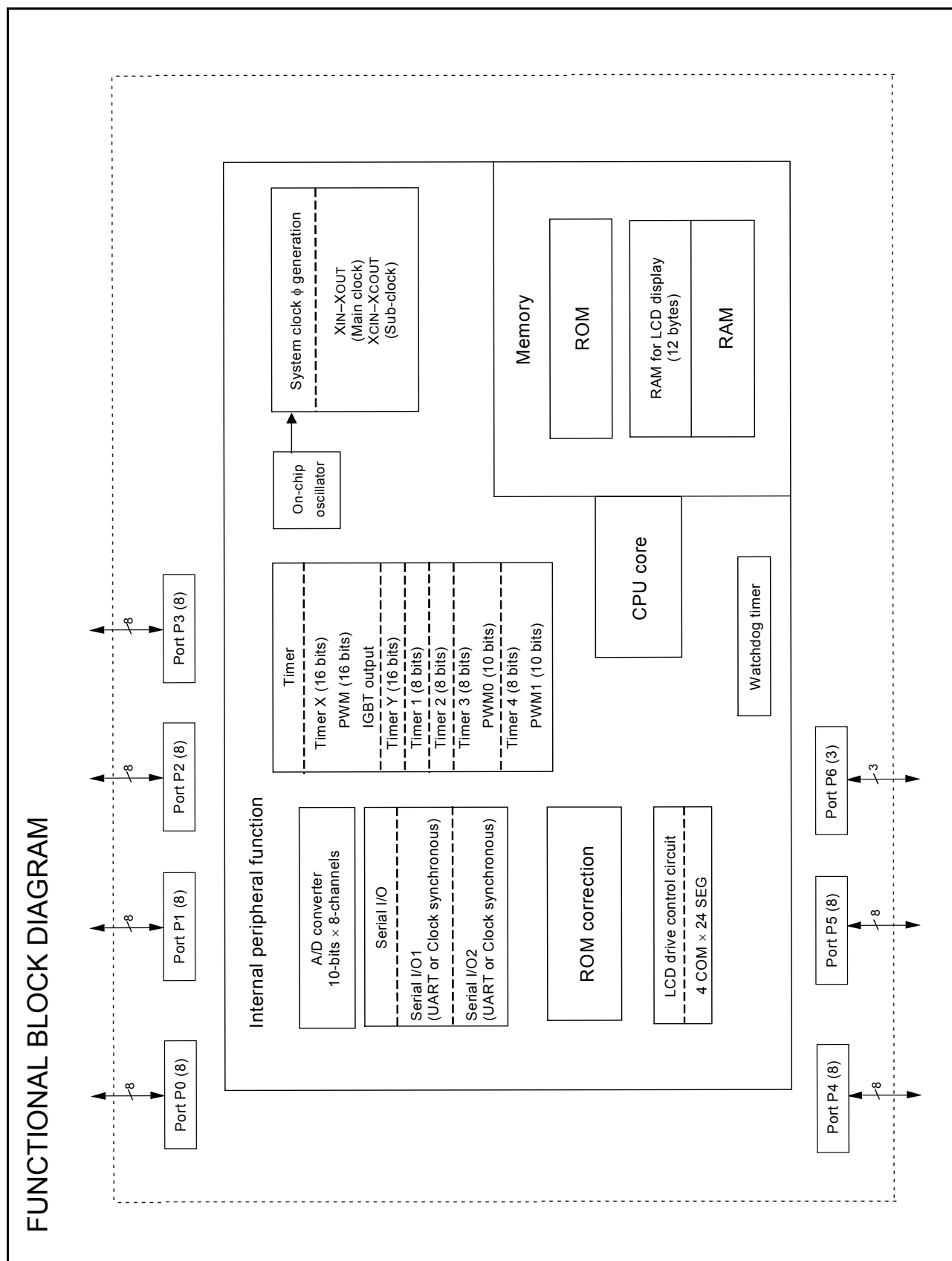


Fig. 2 Functional block diagram

PIN DESCRIPTION

Table 2 Pin description (1)

Pin	Name	Function	
			Function except a port function
VCC, VSS	Power source	• Apply 1.8 to 5.5 V to VCC, and 0 V to VSS.	
RESET	Reset input	• Reset input pin for active “L”.	
XIN	Clock input	• Input and output pins for the main clock generating circuit.	
XOUT	Clock output	• Connect a ceramic resonator or a quartz-crystal oscillator between the XIN and XOUT pins to set the oscillation frequency. When an external clock is used, connect the clock source to XIN, and leave XOUT pin open. • Feedback resistor is built in between XIN pin and Xout pin.	
VL3	LCD power source	• Input $0 \leq VL1 \leq VL2 \leq VL3$ voltage. • Input 0 – VL3 voltage to LCD.	
COM0–COM3	Common output	• LCD common output pins. • COM2 and COM3 are not used at 1/2 duty ratio. • COM3 is not used at 1/3 duty ratio.	
P00/SEG0/(KW4)–P03/SEG3/(KW7)	I/O port P0	• 8-bit I/O port. • CMOS compatible input level. • CMOS 3-state output structure. • I/O direction register allows each pin to be individually programmed as either input or output. • Pull-up control is enabled in a bit unit.	• LCD segment output pins • Key input interrupt input pins
P04/SEG4–P07/SEG7			
P10/SEG8–P17/SEG15	I/O port P1	• 8-bit I/O port. • CMOS compatible input level. • CMOS 3-state output structure. • I/O direction register allows each pin to be individually programmed as either input or output. • Pull-up control is enabled in a bit unit.	
P20/SEG16–P25/SEG21	I/O port P2	• 8-bit I/O port. • CMOS compatible input level. • CMOS 3-state output structure. • I/O direction register allows each pin to be individually programmed as either input or output. • Pull-up control is enabled in a bit unit.	• LCD power source pins
P26/SEG22/VL1 P27/SEG23/VL2			
P30/SRDY2/(LED0) P31/SCLK2/(LED1) P32/TxD2/(LED2) P33/RxD2/(LED3)	I/O port P3	• 8-bit I/O port. • CMOS compatible input level. • CMOS 3-state output structure. • I/O direction register allows each pin to be individually programmed as either input or output. • Pull-up control is enabled in 4-bit unit.	• Serial I/O2 function pins
P34/INT2/(LED4)			• External interrupt pin
P35/TXOUT1/(LED5) P36/T2OUT/CKOUT/(LED6)			• Timer X, Timer 2 output pins
P37/CNTR0/TXOUT2/(LED7)			• Timer X function pin
P40/OOUT0/AN0 P41/OOUT1/AN1	I/O port P4	• 8-bit I/O port. • CMOS compatible input level. • CMOS 3-state output structure. • I/O direction register allows each pin to be individually programmed as either input or output. • Pull-up control is enabled in 4-bit unit.	• A/D convertor input pins • Oscillation external output pins
P42/AN2/ADKEY			• ADKEY
P43/AN3–P45/AN5			• Real time port function pins
P46/RTP0/AN6 P47/RTP1/AN7			
P50/INT0 P51/INT1	I/O port P5	• 8-bit I/O port. • CMOS compatible input level. • CMOS 3-state output structure. • I/O direction register allows each pin to be individually programmed as either input or output. • Pull-up control is enabled in 4-bit unit	• External input pins
P52/T3OUT/PWM0 P53/T4OUT/PWM1			• Timer 3, Timer 4 output pins • PWM output pins
P54/RxD1/(KW0) P55/TxD1/(KW1) P56/SCLK1/(KW2) P57/SRDY1/(KW3)			• Serial I/O1 function pins • Key input interrupt input pins

Table 3 Pin description (2)

Pin	Name	Function	Function except a port function
P60/CNTR ₁	I/O port P6	• 3-bit I/O port. • CMOS compatible input level. • CMOS 3-state output structure. • I/O direction register allows each pin to be individually programmed as either input or output. • Pull-up control is enabled in 3-bit unit	• Timer Y function pins
P61/XCIN P62/XCOUT			• Sub clock generating circuit I/O pins (oscillator connected)
OSCSEL (Only QzROM version)	Oscillation start selection pin	• Whether oscillation starts by an oscillator between the X_{IN} and X_{OUT} pins or an on-chip oscillator is selected. • V_{PP} power source input pin in the QzROM writing mode.	
CNV _{SS} (Only flash memory version)	CNV _{SS}	• Pin for controlling the operating mode of the chip. Connect to V_{SS}.	
VREF	Analog reference voltage	• Reference voltage input pin for A/D converter.	
AV _{SS}	Analog power source	• Analog power source input pin for A/D converter. Connect to V_{SS}.	

PART NUMBERING

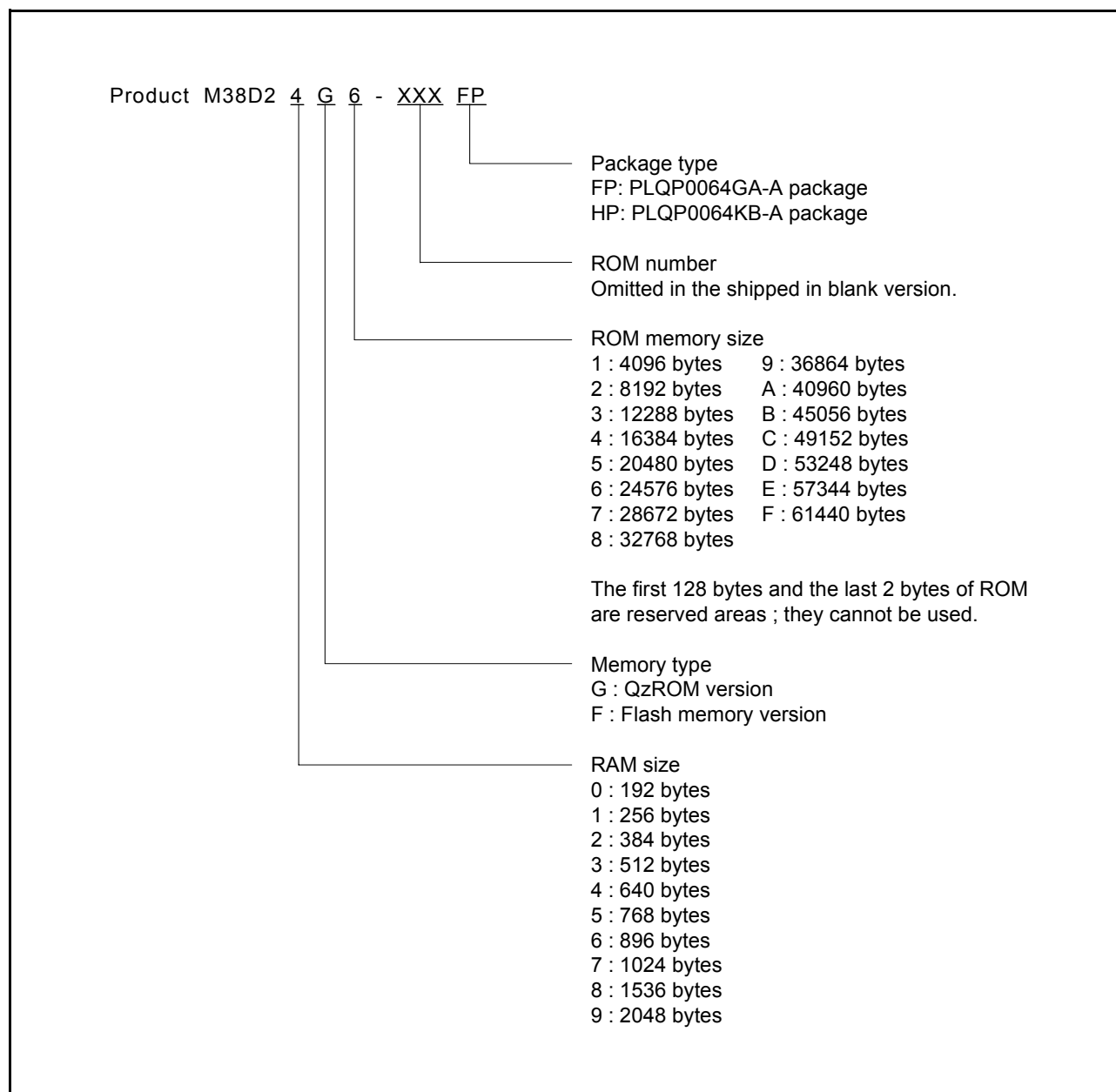


Fig. 3 Part numbering

GROUP EXPANSION

Renesas plans to expand the 38D2 Group as follows.

Memory Size

<QzROM version>

- ROM size 16 K to 60 K bytes
- RAM size 640 to 2048 bytes

<Flash memory version>

- ROM size 60 K bytes
- RAM size 2048 bytes

Packages

- PLQP0064GA-A0.8 mm-pitch plastic molded LQFP
- PLQP0064KB-A0.5 mm-pitch plastic molded LQFP

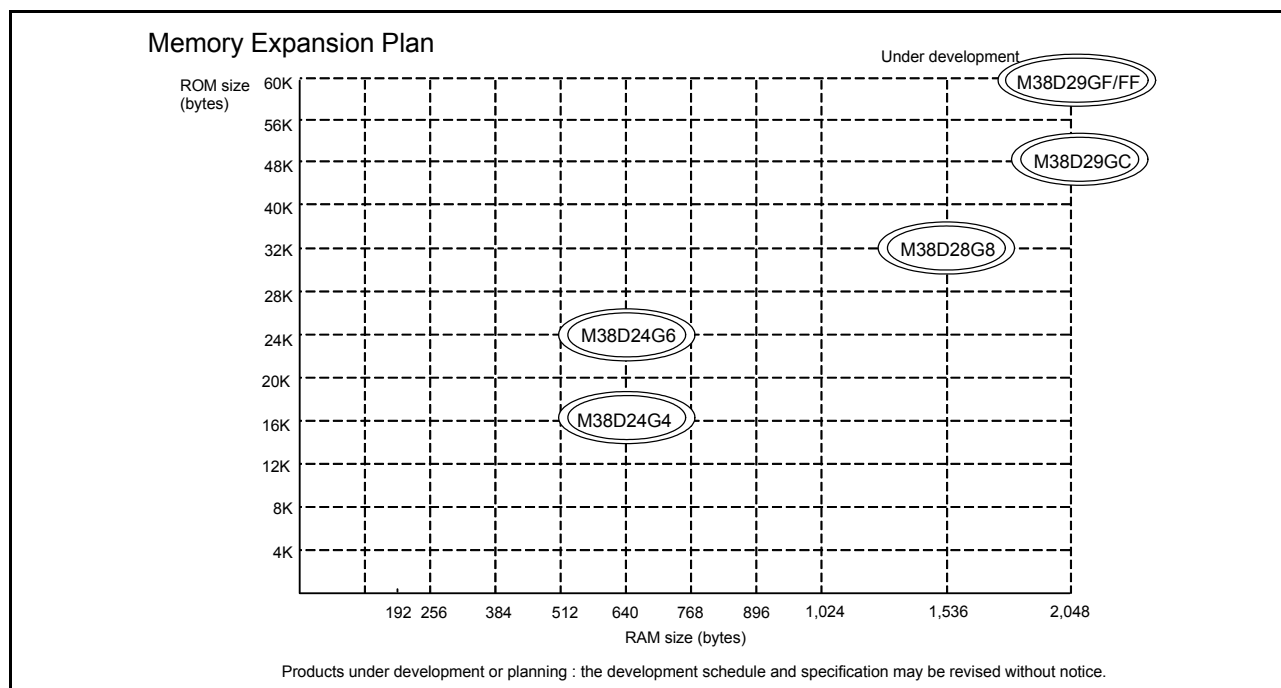


Fig. 4 Memory expansion plan

38D2 Group

Currently supported products are listed below

Table 4 Support products

As of August 2007

Part No.	ROM size (bytes) ROM size for User in ()	RAM size (bytes)	Package	Remarks
M38D29GF-XXXFP	61440 (61310)	2048	PLQP0064GA-A	
M38D29GF-XXXHP			PLQP0064KB-A	
M38D29GFFP			PLQP0064GA-A	Blank
M38D29GFHP			PLQP0064KB-A	Blank
M38D29GC-XXXFP	49152 (49022)	2048	PLQP0064GA-A	
M38D29GC-XXXHP			PLQP0064KB-A	
M38D29GCFP			PLQP0064GA-A	Blank
M38D29GCHP			PLQP0064KB-A	Blank
M38D28G8-XXXFP	32768 (32638)	1536	PLQP0064GA-A	
M38D28G8-XXXHP			PLQP0064KB-A	
M38D28G8FP			PLQP0064GA-A	Blank
M38D28G8HP			PLQP0064KB-A	Blank
M38D24G6-XXXFP	24576 (24446)	640	PLQP0064GA-A	
M38D24G6-XXXHP			PLQP0064KB-A	
M38D24G6FP			PLQP0064GA-A	Blank
M38D24G6HP			PLQP0064KB-A	Blank
M38D24G4-XXXFP	16384 (16254)	640	PLQP0064GA-A	
M38D24G4-XXXHP			PLQP0064KB-A	
M38D24G4FP			PLQP0064GA-A	Blank
M38D24G4HP			PLQP0064KB-A	Blank
M38D29FFFFP	61440	2048	PLQP0064GA-A	Flash memory version
M38D29FFHP			PLQP0064KB-A	

Table 5 Differences between QzROM and flash memory versions

	QzROM version		Flash memory version
Oscillation circuit at reset and at returning from stop mode	Main clock X _{IN} or on-chip oscillator selectable by OSCSEL pin		On-chip oscillator
Termination of OSCEL/CNV _{SS} pin	OSCSEL = "H"	OSCSEL = "L"	CNV _{SS} = "L"
Main clock oscillation at reset and at returning from stop mode	Oscillation on	Stop	Stop
On-chip oscillator oscillation at reset and at returning from stop mode	Stop	Oscillation on	Oscillation on
System clock ϕ oscillation at reset and at returning from stop mode	f(X _{IN})/8	f(OCO)/32	f(OCO)/32
Mounting of main clock oscillation circuit	Required	Optional	Optional
On-chip oscillator oscillation in low speed-mode	Stop		Stop by setting the on-chip oscillator stop bit because it is not stopped.
Writing "1" to on-chip oscillator stop bit in on-chip oscillator mode	On-chip oscillator is stopped		On-chip oscillator is not stopped
Reset input "L" pulse width	2 μ s or more		2 ms or more
Absolute maximum rating: OSCSEL/CNV _{SS} pin	-0.3 to 8.0		-0.3 to V _{CC} + 0.3
Minimum operating power source voltage	1.8 V		2.7 V
A/D converter minimum operating power source voltage	2.0 V		2.7 V

NOTE:

1. For detailed specifications, confirm the descriptions in the Datasheet.

Notes on Differences between QzROM and Flash Memory Versions

- (1) The memory map, the writing modes and programming circuits vary because of the differences in their internal memories.
- (2) The oscillation parameters of X_{IN}-X_{OUT} and X_{CIN}-X_{COUT} may vary.
- (3) The QzROM version and the flash memory version MCUs differ in their manufacturing processes, built-in ROM, and layout patterns. Because of these differences, characteristic values, operation margins, A/D conversion accuracy, noise immunity, and noise radiation may vary within the specified range of electrical characteristics.
- (4) When switching from the flash memory version to the QzROM version, implement system evaluations equivalent to those implemented in the flash memory version.
- (5) The both operations except the electrical characteristics are same at the emulator (emulator MCU board: M38D29T-RLFS).

FUNCTIONAL DESCRIPTION

Central Processing Unit (CPU)

The 38D2 Group uses the standard 740 Family instruction set. Refer to the 740 Family Software Manual for details on the instruction set.

Machine-resident 740 Family instructions are as follows:

The FST and SLW instructions cannot be used.

The STP, WIT, MUL, and DIV instructions can be used.

The central processing unit (CPU) has six registers. Figure 5 shows the 740 Family CPU register structure.

[Accumulator (A)]

The accumulator is an 8-bit register. Data operations such as arithmetic data transfer, etc., are executed mainly through the accumulator.

[Index Register X (X)]

The index register X is an 8-bit register. In the index addressing modes, the value of the OPERAND is added to the contents of register X and specifies the real address.

[Index Register Y (Y)]

The index register Y is an 8-bit register. In partial instruction, the value of the OPERAND is added to the contents of register Y and specifies the real address.

[Stack Pointer (S)]

The stack pointer is an 8-bit register used during subroutine calls and interrupts. This register indicates start address of stored area (stack) for storing registers during subroutine calls and interrupts.

The low-order 8 bits of the stack address are determined by the contents of the stack pointer. The high-order 8 bits of the stack address are determined by the stack page selection bit. If the stack page selection bit is "0", the high-order 8 bits becomes "0016". If the stack page selection bit is "1", the high-order 8 bits becomes "0116".

The operations of pushing register contents onto the stack and popping them from the stack are shown in Figure 6.

Table 6 shows the push and pop instructions of accumulator or processor status register.

Store registers other than those described in Figure 6 with program when the user needs them during interrupts or subroutine calls.

[Program Counter (PC)]

The program counter is a 16-bit counter consisting of two 8-bit registers PCH and PCL. It is used to indicate the address of the next instruction to be executed.

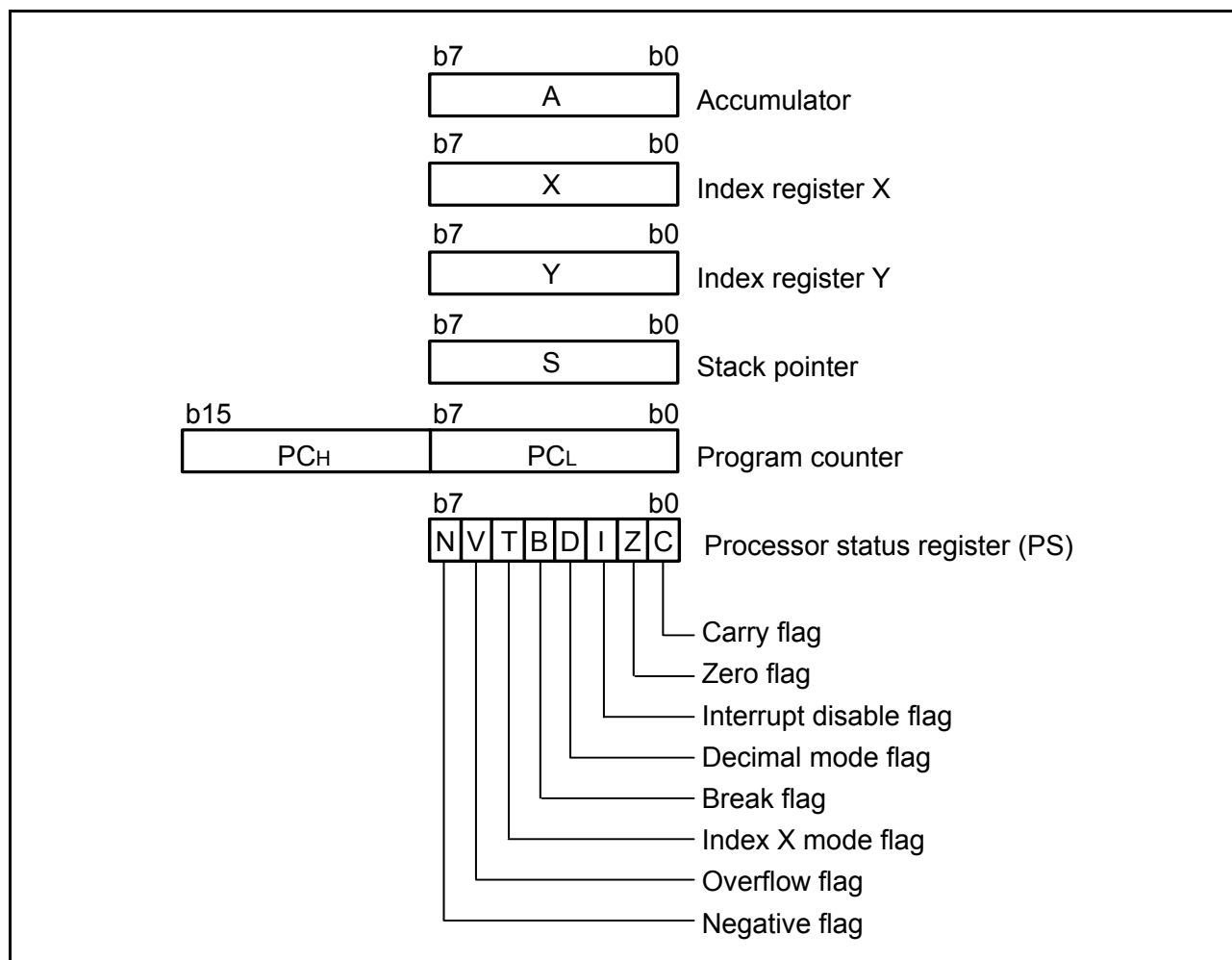


Fig. 5 740 Family CPU register structure

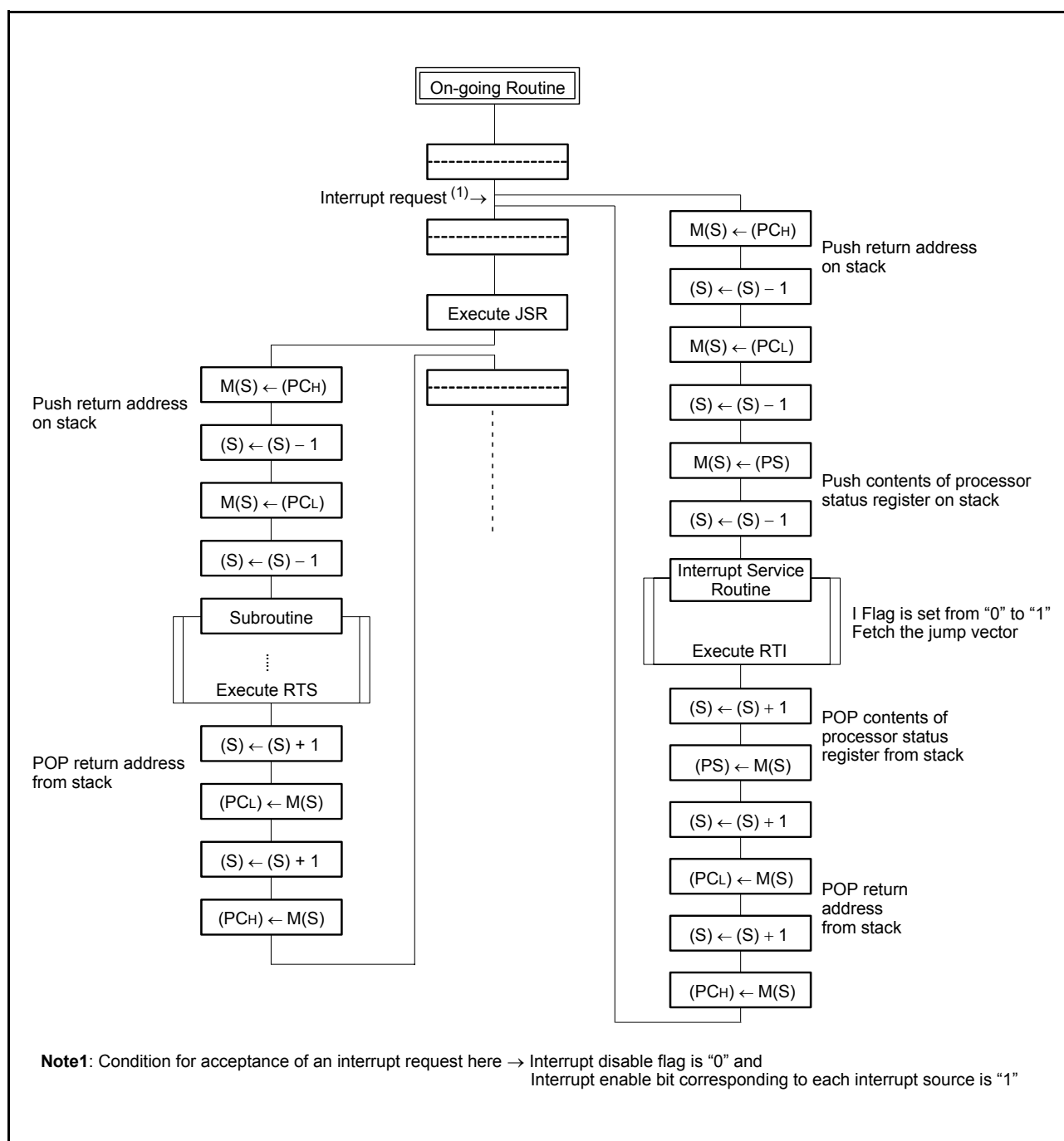


Fig. 6 Register push and pop at interrupt generation and subroutine call

Table 6 Push and pop instructions of accumulator or processor status register

	Push instruction to stack	Pop instruction from stack
Accumulator	PHA	PLA
Processor status register	PHP	PLP

[Processor Status Register (PS)]

The processor status register is an 8-bit register consisting of 5 flags which indicate the status of the processor after an arithmetic operation and 3 flags which decide MCU operation. Branch operations can be performed by testing the Carry (C) flag, Zero (Z) flag, Overflow (V) flag, or the Negative (N) flag. In decimal mode, the Z, V, N flags are not valid.

- Bit 0: Carry flag (C)

The C flag contains a carry or borrow generated by the arithmetic logic unit (ALU) immediately after an arithmetic operation. It can also be changed by a shift or rotate instruction.

- Bit 1: Zero flag (Z)

The Z flag is set to “1” if the result of an immediate arithmetic operation or a data transfer is “0”, and set to “0” if the result is anything other than “0”.

- Bit 2: Interrupt disable flag (I)

The I flag disables all interrupts except for the interrupt generated by the BRK instruction.

Interrupts are disabled when the I flag is “1”.

- Bit 3: Decimal mode flag (D)

The D flag determines whether additions and subtractions are executed in binary or decimal. Binary arithmetic is executed when this flag is “0”; decimal arithmetic is executed when it is “1”.

Decimal correction is automatic in decimal mode. Only the ADC and SBC instructions can be used for decimal arithmetic.

- Bit 4: Break flag (B)

The B flag is used to indicate that the current interrupt was generated by the BRK instruction. When the BRK instruction is generated, the B flag is set to “1” automatically. When the other interrupts are generated, the B flag is set to “0”, and the processor status register is pushed onto the stack.

- Bit 5: Index X mode flag (T)

When the T flag is “0”, arithmetic operations are performed between accumulator and memory. When the T flag is “1”, direct arithmetic operations and direct data transfers are enabled between memory locations.

- Bit 6: Overflow flag (V)

The V flag is used during the addition or subtraction of one byte of signed data. It is set if the result exceeds +127 to -128. When the BIT instruction is executed, bit 6 of the memory location operated on by the BIT instruction is stored in the overflow flag.

- Bit 7: Negative flag (N)

The N flag is set to “1” if the result of an arithmetic operation or data transfer is negative. When the BIT instruction is executed, bit 7 of the memory location operated on by the BIT instruction is stored in the negative flag.

Table 7 Set and clear instructions of each bit of processor status register

	C flag	Z flag	I flag	D flag	B flag	T flag	V flag	N flag
Set instruction	SEC	–	SEI	SED	–	SET	–	–
Clear instruction	CLC	–	CLI	CLD	–	CLT	CLV	–

[CPU Mode Register (CPUM)] 003B16

The CPU mode register contains the stack page selection bit, etc. This register is allocated at address 003B16.

After the system is released from reset, the mode depends on the OSCSEL pin state in the QzROM version.

When the OSCSEL pin state is GND level, only the on-chip oscillator starts oscillation. The XIN-XOUT oscillation stops oscillating, and XCIN and XCOOUT pins function as I/O ports. The operating mode is the on-chip oscillator mode.

When the OSCSEL pin state is Vcc level, the XIN-XOUT oscillation divided by 8 starts oscillation. The on-chip oscillator stops oscillating, and the XCIN and XCOOUT pins function as I/O ports. The operating mode is the frequency/8 mode.

In the flash memory version, only the on-chip oscillator starts oscillating. The XIN-XOUT oscillation stops oscillating, and the XCIN and XCOOUT pins function as I/O ports. The operating mode is the on-chip oscillator mode.

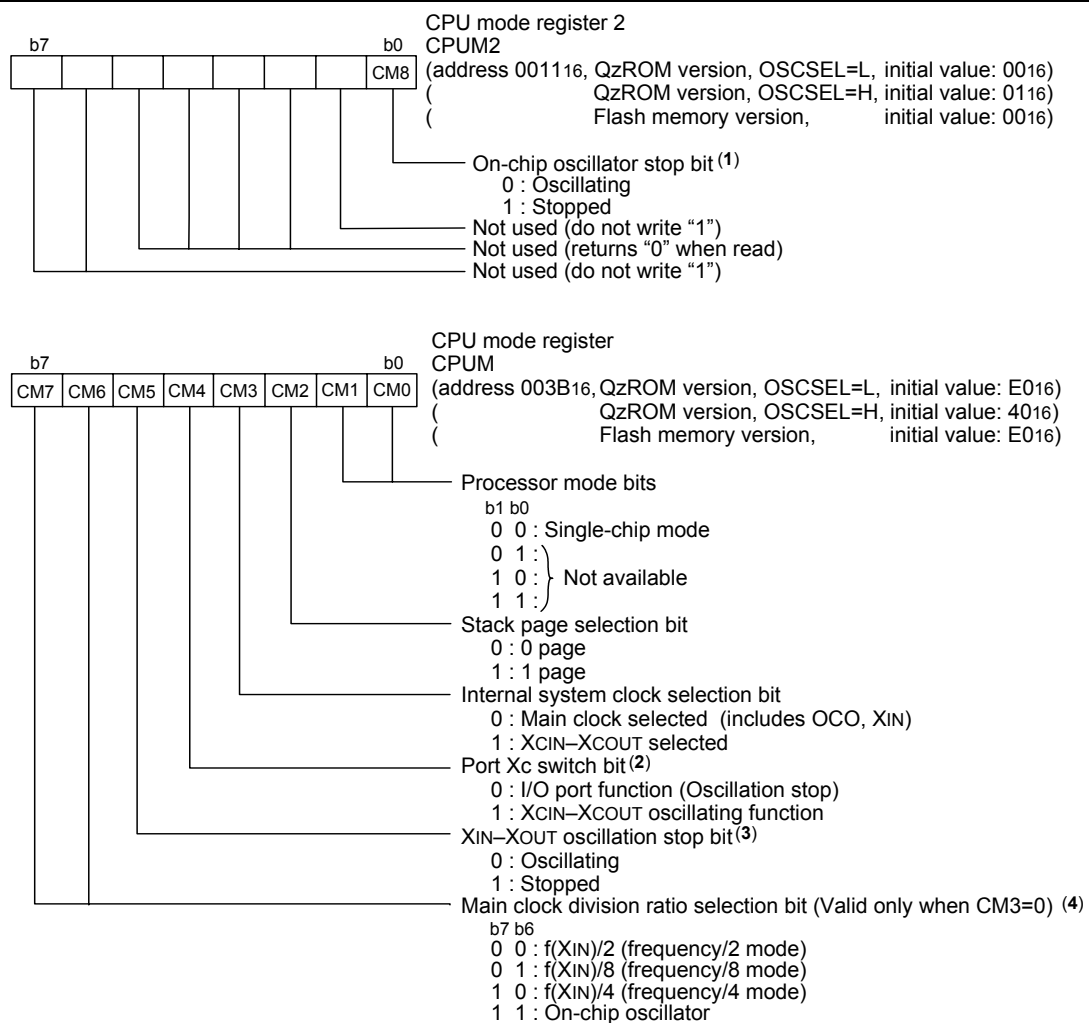
When the main clock or sub-clock is used, after the XIN-XOUT oscillation and the XCIN-XCOOUT oscillation are enabled, wait in the on-chip oscillator mode etc. until the oscillation stabilizes, and then switch the operation mode.

When the main clock is not used (XIN-XOUT oscillation and an external clock input are not used), connect the XIN pin to VCC through a resistor and leave XOUT open.

[CPU Mode Register 2 (CPUM2)] 001116

The CPU mode register 2 contains the control bits for the on-chip oscillator.

The CPU mode register 2 is allocated at address 001116.



Notes 1: When the on-chip oscillator is selected by the watchdog timer count source selection bit 2 (bit 5 of watchdog timer control register (address 002916)), the on-chip oscillator does not stop even when the on-chip oscillator stop bit is set to "1".

Also, when the low-speed mode is set, the on-chip oscillator stops regardless of the value of this bit in the QzROM version. The on-chip oscillator does not stop in the flash memory version, so set this bit to "1" to stop the oscillation.

In on-chip oscillator mode, even if this bit is set to "1", the on-chip oscillator does not stop in the flash memory version, but stops in the QzROM version.

2: In low-speed mode, the XCIN-XCOOUT oscillation stops if the port Xc switch bit is set to "0".

3: In XIN mode, the XIN-XOUT oscillation does not stop even if the XIN-XOUT oscillation stop bit is set to "1".

4: 12.5 MHz < f(XIN) ≤ 16 MHz is not available in the frequency/2 mode.

Fig. 7 Structure of CPU mode register

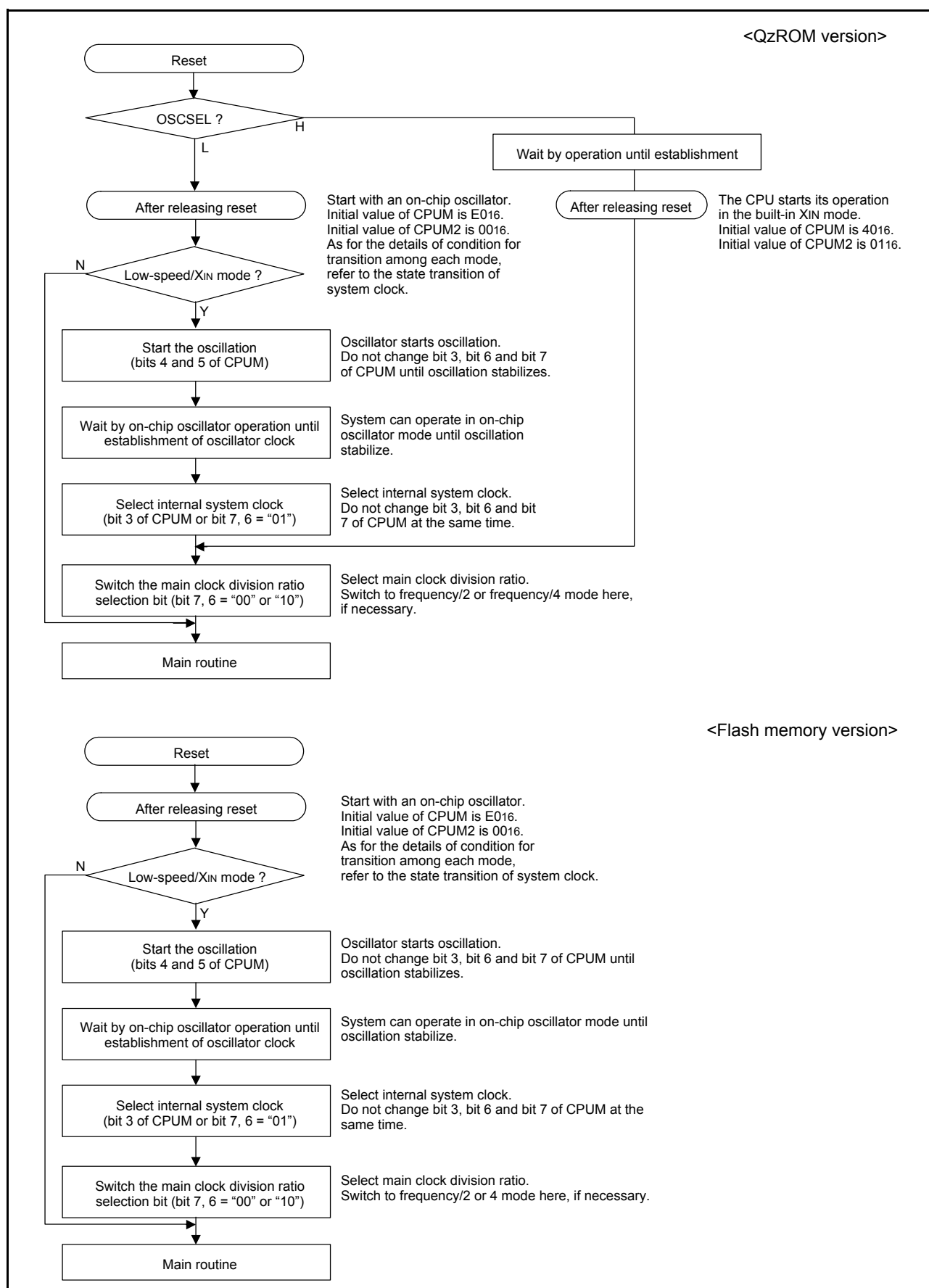


Fig. 8 Switch procedure of CPU mode register

MEMORY**• Special Function Register (SFR) Area**

The Special Function Register area in the zero page contains control registers such as I/O ports and timers.

• RAM

RAM is used for data storage and for stack area of subroutine calls and interrupts.

• ROM

In the QzROM version, the first 128 Kbytes and the last 2 bytes are reserved for device testing and the rest is the user area. Also, 1 byte of address FFDB₁₆ is reserved.

In the flash memory version, programming and erase operations can be performed to reserved ROM areas.

• Interrupt Vector Area

The interrupt vector area contains reset and interrupt vectors.

• Zero Page

Access to this area with only 2 bytes is possible in the zero page addressing mode.

• Special Page

Access to this area with only 2 bytes is possible in the special page addressing mode.

• ROM Code Protect Address in QzROM Version (Address FFDB₁₆)

Address FFDB₁₆ as reserved ROM area in the QzROM version is ROM code protect address. "00₁₆" or "FE₁₆" is written into this address when selecting the protect bit write by using a serial programmer and selecting protect enabled for writing shipment by Renesas Technology Corp. When "00₁₆" or "FE₁₆" is set to the ROM code protect address, the protect function is enabled, so that reading or writing from/to the corresponding area is disabled by a serial programmer.

As for the QzROM product in blank, the ROM code is protected by selecting the protect bit write at ROM writing with a serial programmer.

The protect can be performed, dividing twice. The protect area 1 is from the beginning address of ROM to address "EFFF₁₆".

As for the QzROM product shipped after writing, "00₁₆" (protect enabled to all area), "FE₁₆" (protect enabled to the protect area 1) or "FF₁₆" (protect disabled) is written into the ROM code protect address when Renesas Technology Corp. performs writing. The writing of "00₁₆", "FE₁₆" or "FF₁₆" can be selected as ROM option setup ("MASK option" written in the mask file converter) when ordering.

For the ROM code protect in the flash memory version, refer to the "FLASH MEMORY MODE".

<Notes>

- After a reset, the contents of RAM are undefined. Make sure to set the initial value before use.
- When Renesas ships QzROM write products, we write ROM option data* specified by the mask file converter MM to the ROM code protect address. Therefore, set FF₁₆ to the ROM code protect address in ROM data regardless of the presence or absence of a protect. When data other than FF₁₆ is set, we may ask that the ROM data be submitted again.

* ROM option data: mask option noted in MM

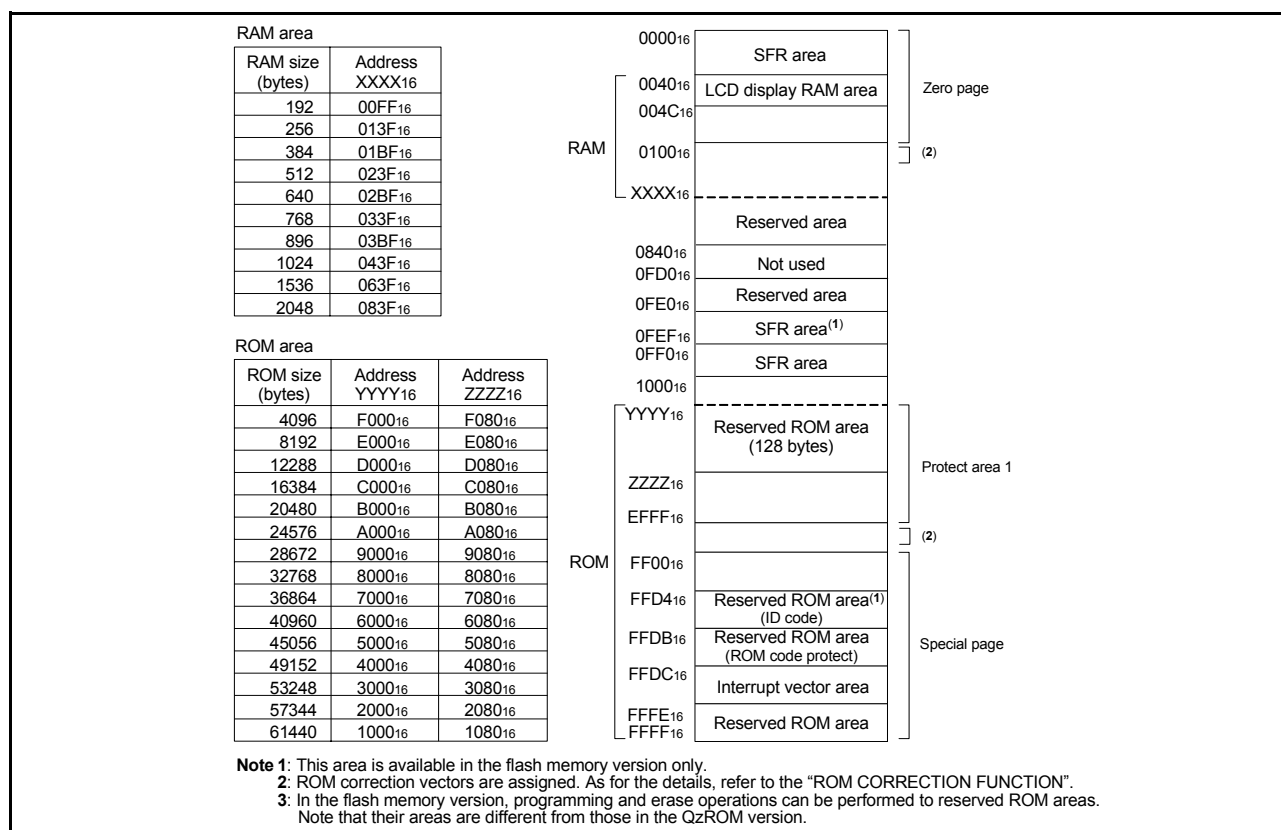


Fig. 9 Memory map diagram

0000 ₁₆	Port P0 (P0)	0020 ₁₆	Timer 1 (T1)
0001 ₁₆	Port P0 direction register (P0D)	0021 ₁₆	Timer 2 (T2)
0002 ₁₆	Port P1 (P1)	0022 ₁₆	Timer 3 (T3)
0003 ₁₆	Port P1 direction register (P1D)	0023 ₁₆	Timer 4 (T4)
0004 ₁₆	Port P2 (P2)	0024 ₁₆	PWM01 register (PWM01)
0005 ₁₆	Port P2 direction register (P2D)	0025 ₁₆	Timer 12 mode register (T12M)
0006 ₁₆	Port P3 (P3)	0026 ₁₆	Timer 34 mode register (T34M)
0007 ₁₆	Port P3 direction register (P3D)	0027 ₁₆	Timer 1234 mode register (T1234M)
0008 ₁₆	Port P4 (P4)	0028 ₁₆	Timer 1234 frequency division selection register (PRE1234)
0009 ₁₆	Port P4 direction register (P4D)	0029 ₁₆	Watchdog timer control register (WDTCON)
000A ₁₆	Port P5 (P5)	002A ₁₆	Timer X (low-order) (TXL)
000B ₁₆	Port P5 direction register (P5D)	002B ₁₆	Timer X (high-order) (TXH)
000C ₁₆	Port P6 (P6)	002C ₁₆	Timer X (extension) (TXEX)
000D ₁₆	Port P6 direction register (P6D)	002D ₁₆	Timer X mode register (TXM)
000E ₁₆		002E ₁₆	Timer X control register 1 (TXCON1)
000F ₁₆		002F ₁₆	Timer X control register 2 (TXCON2)
0010 ₁₆	Oscillation output control register (OSCON)	0030 ₁₆	Compare register 1 (low-order) (COMP1L)
0011 ₁₆	CPU mode register 2 (CPUM2)	0031 ₁₆	Compare register 1 (high-order) (COMP1H)
0012 ₁₆	RRF register (RRFR)	0032 ₁₆	Compare register 2 (low-order) (COMP2L)
0013 ₁₆	LCD mode register (LM)	0033 ₁₆	Compare register 2 (high-order) (COMP2H)
0014 ₁₆	LCD power control register (VLCON)	0034 ₁₆	Compare register 3 (low-order) (COMP3L)
0015 ₁₆	AD control register (ADCON)	0035 ₁₆	Compare register 3 (high-order) (COMP3H)
0016 ₁₆	AD conversion register (low-order) (ADL)	0036 ₁₆	Timer Y (low-order) (TYL)
0017 ₁₆	AD conversion register (high-order) (ADH)	0037 ₁₆	Timer Y (high-order) (TYH)
0018 ₁₆	Transmit/receive buffer register 1 (TB1/RB1)	0038 ₁₆	Timer Y mode register (TYM)
0019 ₁₆	Serial I/O1 status register (SIO1STS)	0039 ₁₆	Timer Y control register (TYCON)
001A ₁₆	Serial I/O1 control register (SIO1CON)	003A ₁₆	Interrupt edge selection register (INTEDGE)
001B ₁₆	UART1 control register (UART1CON)	003B ₁₆	CPU mode register (CPUM)
001C ₁₆	Baud rate generator 1 (BRG1)	003C ₁₆	Interrupt request register 1 (IREQ1)
001D ₁₆	Transmit/receive buffer register 2 (TB2/RB2)	003D ₁₆	Interrupt request register 2 (IREQ2)
001E ₁₆	Serial I/O2 status register (SIO2STS)	003E ₁₆	Interrupt control register 1 (ICON1)
001F ₁₆	Serial I/O2 control register (SIO2CON)	003F ₁₆	Interrupt control register 2 (ICON2)
0FE0 ₁₆	Flash memory control register 0 (FMCR0)	0FF0 ₁₆	PULL register (PULL)
0FE1 ₁₆	Flash memory control register 1 (FMCR1)	0FF1 ₁₆	UART2 control register (UART2CON)
0FE2 ₁₆	Flash memory control register 2 (FMCR2)	0FF2 ₁₆	Baud rate generator 2 (BRG2)
0FE3 ₁₆	Reserved ⁽¹⁾	0FF3 ₁₆	Clock output control register (CKOUT)
0FE4 ₁₆	Reserved ⁽¹⁾	0FF4 ₁₆	Segment output disable register 0 (SEG0)
0FE5 ₁₆	Reserved ⁽¹⁾	0FF5 ₁₆	Segment output disable register 1 (SEG1)
0FE6 ₁₆	Reserved ⁽¹⁾	0FF6 ₁₆	Segment output disable register 2 (SEG2)
0FE7 ₁₆	Reserved ⁽¹⁾	0FF7 ₁₆	Key input control register (KIC)
0FE8 ₁₆	Reserved ⁽¹⁾	0FF8 ₁₆	ROM correction address 1 high-order register (RCA1H)
0FE9 ₁₆	Reserved ⁽¹⁾	0FF9 ₁₆	ROM correction address 1 low-order register (RCA1L)
0FEA ₁₆	Reserved ⁽¹⁾	0FFA ₁₆	ROM correction address 2 high-order register (RCA2H)
0FEB ₁₆	Reserved ⁽¹⁾	0FFB ₁₆	ROM correction address 2 low-order register (RCA2L)
0FEC ₁₆	Reserved ⁽¹⁾	0FFC ₁₆	ROM correction enable register (RCR)
0FED ₁₆	Reserved ⁽¹⁾	0FFD ₁₆	Reserved ⁽¹⁾
0FEE ₁₆	Reserved ⁽¹⁾	0FFE ₁₆	Reserved ⁽¹⁾
0FEF ₁₆	Reserved ⁽¹⁾	0FFF ₁₆	Reserved ⁽¹⁾

Note 1: The blanks are reserved. Do not write data to these areas.
2: No memory access is allowed to the blank areas within the SFRs.
3: Addresses 0FE0₁₆ to 0FEF₁₆ are available in the flash memory version only.

Fig. 10 Memory map of special function register (SFR)

I/O PORTS

• Direction Registers

The I/O ports P0–P6 have direction registers which determine the input/output direction of each individual pin. Each bit in a direction register corresponds to one pin, each pin can be set to be input port or output port.

When “0” is written to the bit of the direction register, the corresponding pin becomes an input pin. As for ports P0–P2, when “1” is written to the bit of the direction register and the segment output disable register, the corresponding pin becomes an output pin. As for ports P3–P6, when “1” is written to the bit of the direction register, the corresponding pin becomes an output pin.

If data is read from a pin set to output, the value of the port latch is read, not the value of the pin itself. However, when peripheral output (RTP1, RTP0, TXOUT1, T4OUT, T3OUT, T2OUT/CKOUT, OOUT0, and OOUT1) is selected, the output value is read. Pins set to input are floating. If a pin set to input is written to, only the port output latch is written to and the pin remains floating.

• Pull-up Control

Each individual bit of ports P0–P2 can be pulled up with a program by setting direction registers and segment output disable registers 0 to 2 (addresses 0FF416 to 0FF616).

The pin is pulled up by setting “0” to the direction register and “1” to the segment output disable register.

By setting the PULL register (addresses 0FF016), ports P3–P6 can control pull-up with a program.

However, the contents of PULL register do not affect ports programmed as the output ports.

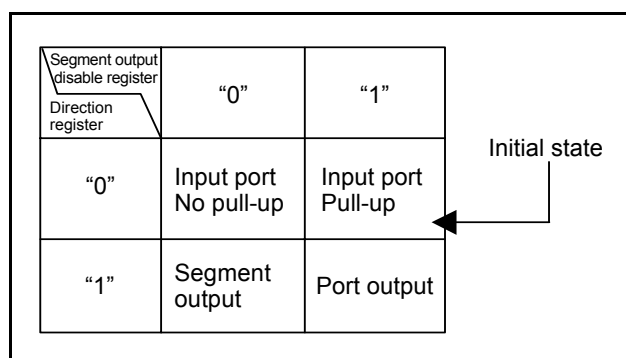


Fig. 11 Structure of ports P0 to P2

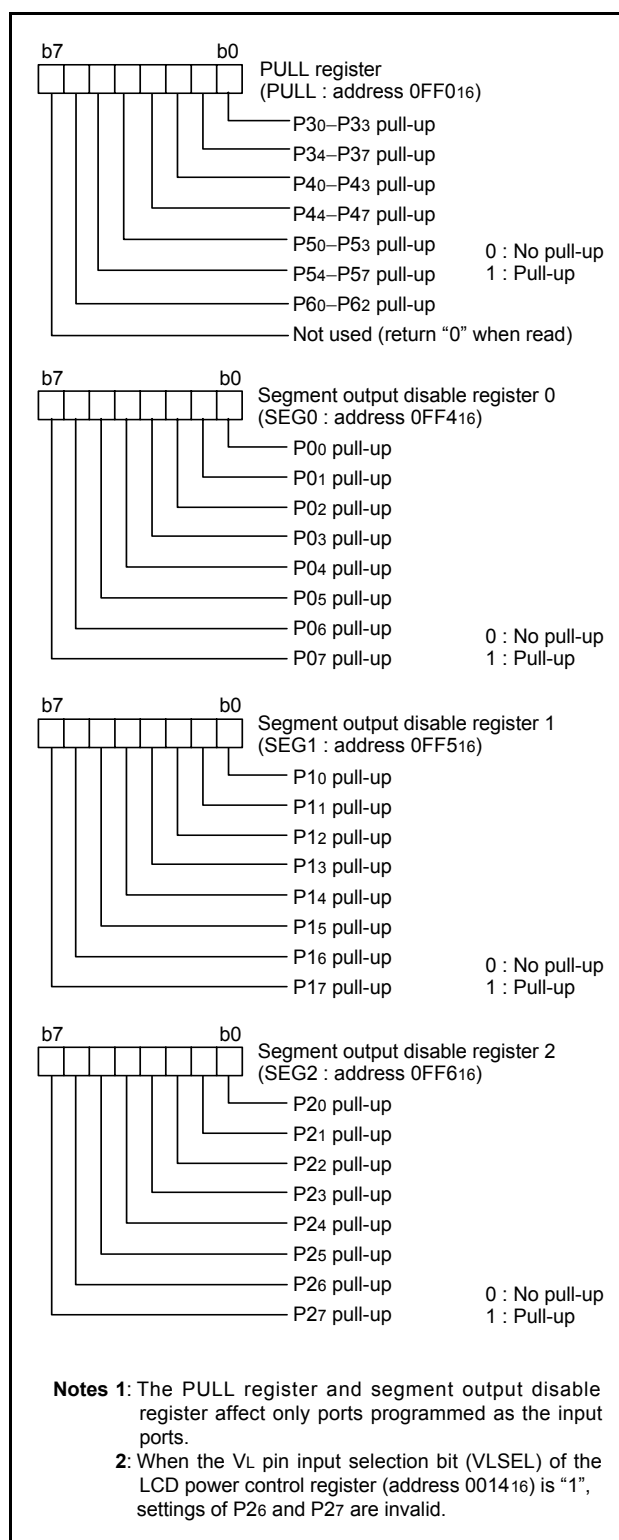


Fig. 12 Structure of PULL register and segment output disable register

Table 8 List of I/O port function

Pin	Name	Input/Output	I/O format	Non-port function		Related SFRs	Ref. No.
P00/SEG0/(KW4)– P03/SEG3/(KW7)	Port P0	Input/Output, individual bits	CMOS compatible input level CMOS 3-state output	LCD segment output	Key input (key-on wakeup) interrupt input	Segment output disable register 0	(1)
P04/SEG4– P07/SEG7							(2)
P10/SEG8– P17/SEG15	Port P1	Input/Output, individual bits	CMOS compatible input level CMOS 3-state output		Segment output disable register 1		
P20/SEG16– P25/SEG21	Port P2	Input/Output, individual bits	CMOS compatible input level CMOS 3-state output		LCD power input	Segment output disable register 2	
P26/SEG22/VL1 P27/SEG23/VL2							
P30/ŚRDY2/(LED0) P31/SCLK2/(LED1) P32/TxD2/(LED2) P33/RxD2/(LED3)	Port P3	Input/Output, individual bits	CMOS compatible input level CMOS 3-state output	Serial I/O2 function I/O		PULL register Serial I/O2 control register Serial I/O2 status register UART2 control register	(3) (4) (5) (6)
P34/INT2/(LED4)				External interrupt input		PULL register Interrupt edge selection register	(7)
P35/TXOUT1/(LED5) P36/T2OUT/CKOUT /(LED6)				Timer X output 1 Timer 2 output	Clock output	PULL register Timer X mode register Timer 12 mode register Clock output control register	(8) (9)
				Timer X function input Timer X output 2		PULL register Timer X mode register	(10)
P40/OOUT0/AN0 P41/OOUT1/AN1				Port P4	Input/Output, individual bits	CMOS compatible input level CMOS 3-state output	
P42/AN2/ADKEY	A/D conversion input		PULL register AD control register				
P43/AN3–P45/AN5		Real time port function output	PULL register AD control register Timer Y mode register				(13)
P46/RTP0/AN6 P47/RTP1/AN7							
P50/INT0 P51/INT1	Port P5	Input/Output, individual bits	CMOS compatible input level CMOS 3-state output	External interrupt input		PULL register Interrupt edge selection register	(7)
P52/T3OUT/PWM0 P53/T4OUT/PWM1				Timer 3 output Timer 4 output PWM output		PULL register Timer 34 mode register	(9)
P54/RxD1/(KW0) P55/TxD1/(KW1) P56/SCLK1/(KW2) P57/ŚRDY1/(KW3)				Serial I/O1 function I/O	Key input (key-on wakeup) interrupt input	PULL register Serial I/O1 control register Serial I/O1 status register UART1 control register	(14) (15) (16) (17)
P60/CNTR1	Port P6	Input/Output, individual bits	CMOS compatible input level CMOS 3-state output	Timer Y function input		PULL register Timer Y mode register	(7)
P61/XCIN				Sub-clock oscillation circuit		PULL register CPU mode register	(18) (19)
P62/XCOUT							
COM0 –COM3	Common	Output	LCD common output			LCD mode register	(20)

Notes 1: For details of how to use double/triple function ports as function I/O ports, refer to the applicable sections.

2: Make sure that the input level at each pin is either 0 V or V_{CC} during execution of the STP instruction.

When an input level is at an intermediate potential, a current will flow from V_{CC} to V_{SS} through the input-stage gate.

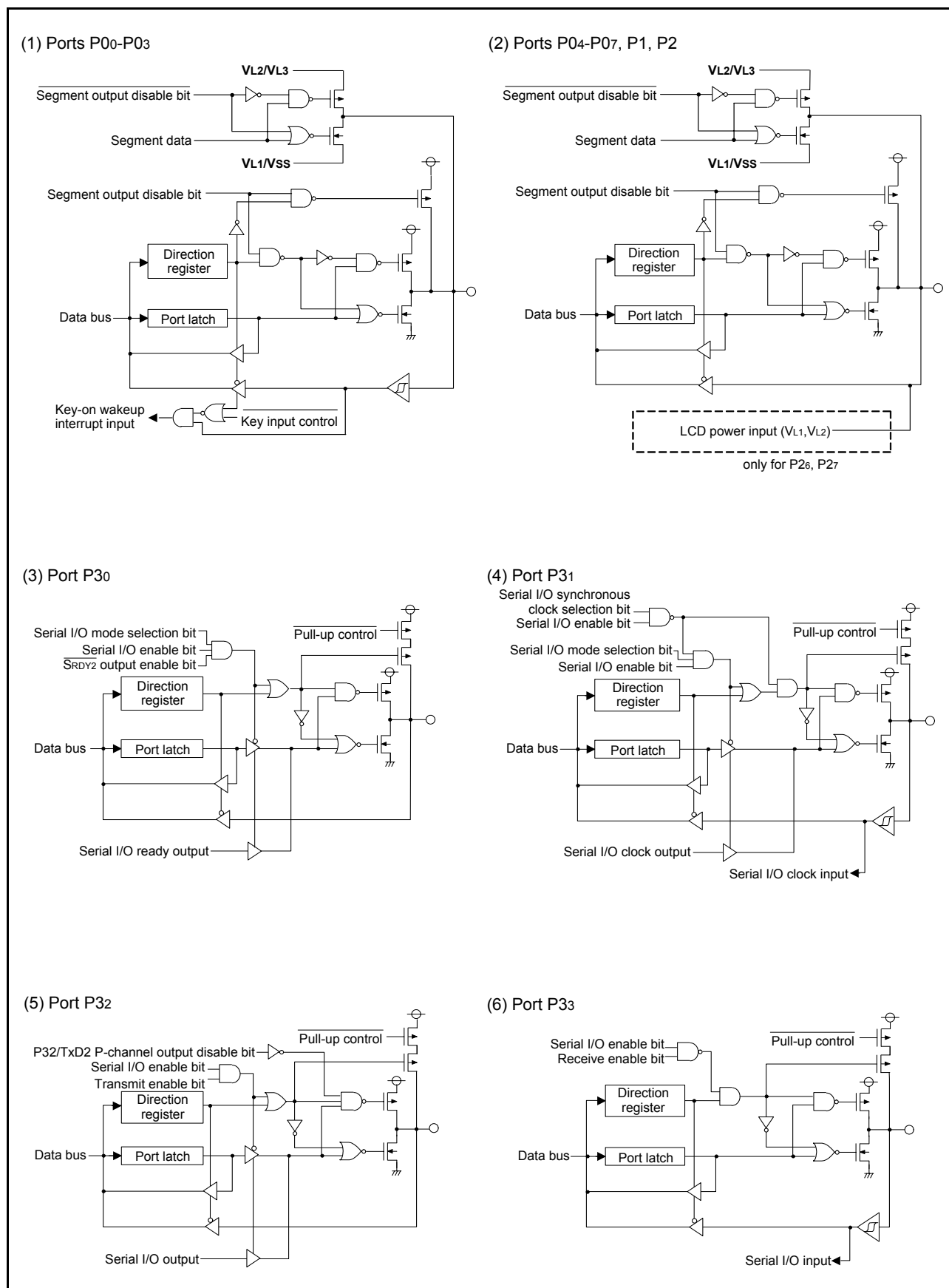


Fig. 13 Port block diagram (1)

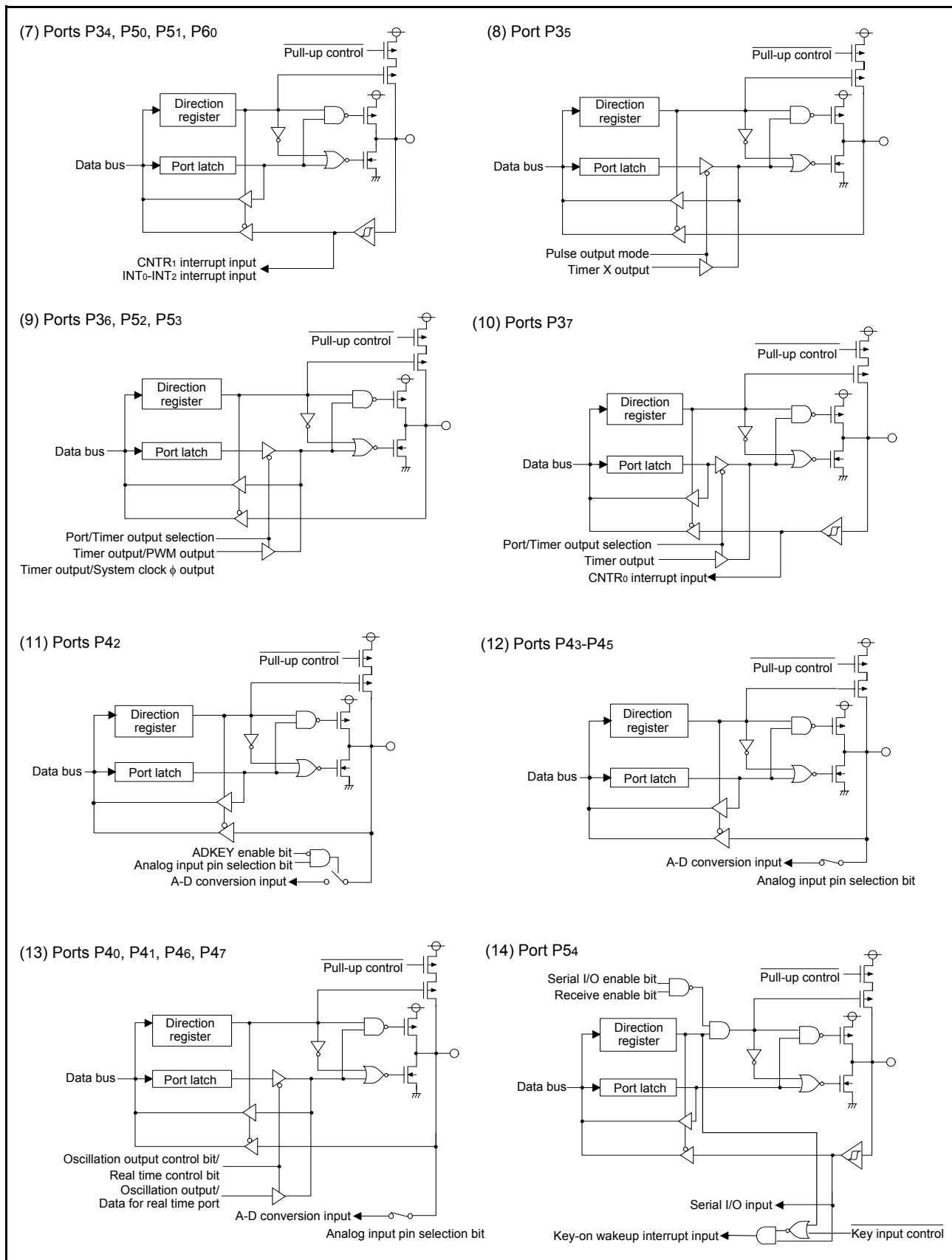


Fig. 14 Port block diagram (2)

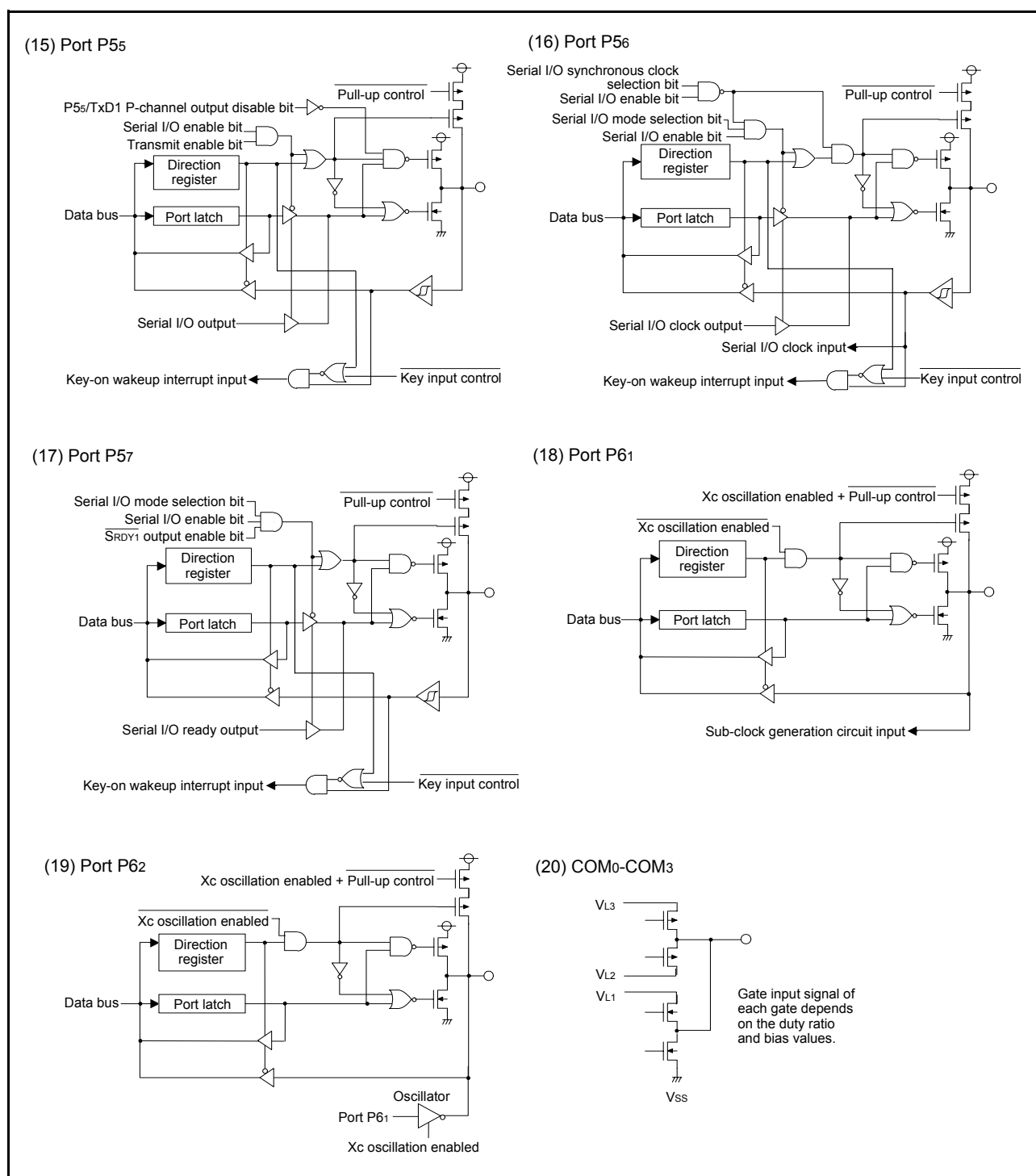


Fig. 15 Port block diagram (3)

• Termination of unused pins

• Termination of common pins

I/O ports: Select an input port or an output port and follow each processing method.

In addition, it is recommended that related registers be overwritten periodically to prevent malfunctions, etc.

Output ports: Open.

Input ports: If the input level become unstable, through current flow to an input circuit, and the power supply current may increase.

Especially, when expecting low consumption current (at STP or WIT instruction execution etc.), pull-up or pull-down input ports to prevent through current (built-in resistor can be used).

We recommend processing unused pins through a resistor which can secure $I_{OH(ave)}$ or $I_{OL(ave)}$.

Because, when an I/O port or a pin which have an output function is selected as an input port, it may operate as an output port by incorrect operation etc.

Table 9 Termination of unused pins

Pin	Termination 1	Termination 2	Termination 3
P00/SEG0/(KW4)–P07/SEG7	I/O port	When selecting SEG output, open.	–
P10/SEG8–P17/SEG15			
P20/SEG16–P27/SEG23/VL2			
P30/ $\overline{SRDY}2$ /(LED0), P57/ $\overline{SRDY}1$ /(KW3)		When selecting $\overline{SRDY}$ function, perform termination of output port.	–
P31/SCLK2/(LED1), P56/SCLK1/(KW2)		When selecting external clock input, perform termination of input port.	When selecting internal clock output, perform termination of output port.
P32/TxD2/(LED2), P55/TxD1/(KW1)		When selecting TxD function, perform termination of output port.	–
P33/RxD2/(LED3), P54/RxD1/(KW0)		When selecting RxD function, perform termination of input port.	–
P34/INT2/(LED4)		When selecting INT function, perform termination of input port.	–
P35/TXOUT1/(LED5)		When selecting TXOUT function, perform termination of output port.	–
P36/T2OUT/CKOUT/(LED6)		When selecting T2OUT function or CKOUT function, perform termination of output port.	–
P37/CNTR0/TXOUT2/(LED7)		When selecting TXOUT function, perform termination of output port.	–
P40/OOUT0/AN0, P41/OOUT1/AN1		When selecting AN function, these pins can be opened. (A/D conversion result cannot be guaranteed.)	When selecting oscillation output, perform termination of output port.
P42/AN2/ADKEY			When selecting ADKEY function, pull-up this pin through a resistor.
P43/AN3–P47/RTP1/AN7			–
P50/INT0, P51/INT1		When selecting INT function, perform termination of input port.	–
P52/T3OUT/PWM0, P53/T4OUT/PWM1		When selecting PWM, T3OUT, or T4OUT function, perform termination of output port.	–
P60/CNTR1		When selecting CNTR input function, perform termination of input port.	–
P61/XCIN, P62/XCOUT		Do not select XCIN-XCOUT oscillation function by program.	–
VL3	Set the VL3 connect bit to "1" and apply a Vcc level voltage to VL3 pin.	Set the VL3 connect bit to "0" and leave the VL3 pin open.	–
COM0–COM3	Open	–	–
AVss	Connect to Vss	–	–
VREF	Connect to Vcc	–	–
XIN	When only on-chip oscillator is used, connect to Vcc through a resistor.	–	–
XOUT	When external clock is input or when only on-chip oscillator is used, open.	–	–

INTERRUPTS

The 38D2 Group interrupts are vector interrupts with a fixed priority scheme, and generated by 16 sources among 18 sources: 6 external, 11 internal, and 1 software.

The interrupt sources, vector addresses⁽¹⁾, and interrupt priority are shown in Table 10.

Each interrupt except the BRK instruction interrupt has the interrupt request bit and the interrupt enable bit. These bits and the interrupt disable flag (I flag) control the acceptance of interrupt requests. Figure 16 shows an interrupt control diagram.

An interrupt requests is accepted when all of the following conditions are satisfied:

- Interrupt disable flag “0”
- Interrupt request bit “1”
- Interrupt enable bit “1”

Though the interrupt priority is determined by hardware, priority processing can be performed by software using the above bits and flag.

Table 10 Interrupt vector addresses and priority

Interrupt Source	Priority	Vector Addresses ⁽¹⁾		Interrupt Request Generating Conditions	Remarks
		High	Low		
Reset ⁽²⁾	1	FFFD ₁₆	FFFC ₁₆	At reset	Non-maskable
INT ₀	2	FFFB ₁₆	FFFA ₁₆	At detection of either rising or falling edge of INT ₀ input	External interrupt (active edge selectable)
INT ₁	3	FFF9 ₁₆	FFF8 ₁₆	At detection of either rising or falling edge of INT ₁ input	External interrupt (active edge selectable)
INT ₂	4	FFF7 ₁₆	FFF6 ₁₆	At detection of either rising or falling edge of INT ₂ input	Valid when INT ₂ interrupt is selected External interrupt (active edge selectable)
Key input (key-on wakeup)				At falling of ports P0 ₀ –P0 ₃ , P5 ₄ –P5 ₇ input logical level AND	Valid when key input interrupt is selected External interrupt (falling valid)
CNTR ₀	5	FFF5 ₁₆	FFF4 ₁₆	At detection of either rising or falling edge of CNTR ₀ input	External interrupt (active edge selectable)
Timer X	6	FFF3 ₁₆	FFF2 ₁₆	At timer X underflow	
Timer 1	7	FFF1 ₁₆	FFF0 ₁₆	At timer 1 underflow	Valid when timer 1 interrupt is selected
Timer 2	8	FFEF ₁₆	FFEE ₁₆	At timer 2 underflow	Valid when timer 2 interrupt is selected
Timer 3	9	FFED ₁₆	FFEC ₁₆	At timer 3 underflow	Valid when timer 3 interrupt is selected
Timer 4	10	FFEB ₁₆	FFEA ₁₆	At timer 4 underflow	Valid when timer 4 interrupt is selected
Serial I/O1 receive	11	FFE9 ₁₆	FFE8 ₁₆	At completion of serial I/O1 data receive	Valid only when serial I/O1 is selected
Serial I/O1 transmit	12	FFE7 ₁₆	FFE6 ₁₆	At completion of serial I/O1 transmit shift or transmit buffer is empty	Valid only when serial I/O1 is selected
Serial I/O2 receive	13	FFE5 ₁₆	FFE4 ₁₆	At completion of serial I/O2 data receive	Valid only when serial I/O2 is selected
Serial I/O2 transmit	14	FFE3 ₁₆	FFE2 ₁₆	At completion of serial I/O2 data transmit shift or transmit buffer is empty	Valid only when serial I/O2 is selected
Timer Y	15	FFE1 ₁₆	FFE0 ₁₆	At timer Y underflow	
CNTR ₁				At detection of either rising or falling edge of CNTR ₁ input	External interrupt (active edge selectable)
A/D conversion	16	FFDF ₁₆	FFDE ₁₆	At completion of A/D conversion	Valid when A/D interrupt is selected
BRK instruction	17	FFDD ₁₆	FFDC ₁₆	At BRK instruction execution	Non-maskable software interrupt

Notes 1: Vector addresses contain interrupt jump destination addresses.

2: Reset function in the same way as an interrupt with the highest priority.

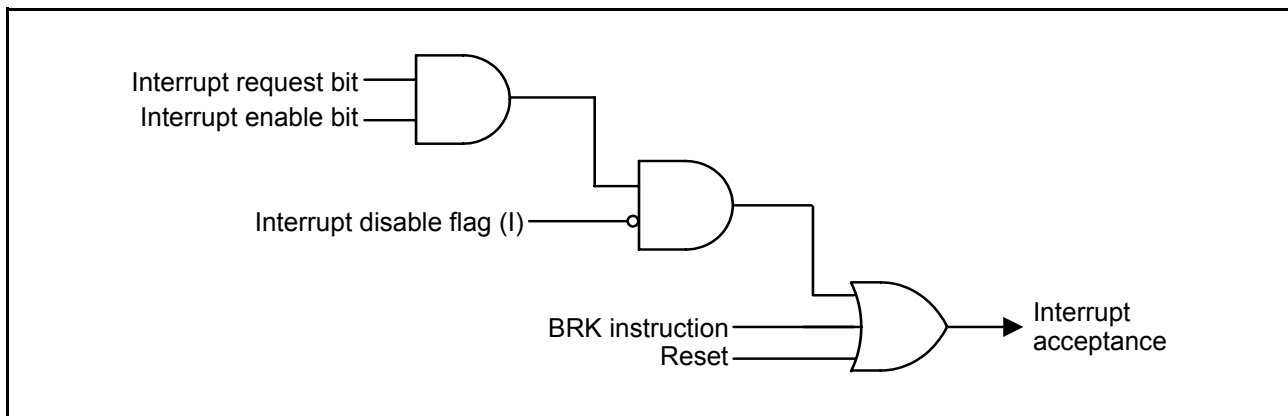


Fig. 16 Interrupt control

• Interrupt Disable Flag

The interrupt disable flag is assigned to bit 2 of the processor status register. This flag controls the acceptance of all interrupt requests except for the BRK instruction. When this flag is set to “1”, the acceptance of interrupt requests is disabled. When it is set to “0”, acceptance of interrupt requests is enabled. This flag is set to “1” with the SEI instruction and set to “0” with the CLI instruction.

When an interrupt request is accepted, the contents of the processor status register are pushed onto the stack while the interrupt disable flag remains set to “0”. Subsequently, this flag is automatically set to “1” and multiple interrupts are disabled.

To use multiple interrupts, set this flag to “0” with the CLI instruction within the interrupt processing routine.

The contents of the processor status register are popped off the stack with the RTI instruction.

• Interrupt Request Bits

Once an interrupt request is generated, the corresponding interrupt request bit is set to “1” and remains “1” until the request is accepted. When the request is accepted, this bit is automatically set to “0”.

Each interrupt request bit can be set to “0”, but cannot be set to “1”, by software.

• Interrupt Enable Bits

The interrupt enable bits control the acceptance of the corresponding interrupt requests. When an interrupt enable bit is set to “0”, the acceptance of the corresponding interrupt request is disabled. If an interrupt request occurs in this condition, the corresponding interrupt request bit is set to “1”, but the interrupt request is not accepted. When an interrupt enable bit is set to “1”, acceptance of the corresponding interrupt request is enabled.

Each interrupt enable bit can be set to “0” or “1” by software.

The interrupt enable bit for an unused interrupt should be set to “0”.

• Interrupt Source Selection

Any of the following combinations can be selected by the interrupt edge selection register (003A16).

- INT2 or key input
- Timer Y or CNTR1

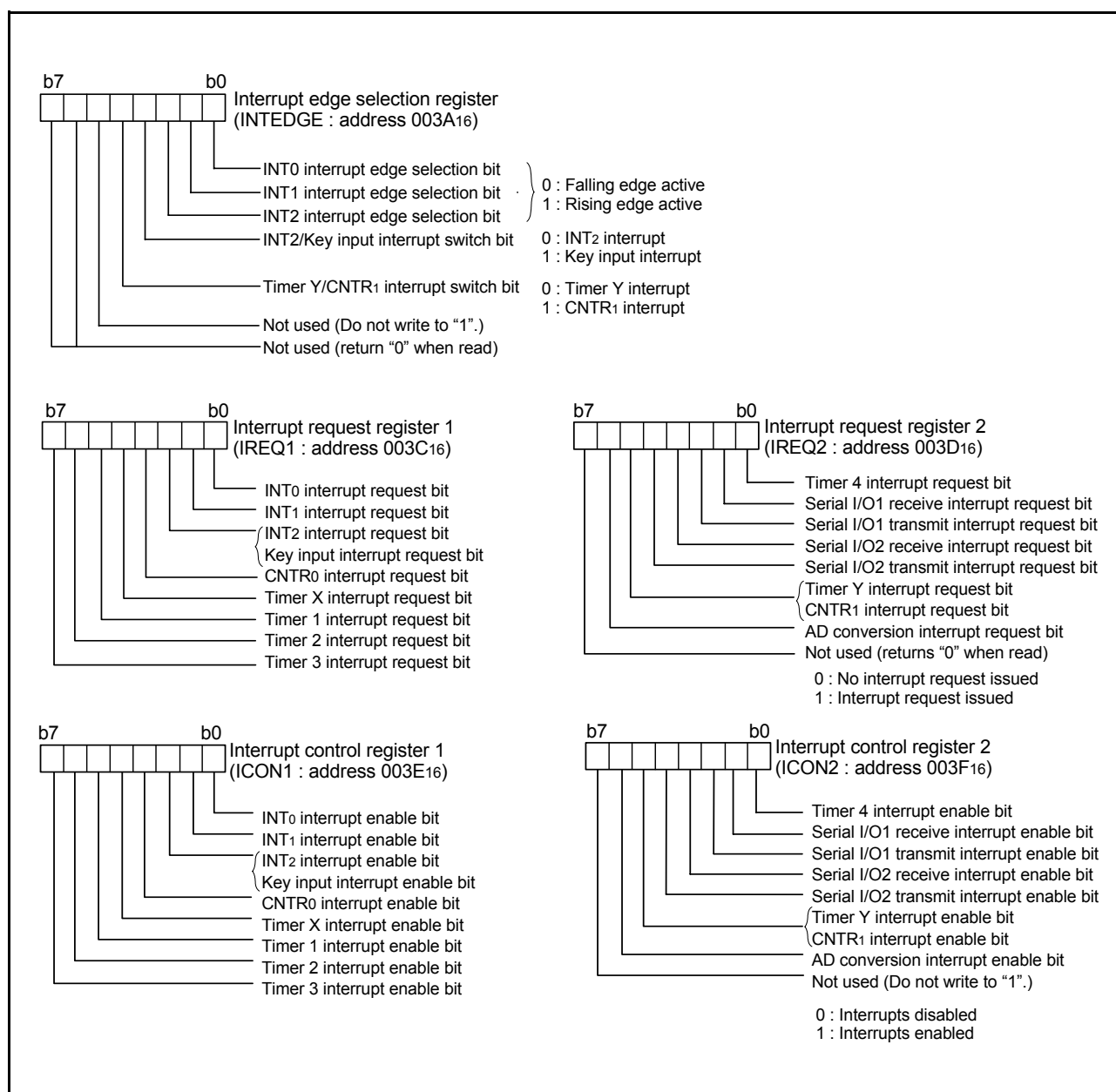


Fig. 17 Structure of interrupt-related registers

• Interrupt Request Generation, Acceptance, and Handling

Interrupts have the following three phases.

- (i) **Interrupt Request Generation**
An interrupt request is generated by an interrupt source (external interrupt signal input, timer underflow, etc.) and the corresponding request bit is set to "1".
- (ii) **Interrupt Request Acceptance**
Based on the interrupt acceptance timing in each instruction cycle, the interrupt control circuit determines acceptance conditions (interrupt request bit, interrupt enable bit, and interrupt disable flag) and interrupt priority levels for accepting interrupt requests. When two or more interrupt requests are generated simultaneously, the highest priority interrupt is accepted. The value of interrupt request bit for an unaccepted interrupt remains the same and acceptance is determined at the next interrupt acceptance timing point.
- (iii) **Handling of Accepted Interrupt Request**
The accepted interrupt request is processed.

Figure 18 shows the time up to execution in the interrupt routine, and Figure 19 shows the interrupt sequence.

Figure 20 shows the timing of interrupt request generation, interrupt request bit, and interrupt request acceptance.

• Interrupt Handling Execution

When interrupt handling is executed, the following operations are performed automatically.

- (1) Once the currently executing instruction is completed, an interrupt request is accepted.
- (2) The contents of the program counters and the processor status register at this point are pushed onto the stack area in order from 1 to 3.
 1. High-order bits of program counter (PCH)
 2. Low-order bits of program counter (PCL)
 3. Processor status register (PS)
- (3) Concurrently with the push operation, the jump address of the corresponding interrupt (the start address of the interrupt processing routine) is transferred from the interrupt vector to the program counter.
- (4) The interrupt request bit for the corresponding interrupt is set to "0". Also, the interrupt disable flag is set to "1" and multiple interrupts are disabled.
- (5) The interrupt routine is executed.
- (6) When the RTI instruction is executed, the contents of the registers pushed onto the stack area are popped off in the order from 3 to 1. Then, the routine that was before running interrupt processing resumes.

As described above, it is necessary to set the stack pointer and the jump address in the vector area corresponding to each interrupt to execute the interrupt processing routine.

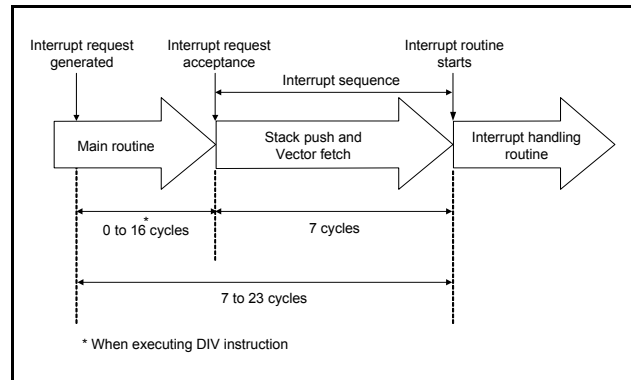


Fig. 18 Time up to execution in interrupt routine

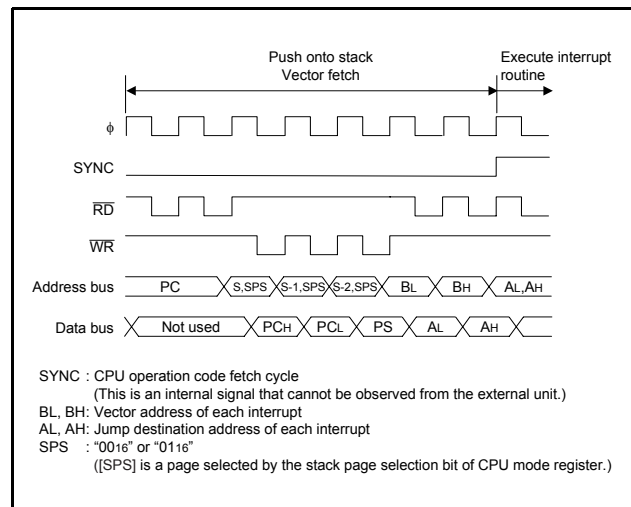


Fig. 19 Interrupt sequence

<Notes>

The interrupt request bit may be set to "1" in the following cases.

- When setting the external interrupt active edge

Related bits: INT0 interrupt edge selection bit
(bit 0 of interrupt edge selection register
(address 003A16))
INT1 interrupt edge selection bit
(bit 1 of interrupt edge selection register)
INT2 interrupt edge selection bit
(bit 2 of interrupt edge selection register)
CNTR0 activate edge switch bit
(bits 6 and 7 of timer X control register 1
(address 002E16))
CNTR1 activate edge switch bit
(bits 6 of timer Y mode register
(address 003816))

- When switching the interrupt sources of an interrupt vector address where two or more interrupt sources are assigned

Related bit: Timer Y/CNTR1 interrupt switch bit
(bit 3 of interrupt edge selection register)

If it is not necessary to generate an interrupt synchronized with these settings, take the following sequence.

- (1) Set the corresponding enable bit to "0" (disabled).
- (2) Set the interrupt edge selection bit (the active edge switch bit) or the interrupt source bit.
- (3) Set the corresponding interrupt request bit to "0" after one or more instructions have been executed.
- (4) Set the corresponding interrupt enable bit to "1" (enabled).

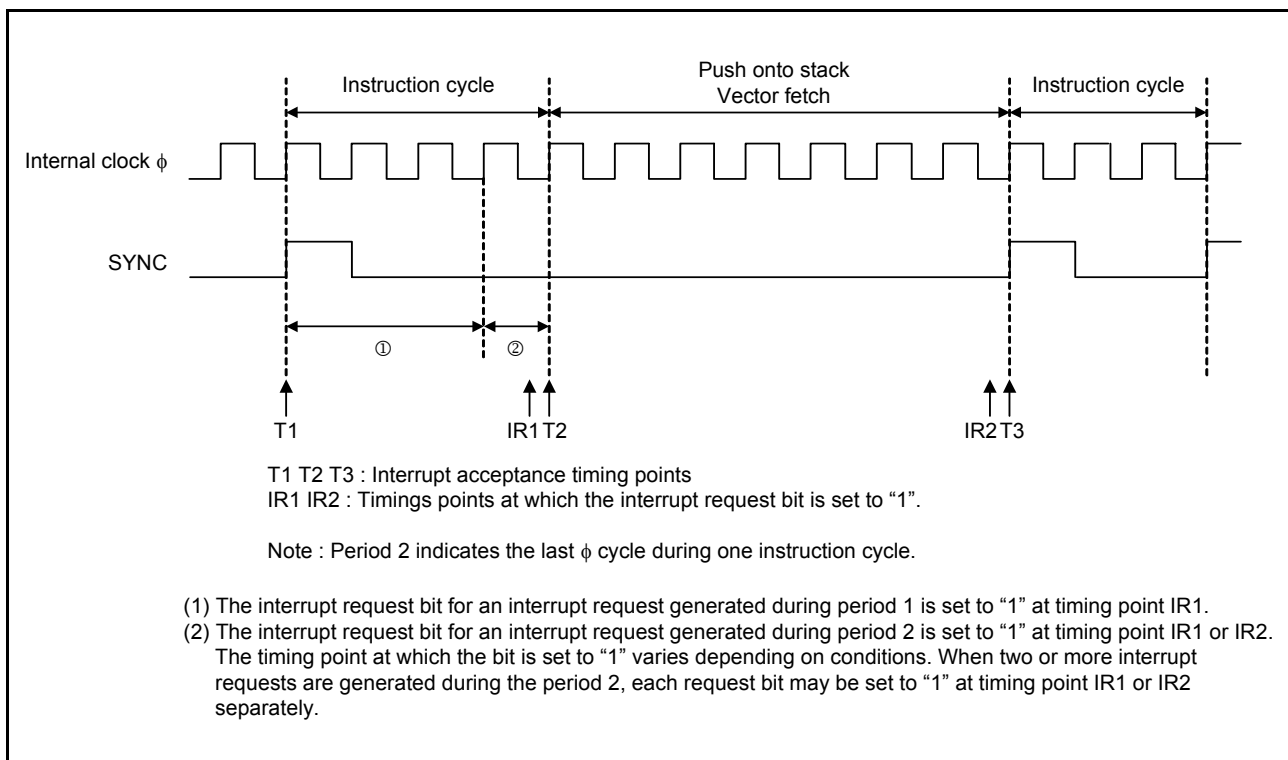


Fig. 20 Timing of interrupt request generation, interrupt request bit, and interrupt acceptance

• Key Input Interrupt (Key-on Wake-Up)

A key input interrupt request is generated by detecting the falling edge from any pin of ports P00–P03, P54–P57 that have been set to input mode. In other words, it is generated when AND of input level goes from “1” to “0”. An example of using a key input

interrupt is shown in Figure 21, where an interrupt request is generated by pressing one of the keys consisted as an active-low key matrix which inputs to ports P54–P57.

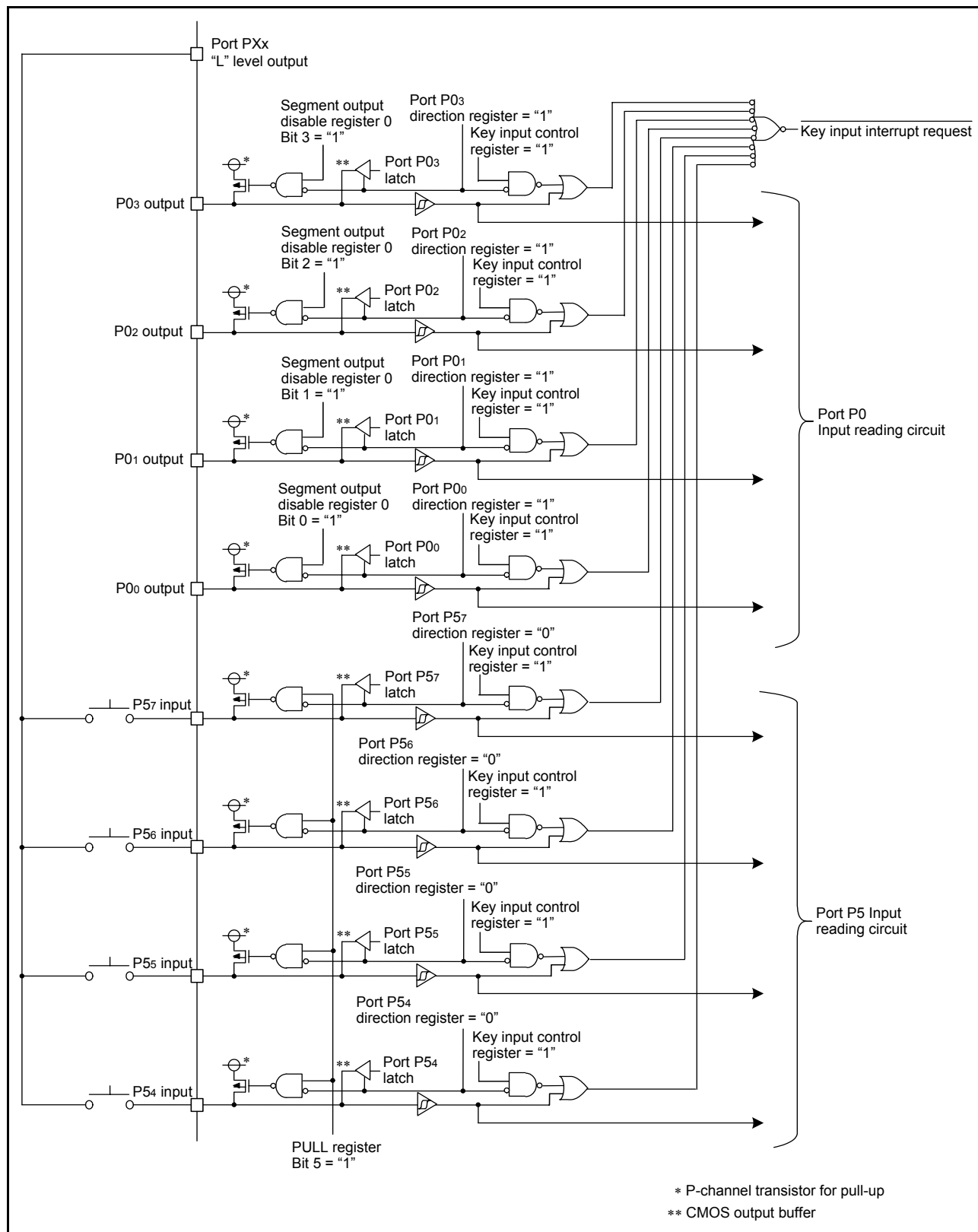


Fig. 21 Connection example when using key input interrupt

A key input interrupt is controlled by the key input control register and port direction registers. When the key input interrupt is enabled, set "1" to the key input control register. A key input of any pin of ports P00–P03, P54–P57 that have been set to input mode is accepted.

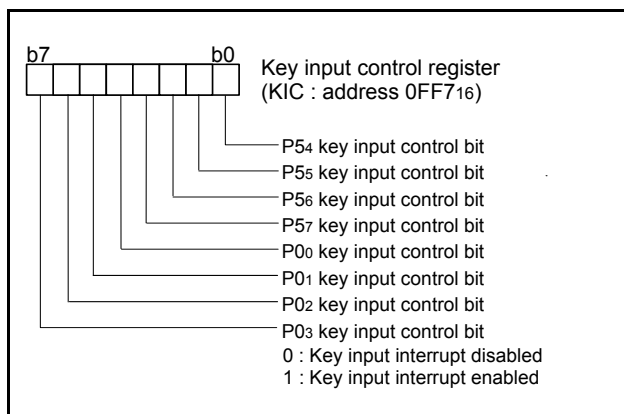


Fig. 22 Structure of key input control register

TIMERS

8-Bit Timer

The 38D2 Group has four built-in 8-bit timers: timer 1, timer 2, timer 3, and timer 4.

Each timer has the 8-bit timer latch. All timers are down-counters.

When the timer reaches "0016", the contents of the timer latch is reloaded into the timer with the next count pulse. In this mode, the interrupt request bit corresponding to that timer is set to "1". The count can be stopped by setting the stop bit of each timer to "1".

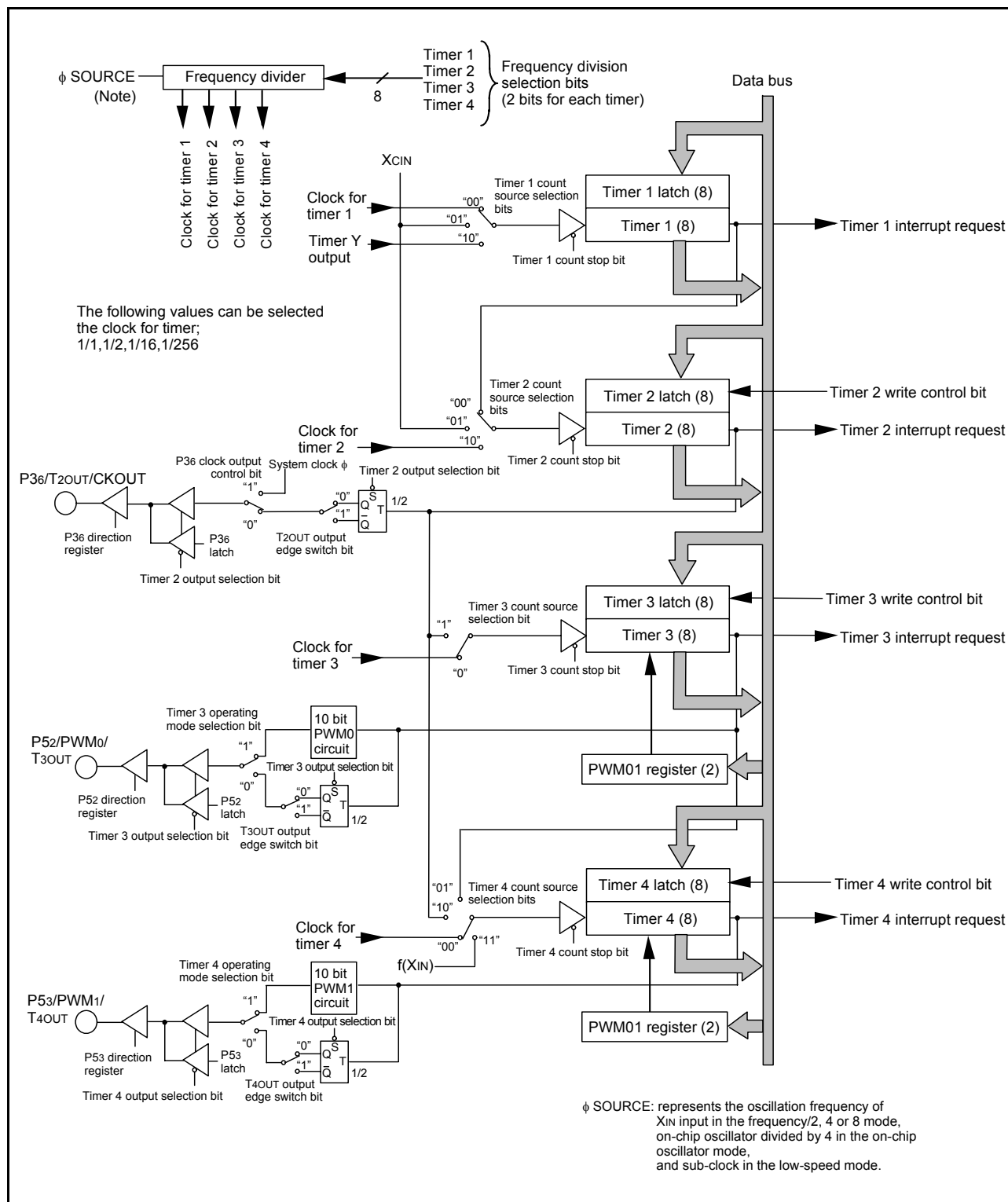


Fig. 23 Timer 1-4 block diagram

• Frequency Divider For Timer

Timer 1, timer 2, timer 3 and timer 4 have the frequency divider for the count source. The count source of the frequency divider is switched to XIN, XCIN, or the on-chip oscillator OCO divided by 4 in the on-chip oscillator mode by the CPU mode register. The frequency divider is controlled by each timer division ratio selection bit. The division ratio can be selected from as follows; 1/1, 1/2, 1/16, 1/256 of $f(XIN)$, $f(XCIN)$ or $f(OCO)/4$. Switch the frequency division or count source* while the timer count is stopped.

*This also applies when the frequency divider output is selected as the timer count source and the count source is switched in conjunction with a transition between operating modes (on-chip oscillator mode, XIN mode, or low-speed mode). Be careful when changing settings in the CPU mode register.

• Timer 1, Timer 2

The count source for timer 1 and timer 2 can be set using the timer 12 mode register. XCIN may be selected as the count source. If XCIN is selected, count operation is possible regardless of whether or not the XIN input oscillator or the on-chip oscillator is operating. In addition, the timer 12 mode register can be used to output from the P36/T2OUT pin a signal to invert the polarity every time timer 2 underflows.

At reset, all bits of the timer 12 mode register are set to "0", timer 1 is set to "FF16", and timer 2 is set to "0116".

When executing the STP instruction, previously set the wait time at return.

• Timer 3, Timer 4

The count sources of timer 3 and timer 4 can be selected by setting the timer 34 mode register. Also, by the timer 34 mode register, each time timer 3 or timer 4 underflows, the signal of which polarity is inverted can be output from P52/T3OUT pin or P53/T4OUT pin.

• Timer 3 PWM0 Mode, Timer 4 PWM1 Mode

A PWM rectangular waveform corresponding to the 10-bit accuracy can be output from the P52/PWM0 pin and P53/PWM1 pin by setting the timer 34 mode register and PWM01 register (refer to Figure 24).

One output pulse is the short interval. Four output pulses are the long interval. The "n" is the value set in the timer 3 (address 002216) or the timer 4 (address 002316). The "ts" is one period of timer 3 or timer 4 count source. "H" width of the short interval is obtained by $n \times ts$.

However, in the long interval, "H" width of output pulse is extended for ts which is set by the PWM01 register (address 002416).

<Notes on Timer 1 to Timer 4>

(1) Timer 3 PWM0 Mode, Timer 4 PWM1 Mode

- When PWM output is suspended after starting PWM output, depending on the level of the output pulse at that time to resume an output, the delay of the one section of the short interval may be needed.

Stop at "H": No output delay

Stop at "L": Output is delayed time of $256 \times ts$

- In the PWM mode, the follows are performed every cycle of the long interval ($4 \times 256 \times ts$).

- Generation of timer 3, timer 4 interrupt requests
- Update of timer 3, timer 4

(2) Write to Timer 2, Timer 3, Timer 4

When writing to the latch only, if the write timing to the reload latch and the underflow timing are almost the same, the value is set into the timer and the timer latch at the same time. In this time, counting is stopped during writing to the reload latch.

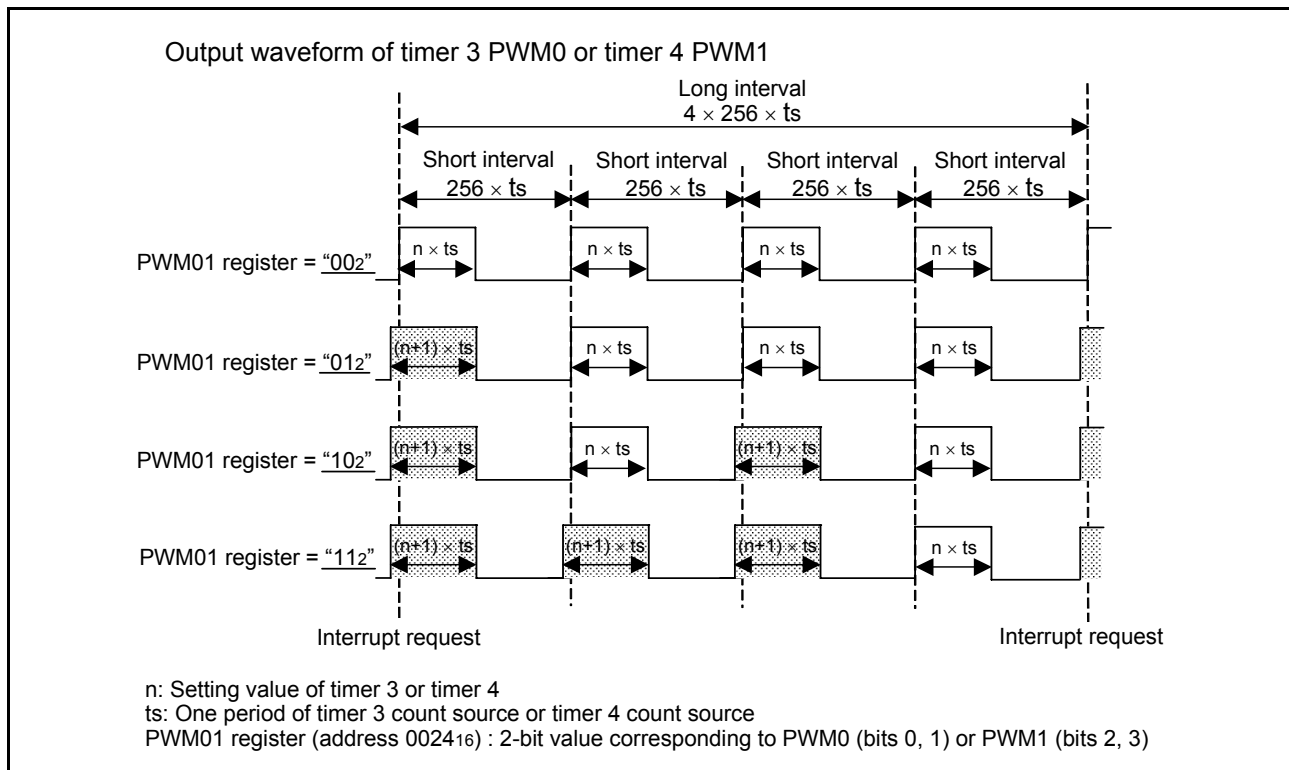


Fig. 24 Waveform of PWM0 and PWM1

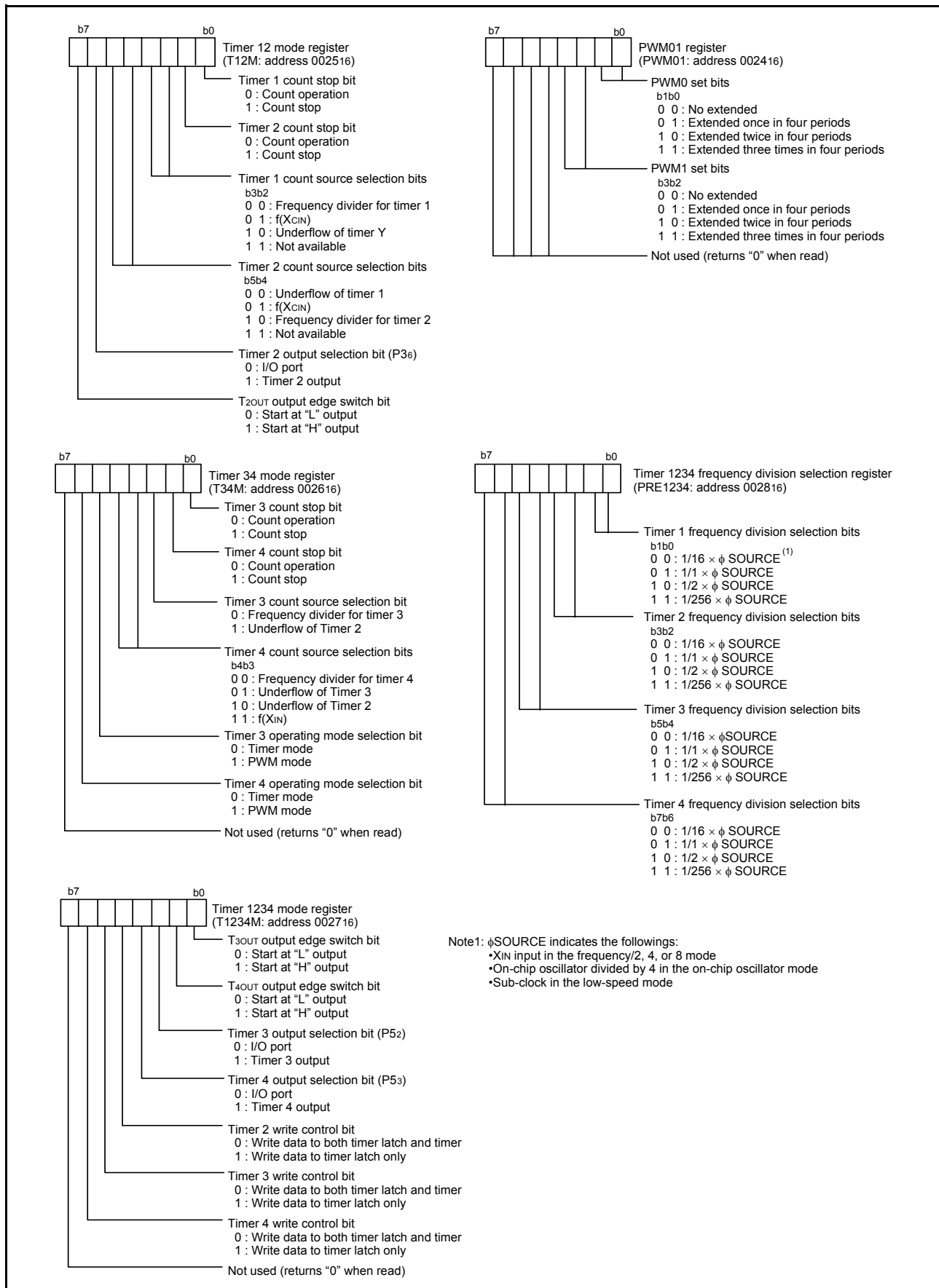


Fig. 25 Structure of timer 1 to timer 4 related registers

16-bit Timer

Read and write operation on 16-bit timer must be performed for both high and low-order bytes. When reading a 16-bit timer, read the high-order byte first. When writing to a 16-bit timer, write the low-order byte first. The 16-bit timer cannot perform the correct operation when reading during the write operation, or when writing during the read operation.

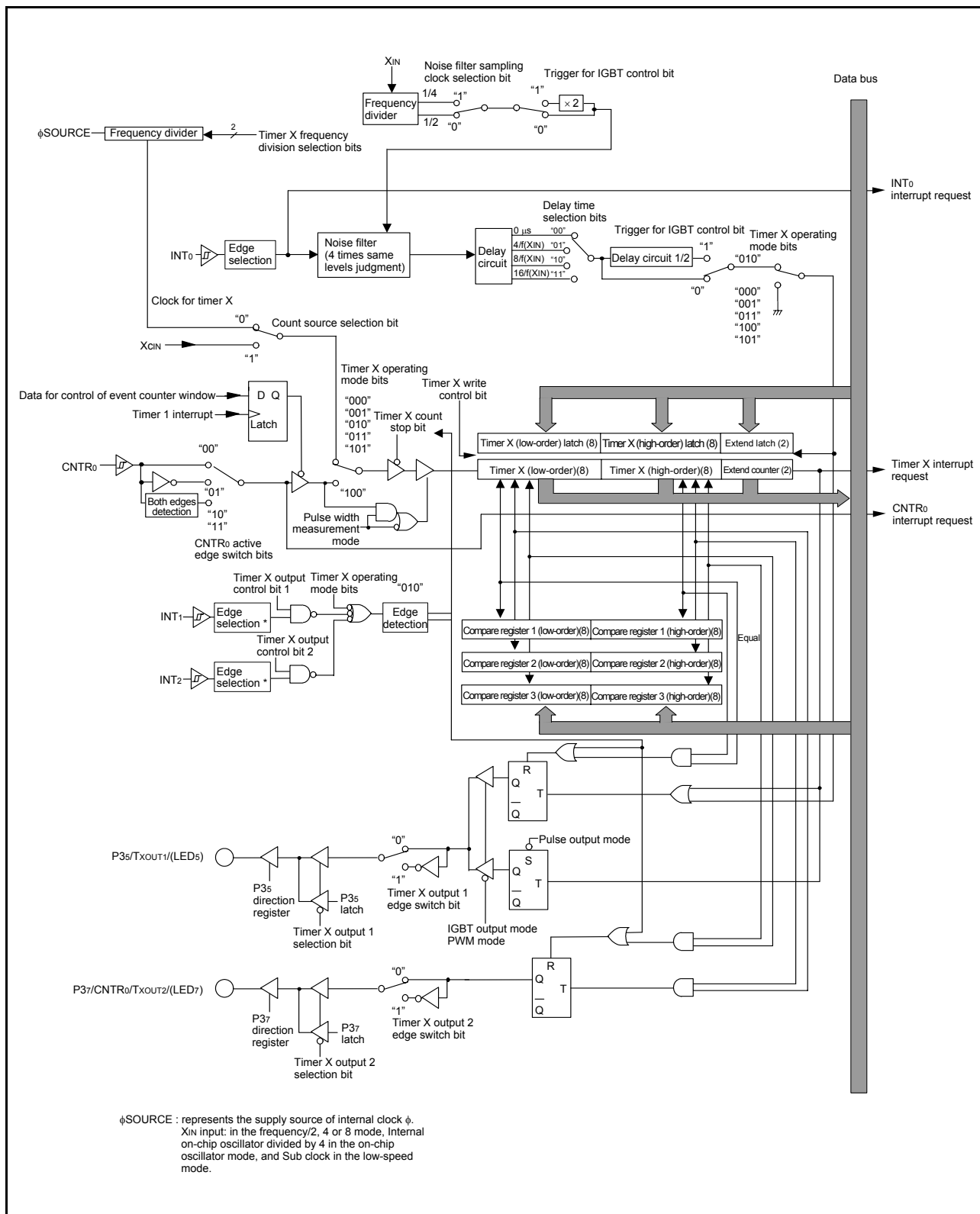


Fig. 26 Timer X block diagram

• Frequency Divider For Timer

Each timer X and timer Y have the frequency dividers for the count source. The count source of the frequency divider is switched to XIN, XCIN, or the on-chip oscillator OCO divided by 4 in the on-chip oscillator mode by the CPU mode register. The division ratio of each timer can be controlled by each timer division ratio selection bit. The division ratio can be selected from as follows;

1/1, 1/2, 1/16, 1/256 of $f(XIN)$, $f(XCIN)$ or $f(OCO)/4$.

Switch the frequency division or count source* while the timer count is stopped.

*This also applies when the frequency divider output is selected as the timer count source and the count source is switched in conjunction with a transition between operating modes (on-chip oscillator mode, XIN mode, or low-speed mode). Be careful when changing settings in the CPU mode register.

• Timer X

The count source for timer X can be set using the timer X mode register. XCIN may be selected as the count source. If XCIN is selected, count operation is possible regardless of whether or not the XIN input oscillator or the on-chip oscillator is operating.

The timer X operates as down-count. When the timer contents reach "0000₁₆", an underflow occurs at the next count pulse and the timer latch contents are reloaded. After that, the timer continues countdown. When the timer underflows, the interrupt request bit corresponding to the timer X is set to "1".

Six operating modes can be selected for timer X by the timer X mode register and timer X control register.

(1) Timer Mode

The count source can be selected by setting the timer X mode register. In this mode, timer X operates as the 18-bit counter by setting the timer X register (extension).

(2) Pulse Output Mode

Pulses of which polarity is inverted each time the timer underflows are output from the TXOUT1 pin. Except for that, this mode operates just as in the timer mode.

When using this mode, set the port sharing the TXOUT1 pin to output mode.

(3) IGBT Output Mode

After dummy output from the TXOUT1 pin, count starts with the INT0 pin input as a trigger. In the case that the timer X output 1 active edge switch bit is "0", when the trigger is detected or the timer X underflows, "H" is output from the TXOUT1 pin. And then, when the count value corresponds with the compare register 1 value, the TXOUT1 output becomes "L".

After noise is cleared by noise filters, judging continuous 4-time same levels with sampling clocks to be signals, the INT0 signal can use 4 types of delay time by a delay circuit.

When using this mode, set the port sharing the INT0 pin to input mode and set the port sharing the pin used as TXOUT1 or TXOUT2 function to output mode.

When the timer X output control bit 1 or 2 of the timer X control register is set to "1", the timer X count stop bit is fixed to "1" forcibly by the interrupt signal of INT1 or INT2. And then, the TXOUT1 output and TXOUT2 output can be set to "L" forcibly at the same time that the timer X stops counting.

Do not write "1" to the timer X register (extension) when using the IGBT output mode.

(4) PWM Mode

IGBT dummy output, an external trigger with the INT0 pin and output control with pins INT1 and INT2 are not used. Except for those, this mode operates just as in the IGBT output mode.

The period of PWM waveform is specified by the timer X set value. In the case that the timer X output 1 active edge switch bit is "0", the "H" interval is specified by the compare register 1 set value. In the case that the timer X output 2 active edge switch bit is "0", the "H" interval is specified by the compare registers 2 and 3 set values.

When using this mode, set the port sharing the pin used as TXOUT1 or TXOUT2 function to output mode.

Do not write "1" to the timer X register (extension) when using the PWM mode.

(5) Event Counter Mode

The timer counts signals input through the CNTR0 pin. In this mode, timer X operates as the 18-bit counter by setting the timer X register (extension). When using this mode, set the port sharing the CNTR0 pin to input mode.

In this mode, the window control can be performed by the timer 1 underflow. When the bit 5 (data for control of event counter window) of the timer X mode register is set to "1", counting is stopped at the next timer 1 underflow. When the bit is set to "0", counting is restarted at the next timer 1 underflow.

(6) Pulse Width Measurement Mode

In this mode, the count source is the output of frequency divider for timer. In this mode, timer X operates as the 18-bit counter by setting the timer X register (extension). When the bit 6 of the CNTR0 active edge switch bits is "0", counting is executed during the "H" interval of CNTR0 pin input. When the bit is "1", counting is executed during the "L" interval of CNTR0 pin input. When using this mode, set the port sharing the CNTR0 pin to input mode.

Also, set to enable ("0") the data for control of event counter window (bit 5 of timer X mode register (address 002D16)).

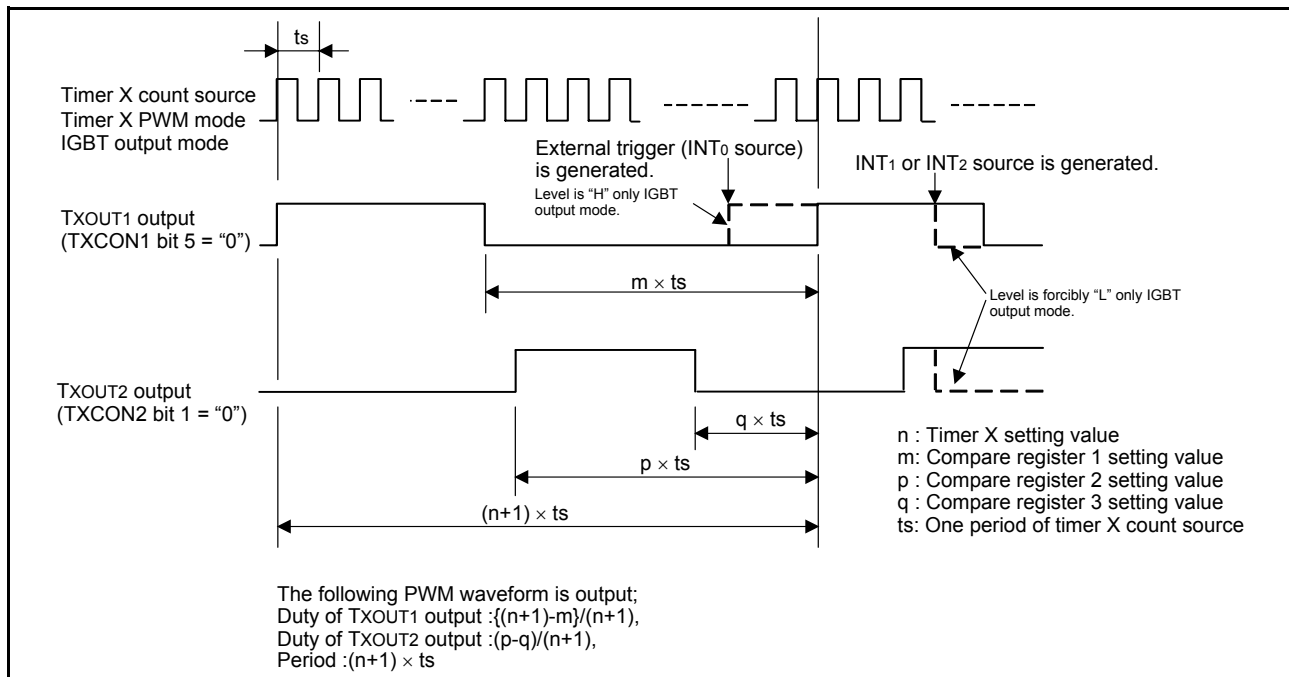


Fig. 27 Waveform of PWM/IGBT

<Notes on Timer X>

(1) Write Order to Timer X

- In the timer mode, pulse output mode, event counter mode and pulse width measurement mode, write to the following registers in the order as shown below;
 - the timer X register (extension),
 - the timer X register (low-order),
 - the timer X register (high-order).
 Do not write to only one of them.
 - When the above mode is set and timer X operates as the 16-bit counter, if the timer X register (extension) is never set after reset is released, setting the timer X register (extension) is not required. In this case, write the timer X register (low-order) first and the timer X register (high-order). However, once writing to the timer X register (extension) is executed, note that the value is retained to the reload latch.
 - Write to the timer X register by the 16-bit unit. Do not read the timer X register while write operation is performed. If the write operation is not completed, normal operation will not be performed.
 - In the IGBT output and PWM modes, do not write "1" to the timer X register (extension). Also, when "1" is already written to the timer X register, be sure to write "0" to the register before using.
 - Write to the following registers in the order as shown below;
 - the compare registers 1, 2, 3 (high- and low-order),
 - the timer X register (extension),
 - the timer X register (low-order),
 - the timer X register (high-order).
 It is possible to use whichever order to write to the compare registers 1, 2, 3 (high- and low-order). However, write both the compare registers 1, 2, 3 and the timer X register at the same time.
- For the compare registers, set a value less than the setting value in the timer X register. Also, do not set "0016".

(2) Read Order to Timer X

- In all modes, read the following registers in the order as shown below;
 - the timer X register (extension),
 - the timer X register (high-order),
 - the timer X register (low-order).
 When reading the timer X register (extension) is not required, read the timer X register (high-order) first and the timer X register (low-order).
- Read order to the compare registers 1, 2, 3 is not specified.
- Read from the timer X register by the 16-bit unit. Do not write to the timer X register while read operation is performed. If the read operation is not completed, normal operation will not be performed.

(3) Write to Timer X

- Which write control can be selected by the timer X write control bit (b3) of the timer X mode register (address 2D16), writing data to both the latch and the timer at the same time or writing data only to the latch. When writing a value to the timer X address to write to the latch only, the value is set into the reload latch and the timer is updated at the next underflow. After reset release, when writing a value to the timer X address, the value is set into the timer and the timer latch at the same time, because they are written at the same time.
 - When writing to the latch only, if the write timing to the high-order reload latch and the underflow timing are almost the same, the value is set into the timer and the timer latch at the same time. In this time, counting is stopped during writing to the high-order reload latch.
- Switch the frequency division or count source* while the timer count is stopped.

*This also applies when the frequency divider output is selected as the timer count source and the count source is switched in conjunction with a transition between operating modes (on-chip oscillator mode, XIN mode, or low-speed mode). Be careful when changing settings in the CPU mode register.

(4) Set of Timer X Mode Register

Set the write control bit of the timer X mode register to “1” (write to the latch only) when setting the IGBT output and PWM modes.

Output waveform simultaneously reflects the contents of both registers at the next underflow after writing to the timer X register (high-order).

(5) Output Control Function of Timer X

- When using the output control function (INT1 and INT2) in the IGBT output mode, set the levels of INT1 and INT2 to “H” in the falling edge active or to “L” in the rising edge active before switching to the IGBT output mode.

(6) Switch of CNTR0 Active Edge

- When the CNTR0 active edge switch bits are set, at the same time, the interrupt active edge is also affected.

When the pulse width is measured, set the bit 7 of the CNTR0 active edge switch bits to “0”.

(7) When Timer X Pulse Width Measurement Mode Used

When timer X pulse width measurement mode is used, enable the event counter window control data (bit 5 of timer X mode register (address 002D16)) by setting to “0”.

<Reason>

If the event counter window control data (bit 5 of timer X mode register (address 002D16)) is set to “1” (disabled) to enable/disable the CNTR0 input, the input is not accepted after the timer 1 underflow.

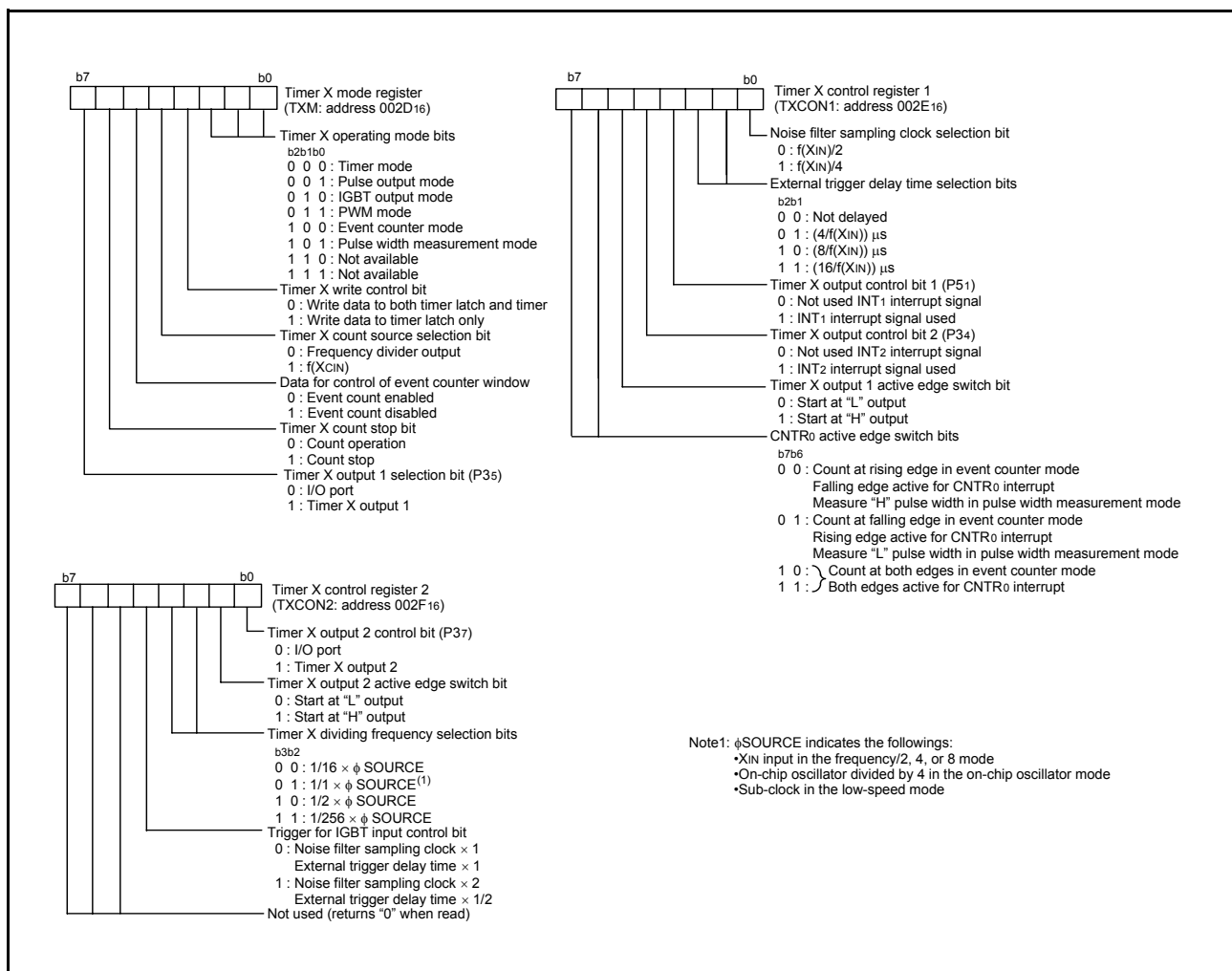


Fig. 28 Structure of timer X related registers

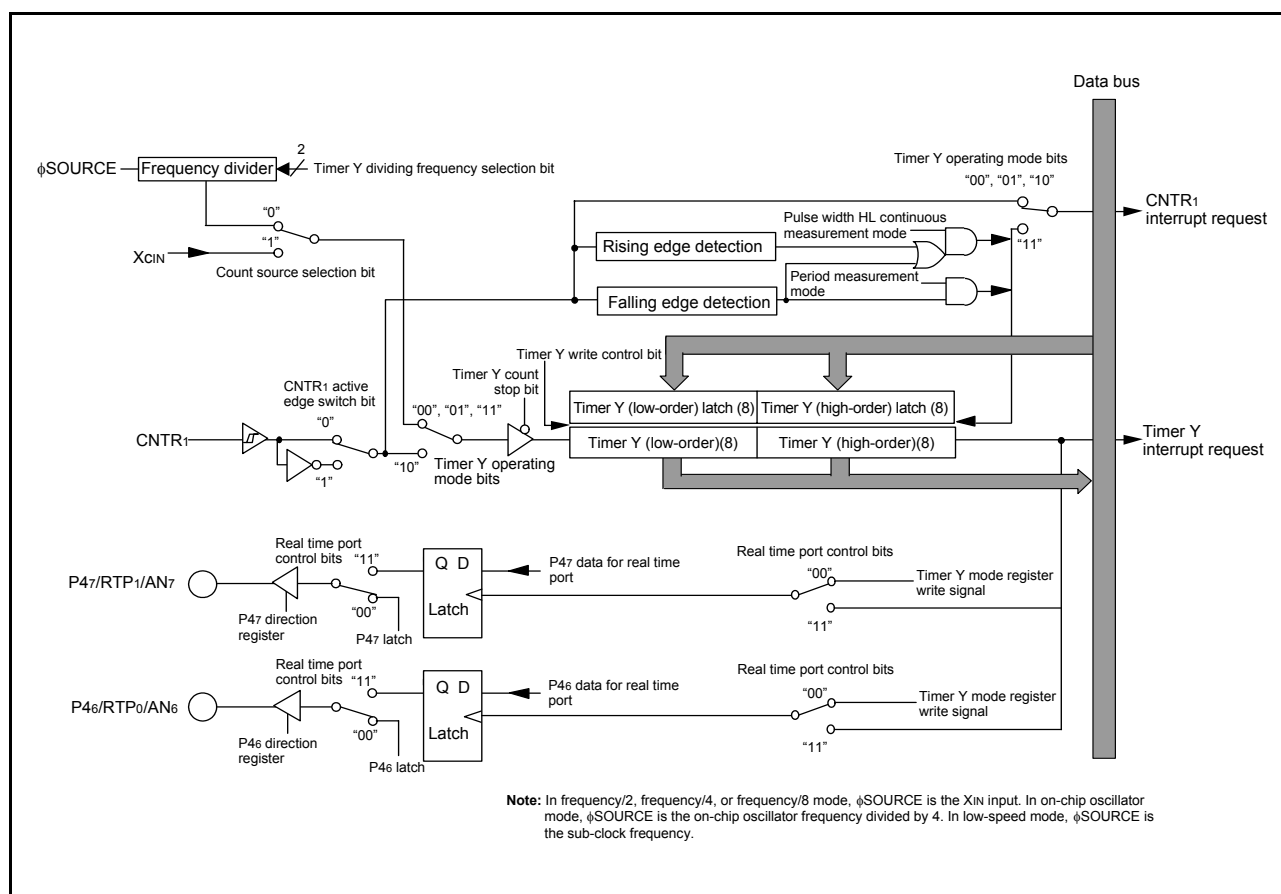


Fig. 29 Block diagram of timer Y

- **Timer Y**

Timer Y is a 16-bit timer. The timer Y count source can be selected by setting the timer Y mode register. XCIN can be selected as the count source. When XCIN is selected as the count source, counting can be performed regardless of XIN oscillation or on-chip oscillator oscillation.

Four operating modes can be selected for timer Y by the timer Y mode register. Also, the real time port can be controlled.

(1) Timer Mode

The timer Y count source can be selected by setting the timer Y mode register.

(2) Period Measurement Mode

The interrupt request is generated at rising or falling edge of CNTR1 pin input signal. Simultaneously, the value in timer Y latch is reloaded in timer Y and timer Y continues counting. Except for that, this mode operates just as in the timer mode. The timer value just before the reloading at rising or falling of CNTR1 pin input is retained until the timer Y is read once after the reload.

The rising or falling timing of CNTR1 pin input is found by CNTR1 interrupt. When using this mode, set the port sharing the CNTR1 pin to input mode.

(3) Event Counter Mode

The timer counts signals input through the CNTR1 pin.

Except for that, this mode operates just as in the timer mode.

When using this mode, set the port sharing the CNTR1 pin to input mode.

(4) Pulse Width HL Continuously Measurement Mode

The interrupt request is generated at both rising and falling edges of CNTR1 pin input signal. Except for that, this mode operates just as in the period measurement mode. When using this mode, set the port sharing the CNTR1 pin to input mode.

(5) Real Time Port Control

When the real time port function is valid, data for the real time port is output from ports P46 and P47 each time the timer Y underflows.

(However, if the real time port control bits are changed from “002” to “112” after both data for real time ports are set, data are output independent of the timer Y operation.) When either or both data for real time ports are changed while the real time port function is valid, the changed data is output at the next underflow of timer Y.

When switching the setting of the real time port control bits between valid and invalid, write to the timer Y mode register in byte units with the LDM or STA instruction so that both bits are switched at the same time. Also, before using this function, set the P46 and P47 port direction registers to output.

<Notes on Timer Y>

• CNTR1 Interrupt Active Edge Selection

CNTR1 interrupt active edge depends on the CNTR1 active edge switch bit. However, in pulse width HL continuously measurement mode, CNTR1 interrupt request is generated at both rising and falling edges of CNTR1 pin input signal regardless of the setting of CNTR1 active edge switch bit.

• Timer Y Read/Write Control

- When reading from/writing to timer Y, read from/write to both the high-order and low-order bytes of timer Y. When the value is read, read the high-order bytes first and the low-order bytes next. When the value is written, write the low-order bytes first and the high-order bytes next.

Write to or read from the timer X register in 16-bit units. If reading from the timer Y register during write operation or writing to it during read operation is performed, normal operation will not be performed.

- Which write control can be selected by the timer Y write control bit (b0) of the timer Y control register (address 0039₁₆), writing data to both the latch and the timer at the same time or writing data only to the latch. When writing a value to the timer Y address to write to the latch only, the value is set into the reload latch and the timer is updated at the next underflow. After reset release, when writing a value to the timer Y address, the value is set into the timer and the timer latch at the same time, because they are set to write at the same time.

When writing to the latch only, if the write timing to the high-order reload latch and the underflow timing are almost the same, the value is set into the timer and the timer latch at the same time. In this time, counting is stopped during writing to the high-order reload latch.

- This also applies when the frequency divider output is selected as the timer count source and the count source is switched in conjunction with a transition between operating modes (on-chip oscillator mode, XIN mode, or low-speed mode). Be careful when changing settings in the CPU mode register.

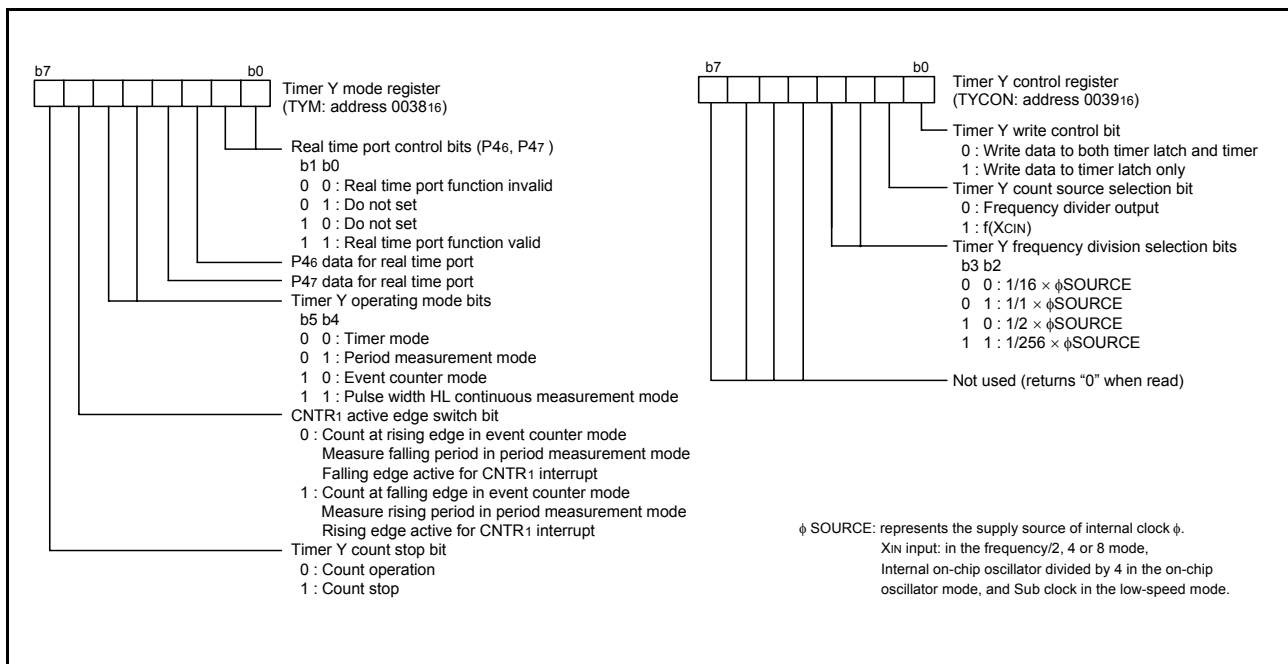


Fig. 30 Structure of timer Y related registers

SERIAL INTERFACE

- **SERIAL I/O**

The 38D2 Group has two 8-bit serial I/O (serial I/O1 and serial I/O2).

Serial I/O can be used as either clock synchronous or asynchronous (UART) serial I/O. A dedicated timer is also provided for baud rate generation.

(1) Clock Synchronous Serial I/O Mode

Clock synchronous serial I/O mode can be selected by setting the serial I/O mode selection bit of the serial I/O control register to “1”

For clock synchronous serial I/O, the transmitter and the receiver must use the same clock. If an internal clock is used, transfer is started by a write signal to the TB/RB.

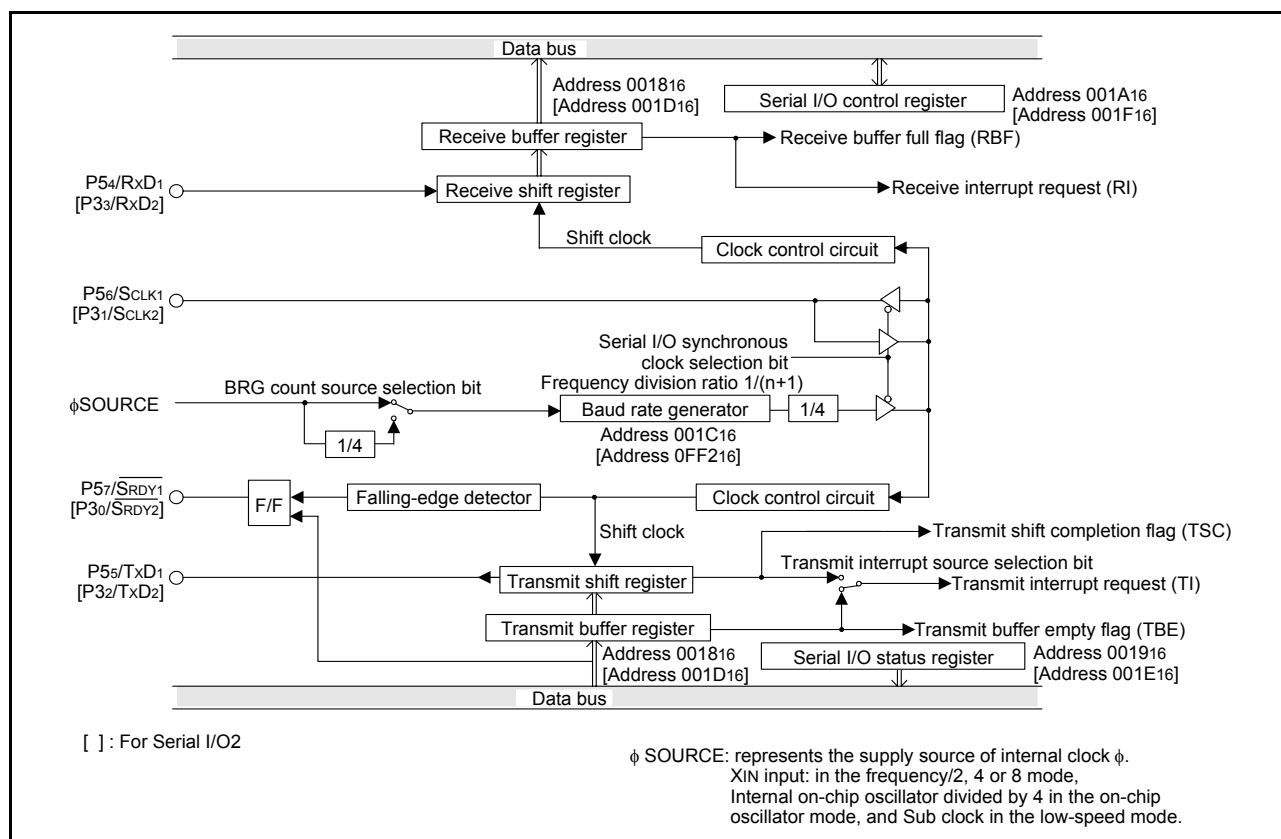


Fig. 31 Block diagram of clock synchronous serial I/O

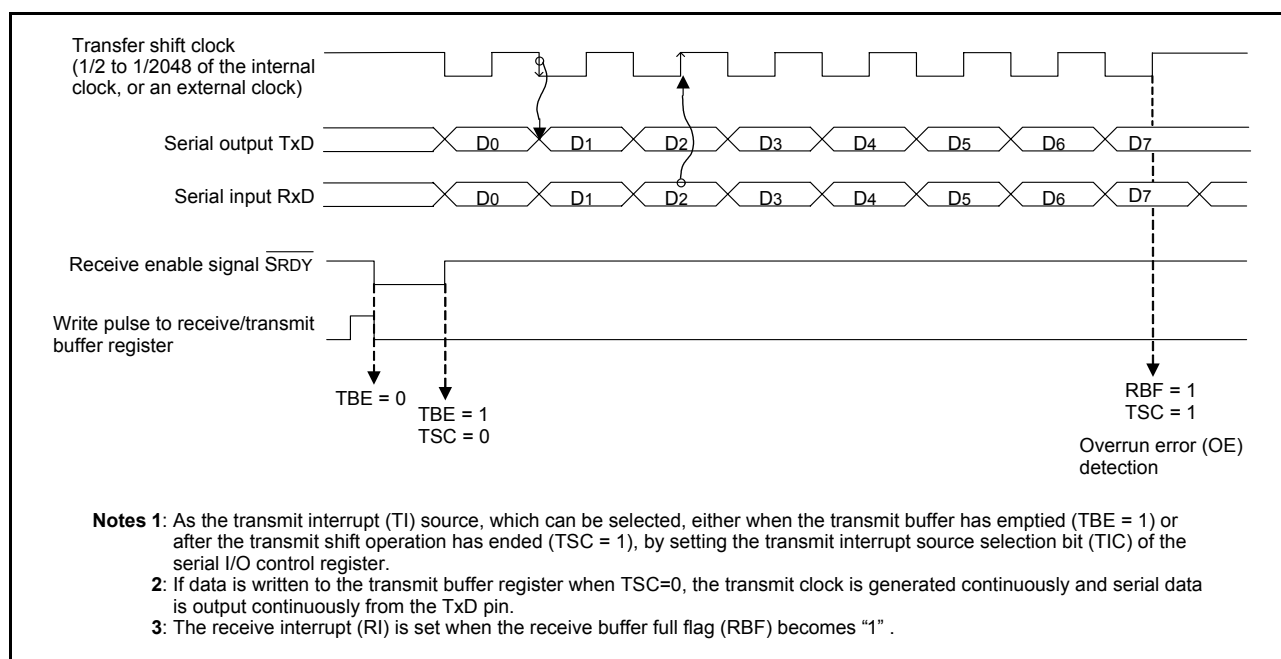


Fig. 32 Operation of clock synchronous serial I/O function

(2) Asynchronous Serial I/O (UART) Mode

Clock asynchronous serial I/O mode (UART) can be selected by setting the serial I/O mode selection bit of the serial I/O control register to "0".

Eight serial data transfer formats can be selected, and the transfer formats used by a transmitter and receiver must be identical.

The transmit and receive shift registers each have a buffer, but the two buffers have the same address in memory. Since the shift

register cannot be written to or read from directly, transmit data is written to the transmit buffer register, and receive data is read from the receive buffer register.

The transmit buffer register can also hold the next data to be transmitted, and the receive buffer register can hold a character while the next character is being received.

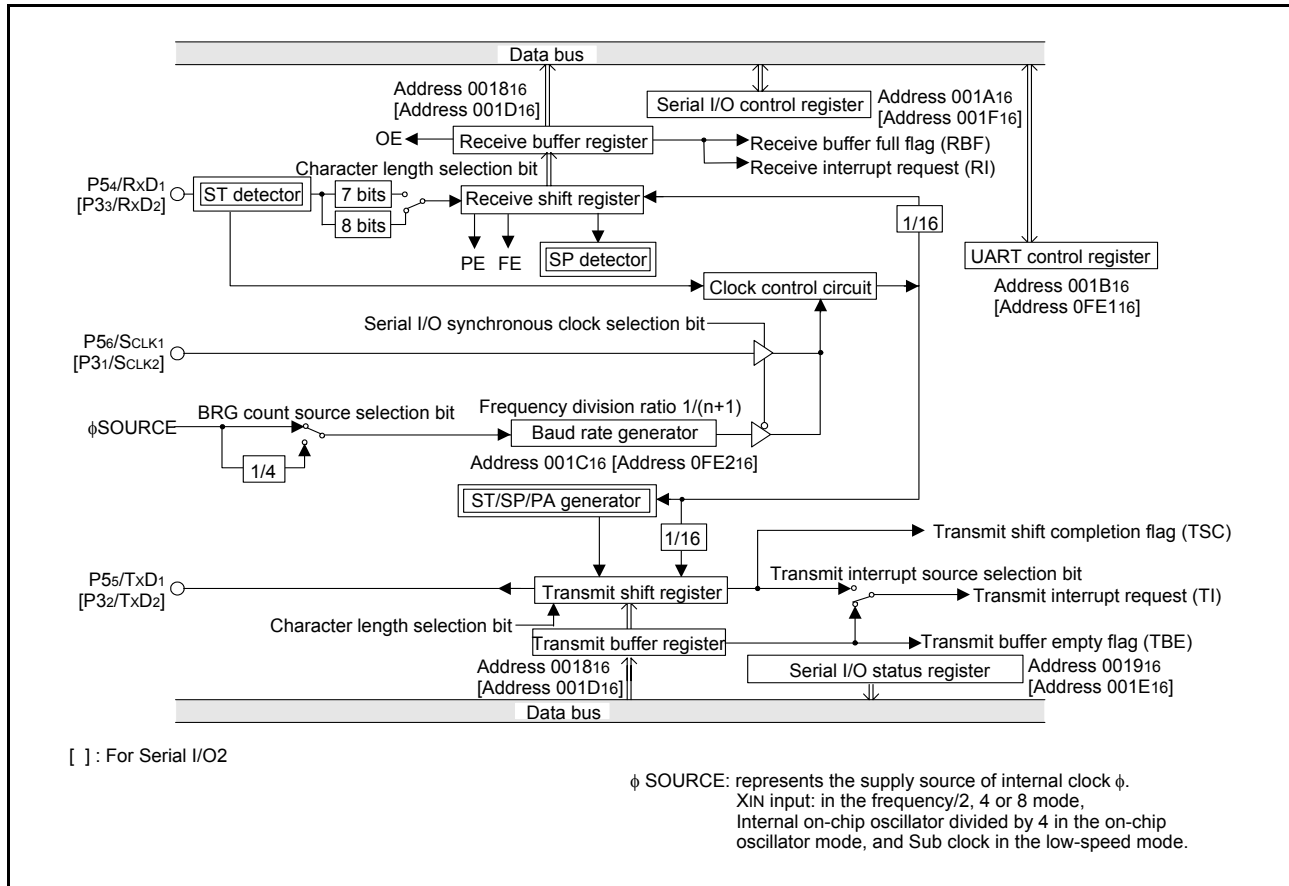


Fig. 33 Block diagram of UART serial I/O

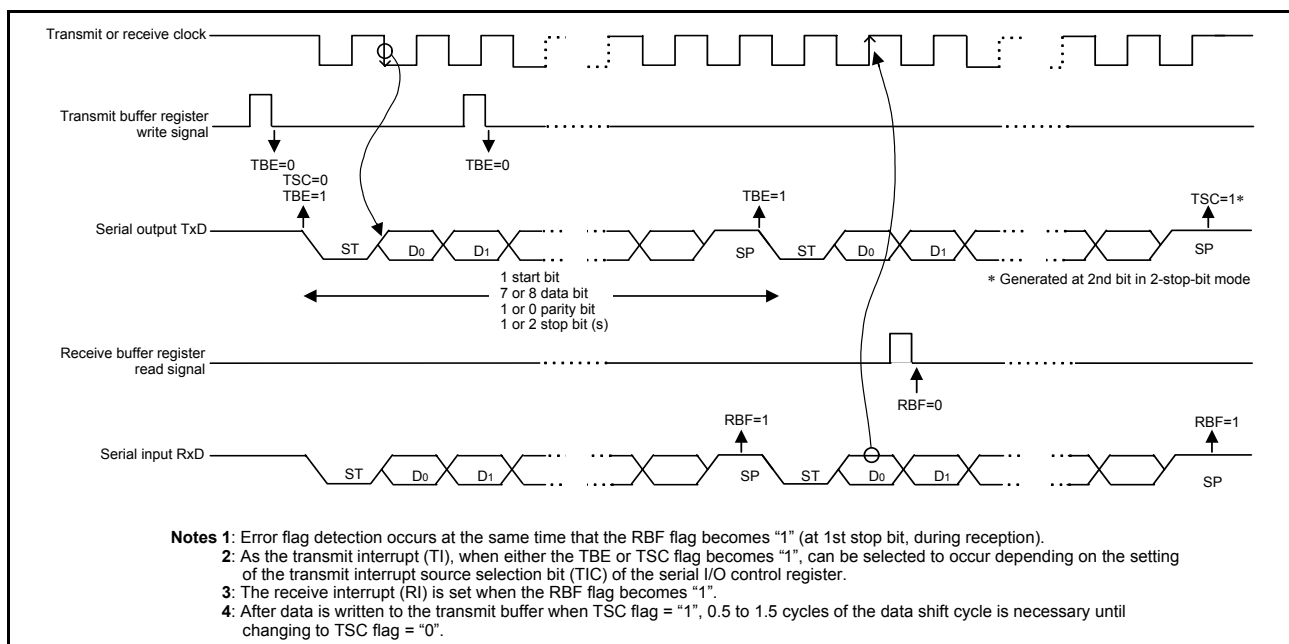


Fig. 34 Operation of UART serial I/O function

[Transmit Buffer Register/Receive Buffer Register (TB1, RB1/TB2, RB2)]

The transmit buffer register and the receive buffer register are located at the same address. The transmit buffer is write-only and the receive buffer is read-only. If a character bit length is 7 bits, the MSB of data stored in the receive buffer is "0".

[Serial I/O Status Register (SIO1STS, SIO2STS)]

The read-only serial I/O status register consists of seven flags (bits 0 to 6) which indicate the operating status of the serial I/O function and various errors.

Three of the flags (bits 4 to 6) are valid only in UART mode.

The receive buffer full flag (bit 1) is set to "0" when the receive buffer register is read.

If there is an error, it is detected at the same time that data is transferred from the receive shift register to the receive buffer register, and the receive buffer full flag is set. A write to the serial I/O status register sets all the error flags OE, PE, FE, and SE (bit 3 to bit 6, respectively) to "0". Writing "0" to the serial I/O enable bit SIOE (bit 7 of the serial I/O control register) also sets all the status flags to "0", including the error flags.

All bits of the serial I/O status register are set to "0" at reset, but if the transmit enable bit (bit 4) of the serial I/O control register has been set to "1", the transmit shift completion flag (bit 2) and the transmit buffer empty flag (bit 0) become "1".

[Serial I/O Control Register (SIO1CON, SIO2CON)]

The serial I/O control register consists of eight control bits for the serial I/O function.

[UART Control Register (UART1CON, UART2CON)]

The UART control register consists of four control bits (bits 0 to 3) which are valid when asynchronous serial I/O is selected and set the data format of the data transfer and one bit (bit 4) which is always valid and sets the output structure of the P5s/TxD1 [P32/TxD2] pin.

[Baud Rate Generator (BRG1, BRG2)]

The baud rate generator determines the baud rate for serial transfer.

The baud rate generator divides the frequency of the count source by $1/(n + 1)$, where n is the value written to the baud rate generator.

<Notes on serial I/O>

When setting transmit enable bit of serial I/O to "1", the serial I/O transmit interrupt request bit is automatically set to "1". When not requiring the interrupt occurrence synchronous with the transmission enabled, take the following sequence.

- (1) Set the serial I/O transmit interrupt enable bit to "0" (disabled).
- (2) Set the transmit enable bit to "1".
- (3) Set the serial I/O transmit interrupt request bit to "0" after 1 or more instructions have been executed.
- (4) Set the serial I/O transmit interrupt enable bit to "1" (enabled).

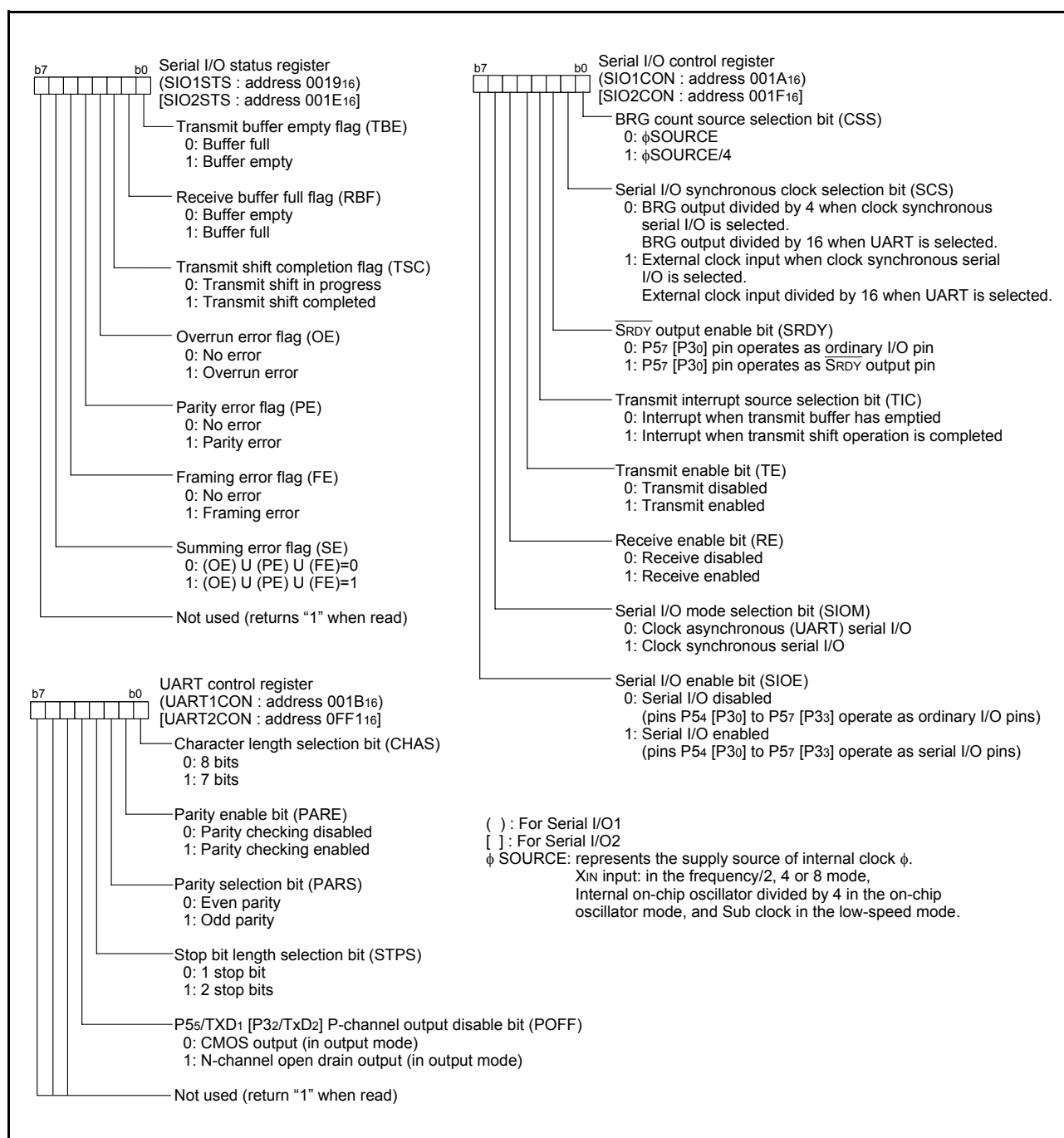


Fig. 35 Structure of serial I/O related registers

A/D CONVERTER

The 38D2 Group has a 10-bit A/D converter. The A/D converter performs successive approximation conversion. The 38D2 Group has the ADKEY function which perform A/D conversion of the “L” level analog input from the ADKEY pin automatically.

[AD Conversion Register (ADL, ADH)]

One of these registers is a high-order register, and the other is a low-order register. The high-order 8 bits of a conversion result is stored in the AD conversion register (high-order) (address 0017₁₆), and the low-order 2 bits of the same result are stored in bit 7 and bit 6 of the AD conversion register (low-order) (address 0016₁₆).

During A/D conversion, do not read these registers.

Also, the connection between the resistor ladder and reference voltage input pin (VREF) can be controlled by the VREF input switch bit (bit 0 of address 0016₁₆). When “1” is written to this bit, the resistor ladder is always connected to VREF. When “0” is written to this bit, the resistor ladder is disconnected from VREF except during the A/D conversion.

[AD Control Register (ADCON)]

This register controls A/D converter. Bits 2 to 0 are analog input pin selection bits. Bit 3 is an AD conversion completion bit and “0” during A/D conversion. This bit is set to “1” upon completion of A/D conversion.

A/D conversion is started by setting “0” in this bit.

Bit 5 is the ADKEY enable bit. The ADKEY function is enabled by setting “1” to this bit. When this function is valid, the analog input pin selection bits are ignored. Also, when bit 5 is “1”, do not set “0” to bit 3 by program.

[Comparison Voltage Generator]

The comparison voltage generator divides the voltage between AVSS and VREF, and outputs the divided voltages.

[Channel Selector]

The channel selector selects one of the input ports P47/AN7–P40/AN0 and inputs it to the comparator.

[Comparator and Control Circuit]

The comparator and control circuit compare an analog input voltage with the comparison voltage and store the result in the AD conversion register. When an A/D conversion is completed, the control circuit sets the AD conversion completion bit and the AD conversion interrupt request bit to “1”.

The comparator is constructed linked to a capacitor. The conversion accuracy may be low because the change is lost if the conversion speed is not enough.

Accordingly, set $f(XIN)$ to at least 500 kHz during A/D conversion in the XIN mode.

Also, do not execute the STP and WIT instructions during the A/D conversion.

In the low-speed mode and on-chip oscillator mode, there is no limit on the oscillation frequency because the on-chip oscillator is used as the A/D conversion clock. In the low-speed mode, on-chip oscillator starts oscillation automatically at the A/D conversion is executed and stops oscillation automatically at the A/D conversion is finished even though it is not oscillating.

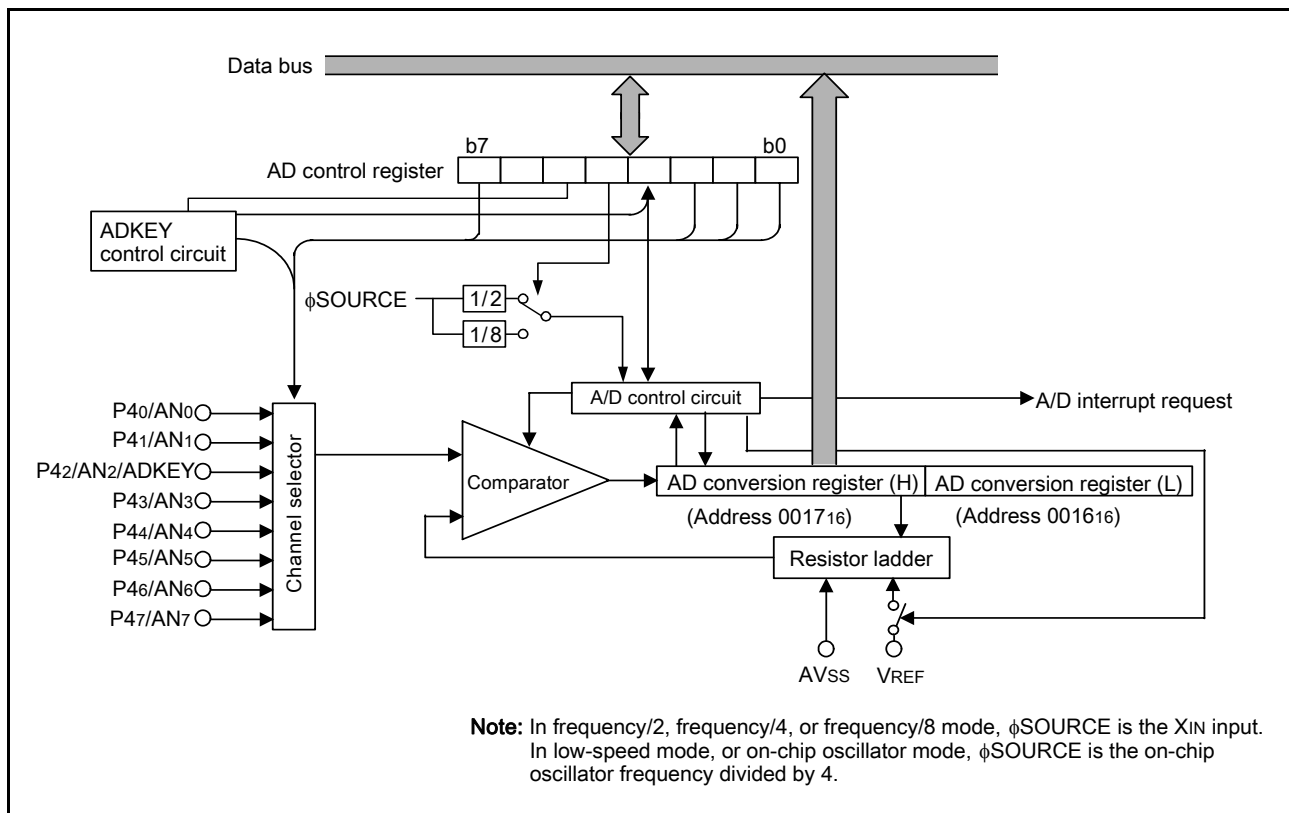


Fig. 36 Block diagram of A/D converter

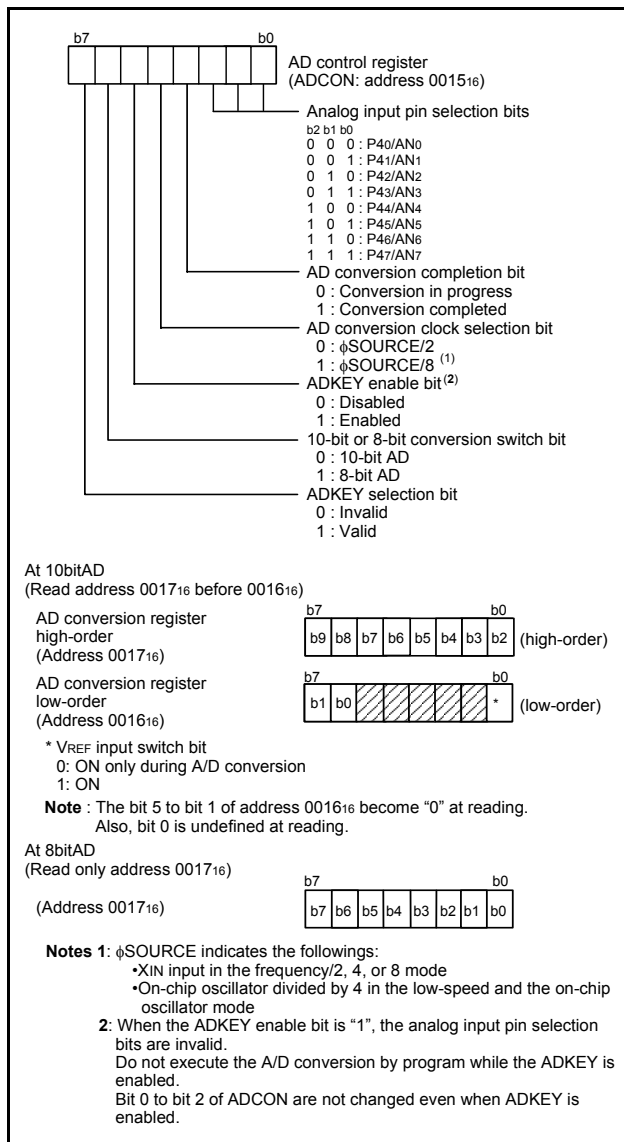


Fig. 37 Structure of AD control register

ADKEY function

The ADKEY function is used to judge the analog input voltage input from the ADKEY pin. When the A/D converter starts operating after V_{IL} ($0.7 \times V_{CC}-0.5$) or less is input, the event of analog voltage input can be judged with the A/D conversion interrupt.

This function can be used with the STP and WIT state.

As for the ADKEY function in 38D2 Group, the A/D conversion of analog input voltage immediately after starting ADKEY function is not performed.

Therefore, the A/D conversion result immediately after an ADKEY function is undefined. Accordingly, when the A/D conversion result of the analog input voltage input from the ADKEY pin is required, start the A/D conversion by program after the analog input pin corresponding to ADKEY is selected.

• ADKEY Selection

When the ADKEY pin is used, set the ADKEY selection bit to "1". The ADKEY selection bit is "0", just after the A/D conversion is started.

• ADKEY Enable

The ADKEY function is enabled by writing "1" to the ADKEY enable bit. Surely, in order to enable ADKEY function, set "1" to the ADKEY enable bit, after setting the ADKEY selection bit to "1".

When the ADKEY enable bit of the AD control register is "1", the analog input pin selection bits become invalid. Please do not write "0" in the AD conversion completion bit by the program during ADKEY enabled state.

[ADKEY Control Circuit]

In order to obtain a more exact conversion result, by the A/D conversion with ADKEY, execute the following;

- set the input to the ADKEY pin into a steep falling waveform,
- stabilize the input voltage within 8 clock cycles ($1 \mu s$ at $f(XIN) = 8 \text{ MHz}$) after the input voltage is under V_{IL}

The threshold voltage with an actual ADKEY pin is the voltage between $V_{IH}-V_{IL}$.

In order not to make ADKEY operation perform superfluously in a noise etc., in the state of the waiting for an input, set the voltage of an ADKEY pin to V_{IH} ($0.9V_{CC}$) or more.

When the following operations are performed, the A/D conversion operation cannot be guaranteed.

- When the CPU mode register is operated during A/D conversion operation,
- When the AD conversion control register is operated during A/D conversion operation,
- When the STP or WIT instruction is executed during A/D conversion operation.

LCD DRIVE CONTROL CIRCUIT

The 38D2 Group has the built-in Liquid Crystal Display (LCD) drive control circuit consisting of the following.

- LCD display RAM
- Segment output disable register
- LCD mode register
- Selector
- Timing controller
- Common driver
- Segment driver
- Bias control circuit

A maximum of 24 segment output pins and 4 common output pins can be used.

Up to 96 pixels can be controlled for an LCD display. When the LCD enable bit is set to "1" after data is set in the LCD mode register, the segment output disable register, and the LCD display

RAM, the LCD drive control circuit starts reading the display data automatically, performs the bias control and the duty ratio control, and displays the data on the LCD panel.

Table 11 Maximum number of display pixels at each duty ratio

Duty ratio	Maximum number of display pixels
2	48 dots or 8 segment LCD 6 digits
3	72 dots or 8 segment LCD 9 digits
4	96 dots or 8 segment LCD 12 digits

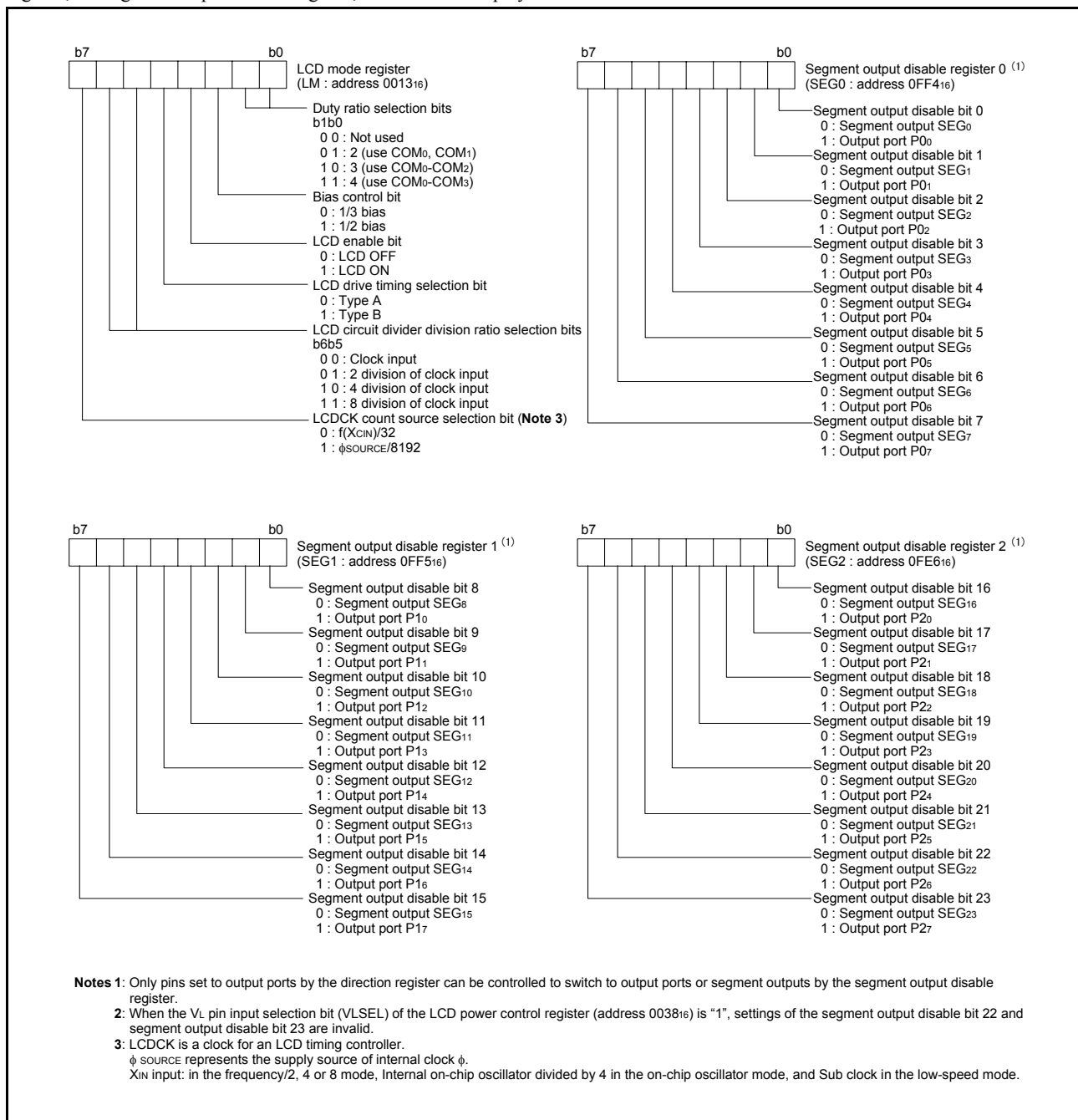


Fig. 38 Structure of LCD related registers

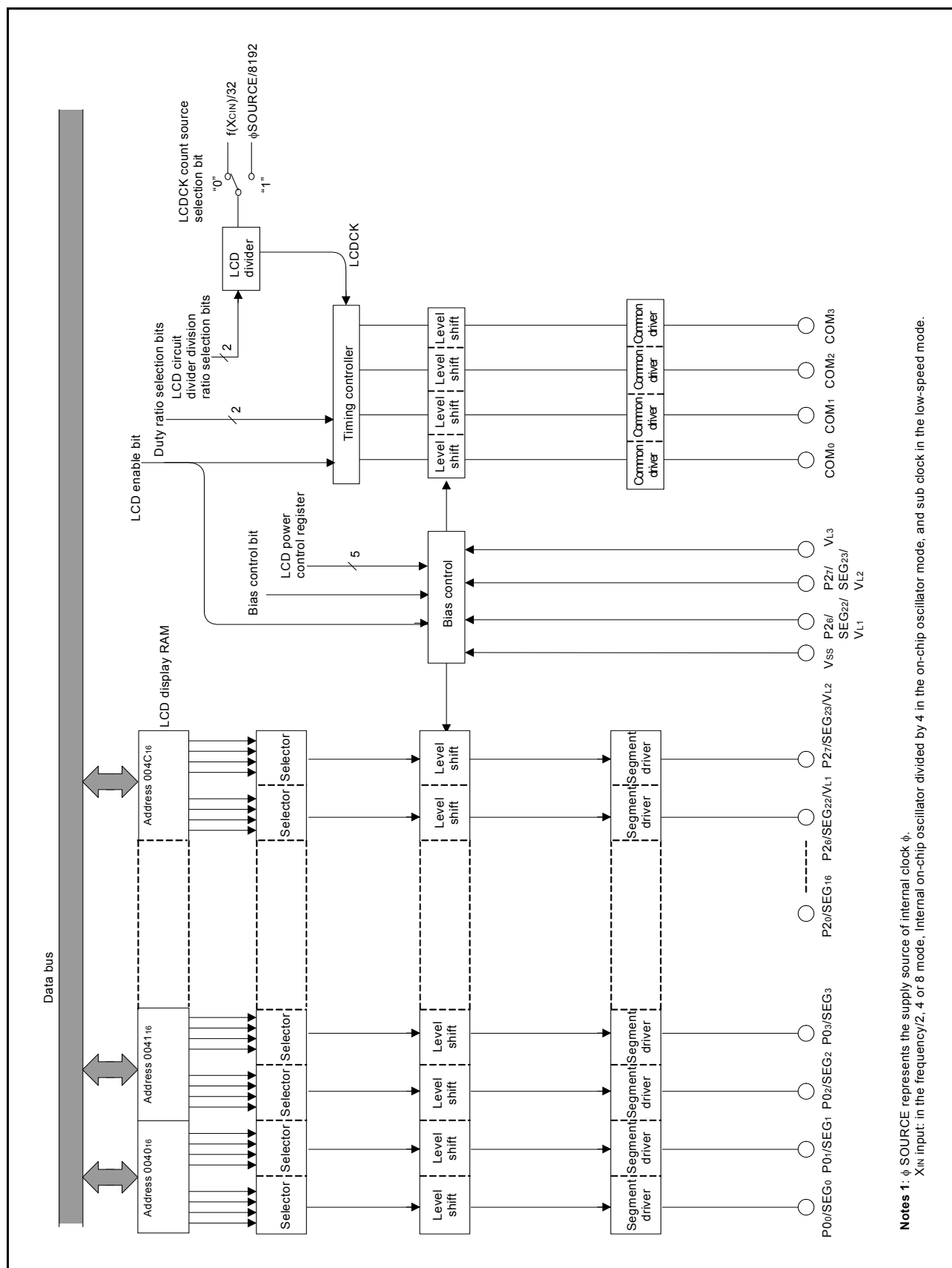


Fig. 39 Block diagram of LCD controller/driver

• Bias Control and Applied Voltage to LCD Power Input Pins

When the voltage is applied from the LCD power input pins (V_{L1} – V_{L3}), set the V_L pin input selection bit (bit 5 of the LCD power control register) and V_{L3} connection bit (bit 6 of LCD power control register) to “1”, apply the voltage value shown in Table 12 according to the bias value. In this case, SEG22 pin and SEG23 pin cannot be used.

Select a bias value by the bias control bit (bit 2 of the LCD mode register).

Table 12 Bias control and applied voltage to V_{L1} – V_{L3}

Bias value	Voltage value
1/3 bias	$V_{L3} = V_{LCD}$ $V_{L2} = 2/3 V_{LCD}$ $V_{L1} = 1/3 V_{LCD}$
1/2 bias	$V_{L3} = V_{LCD}$ $V_{L2} = V_{L1} = 1/2 V_{LCD}$

Note: V_{LCD} is the maximum value of supplied voltage for the LCD panel.

• Common Pin and Duty Ratio Control

The common pins ($COM0$ – $COM3$) to be used are determined by duty ratio. Select duty ratio by the duty ratio selection bits (bits 0 and 1 of the LCD mode register). When reset is released, V_{CC} voltage is output from the common pin.

Table 13 Duty ratio control and common pins used

Duty ratio	Duty ratio selection bits		Common pins used
	Bit 1	Bit 0	
2	0	1	$COM0, COM1$
3	1	0	$COM0$ – $COM2$
4	1	1	$COM0$ – $COM3$

Note: Unused common pin outputs the unselected waveform.

• Segment Signal Output Pin

The segment signal output pins ($SEG0$ – $SEG23$) are shared with ports P0–P2. When these pins are used as the segment signal output pins, set the direction registers of the corresponding pins to “1”, and set the segment output disable register to “0”.

Also, these pins are set to the input port after reset, the V_{CC} voltage is output by the pull-up resistor.

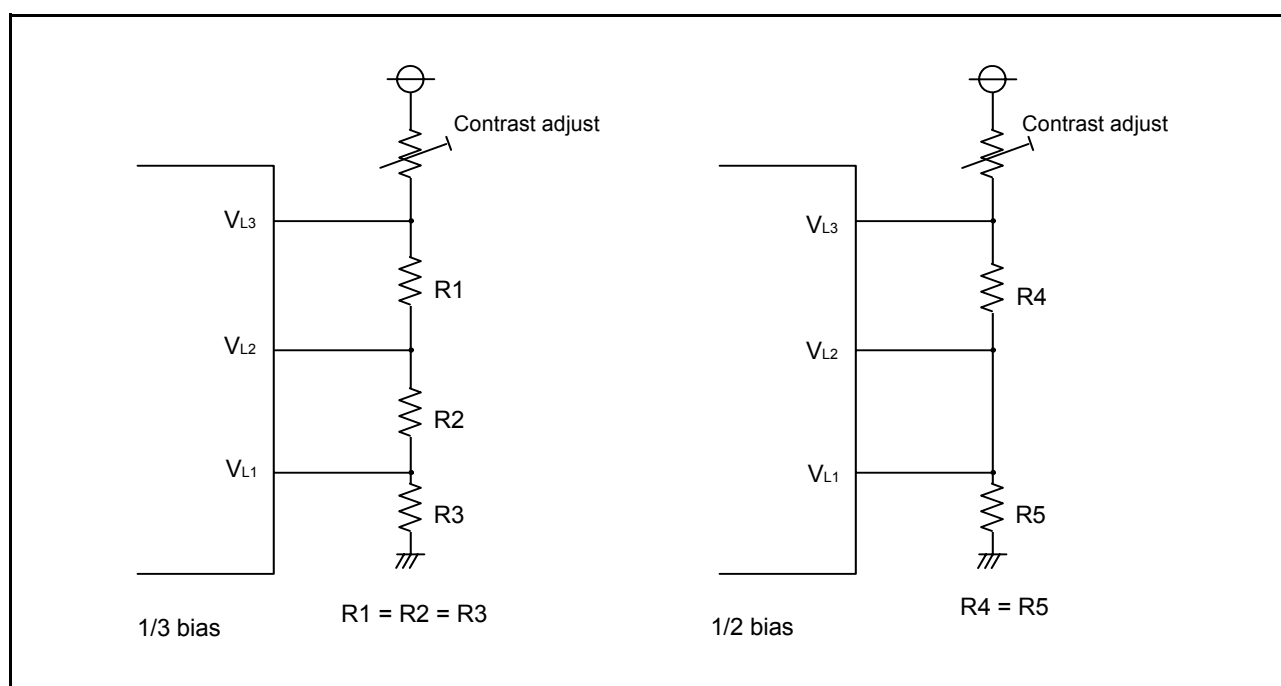


Fig. 40 Example of circuit at each bias (at external power input)

• LCD Power Circuit

The LCD power circuit has the dividing resistor for LCD power which can be connected/disconnected with the LCD power control register.

To use the LCD, apply a voltage externally to the VL3 pin and set the VL3 connect bit to "1". An external voltage should be applied

even if a voltage equivalent to VCC is used for the VL3 pin. When the LCD is not used, perform either of the following.

- Set the VL3 connect bit to "0" and leave the VL3 pin open.
- Set the VL3 connect bit to "1" and apply a VCC level to VL3 pin.

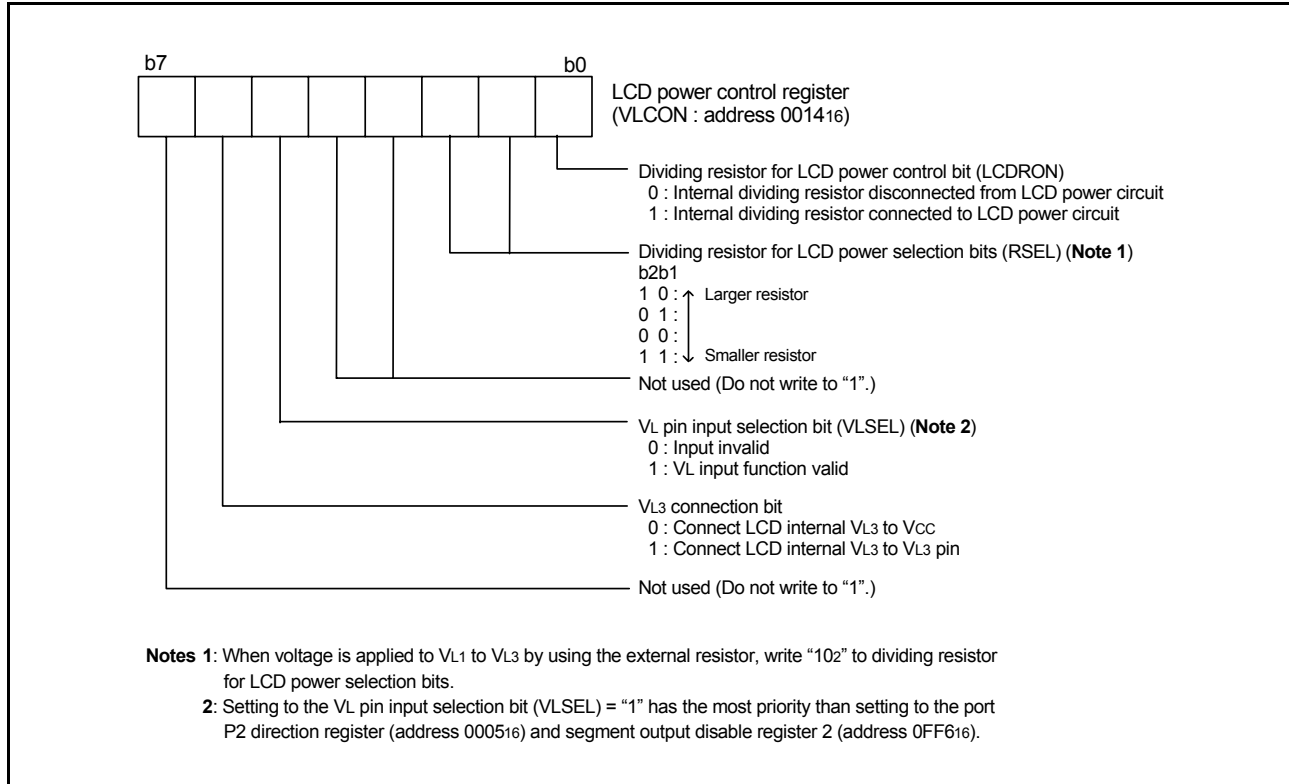


Fig. 41 Structure of LCD power control register

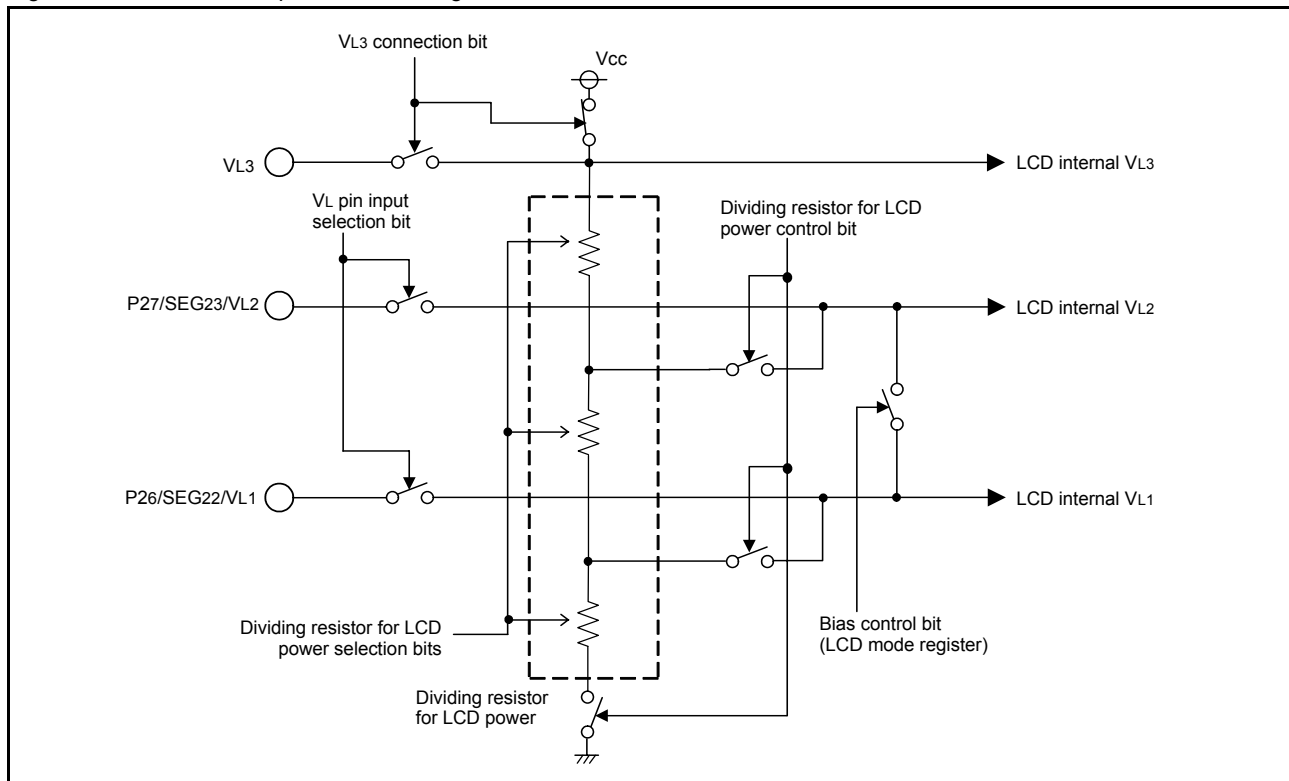


Fig. 42 VL block diagram

• LCD Display RAM

The 12-byte area of address 0040₁₆ to 004B₁₆ is the designated RAM for the LCD display. When “1” is written to these addresses, the corresponding segments of the LCD display panel are turned on.

• LCD Drive Timing

For the LCD drive timing, type A or type B can be selected. The LCD drive timing is selected by the timing selection bit (bit 4 of LCD mode register).

Type A is selected by setting the LCD drive timing selection bit to “0”, type B is selected by setting the bit to “1”. Type A is selected after reset.

The LCDCK timing frequency (LCD drive timing) is generated internally and the frame frequency can be determined with the following equation;

$$f(\text{LCDCK}) = \frac{(\text{frequency of count source for LCDCK})}{(\text{divider division ratio for LCD})}$$

$$\text{Frame frequency} = \frac{f(\text{LCDCK})}{\text{duty ratio}}$$

<Notes>

- (1) When the STP instruction is executed, the following bits are set to “0”;
 - LCD enable bit (bit 3 of LCD mode register)
 - Bits other than bit 6 of the LCD power control register.
 And the LCD panel turns off.
 To make the LCD panel turn on after returning from the stop mode, set these bits to “1”.
- (2) When the voltage is applied to VL1 to VL3 by using the external resistor, write “102” to dividing resistor for LCD power selection bits (RSEL) of the LCD power control register (address 0038₁₆).
- (3) When the LCD drive control circuit is used at VL3 = VCC, apply VCC to VL3 pin and write “1” to VL3 connection bit of the LCD power control register (address 0038₁₆).

Bit Address	7	6	5	4	3	2	1	0
0040 ₁₆	SEG ₁				SEG ₀			
0041 ₁₆	SEG ₃				SEG ₂			
0042 ₁₆	SEG ₅				SEG ₄			
0043 ₁₆	SEG ₇				SEG ₆			
0044 ₁₆	SEG ₉				SEG ₈			
0045 ₁₆	SEG ₁₁				SEG ₁₀			
0046 ₁₆	SEG ₁₃				SEG ₁₂			
0047 ₁₆	SEG ₁₅				SEG ₁₄			
0048 ₁₆	SEG ₁₇				SEG ₁₆			
0049 ₁₆	SEG ₁₉				SEG ₁₈			
004A ₁₆	SEG ₂₁				SEG ₂₀			
004B ₁₆	SEG ₂₃				SEG ₂₂			
	COM ₃	COM ₂	COM ₁	COM ₀	COM ₃	COM ₂	COM ₁	COM ₀

Fig. 43 LCD display RAM map

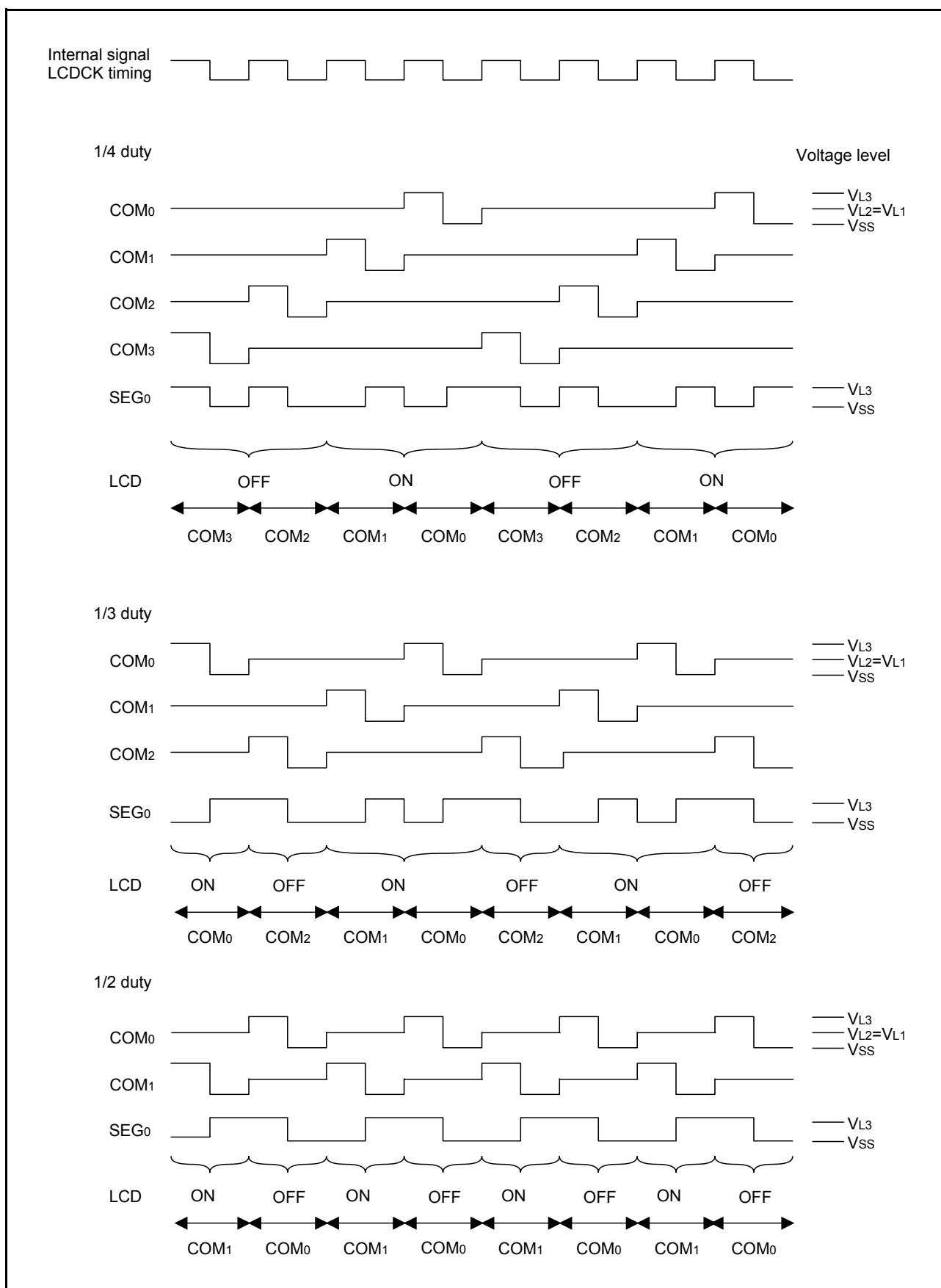


Fig. 44 LCD drive waveform (1/2 bias, type A)

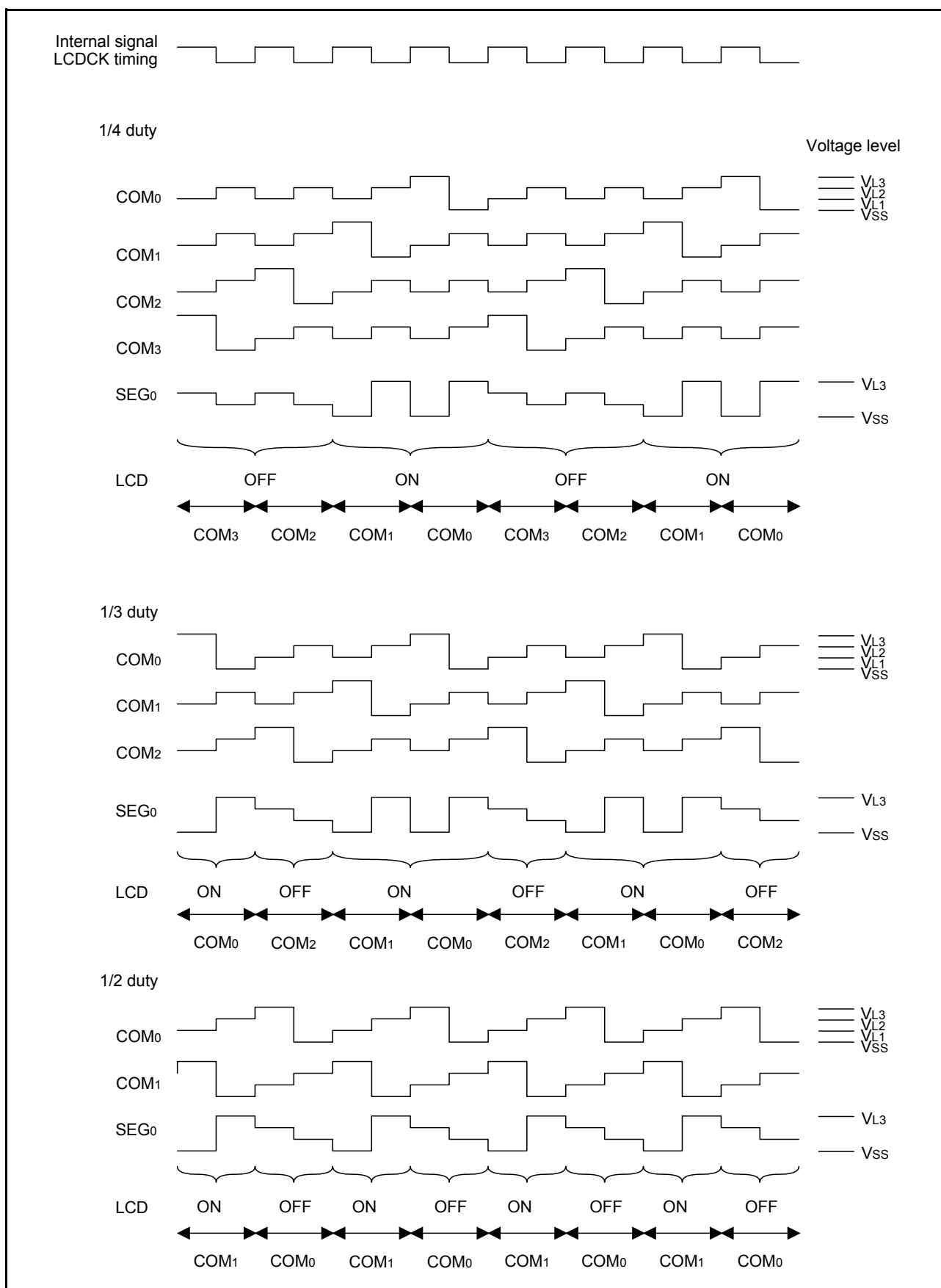


Fig. 45 LCD drive waveform (1/3 bias, type A)

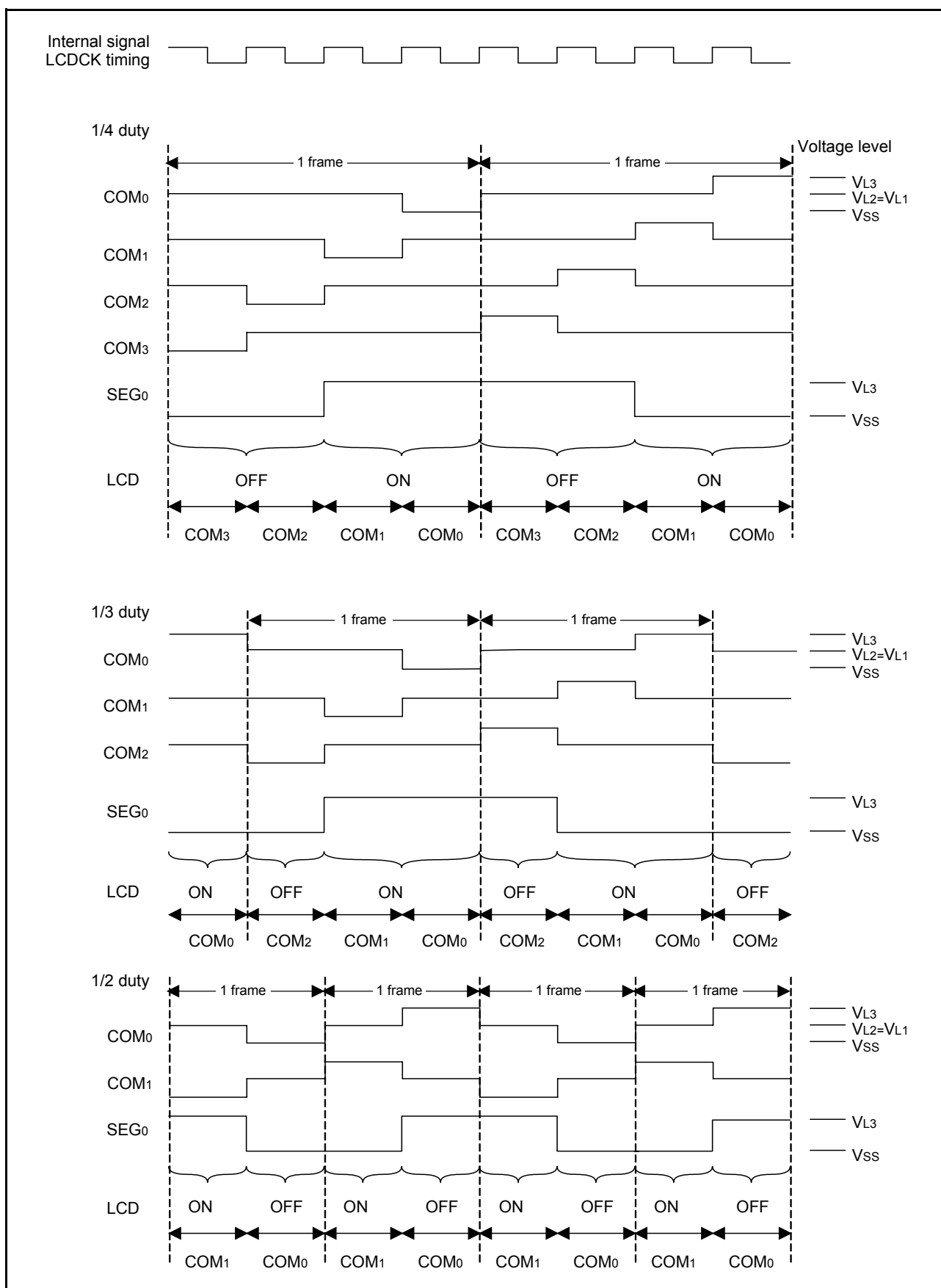


Fig. 46 LCD drive waveform (1/2 bias, type B)

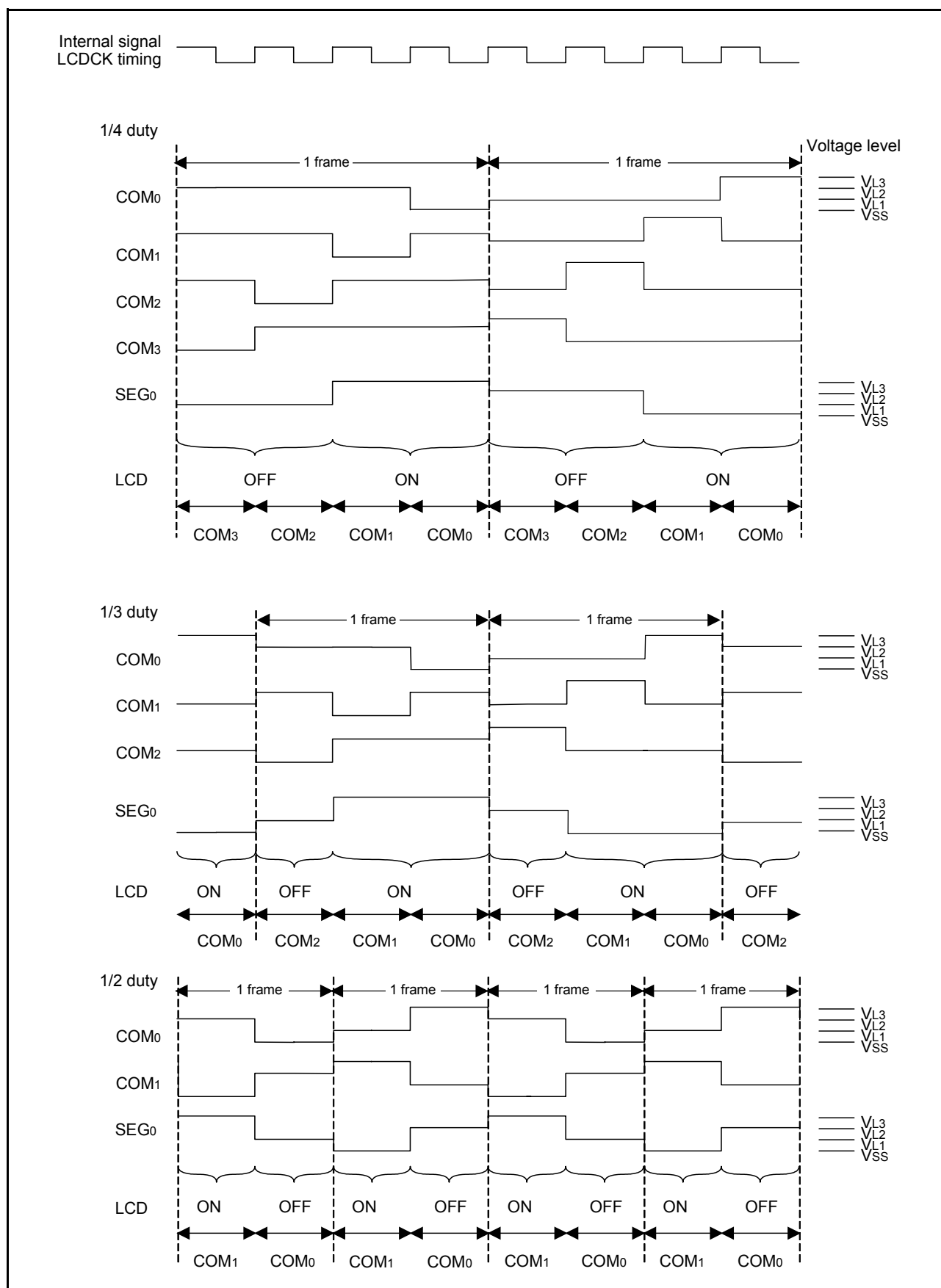


Fig. 47 LCD drive waveform (1/3 bias, type B)

ROM CORRECTION FUNCTION

A part of program in ROM can be corrected.

Set the start address of the corrected ROM data (i.e. an Op code address of the beginning instruction) to the ROM correction address high-order and low-order registers.

When the program is being executed and the value of the program counter matches with the set address value in the ROM correction address registers, the program is branched to the ROM correction vectors and then the correction program can be executed by setting it to the ROM correction vectors.

Use the JMP instruction (3-byte instruction) to return the main program from the correction program.

The correctable area is up to two. There are two vectors for ROM correction.

Also, ROM correction vector can be selected from the RAM area or ROM area by the ROM correction memory selection bit.

	RAM area RC2 = "0"	ROM area RC2 = "1"
Vector 1	address 0100 ₁₆	address F100 ₁₆
Vector 2	address 0120 ₁₆	address F120 ₁₆

The ROM correction function is controlled by the ROM correction address 1 enable bit and ROM correction address 2 enable bit.

If the ROM correction function is not used, the ROM correction vector may be used as normal RAM/ROM. When using the ROM correction vector as normal RAM/ROM, make sure to set bits 1 and 0 in the ROM correction enable register to "0" (Disable).

<Notes>

1. When using the ROM correction function, set the ROM correction address registers and then enable the ROM correction with the ROM correction enable register.
2. Do not set addresses other than the ROM area in the ROM correction address registers.
Do not set the same ROM correction addresses in both the ROM correction address registers 1 and ROM correction address registers 2.
3. It is necessary to contain the process for ROM correction in the program.

ROM correction address 1 high-order register (RCA1H)	0FF8 ₁₆
ROM correction address 1 low-order register (RCA1L)	0FF9 ₁₆
ROM correction address 2 high-order register (RCA2H)	0FFA ₁₆
ROM correction address 2 low-order register (RCA2L)	0FFB ₁₆

Note: Do not set address other than ROM area.

Fig. 48 ROM correction address register

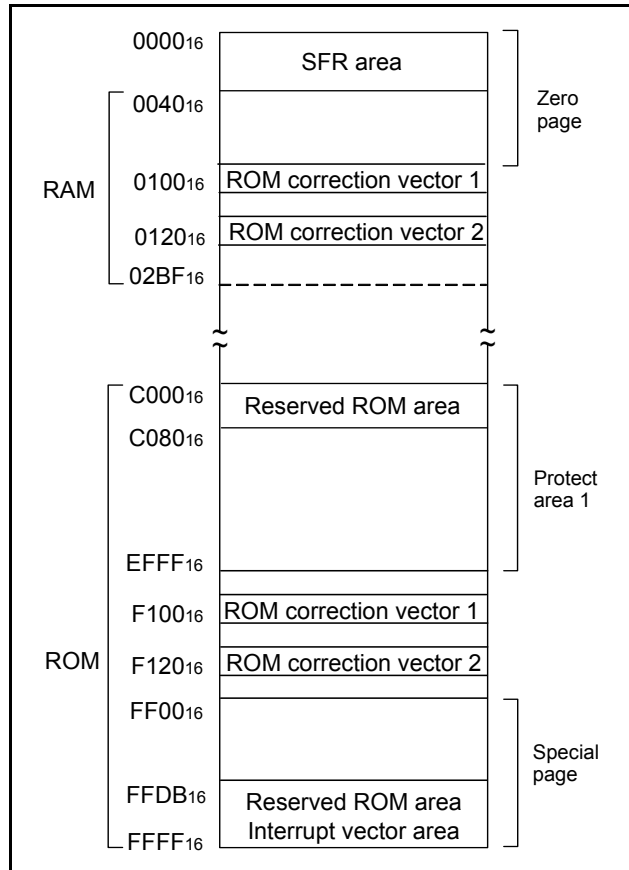


Fig. 49 Memory map of M38D24G4

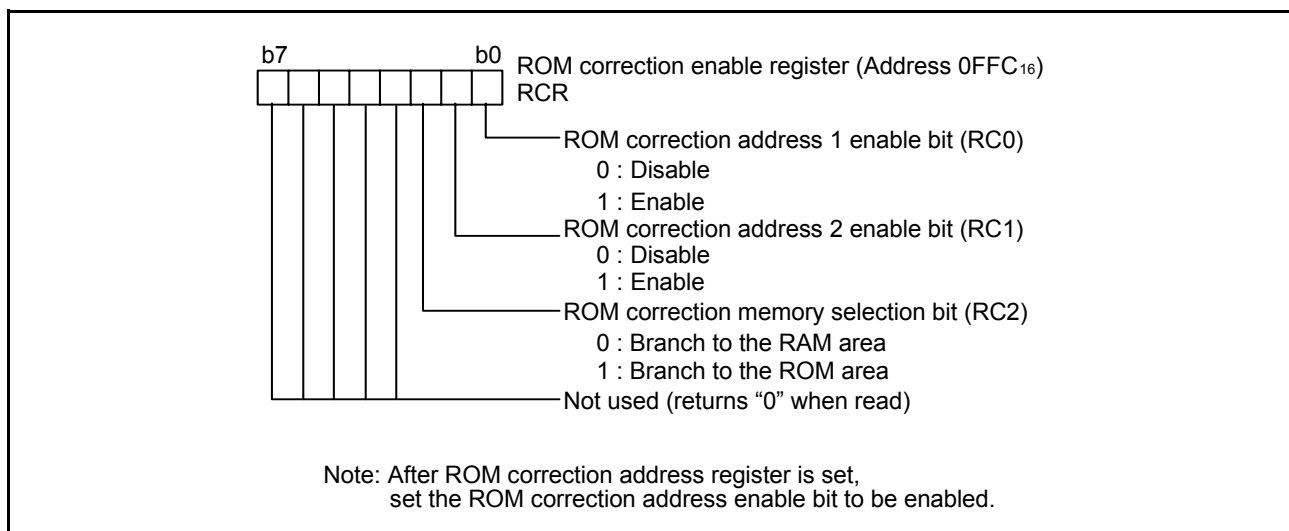


Fig. 50 Structure of ROM correction enable register

WATCHDOG TIMER

The watchdog timer gives a mean of returning to the reset status when a program cannot run on a normal loop (for example, because of a software run-away). The watchdog timer consists of an 8-bit counter.

• Initial Value of Watchdog Timer

At reset or writing to the watchdog timer control register, each watchdog timer is set to "FF16". Instructions such as STA, LDM and CLB to generate the write signals can be used. The written data in bits 7, 6 or 5 are not valid, and the above values are set.

Bits 7 to 5 can be rewritten only once after releasing reset. After rewriting it is disable to write any data to this bit. This bit becomes "0" after reset.

• Standard Operation of Watchdog Timer

The watchdog timer is in the stop state at reset and the watchdog timer starts to count down by writing an optional value in the watchdog timer control register. An internal reset occurs at an underflow of the watchdog timer. Then, reset is released after the reset release time is elapsed, the program starts from the reset vector address.

Normally, writing to the watchdog timer control register before an underflow of the watchdog timer is programmed. If writing to the watchdog timer control register is not executed, the watchdog timer does not operate.

When reading the watchdog timer control register is executed, the contents of the high-order 5-bit counter, the count source selection bit 2 (bit 5), the STP instruction function selection bit (bit 6), and the count source selection bit (bit 7) are read out.

• Bit 6 of Watchdog Timer Control Register

- When bit 6 of the watchdog timer control register is "0", the MCU enters the stop mode by execution of STP instruction. Just after releasing the stop mode, the watchdog timer restarts counting (Note 1). When executing the WIT instruction, the watchdog timer does not stop.
- When bit 6 is "1", execution of STP instruction causes an internal reset. When this bit is set to "1" once, it cannot be rewritten to "0" by program. Bit 6 is "0" at reset.
- The time until the underflow of the watchdog timer register after writing to the watchdog timer control register is executed is as follows (when the bit 7 of the watchdog timer control register is "0");
- at XIN mode ($f(XIN) = 8 \text{ MHz}$): 32.768 ms
- at low-speed mode ($f(XCIN) = 32 \text{ KHz}$): 8.19s

<Notes>

- The watchdog timer continues to count even during the wait time set by timer 1 and timer 2 to release the stop state and in the wait mode. Accordingly, write to the watchdog timer control register to not underflow the watchdog timer in this time.
- When the on-chip oscillator is selected by the watchdog timer count source selection bit 2, the on-chip oscillator forcibly oscillates and it cannot be stopped. Also, in this time, set the STP instruction function selection bit to "1" at this time.
Select "0" (ϕ SOURCE) the watchdog timer count source selection bit 2 at the system which on-chip oscillator is stopped.

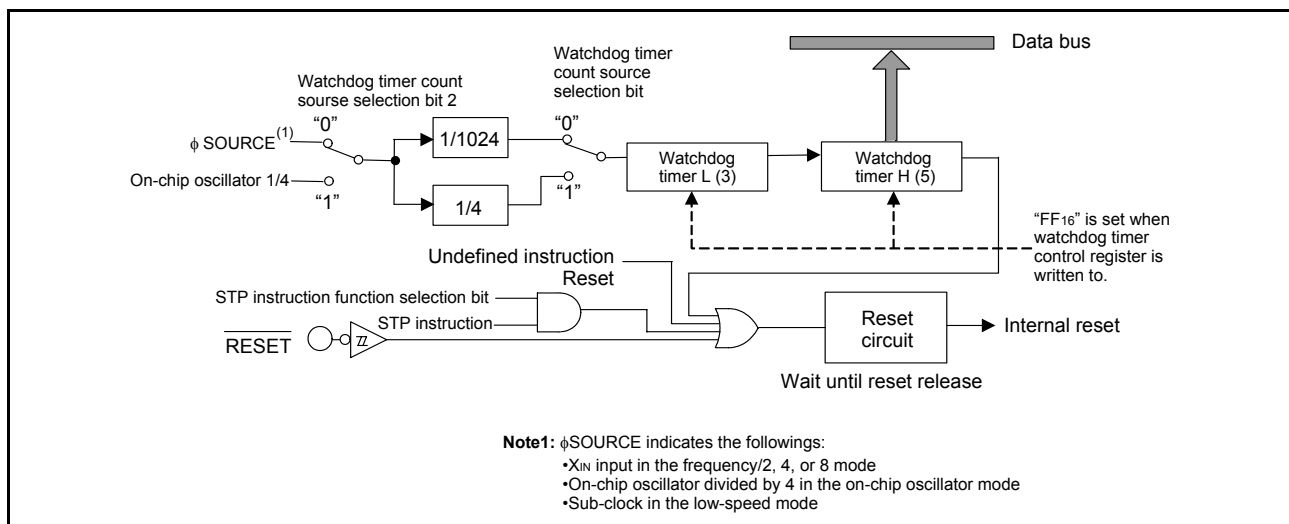


Fig. 51 Block diagram of watchdog timer

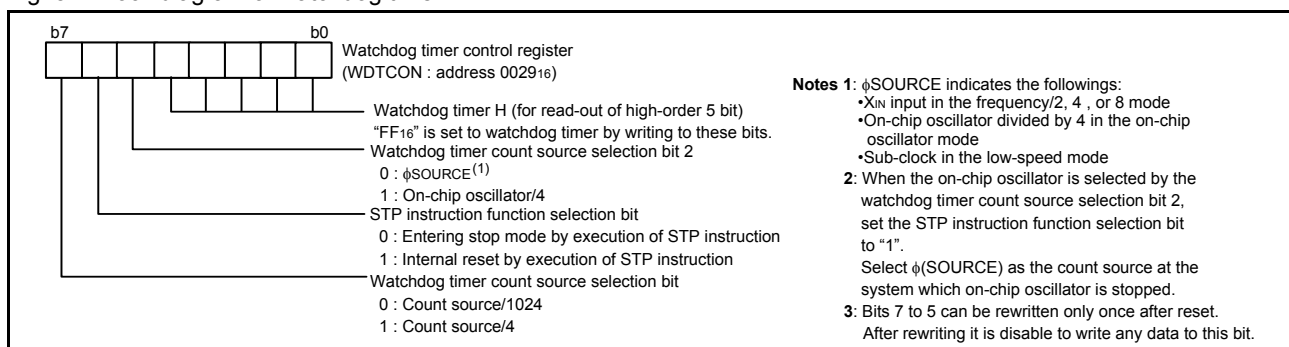


Fig. 52 Structure of watchdog timer control register

CLOCK OUTPUT FUNCTION

A system clock ϕ can be output from I/O port P36. The triple function of I/O port, timer 2 output function and system clock ϕ output function is performed by the clock output control register (address 0FF3₁₆) and the timer 2 output selection bit of the timer 12 mode register (address 0025₁₆).

In order to output a system clock ϕ from I/O port P36, set the timer 2 output selection bit and bit 0 of the clock output control register to "1".

When the clock output function is selected, a clock is output while the direction register of port P36 is set to the output mode. P36 is switched to the port output or the output (timer 2 output and the clock output) except port at the cycle after the timer 2 output control bit is switched.

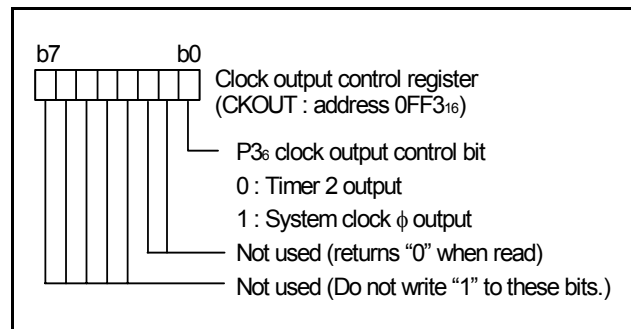


Fig. 53 Structure of clock output control register

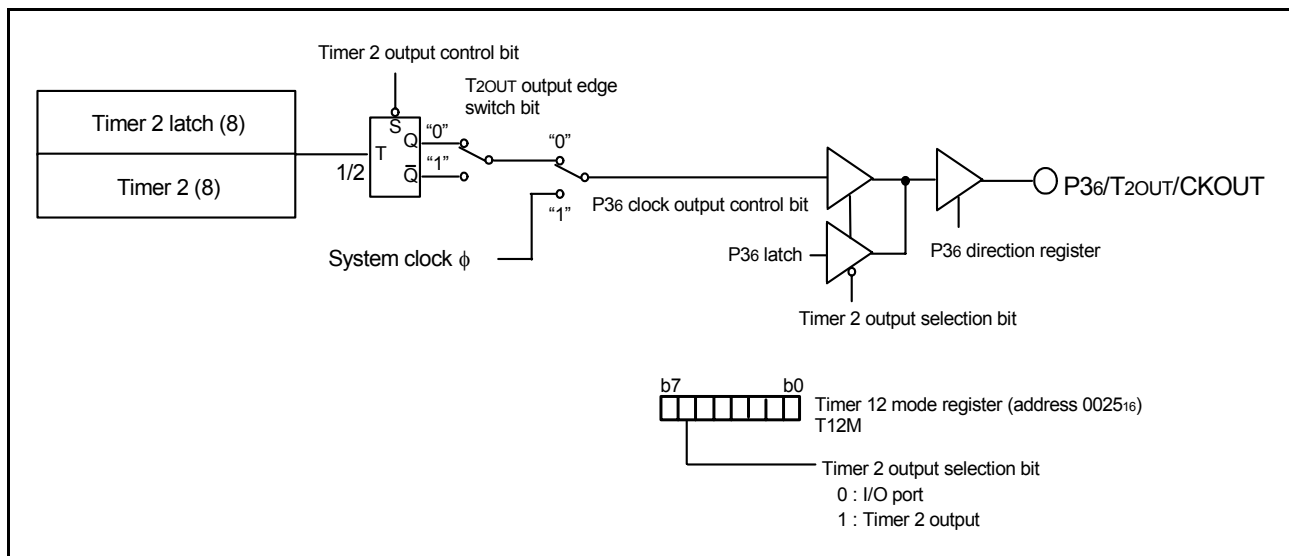


Fig. 54 Block diagram of clock output function

Other function registers

[RRF register (RRFR)]

The RRF register (address 0012₁₆) is the 8-bit register and does not have the control function.

As for the value written in this register, high-order 4 bits and low-order 4 bits interchange.

It is initialized after reset.

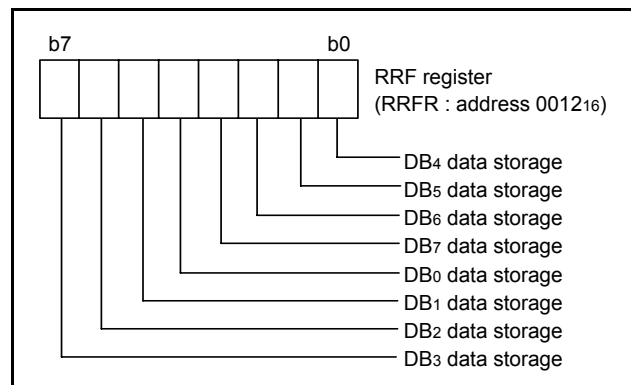


Fig. 55 Structure of RRF register

RESET CIRCUIT

To reset the microcomputer, $\overline{\text{RESET}}$ pin should be held at an “L” level for 2 μs or more. Then the $\overline{\text{RESET}}$ pin is returned to an “H” level (the power source voltage should be between V_{CC} (min.) and 5.5 V), reset is released.

After the reset is completed, the program starts from the address FFFD₁₆ (high-order byte) and address FFFC₁₆ (low-order byte). Make sure that the reset input voltage meets V_{IL} spec. When a power source voltage passes V_{CC} (min.). In the flash memory version, input to the $\overline{\text{RESET}}$ pin in the following procedure.

- When power source is stabilized
 - (1) Input “L” level for 2 μs or more to $\overline{\text{RESET}}$ pin.
 - (2) Input “H” level to $\overline{\text{RESET}}$ pin.
- At power-on
 - (1) Input “L” level to $\overline{\text{RESET}}$ pin.
 - (2) Increase the power source voltage to 2.7 V.
 - (3) Wait for $t_d(\text{P-R})$ until internal power source has stabilized.
 - (4) Input “H” level to $\overline{\text{RESET}}$ pin.

In the QzROM version, the input level applied to the OSCSEL pin is determined when the $\overline{\text{RESET}}$ pin changes from “L” to “H”.

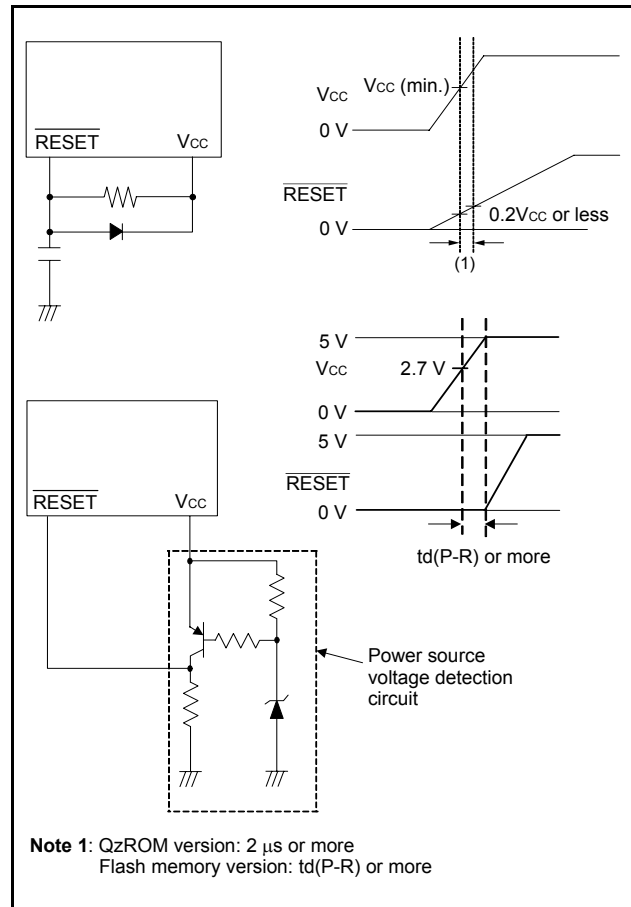


Fig. 56 Reset circuit example

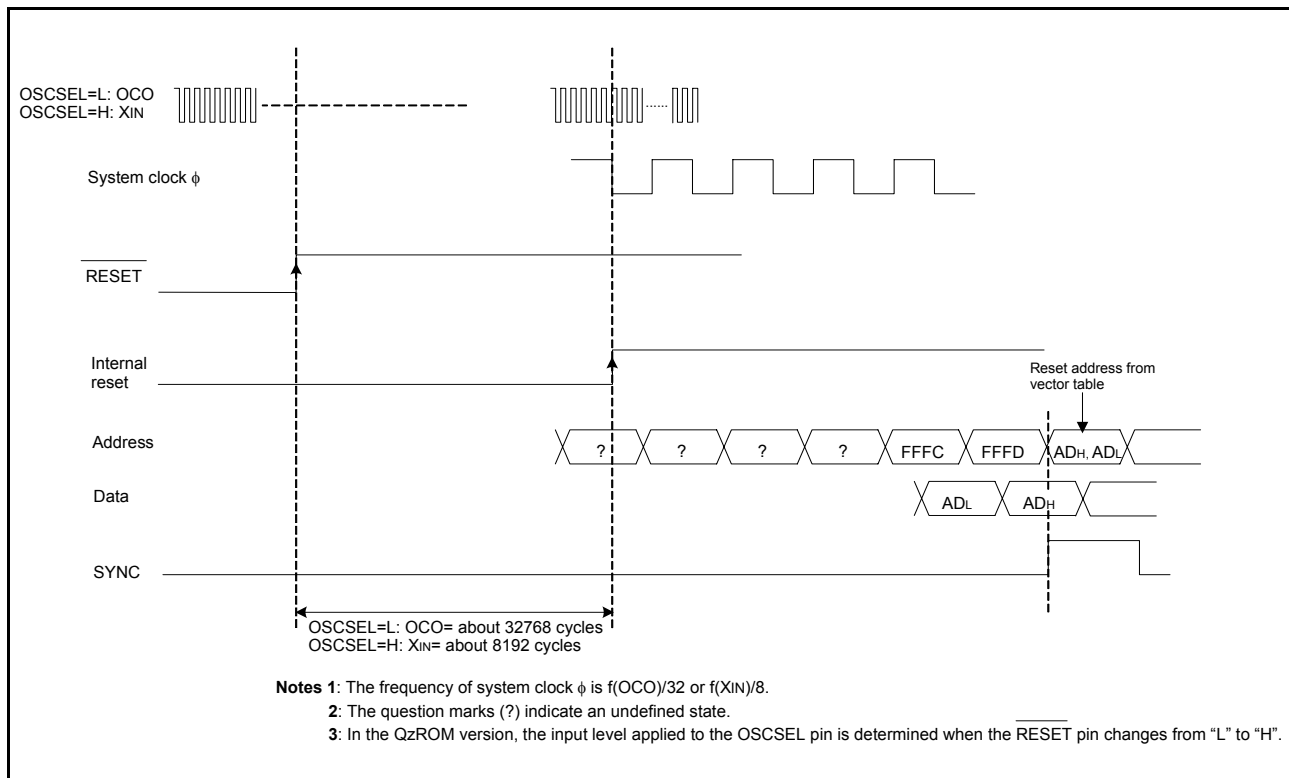


Fig. 57 Reset sequence

	Address	Register contents		Address	Register contents
(1) Port P0	0000 ₁₆	00 ₁₆	(36) Timer X (low-order)	002A ₁₆	FF ₁₆
(2) Port P0 direction register	0001 ₁₆	00 ₁₆	(37) Timer X (high-order)	002B ₁₆	FF ₁₆
(3) Port P1	0002 ₁₆	00 ₁₆	(38) Timer X (extension)	002C ₁₆	00 ₁₆
(4) Port P1 direction register	0003 ₁₆	00 ₁₆	(39) Timer X mode register	002D ₁₆	00 ₁₆
(5) Port P2	0004 ₁₆	00 ₁₆	(40) Timer X control register 1	002E ₁₆	00 ₁₆
(6) Port P2 direction register	0005 ₁₆	00 ₁₆	(41) Timer X control register 2	002F ₁₆	00 ₁₆
(7) Port P3	0006 ₁₆	00 ₁₆	(42) Compare register 1 (low-order)	0030 ₁₆	00 ₁₆
(8) Port P3 direction register	0007 ₁₆	00 ₁₆	(43) Compare register 1 (high-order)	0031 ₁₆	00 ₁₆
(9) Port P4	0008 ₁₆	00 ₁₆	(44) Compare register 2 (low-order)	0032 ₁₆	00 ₁₆
(10) Port P4 direction register	0009 ₁₆	00 ₁₆	(45) Compare register 2 (high-order)	0033 ₁₆	00 ₁₆
(11) Port P5	000A ₁₆	00 ₁₆	(46) Compare register 3 (low-order)	0034 ₁₆	00 ₁₆
(12) Port P5 direction register	000B ₁₆	00 ₁₆	(47) Compare register 3 (high-order)	0035 ₁₆	00 ₁₆
(13) Port P6	000C ₁₆	00 ₁₆	(48) Timer Y (low-order)	0036 ₁₆	FF ₁₆
(14) Port P6 direction register	000D ₁₆	00 ₁₆	(49) Timer Y (high-order)	0037 ₁₆	FF ₁₆
(15) Oscillation output control register	0010 ₁₆	00 ₁₆	(50) Timer Y mode register	0038 ₁₆	00 ₁₆
(16) CPU mode register 2	0011 ₁₆	0 0 0 0 0 0 0 *	(51) Timer Y control register	0039 ₁₆	00 ₁₆
(17) RRF register	0012 ₁₆	00 ₁₆	(52) Interrupt edge selection register	003A ₁₆	00 ₁₆
(18) LCD mode register	0013 ₁₆	00 ₁₆	(53) CPU mode register	003B ₁₆	* 1 * 0 0 0 0 0
(19) LCD power control register	0014 ₁₆	00 ₁₆	(54) Interrupt request register 1	003C ₁₆	00 ₁₆
(20) AD control register	0015 ₁₆	08 ₁₆	(55) Interrupt request register 2	003D ₁₆	00 ₁₆
(21) Serial I/O1 status register	0019 ₁₆	1 0 0 0 0 0 0 0	(56) Interrupt control register 1	003E ₁₆	00 ₁₆
(22) Serial I/O1 control register	001A ₁₆	00 ₁₆	(57) Interrupt control register 2	003F ₁₆	00 ₁₆
(23) UART1 control register	001B ₁₆	1 1 1 0 0 0 0 0	(58) PULL register	0FF0 ₁₆	00 ₁₆
(24) Serial I/O2 status register	001E ₁₆	1 0 0 0 0 0 0 0	(59) UART2 control register	0FF1 ₁₆	1 1 1 0 0 0 0 0
(25) Serial I/O2 control register	001F ₁₆	00 ₁₆	(60) Clock output control register	0FF3 ₁₆	00 ₁₆
(26) Timer 1	0020 ₁₆	FF ₁₆	(61) Segment output disable register 0	0FF4 ₁₆	FF ₁₆
(27) Timer 2	0021 ₁₆	01 ₁₆	(62) Segment output disable register 1	0FF5 ₁₆	FF ₁₆
(28) Timer 3	0022 ₁₆	FF ₁₆	(63) Segment output disable register 2	0FF6 ₁₆	FF ₁₆
(29) Timer 4	0023 ₁₆	FF ₁₆	(64) Key input control register	0FF7 ₁₆	00 ₁₆
(30) PWM01 register	0024 ₁₆	00 ₁₆	(65) ROM correction address 1 high-order register (RCA1H)	0FF8 ₁₆	00 ₁₆
(31) Timer 12 mode register	0025 ₁₆	00 ₁₆	(66) ROM correction address 1 low-order register (RCA1L)	0FF9 ₁₆	00 ₁₆
(32) Timer 34 mode register	0026 ₁₆	00 ₁₆	(67) ROM correction address 2 high-order register (RCA2H)	0FFA ₁₆	00 ₁₆
(33) Timer 1234 mode register	0027 ₁₆	00 ₁₆	(68) ROM correction address 2 low-order register (RC2AL)	0FFB ₁₆	00 ₁₆
(34) Timer 1234 frequency division selection register	0028 ₁₆	00 ₁₆	(69) ROM correction enable register	0FFC ₁₆	00 ₁₆
(35) Watchdog timer control register	0029 ₁₆	0 0 0 1 1 1 1 1	(70) Processor status register (PS)		x x x x x 1 x x
			(71) Program counter (PCH)		FFFD ₁₆ contents
				(PCL)	FFFC ₁₆ contents

x: Not fixed
 *: Depends on OSCSEL setting at the QzROM version.
 In the flash memory version, the CPU mode register 2 (address 0011₁₆), is set to "00₁₆" and the CPU mode register (address 003B₁₆) is set to "E0₁₆". Since the initial values for other than above mentioned registers and RAM contents are indefinite at reset, they must be set.

Fig. 58 Internal status at reset

CLOCK GENERATING CIRCUIT

The oscillation circuit of 38D2 Group can be formed by connecting an oscillator, capacitor and resistor between XIN and XOUT (XCIN and XCOUT). To supply a clock signal externally, input it to the XIN pin and make the XOUT pin open. The clocks that are externally generated cannot be directly input to XCIN. Use the circuit constants in accordance with the oscillator manufacturer's recommended values. No external resistor is needed between XIN and XOUT since a feed-back resistor exists on-chip. (An external feed-back resistor may be needed depending on conditions.) However, an about 10 MΩ external feedback resistor is needed between XCIN and XCOUT. The 38D2 Group operation mode immediately after reset depends on the OSCSEL pin state in the QzROM version. When the OSCSEL pin state is GND level, the only on-chip oscillator starts oscillating. The XIN-XOUT oscillation stops oscillating, and XCIN and XCOUT pins function as I/O ports. Flash memory version as same.

When the OSCSEL pin state is VCC level, the XIN-XOUT oscillation divided by 8 starts oscillating. The on-chip oscillator stops oscillating, and the XCIN and XCOUT pins function as I/O ports.

Note the following in each mode.

• XIN Mode

The XIN-XOUT oscillation does not stop even if the XIN-XOUT oscillation stop bit is set to "1".

• Low-Speed Mode

The XCIN-XCOUT oscillation stops if the port Xc switch bit is set to "0".

• On-Chip Oscillator Mode

Even if the on-chip oscillator stop bit is set to "1", the on-chip oscillator oscillation does not stop in the flash memory version, but stops in the QzROM version.

• Frequency Control

(1) On-chip oscillation mode

The system clock ϕ is the on-chip oscillator oscillation divided by 32.

(2) XIN mode

Frequency/2 mode, frequency /4 mode, and frequency/8 mode are collectively referred as XIN mode.

- Frequency/8 Mode

The system clock ϕ is the frequency of XIN divided by 8.

- Frequency/4 Mode

The system clock ϕ is the frequency of XIN divided by 4.

- Frequency/2 Mode

The system clock ϕ is half the frequency of XIN.

(3) Low-speed Mode

The system clock ϕ is half the frequency of sub clock.

After reset and when system returns from the stop mode, the operation mode depends on the OSCSEL pin state in the QzROM version and the flash memory version operation mode is the on-chip oscillator mode.

When the RESET pin changes from "L" to "H" and when the STP instruction is executed, determine the input level applied to the OSCSEL pin.

Refer to the clock state transition diagram for the setting of transition to each mode.

The XIN-OUT oscillation is controlled by the bit 5 of CPUM, and the sub-clock oscillation is controlled by the bit 4 of CPUM and the on-chip oscillator oscillation is controlled by the bit 0 of CPUM2.

In the on-chip oscillator mode, the oscillation by the oscillator can be stopped. In the low-speed mode, the power consumption can be reduced by stopping the XIN-XOUT oscillation.

In low-speed mode, the on-chip oscillator stops in the QzROM version regardless of the on-chip oscillator stop bit value. The on-chip oscillator does not stop in the flash memory version, so set the on-chip oscillator stop bit to "1" to stop the oscillation. Set enough time for oscillation to stabilize by programming to restart the stopped oscillation and switch the operation mode. Also, set enough time for oscillation to stabilize by programming to switch the timer count source.

<Notes on Clock Generating Circuit>

If you switch the mode between on-chip oscillator mode, XIN mode and low-speed mode, stabilize both XIN and XCIN oscillations. Especially be careful immediately after power-on and at returning from stop mode. Refer to the clock state transition diagram for the setting of transition to each mode. Set the frequency in the condition that $f(XIN) > 3 \cdot f(XCIN)$.

When the XIN mode is not used (XIN-XOUT oscillation and external clock input are not performed), connect XIN to VCC through a resistor.

• Oscillation Control

(1) Stop Mode

If the STP instruction is executed, the system clock ϕ stops at an "H" level, and main clock and sub-clock oscillators stop.

In this time, values set previously to timer 1 latch and timer 2 latch are loaded automatically to timer 1 and timer 2. Set the values * to generate the wait time required for oscillation stabilization to timer 1 latch and timer 2 latch (low-order 8 bits of timer 1 and high-order 8 bits of timer 2) before the STP instruction.

The frequency divider for timer 1 is used for the timer 1 count source, and the output of timer 1 is forcibly connected to timer 2. In this time, bits 0 to 5 of the timer 12 mode register are cleared to "0". The values of the timer 1234 frequency divider selection register are not changed.

Set the interrupt enable bits of the timer 1 and timer 2 to be disabled ("0") before executing the STP instruction.

*: Reference (Set values according to your oscillator and system.)

OSCSEL = "L" of the QzROM version and flash memory version:

.....0005₁₆ or more

OSCSEL = "H" of the QzROM version:

.....01FF₁₆ or more

When an external interrupt is received, the clock set according to the OSCSEL pin state starts oscillating in the QzROM version. The operation mode at returning is decided by the clock that set according to the OSCSEL pin state.

Bits 3, 5, 6, and 7 of CPUM and bit 0 of CPUM2 are forcibly changed by the OSCSEL pin state. In the flash memory version, the on-chip oscillator starts oscillating and the operation mode at returning is set to on-chip oscillator mode. The bit 3 of CPUM is changed to "0", bits 5, 6 and 7 of CPUM are changed to "1", and the bit 0 of CPUM2 is changed to "0" forcibly.

Oscillator restarts when reset occurs or an interrupt request is received, but the system clock ϕ is not supplied to the CPU until timer 2 underflows. This allows time for the clock circuit oscillation to stabilize.

(2) Wait Mode

If the WIT instruction is executed, only the system clock ϕ stops at an "H" state. The states of main clock, on-chip oscillator and sub clock are the same as the state before executing the WIT instruction, and oscillation does not stop. Since supply of system clock ϕ is started immediately after the interrupt is received, the instruction can be executed immediately.

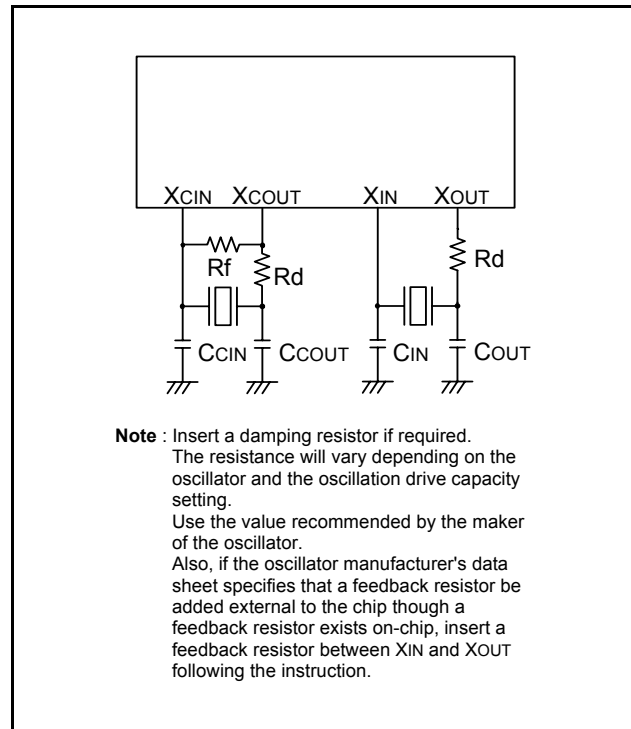


Fig. 59 Ceramic resonator circuit example

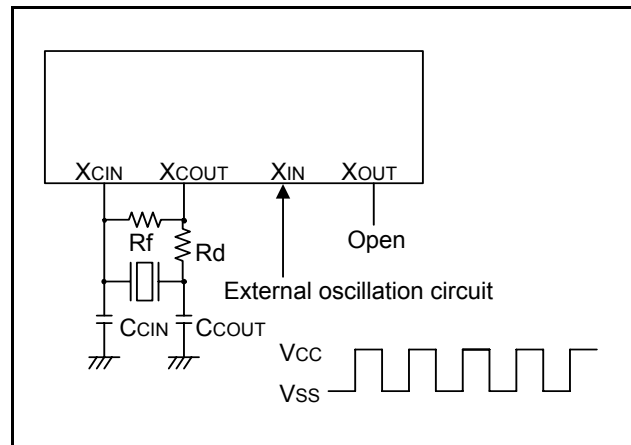


Fig. 60 External clock input circuit

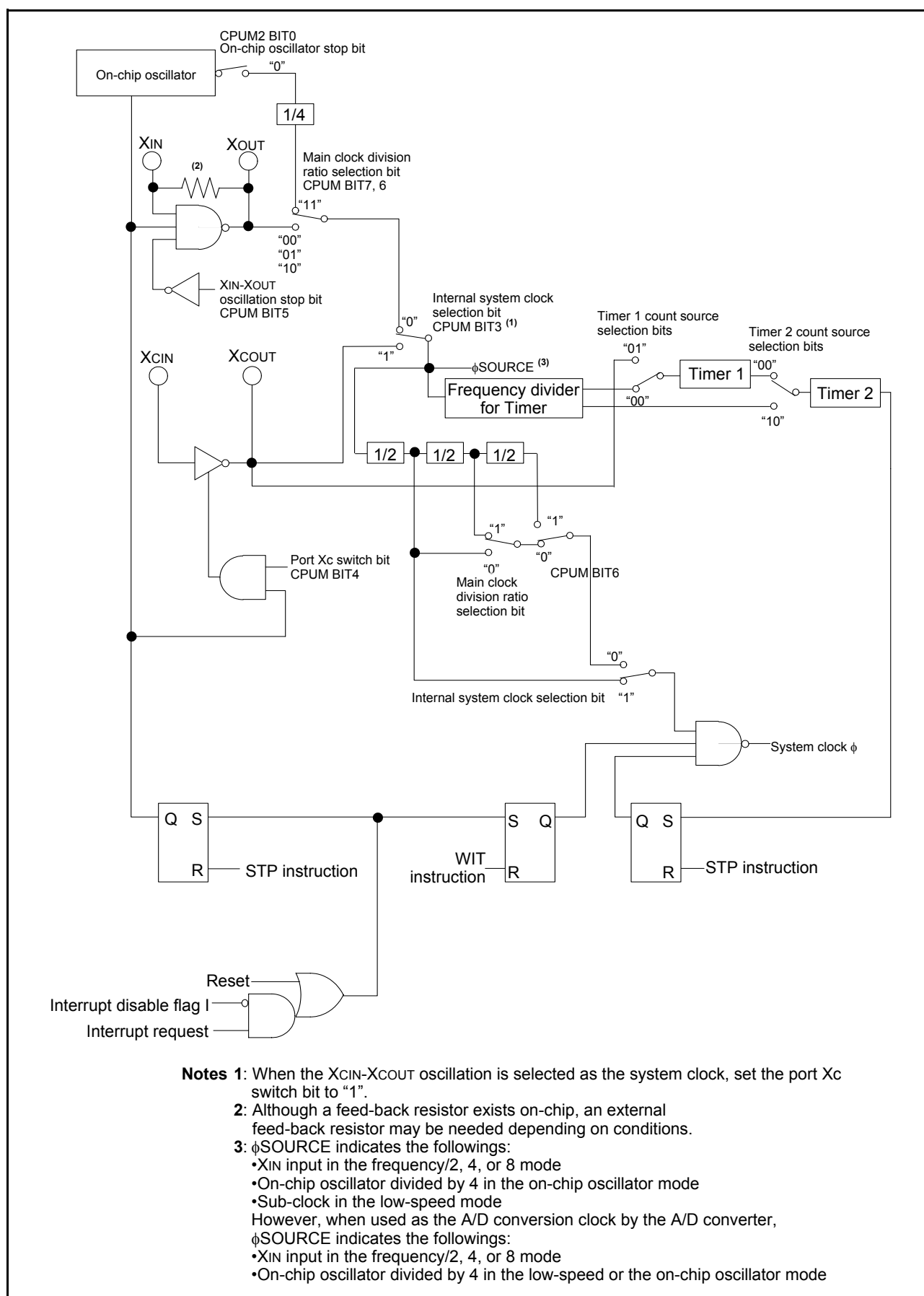


Fig. 61 Clock generating circuit block diagram

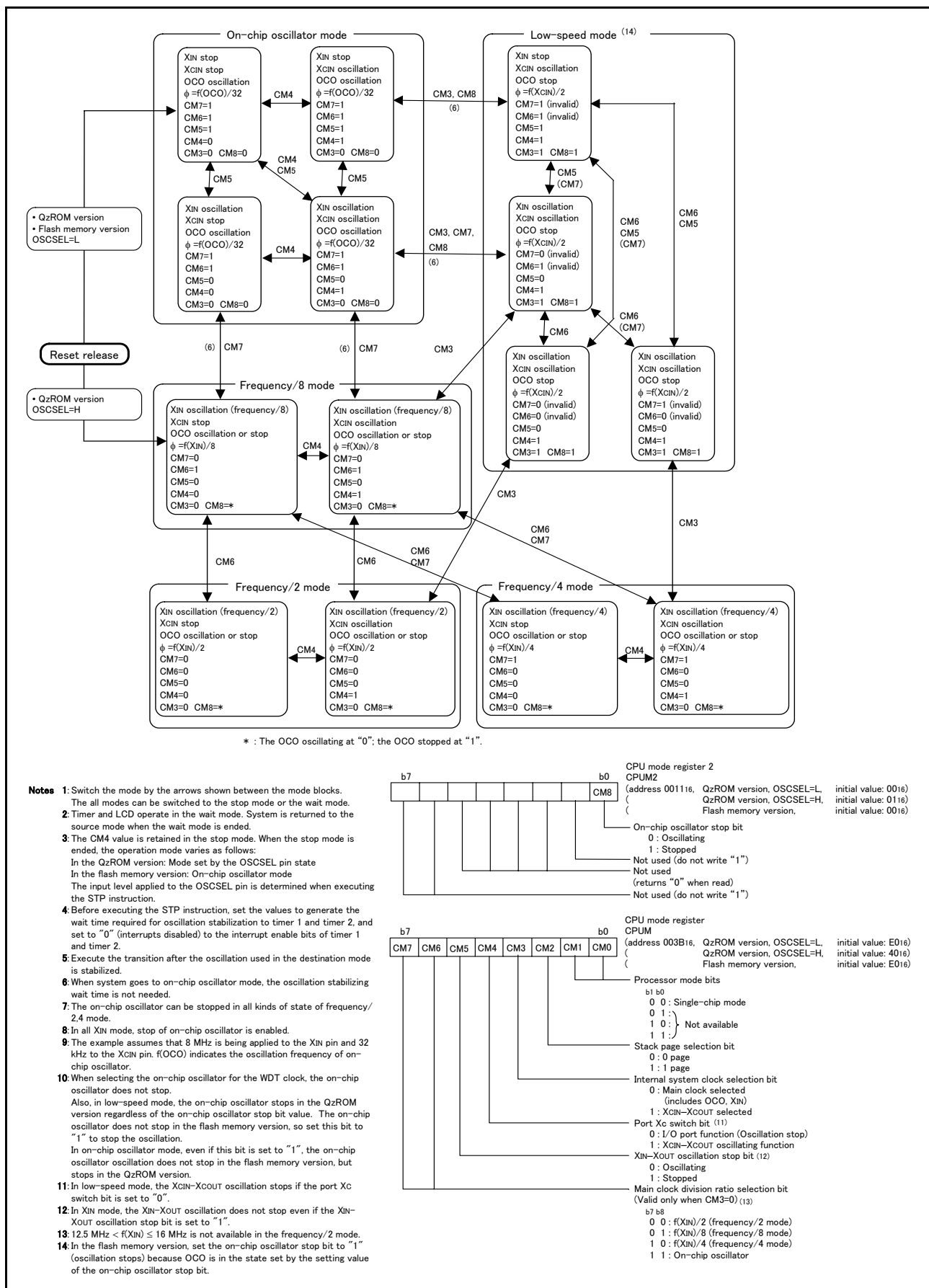


Fig. 62 State transitions of system clock

• Oscillation External Output Function

The 38D2 group has the oscillation external output function to output the rectangular waveform of the clock obtained by the oscillation circuits from P41 and P40.

In order to validate the oscillation external output function, set P40 or P41, or both to the output mode (set the corresponding direction register to “1”).

The level of the XCOUT external output signal becomes “H” by the P40/P41 oscillation output control bits (bits 0 and 1) of the oscillation output control register (address 0010₁₆) in the following states;

- the function to output the signal from the XCOUT pin externally is selected
- the sub clock (XCIN–XCOUT) is in the stop oscillating or stop mode.

Likewise, the level of the XOUT external output signal becomes “H” by the P40/P41 oscillation output control bits (bits 0 and 1) of the oscillation output control register (address 0010₁₆) in the following states;

- the function to output the signal from the XOUT pin externally is selected
- the main clock (XIN–XOUT) is in the stop oscillating or stop mode.

<Note>

When the signal from the XOUT pin or XCOUT pin of the oscillation circuit is input directly to the circuit except this MCU and used, the system operation may be unstabilized.

In order to share the oscillation circuit safely, use the clock output from P40 and P41 by this function for the circuits except this MCU.

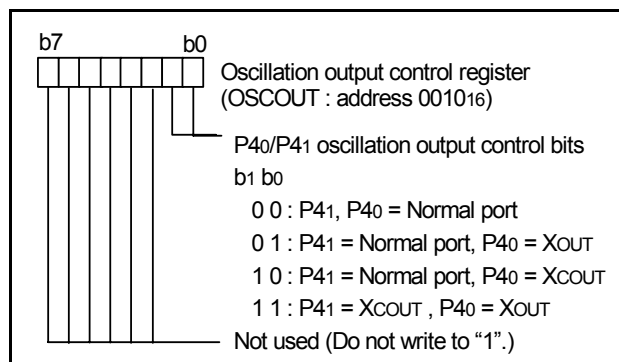


Fig. 63 Structure of oscillation output control register

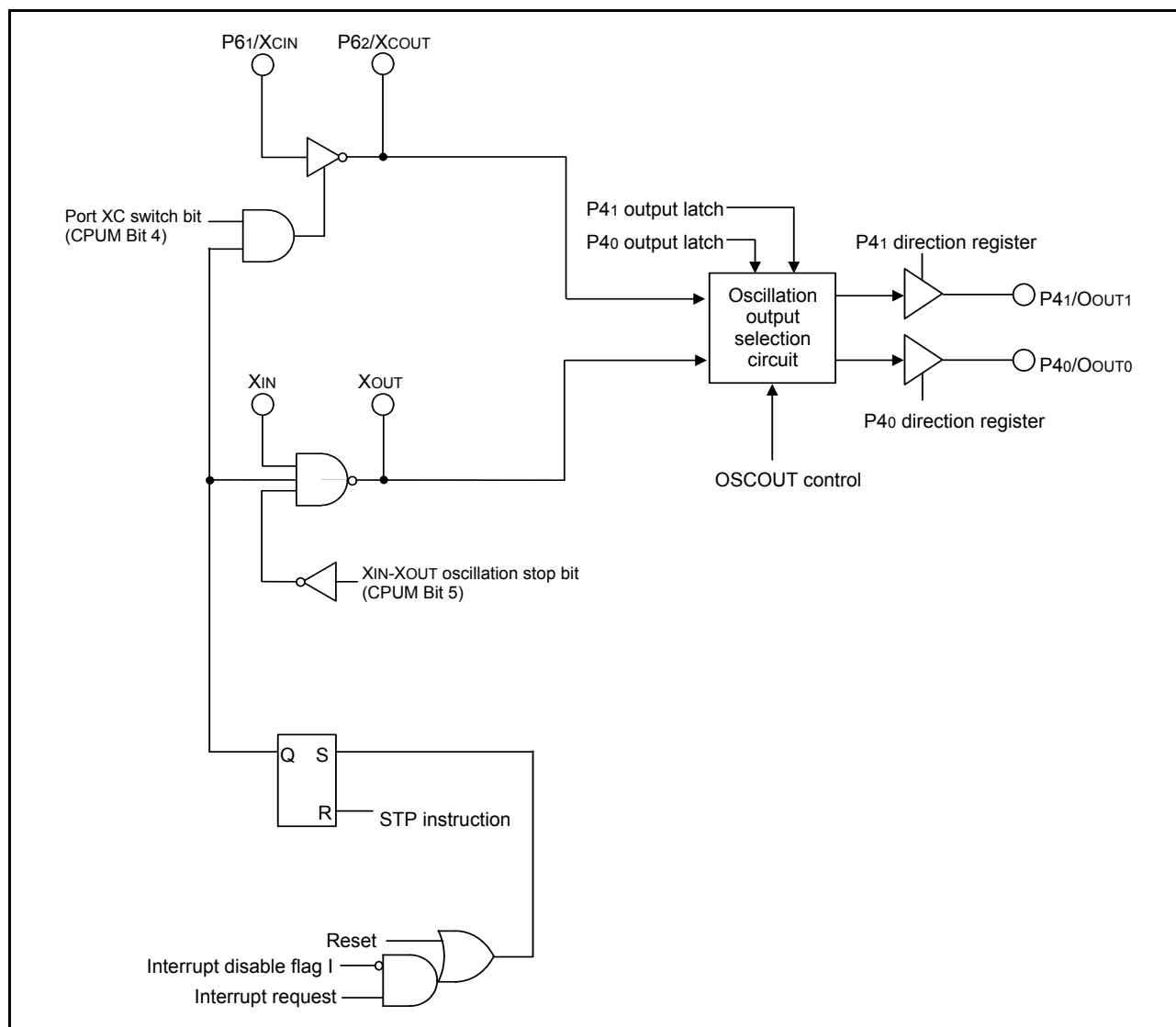


Fig. 64 Block diagram of oscillation external output function

QzROM WRITING MODE

In the QzROM writing mode, the user ROM area can be rewritten while the microcomputer is mounted on-board by using a serial programmer which is applicable for this microcomputer. Table 14 lists the pin description (QzROM writing mode) and Figure 65 shows the pin connection.

Refer to Figure 66 to Figure 69 for examples of a connection with a serial programmer.

Contact the manufacturer of your serial programmer for serial programmer. Refer to the user's manual of your serial programmer for details on how to use it.

Table 14 Pin description (QzROM writing mode)

Pin	Name	I/O	Function
VCC, VSS	Power source	Input	• Apply 2.7 to 5.5 V to VCC, and 0 V to VSS.
$\overline{\text{RESET}}$	Reset input	Input	• Reset input pin for active "L". Reset occurs when $\overline{\text{RESET}}$ pin is held at an "L" level for 16 cycles or more of XIN.
XIN	Clock input	Input	• Set the same termination as the single-chip mode.
XOUT	Clock output	Output	
VREF	Analog reference voltage	Input	• Input the reference voltage of A/D converter to VREF.
AVSS	Analog power source	Input	• Connect AVSS to VSS.
P00–P07 P10–P17 P20–P27 P33–P37 P40–P47 P50–P57 P60–P62	I/O port	I/O	• Input "H" or "L" level signal or leave the pin open.
OSCSEL	VPP input	Input	• QzROM programmable power source pin.
P32	ESDA input/output	I/O	• Serial data I/O pin.
P31	ESCLK input	Input	• Serial clock input pin.
P30	ESPGMB input	Input	• Read/program pulse input pin.

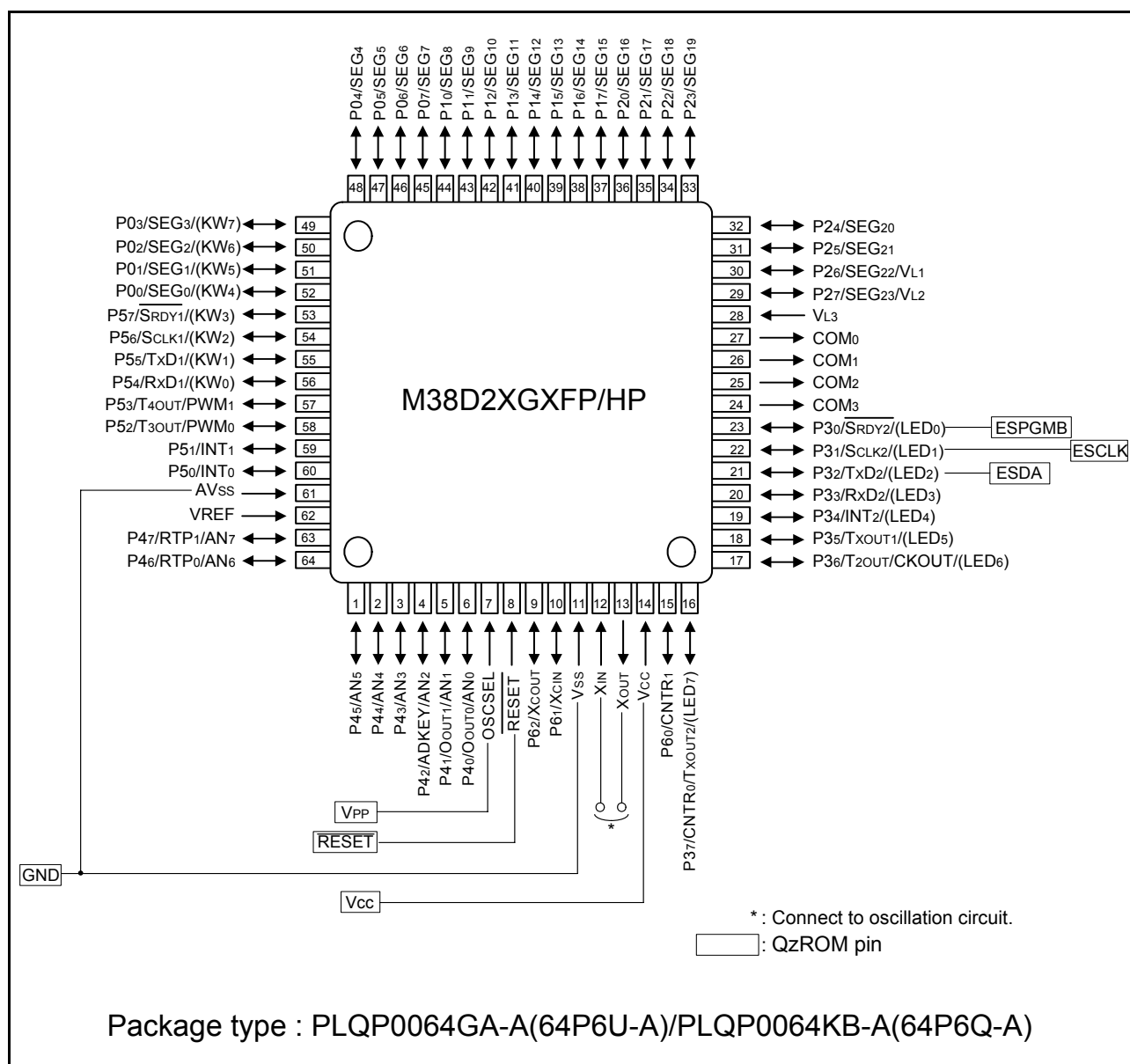


Fig. 65 Pin connection diagram

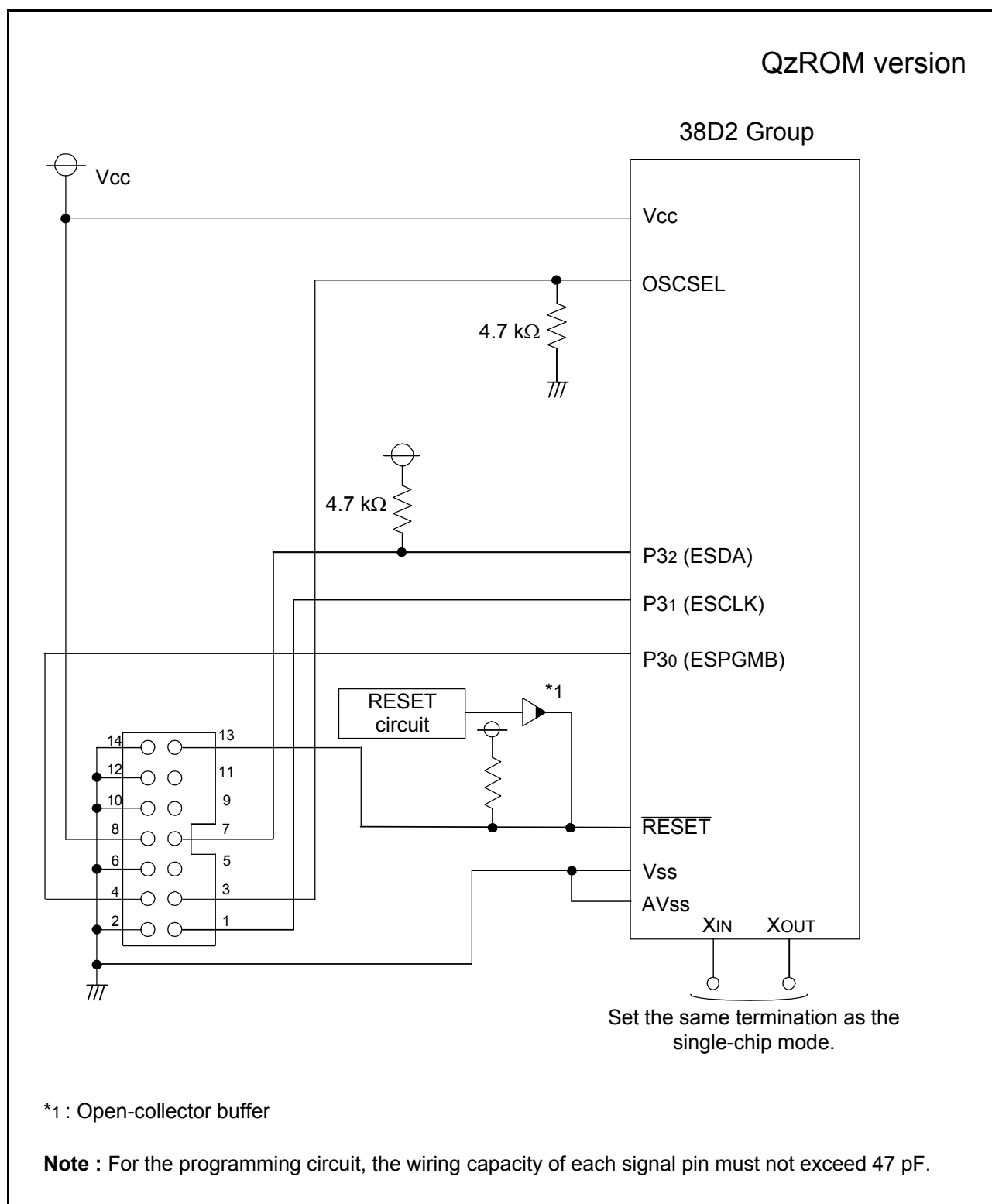


Fig. 66 When using E8 programmer, connection example (1) (OSCSEL = "L")

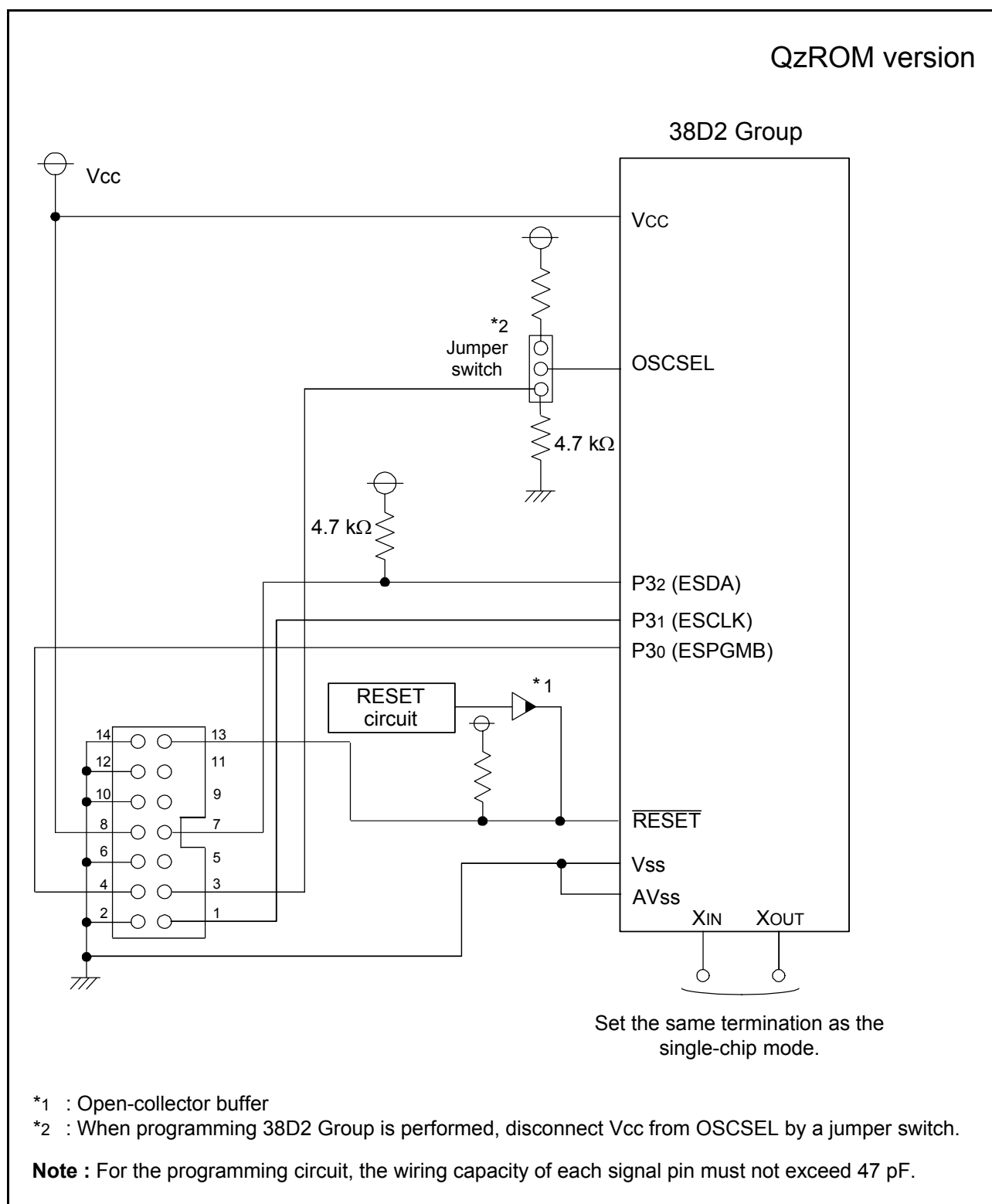


Fig. 67 When using E8 programmer, connection example (2) (OSCSEL = "H")

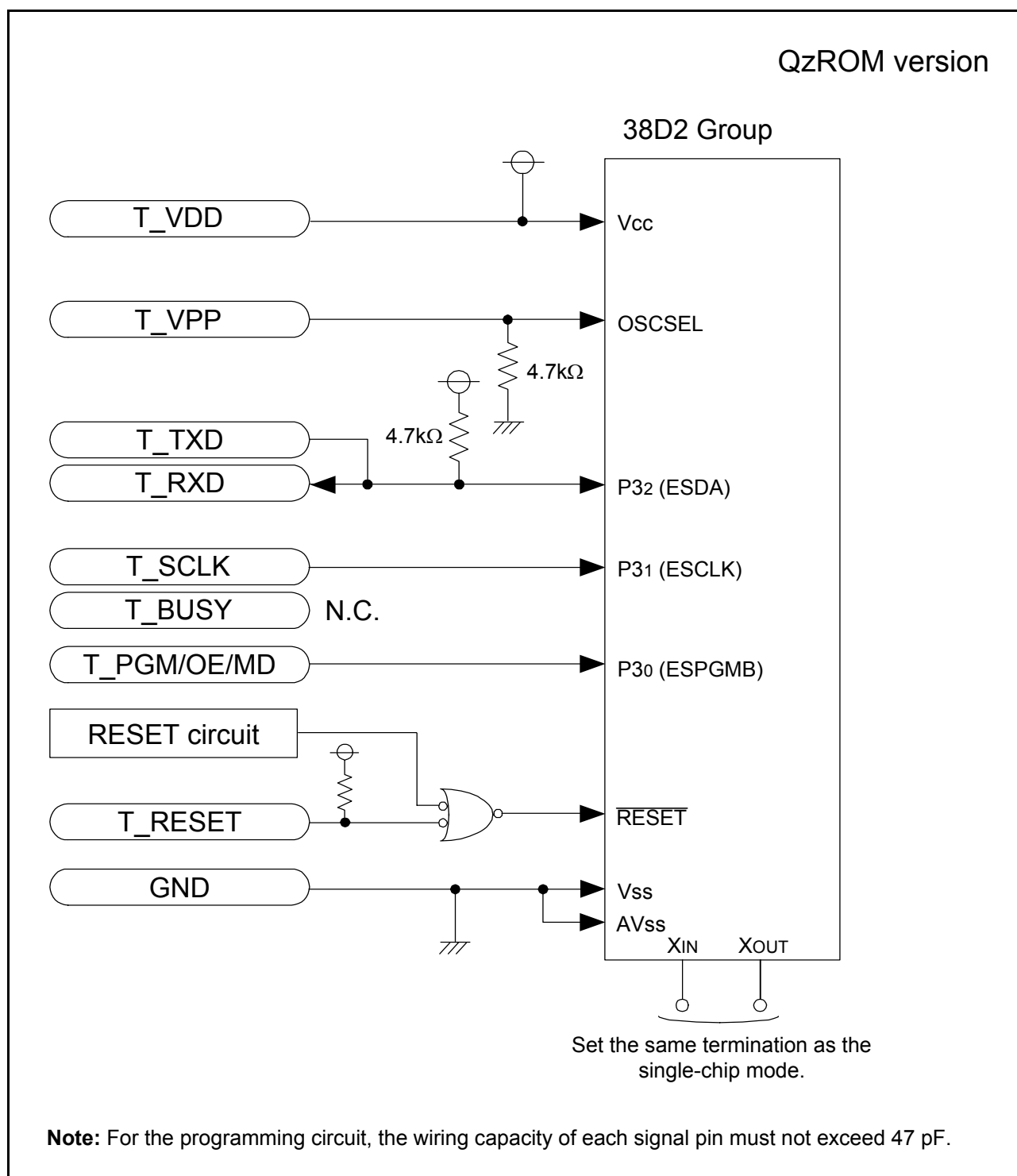


Fig. 68 When using programmer of Suisai Electronics System Co., LTD, connection example (1) (OSCSEL = "L")

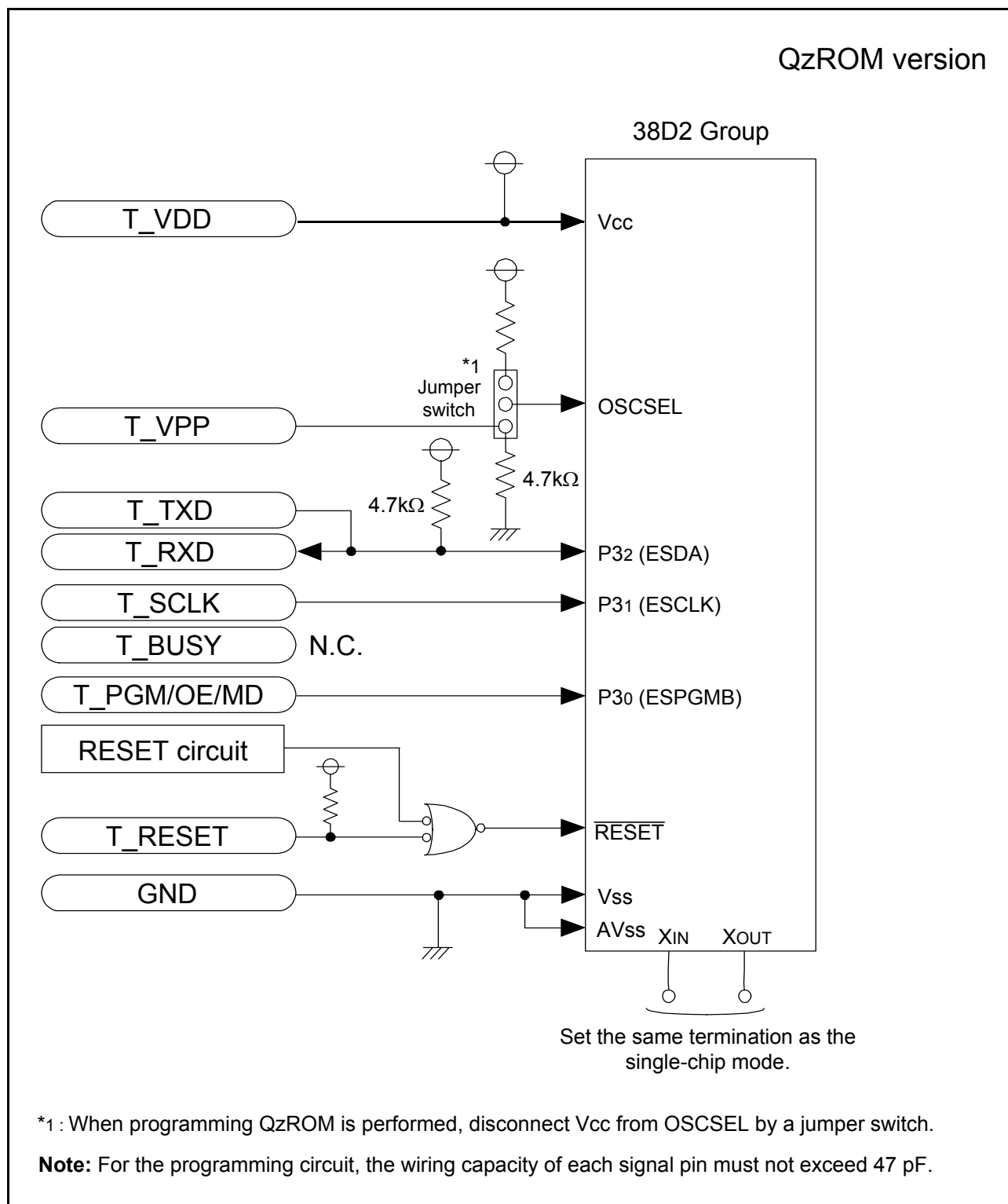


Fig. 69 When using programmer of Suisai Electronics System Co., LTD, connection example (2) (OSCSEL = "H")

FLASH MEMORY MODE

The 38D2 Group flash memory version has the flash memory that can be rewritten with a single power source.

For this flash memory, three flash memory modes are available in which to read, program, and erase: the parallel I/O and standard serial I/O modes in which the flash memory can be manipulated using a programmer and the CPU rewrite mode in which the flash memory can be manipulated by the Central Processing Unit (CPU). For details of each mode, refer to the next and after pages. Contact the manufacturer of your programmer for the programmer. Refer to the user's manual of your programmer for details on how to use it.

This flash memory version has some blocks on the flash memory as shown in Figure 70 and each block can be erased.

In addition to the ordinary User ROM area to store the MCU operation control program, the flash memory has a Boot ROM area that is used to store a program to control rewriting in CPU rewrite and standard serial I/O modes. This Boot ROM area has had a standard serial I/O mode control program stored in it when shipped from the factory. However, the user can write a rewrite control program in this area that suits the user's application system. This Boot ROM area can be rewritten in only parallel I/O mode.

Performance overview

Table 15 lists the performance overview of the 38D2 Group flash memory version.

Table 15 Performance overview of 38D2 Group flash memory version

Parameter		Function
Power source voltage (Vcc)		Vcc = 2.7 to 5.5 V
Program/Erase VPP voltage (VPP)		Vcc = 2.7 to 5.5 V
Flash memory mode		3 modes; Parallel I/O mode, Standard serial I/O mode, CPU rewrite mode
Erase block division	User ROM area/Data ROM area	Refer to Figure 70.
	Boot ROM area ⁽¹⁾	Not divided (4K bytes)
Program method		In units of bytes
Erase method		Block erase
Program/Erase control method		Program/Erase control by software command
Number of commands		5 commands
Number of program/Erase times		100
ROM code protection		Available in parallel I/O mode and standard serial I/O mode

NOTE:

1. The Boot ROM area has had a standard serial I/O mode control program stored in it when shipped from the factory. This Boot ROM area can be erased and written in only parallel I/O mode.

Boot Mode

The control program for CPU rewrite mode must be written into the User ROM or Boot ROM area in parallel I/O mode beforehand. (If the control program is written into the Boot ROM area, the standard serial I/O mode becomes unusable.) See Figure 70 for details about the Boot ROM area.

Normal microcomputer mode is entered when the microcomputer is reset with pulling CNVss pin low. In this case, the CPU starts operating using the control program in the User ROM area.

When the microcomputer is reset and the CNVss pin high after pulling the P32/TxD2 pin and CNVss pin high, the CPU starts operating (start address of program is stored into addresses FFFC₁₆ and FFFD₁₆) using the control program in the Boot ROM area. This mode is called the “Boot mode”. Also, User ROM area can be rewritten using the control program in the Boot ROM area.

Block Address

Block addresses refer to the maximum address of each block. These addresses are used in the block erase command.

CPU Rewrite Mode

In CPU rewrite mode, the internal flash memory can be operated on (read, program, or erase) under control of the Central Processing Unit (CPU).

In CPU rewrite mode, only the User ROM area shown in Figure 70 can be rewritten; the Boot ROM area cannot be rewritten. Make sure the program and block erase commands are issued for only the User ROM area and each block area.

The control program for CPU rewrite mode can be stored in either User ROM or Boot ROM area. In the CPU rewrite mode, because the flash memory cannot be read from the CPU, the rewrite control program must be transferred to internal RAM area before it can be executed.

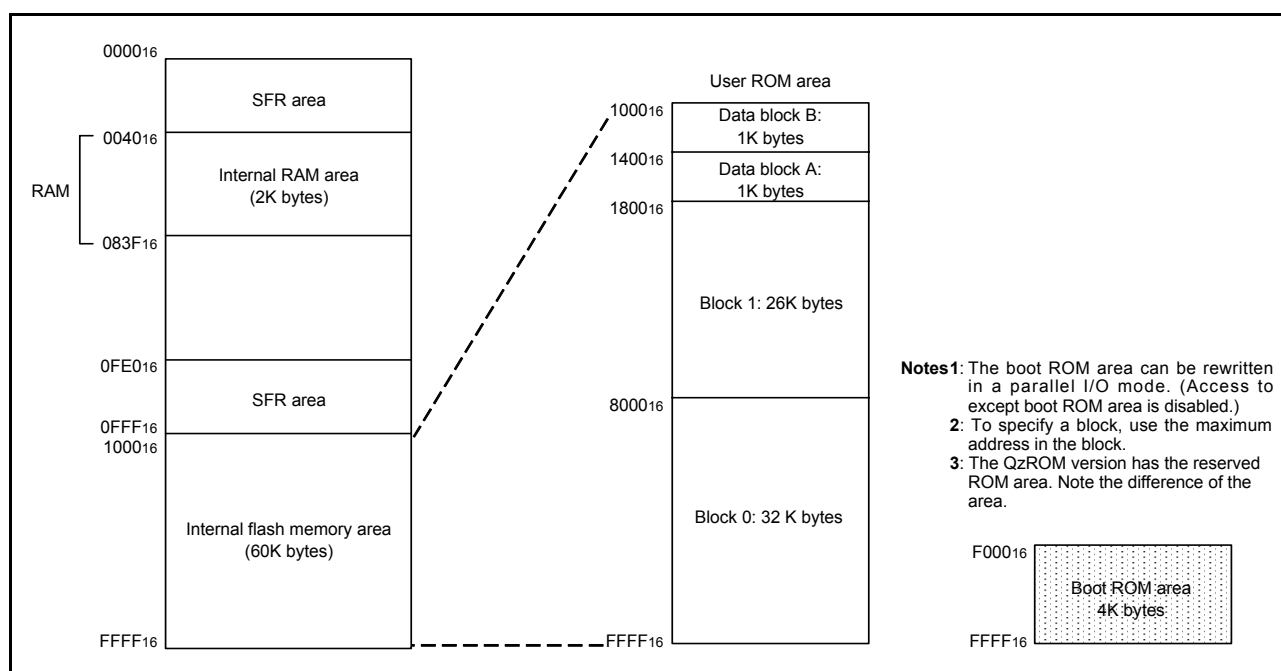


Fig 70. Block diagram of built-in flash memory

Outline Performance

CPU rewrite mode is usable in the single-chip or Boot mode. The only User ROM area can be rewritten.

In CPU rewrite mode, the CPU erases, programs and reads the internal flash memory as instructed by software commands. This rewrite control program must be transferred to internal RAM area before it can be executed.

The MCU enters CPU rewrite mode by setting "1" to the CPU rewrite mode select bit (bit 1 of address 0FE0₁₆). Then, software commands can be accepted.

Use software commands to control program and erase operations. Whether a program or erase operation has terminated normally or in error can be verified by reading the status register. Figure 71 shows the flash memory control register 0.

Bit 0 of the flash memory control register 0 is the RY/BY status flag used exclusively to read the operating status of the flash memory. During programming and erase operations, it is "0" (busy). Otherwise, it is "1" (ready).

Bit 1 of the flash memory control register 0 is the CPU rewrite mode select bit. When this bit is set to "1", the MCU enters CPU rewrite mode. And then, software commands can be accepted. In CPU rewrite mode, the CPU becomes unable to access the internal flash memory directly. Therefore, use the control program in the internal RAM for write to bit 1. To set this bit 1 to "1", it is necessary to write "0" and then write "1" in succession to bit 1. The bit can be set to "0" by only writing "0".

Bit 2 of the flash memory control register 0 is the user block 1 E/W enable bit. By setting combination of bit 4 (user block 0 E/W enable bit) of the flash memory control register 2 (address 0FE2₁₆) and this bit as shown in Table 16, E/W is disabled to user block in the CPU rewriting mode.

Bit 3 of the flash memory control register 0 is the flash memory reset bit used to reset the control circuit of internal flash memory. This bit is used when flash memory access has failed. When the CPU rewrite mode select bit is "1", setting "1" for this bit resets the control circuit. To release the reset, it is necessary to set this bit to "0".

Bit 5 of the flash memory control register 0 is the User ROM area select bit and is valid only in the boot mode. Setting this bit to "1" in the boot mode switches an accessible area from the boot ROM area to the user ROM area. To use the CPU rewrite mode in the boot mode, set this bit to "1". To rewrite bit 5, execute the user original reprogramming control software transferred to the internal RAM in advance.

Bit 6 of the flash memory control register 0 is the program status flag. This bit is set to "1" when writing to flash memory is failed. When program error occurs, the block cannot be used.

Bit 7 of the flash memory control register 0 is the erase status flag.

This bit is set to "1" when erasing flash memory is failed. When erase error occurs, the block cannot be used.

Figure 72 shows the flash memory control register 1.

Bit 0 of the flash memory control register 1 is the Erase suspend enable bit. By setting this bit to "1", the erase suspend mode to suspend erase processing temporary when block erase command is executed can be used. In order to set this bit 0 to "1", writing "0" and "1" in succession to bit 0. In order to set this bit to "0", write "0" only to bit 0.

Bit 1 of the flash memory control register 1 is the erase suspend request bit. By setting this bit to "1" when erase suspend enable bit is "1", the erase processing is suspended.

Bit 6 of the flash memory control register 1 is the erase suspend flag. This bit is cleared to "0" at the flash erasing.

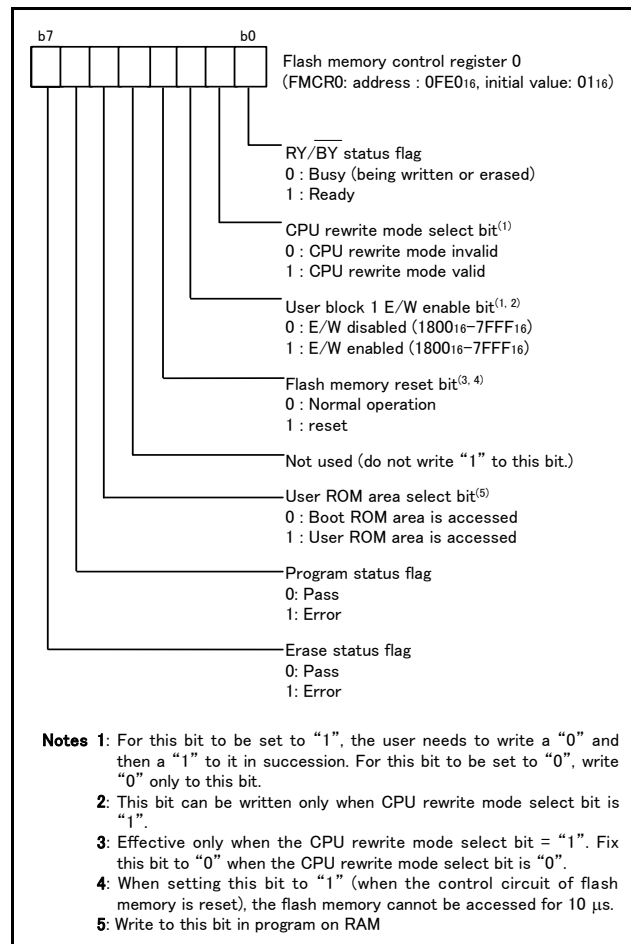


Fig 71. Structure of flash memory control register 0

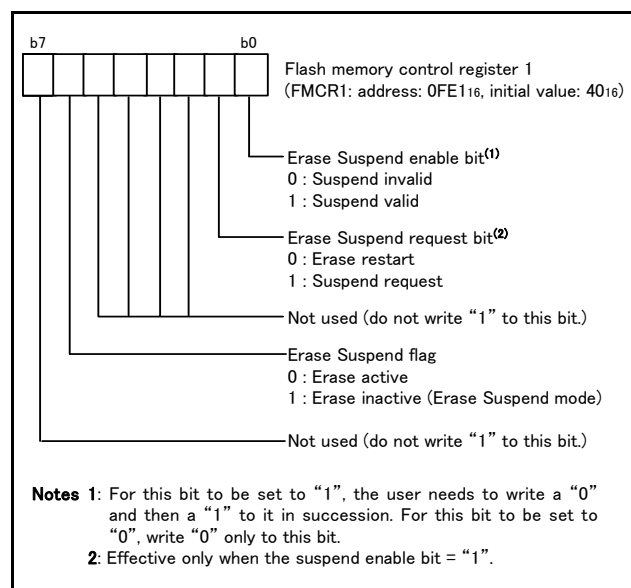


Fig 72. Structure of flash memory control register 1

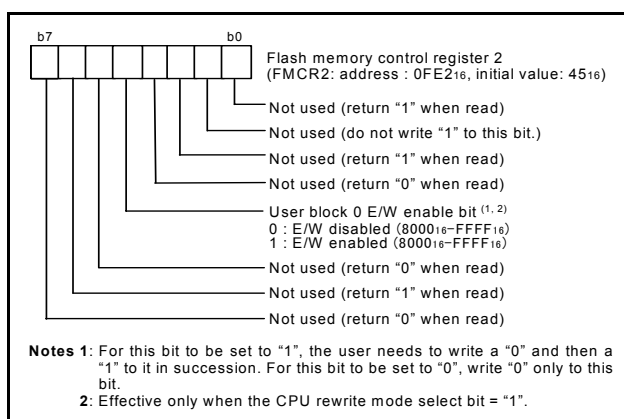


Fig 73. Structure of flash memory control register 2

Table 16 State of E/W inhibition function

User block 0 E/W enable bit	User block 1 E/W enable bit	User block 0 Addresses 8000 ₁₆ to FFFF ₁₆	User block 1 Addresses 1800 ₁₆ to 7FFF ₁₆	Data block Addresses 1000 ₁₆ to 17FF ₁₆
0	0	E/W disabled	E/W disabled	E/W enabled
0	1	E/W disabled	E/W enabled	E/W enabled
1	0	E/W enabled	E/W disabled	E/W enabled
1	1	E/W enabled	E/W enabled	E/W enabled

Figure 74 shows a flowchart for setting/releasing CPU rewrite mode.

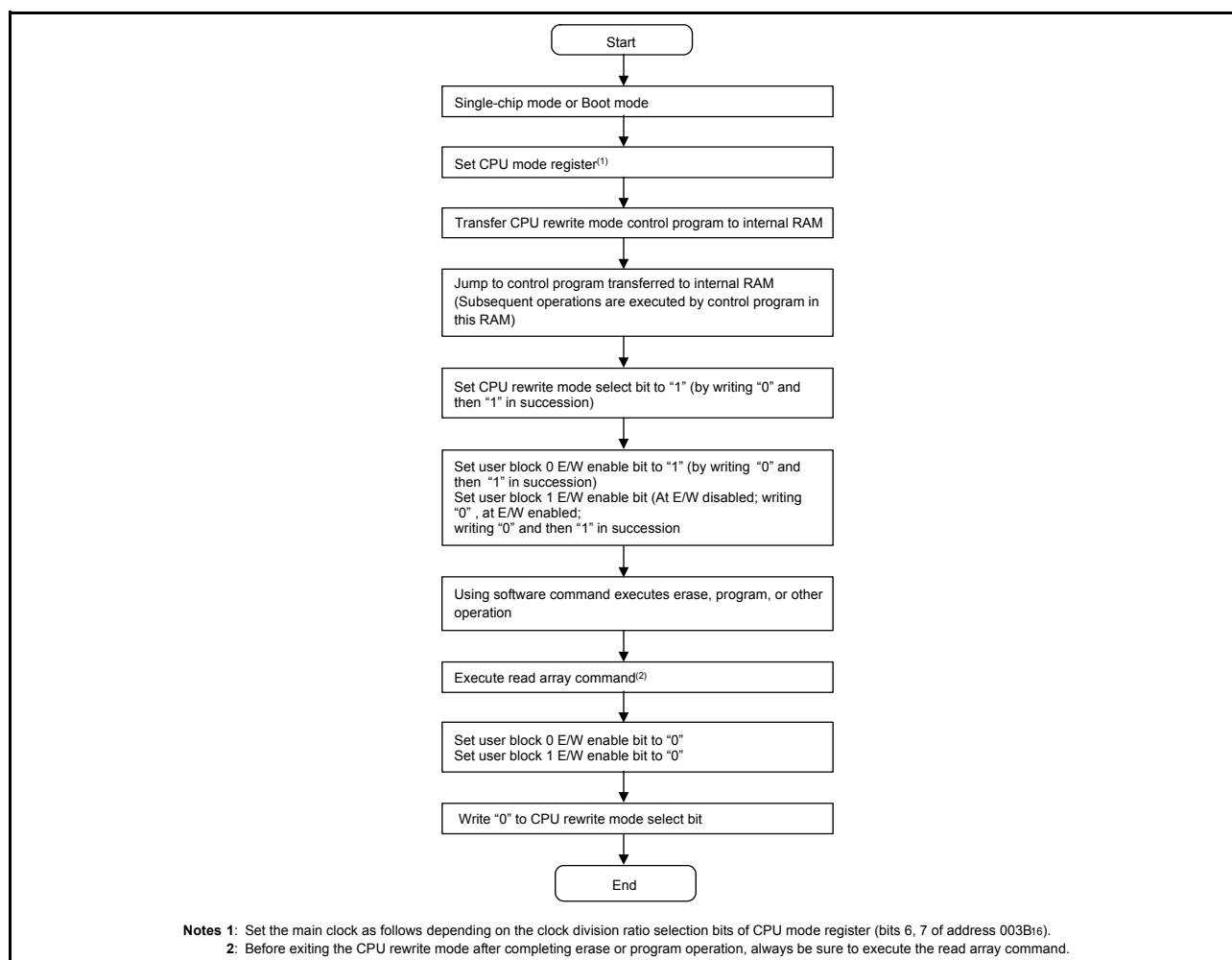


Fig 74. CPU rewrite mode set/release flowchart be sure to execute

<Notes on CPU Rewrite Mode>

Take the notes described below when rewriting the flash memory in CPU rewrite mode.

(1) Operation speed

During CPU rewrite mode, set the system clock ϕ to 4.0 MHz or less using the main clock division ratio selection bits (bits 6 and 7 of address 003B16).

(2) Instructions inhibited against use

The instructions which refer to the internal data of the flash memory cannot be used during CPU rewrite mode.

(3) Interrupts

The interrupts cannot be used during CPU rewrite mode because they refer to the internal data of the flash memory.

(4) Watchdog timer

If the watchdog timer has been already activated, internal reset due to an underflow will not occur because the watchdog timer is surely cleared during program or erase.

(5) Reset

Reset is always valid. The MCU is activated using the boot mode at release of reset in the condition of CNVSS = "H", so that the program will begin at the address which is stored in addresses FFFC16 and FFFD16 of the boot ROM area.

Software Commands

Table 17 lists the software commands.

After setting the CPU rewrite mode select bit to "1", execute a software command to specify an erase or program operation. Each software command is explained below.

- Read Array Command (FF₁₆)

The read array mode is entered by writing the command code "FF₁₆" in the first bus cycle. When an address to be read is input in one of the bus cycles that follow, the contents of the specified address are read out at the data bus (D₀ to D₇). The read array mode is retained until another command is written.

- Read Status Register Command (70₁₆)

When the command code "70₁₆" is written in the first bus cycle, the contents of the status register are read out at the data bus (D₀ to D₇) by a read in the second bus cycle. The status register is explained in the next section.

- Clear Status Register Command (50₁₆)

This command is used to clear the bits SR₄ and SR₅ of the status register after they have been set. These bits indicate that operation has ended in an error. To use this command, write the command code "50₁₆" in the first bus cycle.

- Program Command (40₁₆)

Program operation starts when the command code "40₁₆" is written in the first bus cycle. Then, if the address and data to program are written in the 2nd bus cycle, program operation (data programming and verification) will start.

Whether the write operation is completed can be confirmed by read status register or the RY/ $\overline{\text{BY}}$ status flag. To read the status register, write the read status register command "70₁₆". The status register bit 7 (SR₇) is set to "0" at the same time the program starts and returned to "1" upon completion of the program. The read status mode remains active until the read array command ("FF₁₆") is written.

The RY/ $\overline{\text{BY}}$ status flag is set to "0" during program operation and "1" when the program operation is completed as is the status register bit 7 (SR₇).

At program end, program results can be checked by reading the status register.

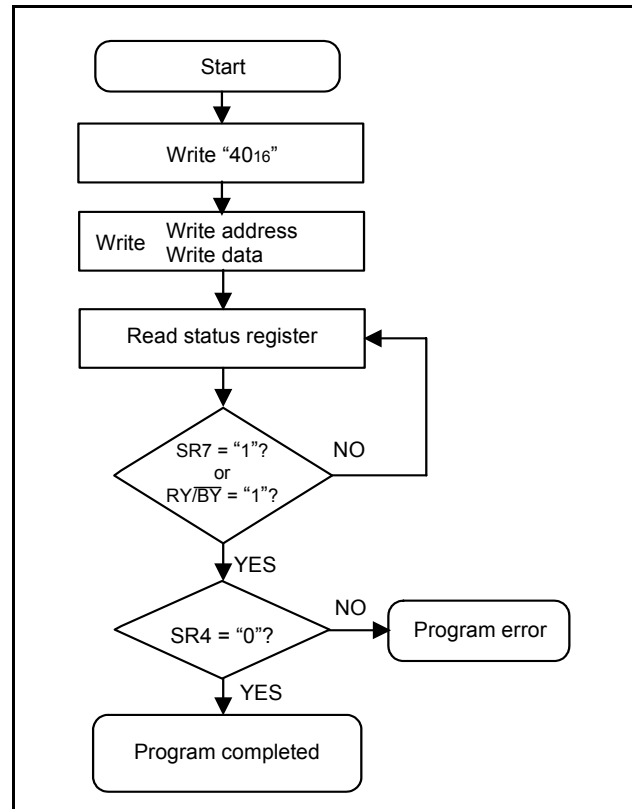


Fig 75. Program flowchart

Table 17 List of software commands (CPU rewrite mode)

Command	cycle number	First bus cycle			Second bus cycle		
		Mode	Address	Data (D ₀ to D ₇)	Mode	Address	Data (D ₀ to D ₇)
Read array	1	Write	X ⁽⁴⁾	FF ₁₆			
Read status register	2	Write	X	70 ₁₆	Read	X	SRD ⁽¹⁾
Clear status register	1	Write	X	50 ₁₆			
Program	2	Write	X	40 ₁₆	Write	WA ⁽²⁾	WD ⁽²⁾
Block erase	2	Write	X	20 ₁₆	Write	BA ⁽³⁾	D0 ₁₆

NOTES:

1. SRD = Status Register Data
2. WA = Write Address, WD = Write Data
3. BA = Block Address to be erased (Input the maximum address of each block.)
4. X denotes a given address in the User ROM area.

• Block Erase Command (20₁₆/D0₁₆)

By writing the command code "20₁₆" in the first bus cycle and the confirmation command code "D0₁₆" and the block address in the second bus cycle that follows, the block erase (erase and erase verify) operation starts for the block address of the flash memory to be specified.

Whether the block erase operation is completed can be confirmed by read status register or the RY/ $\overline{\text{BY}}$ status flag of flash memory control register. To read the status register, write the status register command "70₁₆". The status register bit 7 (SR7) is set to "0" at the same time the block erase operation starts and returned to "1" upon completion of the block erase operation. The read status mode at this time remains active until the read array command ("FF₁₆") is written.

The RY/ $\overline{\text{BY}}$ status flag register is set to "0" during block erase operation and "1" when the block erase operation is completed as is the status register bit 7 (SR7).

After the block erase ends, erase results can be checked by reading the status register. For details, refer to the section where the status register is detailed.

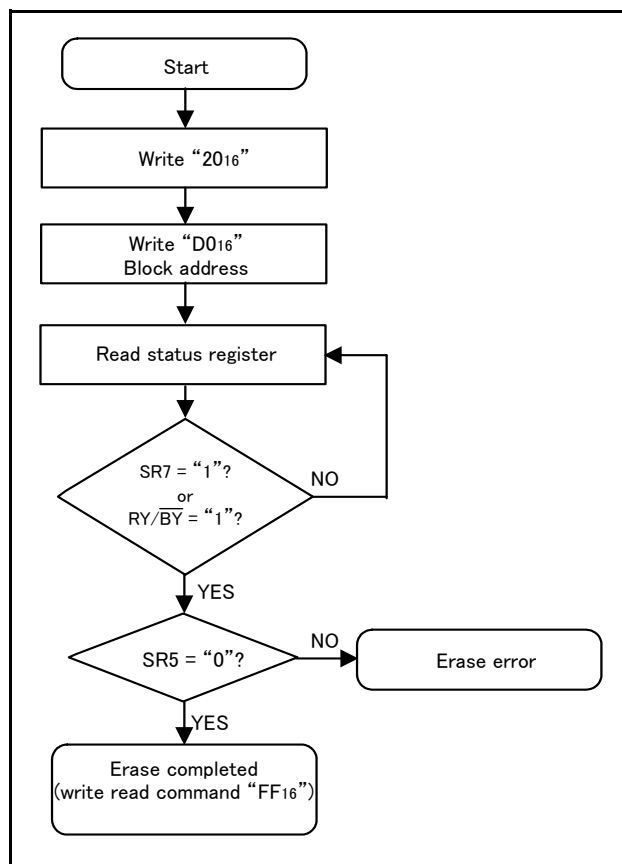


Fig 76. Erase flowchart

• Status Register

The status register shows the operating status of the flash memory and whether erase operations and programs ended successfully or in error. It can be read in the following ways:

- (1) By reading an arbitrary address from the User ROM area after writing the read status register command (70₁₆)
- (2) By reading an arbitrary address from the User ROM area in the period from when the program starts or erase operation starts to when the read array command (FF₁₆) is input.

Also, the status register can be cleared by writing the clear status register command (50₁₆).

After reset, the status register is set to “80₁₆”.

Table 18 shows the status register. Each bit in this register is explained below.

• Sequencer status (SR7)

The sequencer status indicates the operating status of the flash memory. This bit is set to “0” (busy) during write or erase operation and is set to “1” when these operations ends.

After power-on, the sequencer status is set to “1” (ready).

• Erase status (SR5)

The erase status indicates the operating status of erase operation. If an erase error occurs, it is set to “1”. When the erase status is cleared, it is reset to “0”.

• Program status (SR4)

The program status indicates the operating status of write operation.

When a write error occurs, it is set to “1”.

The program status is reset to “0” when it is cleared.

If “1” is written for any of the SR5 and SR4 bits, the read array, program, and block erase commands are not accepted. Before executing these commands, execute the clear status register command (50₁₆) and clear the status register.

Also, if any commands are not correct, both SR5 and SR4 are set to “1”.

Table 18 Definition of each bit in status register

Each bit of SRD bits	Status name	Definition	
		“1”	“0”
SR7 (bit7)	Sequencer status	Ready	Busy
SR6 (bit6)	Reserved	–	–
SR5 (bit5)	Erase status	Terminated in error	Terminated normally
SR4 (bit4)	Program status	Terminated in error	Terminated normally
SR3 (bit3)	Reserved	–	–
SR2 (bit2)	Reserved	–	–
SR1 (bit1)	Reserved	–	–
SR0 (bit0)	Reserved	–	–

Full Status Check

By performing full status check, it is possible to know the execution results of erase and program operations. Figure 77 shows a full status check flowchart and the action to be taken when each error occurs.

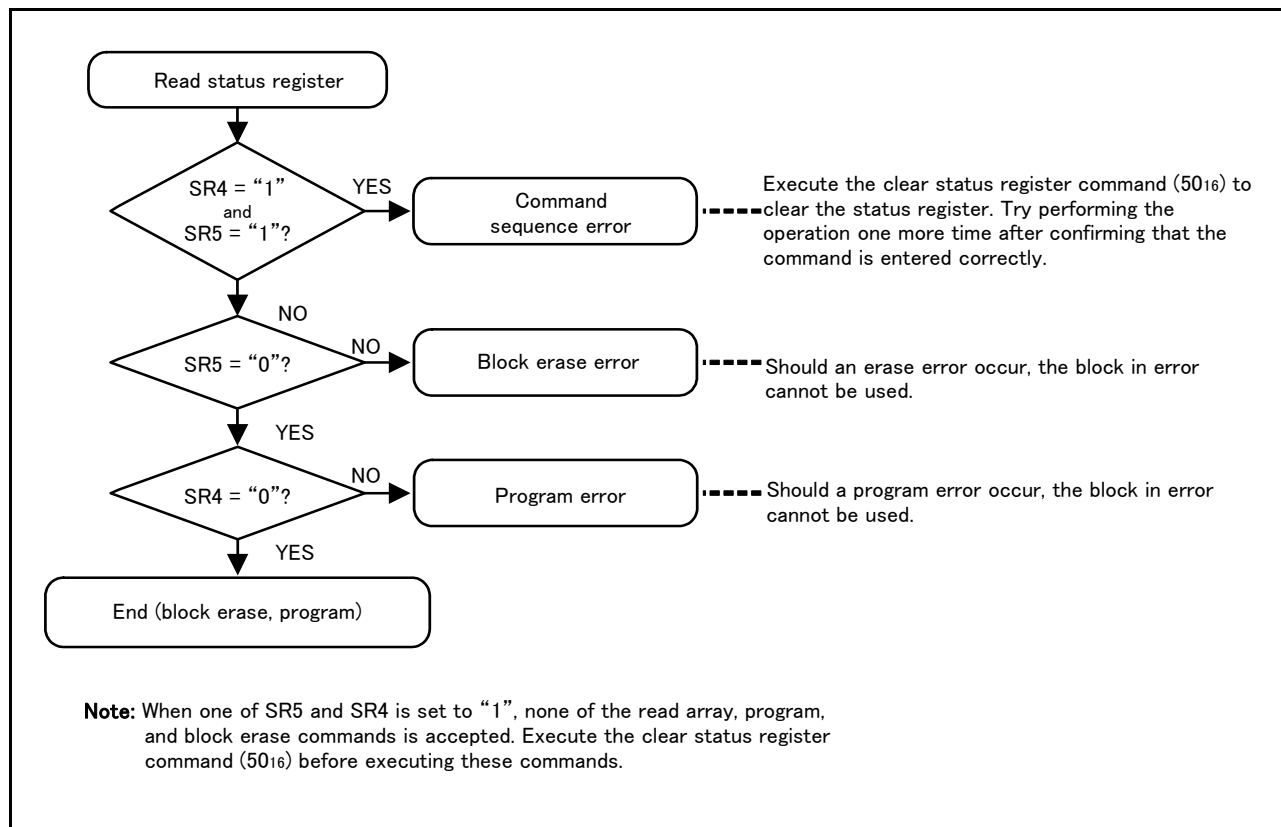


Fig 77. Full status check flowchart and remedial procedure for errors

Functions To Inhibit Rewriting Flash Memory Version

To prevent the contents of internal flash memory from being read out or rewritten easily, this MCU incorporates a ROM code protect function for use in parallel I/O mode and an ID code check function for use in standard serial I/O mode.

• ROM Code Protect Function

The ROM code protect function is the function to inhibit reading out or modifying the contents of internal flash memory by using the ROM code protect control address (address FFDB₁₆) in parallel I/O mode. Figure 78 shows the ROM code protect control address (address FFDB₁₆). (This address exists in the User ROM area.)

If one or both of the pair of ROM code protect bits is set to “0”, the ROM code protect is turned on, so that the contents of internal flash memory are protected against readout and modification. The ROM code protect is implemented in two levels. If level 2 is selected, the flash memory is protected even against readout by a shipment inspection LSI tester, etc. When an attempt is made to select both level 1 and level 2, level 2 is selected by default.

If both of the two ROM code protect reset bits are set to “00”, the ROM code protect is turned off, so that the contents of internal flash memory can be readout or modified. Once the ROM code protect is turned on, the contents of the ROM code protect reset bits cannot be modified in parallel I/O mode. Use standard serial I/O mode or other modes to rewrite the contents of the ROM code protect disable bits.

Rewriting of only the ROM code protect control address (address FFDB₁₆) cannot be performed. When rewriting the ROM code protect reset bit, rewrite the whole user ROM area (block 0) containing the ROM code protect control address.

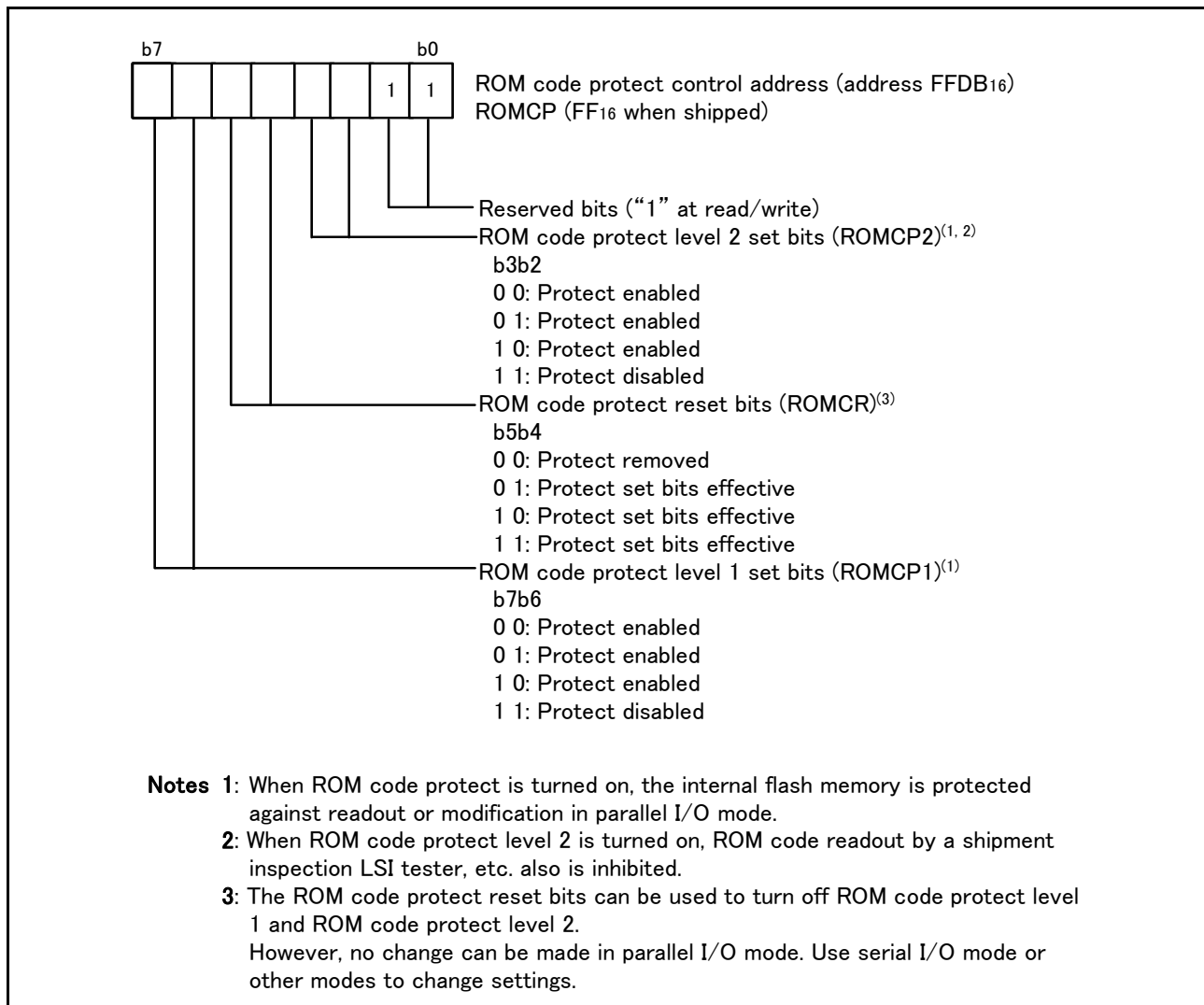


Fig 78. Structure of ROM code protect control address

• ID Code Check Function

Use this function in standard serial I/O mode. When the contents of the flash memory are not blank, the ID code sent from the programmer is compared with the ID code written in the flash memory to see if they match. If the ID codes do not match, the commands sent from the programmer are not accepted. The ID code consists of 8-bit data, and its areas are FFD4₁₆ to FFDA₁₆. Write a program which has had the ID code preset at these addresses to the flash memory.

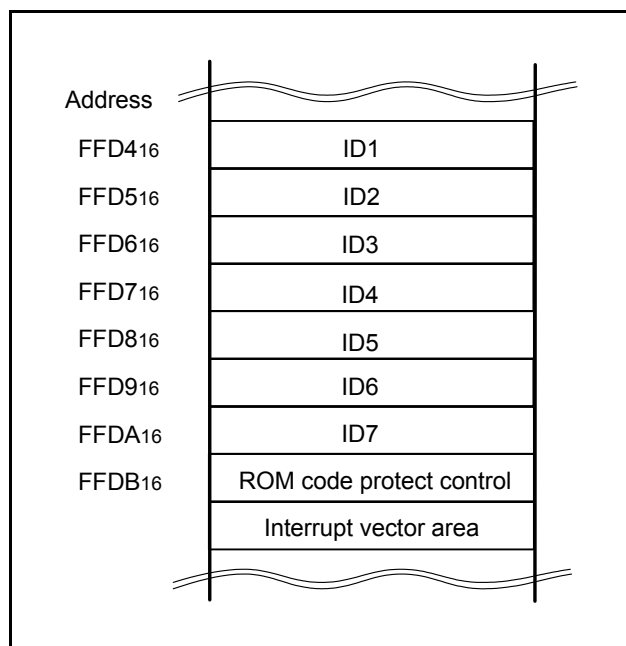


Fig 79. ID code store addresses

Parallel I/O Mode

The parallel I/O mode is used to input/output software commands, address and data in parallel for operation (read, program and erase) to internal flash memory.

• User ROM and Boot ROM Areas

In parallel I/O mode, the User ROM and Boot ROM areas shown in Figure 70 can be rewritten. Both areas of flash memory can be operated on in the same way.

The Boot ROM area is 4 Kbytes in size and located at addresses F000₁₆ through FFFF₁₆. Make sure program and block erase operations are always performed within this address range. (Access to any location outside this address range is prohibited.)

In the Boot ROM area, an erase block operation is applied to only one 4 K byte block. The boot ROM area has had a standard serial I/O mode control program stored in it when shipped from the factory. Therefore, using the MCU in standard serial I/O mode, do not rewrite to the Boot ROM area.

Standard serial I/O Mode

The standard serial I/O mode inputs and outputs the software commands, addresses and data needed to operate (read, program, erase, etc.) the internal flash memory. This I/O is clock synchronized serial. This mode requires a purpose-specific peripheral unit.

The standard serial I/O mode is different from the parallel I/O mode in that the CPU controls flash memory rewrite (uses the CPU rewrite mode), rewrite data input and so forth. The standard serial I/O mode is started by connecting “H” to the CNVss pin and “H” to the P32 (BOOTENT) pin, and releasing the reset operation. (In the ordinary microcomputer mode, set CNVss pin to “L” level.) This control program is written in the Boot ROM area when the product is shipped from Renesas. Accordingly, make note of the fact that the standard serial I/O mode cannot be used if the Boot ROM area is rewritten in parallel I/O mode. The standard serial I/O mode has standard serial I/O mode 1 of the clock synchronous serial and standard serial I/O mode 2 of the clock asynchronous serial. Tables 19 and 20 show description of pin function (standard serial I/O mode). Figure 80 to 82 show the pin connections for the standard serial I/O mode.

In standard serial I/O mode, only the User ROM area shown in Figure 70 can be rewritten. The Boot ROM area cannot be written.

In standard serial I/O mode, a 7-byte ID code is used. When there is data in the flash memory, this function determines whether the ID code sent from the peripheral unit (programmer) and those written in the flash memory match. The commands sent from the peripheral unit (programmer) are not accepted unless the ID code matches.

Table 19 Description of pin function (Flash Memory Standard Serial I/O Mode 1)

Pin name	Signal name	I/O	Function
Vcc,Vss	Power supply	I	Apply 2.7 to 5.5 V to the Vcc pin and 0 V to the Vss pin.
CNVss	CNVss	I	After input of port is set, input "H" level.
RESET	Reset input	I	Reset input pin. To reset the microcomputer, RESET pin should be held at an "L" level for 16 cycles or more of XIN.
XIN	Clock input	I	Connect an oscillation circuit between the XIN and XOUT pins.
XOUT	Clock output	O	As for the connection method, refer to the "clock generating circuit".
AVss	Analog power supply input		Connect AVss to Vss.
VREF	Reference voltage input	I	Apply reference voltage of A/D convertor to this pin.
P00–P07, P10–P17, P20–P27, P34–P37, P40–P47, P50–P57, P60–P62	I/O port	I/O	Input "L" or "H" level, or keep open.
P33	RxD input	I	Serial data input pin.
P32	TxD output	O	Serial data output pin.
P31	SCLK input	I	Serial clock input pin.
P30	BUSY output	O	BUSY signal output pin.

Table 20 Description of pin function (Flash Memory Standard Serial I/O Mode 2)

Pin name	Signal name	I/O	Function
Vcc,Vss	Power supply	I	Apply 2.7 to 5.5 V to the Vcc pin and 0 V to the Vss pin.
CNVss	CNVss	I	After input of port is set, input "H" level.
RESET	Reset input	I	Reset input pin. To reset the microcomputer, RESET pin should be held at an "L" level for 16 cycles or more of XIN.
XIN	Clock input	I	Connect an oscillation circuit between the XIN and XOUT pins.
XOUT	Clock output	O	As for the connection method, refer to the "clock generating circuit".
AVss	Analog power supply input		Connect AVss to Vss.
VREF	Reference voltage input	I	Apply reference voltage of A/D convertor to this pin.
P00–P07, P10–P17, P20–P27, P34–P37, P40–P47, P50–P57, P60–P62	I/O port	I/O	Input "L" or "H" level, or keep open.
P33	RxD input	I	Serial data input pin.
P32	TxD output	O	Serial data output pin.
P31	SCLK input	I	Input "L" level.
P30	BUSY output	O	BUSY signal output pin.

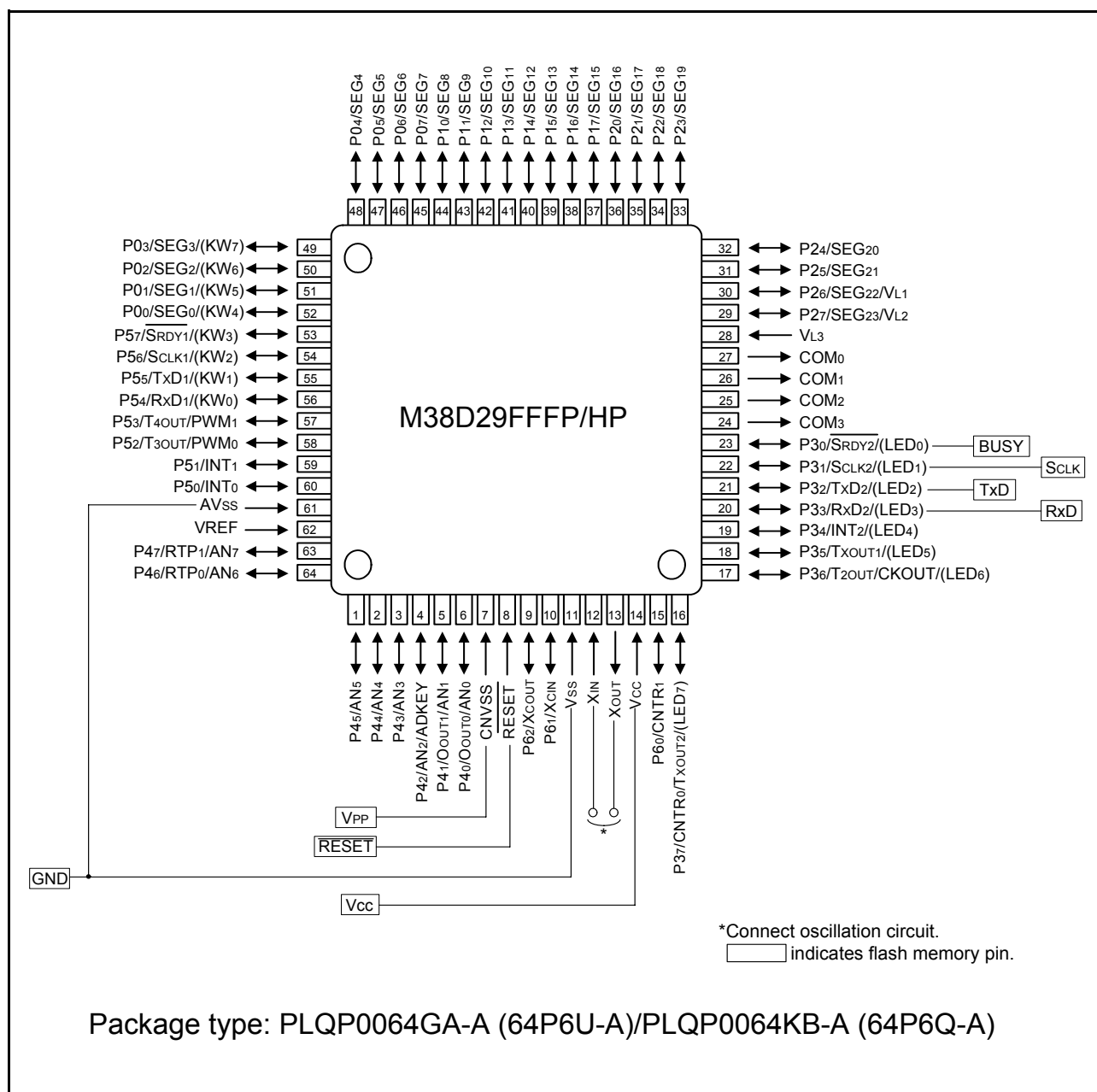


Fig 80. Connection for standard serial I/O mode 1

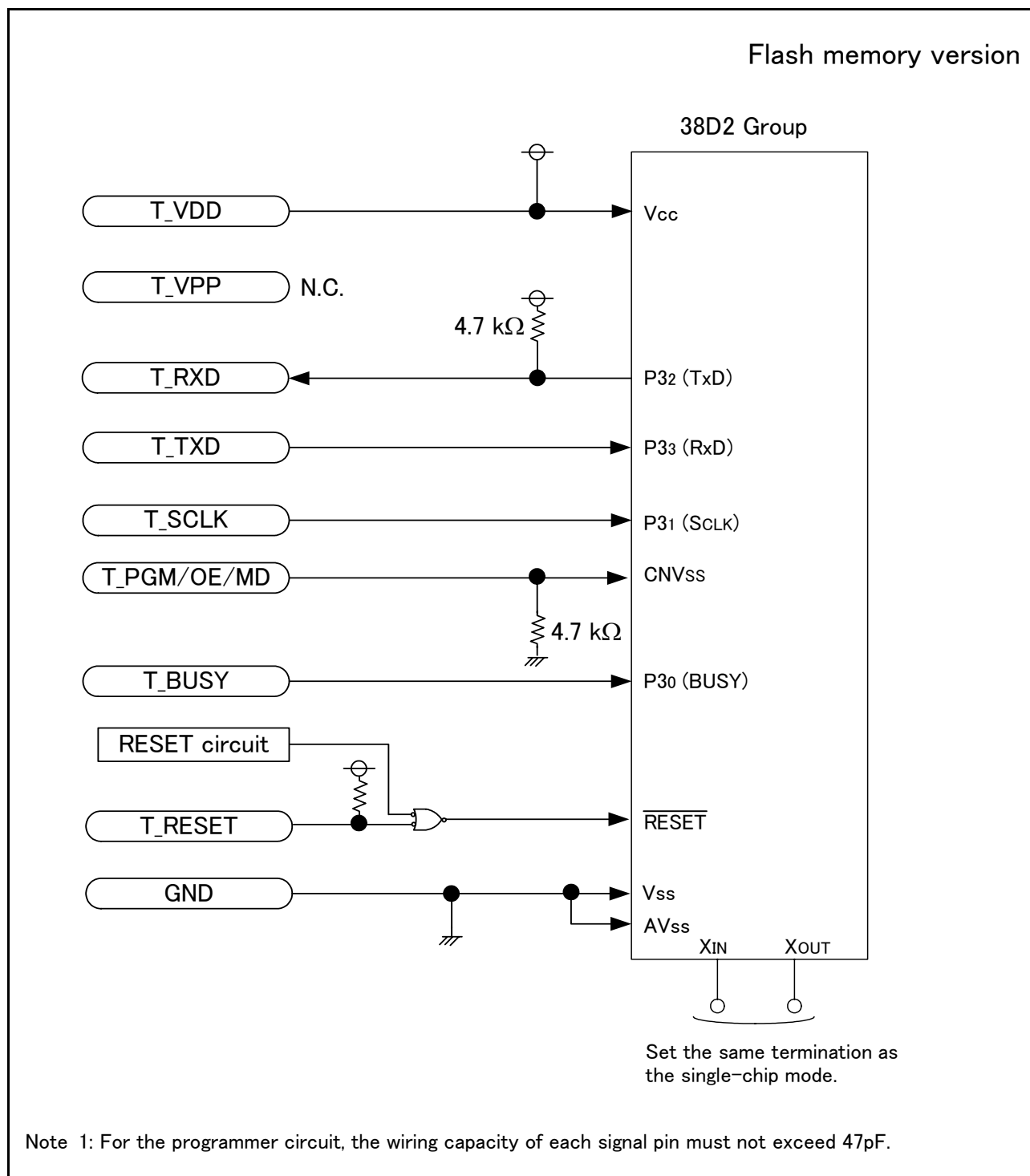


Fig 81. When using programmer (in standard serial I/O mode 1) of Suisai Electronics System Co., LTD, connection example

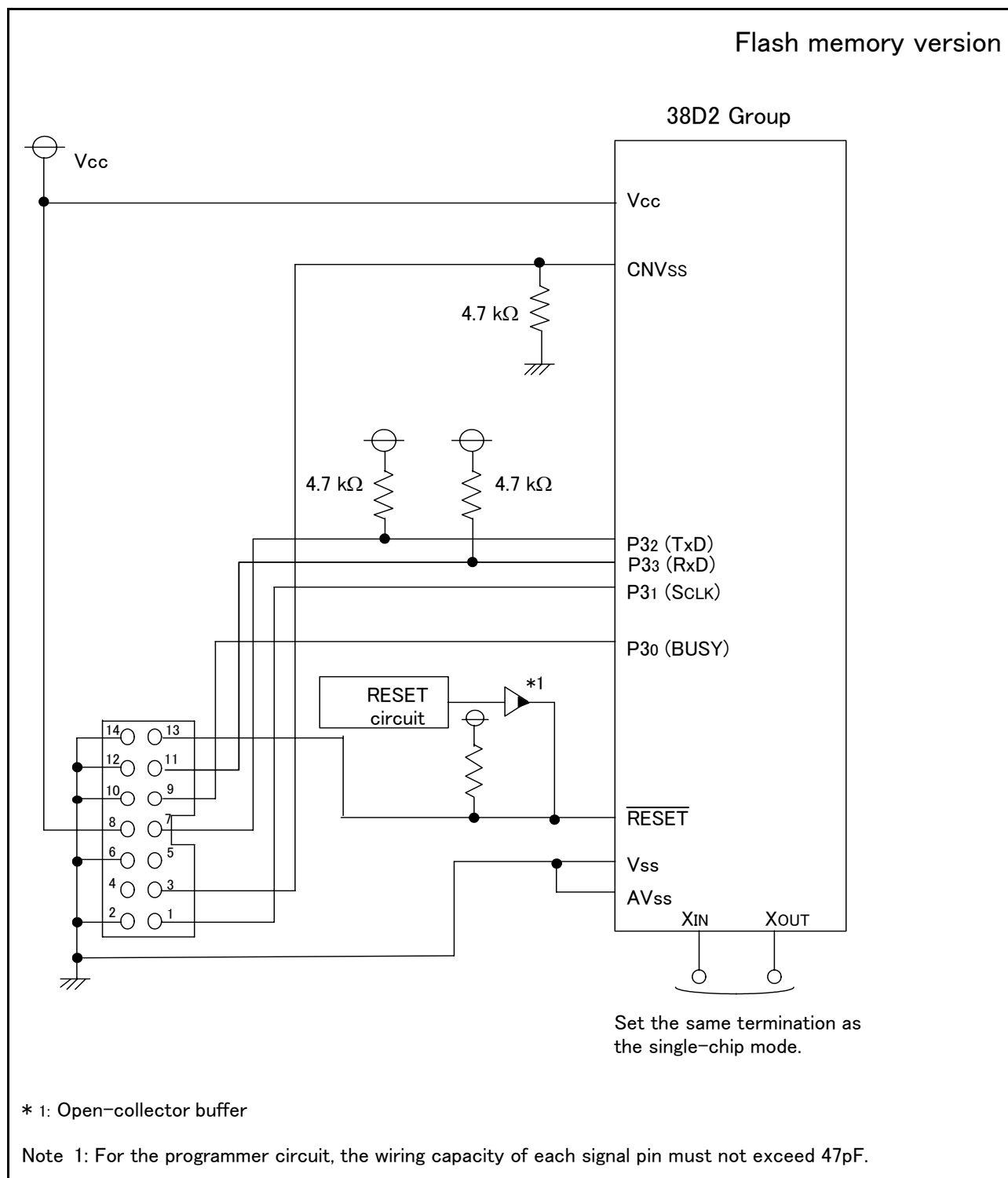


Fig 82. When using E8 programmer (in standard serial I/O mode 1) connection example

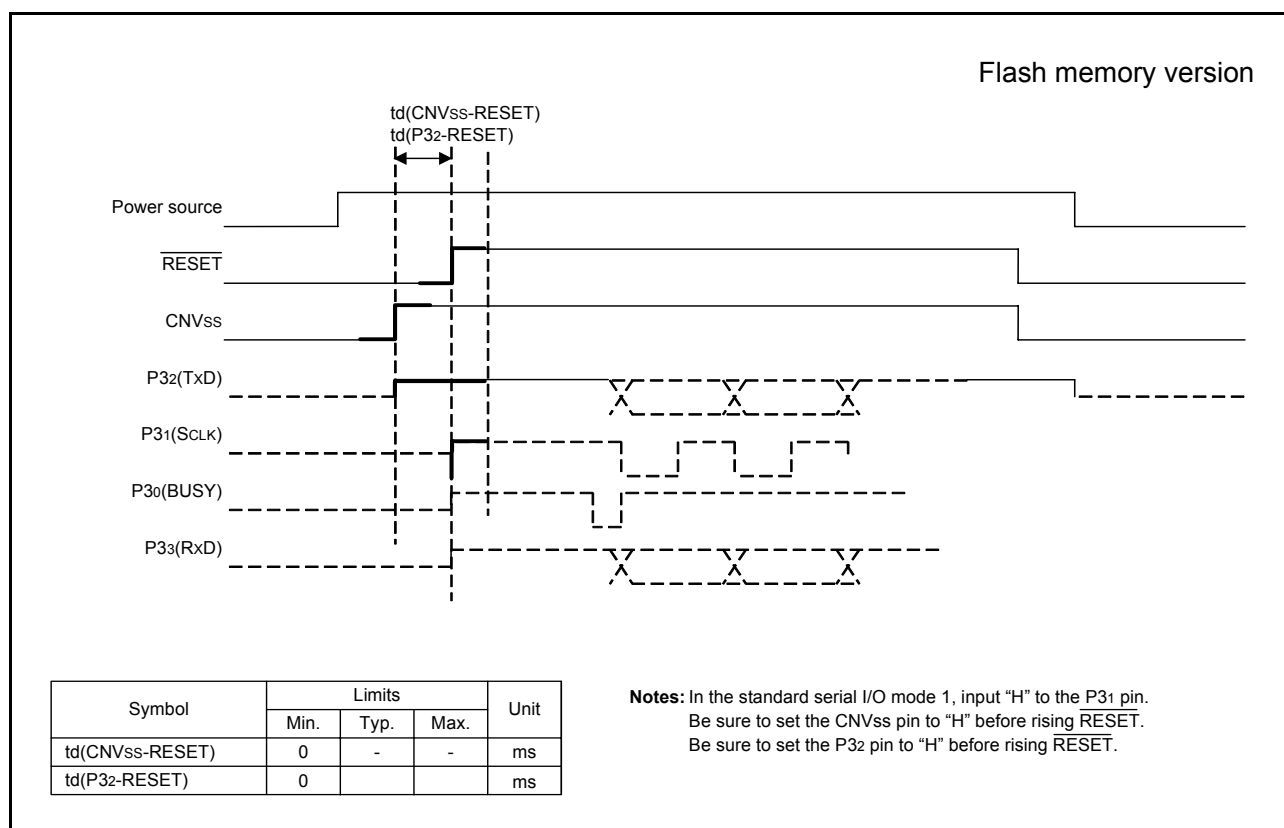


Fig 83. Operating waveform for standard serial I/O mode 1

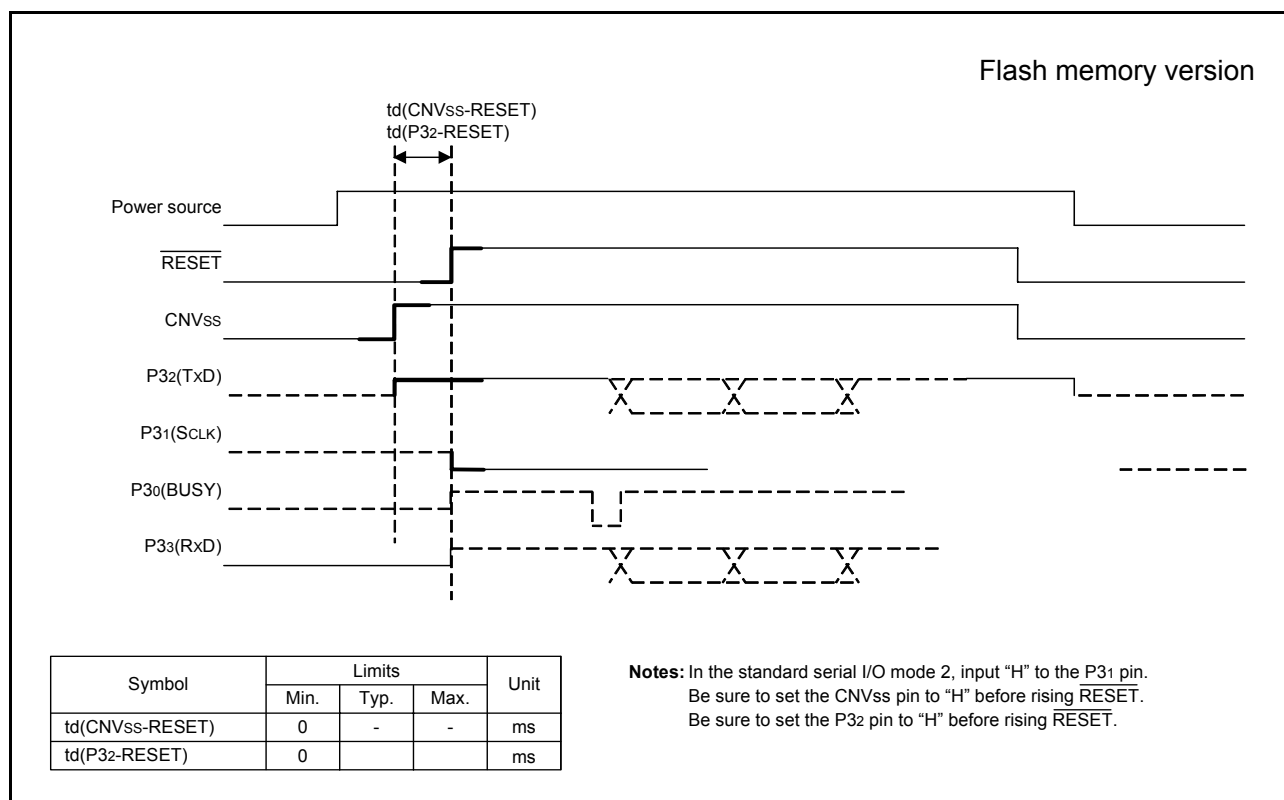


Fig 84. Operating waveform for standard serial I/O mode 2

NOTES ON USE

Processor Status Register

The contents of the processor status register (PS) after a reset are undefined, except for the interrupt disable flag (I) which is "1". After a reset, initialize flags which affect program execution. In particular, it is essential to initialize the index X mode (T) and the decimal mode (D) flags because of their effect on calculations. Initialize these flags at beginning of the program.

Interrupt

The contents of the interrupt request bits do not change immediately after they have been written. After writing to an interrupt request register, execute at least one instruction before performing a BBC or BBS instruction.

Decimal Calculations

- To calculate in decimal notation, set the decimal mode flag (D) to "1", then execute an ADC or SBC instruction. After executing an ADC or SBC instruction, execute at least one instruction before executing a SEC, CLC, or CLD instruction.
- In decimal mode, the values of the negative (N), overflow (V), and zero (Z) flags are invalid.

Timers

The division ratio is $1/(n+1)$ when the value n (0 to 255) is written to the timer latch.

Multiplication and Division Instructions

The index mode (T) and the decimal mode (D) flags do not affect the MUL and DIV instruction.

The execution of these instructions does not change the contents of the processor status register.

Direction Registers

The values of the port direction registers cannot be read. This means, it is impossible to use the LDA instruction, memory operation instruction when the T flag is "1", addressing mode using direction register values as qualifiers, and bit test instructions such as BBC and BBS. It is also impossible to use bit operation instructions such as CLB and SEB, and read-modify-write instructions to direction registers, including calculations such as ROR. To set the direction registers, use instructions such as LDM or STA.

Serial Interface

In clock synchronous serial I/O, if the receive side is using an external clock and it is to output the $\overline{\text{SRDY}}$ signal, set the transmit enable bit, the receive enable bit, and the $\overline{\text{SRDY}}$ output enable bit to "1".

Serial I/O continues to output the final bit from the TxD pin after transmission is completed.

A/D Converter

The comparator is constructed linked to a capacitor. The conversion accuracy may be low because the charge is lost if the conversion speed is not enough. Accordingly, set $f(\text{XIN})$ to at least 500kHz during A/D conversion in the XIN mode.

Also, do not execute the STP or WIT instruction during an A/D conversion.

In the low-speed mode, since the A/D conversion is executed by the on-chip oscillator, the minimum value of $f(\text{XIN})$ frequency is not limited.

LCD Drive Control Circuit

Execution of the STP instruction sets the LCD enable bit (bit 3 of the LCD mode register) and bits 0 to 5 and bit 7 of the LCD power control register to "0" and the LCD panel turns off. To make the LCD panel turn on after returning from the stop mode, set these bits to "1".

Instruction Execution Time

The instruction execution time is obtained by multiplying the frequency of the internal clock ϕ by the number of cycles needed to execute an instruction.

Power Source Voltage

When the power source voltage value of a microcomputer is less than the value which is indicated as the recommended operating conditions, the microcomputer does not operate normally and may perform unstable operation.

In a system where the power source voltage drops slowly when the power source voltage drops or the power supply is turned off, reset a microcomputer when the power source voltage is less than the recommended operating conditions and design a system not to cause errors to the system by this unstable operation.

Handling of Power Source Pin

In order to avoid a latch-up occurrence, connect a capacitor suitable for high frequencies as bypass capacitor between power source pin (VCC pin) and GND pin (Vss pin), and between power source pin (VCC pin) and analog power source pin (AVCC). Besides, connect the capacitor to as close as possible. For bypass capacitor which should not be located too far from the pins to be connected, a ceramic capacitor of 0.1 μF is recommended.

LCD drive power supply

Power supply capacitor may be insufficient with the division resistance for LCD power supply, and the characteristic of the LCD panel. In this case, there is the method of connecting the bypass capacitor about 0.1–0.33 μF to VL1–VL3 pins. The example of a strengthening measure of the LCD drive power supply is shown below.

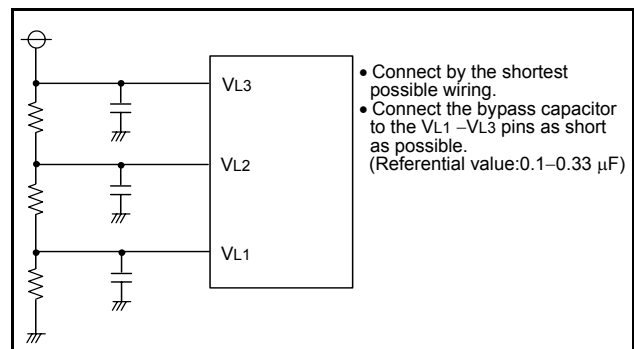


Fig. 85 Strengthening measure example of LCD drive power supply

NOTES ON QzROM VERSION

Wiring to OSCSEL pin

1. OSCSEL = L

Connect the OSCSEL pin the shortest possible to the GND pattern which is supplied to the VSS pin of the microcomputer. In addition connecting an approximately 5 k Ω resistor in series to the GND could improve noise immunity. In this case as well as the above mention, connect the pin the shortest possible to the GND pattern which is supplied to the VSS pin of the microcomputer.

2. OSCSEL = H

Connect the OSCSEL pin the shortest possible to the VCC pattern which is supplied to the VCC pin of the microcomputer. In addition connecting an approximately 5 k Ω resistor in series to the VCC could improve noise immunity. In this case as well as the above mention, connect the pin the shortest possible to the VCC pattern which is supplied to the VCC pin of the microcomputer.

• Reason

The OSCSEL pin is the power source input pin for the built-in QzROM.

When programming in the QzROM, the impedance of the OSCSEL pin is low to allow the electric current for writing to flow into the built-in QzROM. Because of this, noise can enter easily. If noise enters the OSCSEL pin, abnormal instruction codes or data are read from the QzROM, which may cause a program runaway.

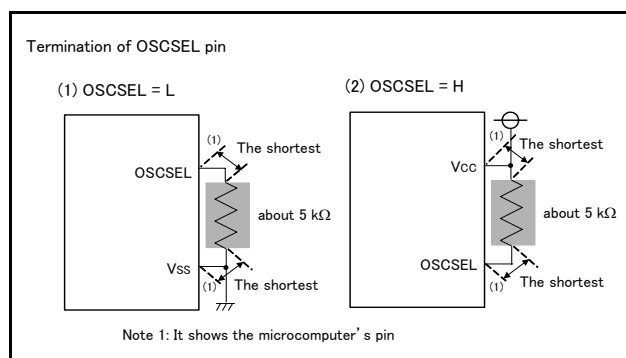


Fig. 86 Wiring for the OSCSEL pin

Precautions Regarding Overvoltage in QzROM Version

Make sure that voltage exceeding the VCC pin voltage is not applied to other pins. In particular, ensure that the state indicated by bold lines in figure below does not occur for OSCSEL pin (VPP power source pin for QzROM) during power-on or power-off. Otherwise the contents of QzROM could be rewritten.

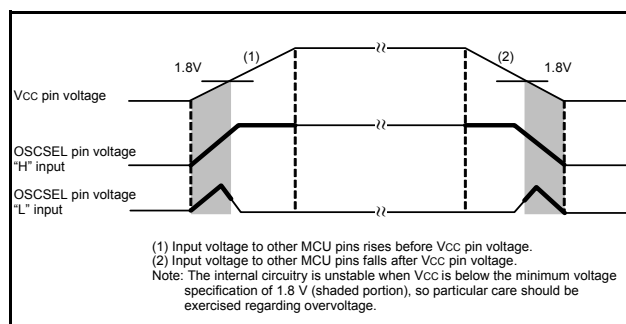


Fig. 87 Example of Overvoltage

Product shipped in blank

As for the product shipped in blank, Renesas does not perform the writing test to user ROM area after the assembly process though the QzROM writing test is performed enough before the assembly process. Therefore, a writing error of approximate 0.1% may occur.

Moreover, please note the contact of cables and foreign bodies on a socket, etc. because a writing environment may cause some writing errors.

Notes On QzROM Writing Orders

When ordering the QzROM product shipped after writing, submit the mask file (extension: .msk) which is made by the mask file converter MM.

- Be sure to set the ROM option data* setup when making the mask file by using the mask file converter MM.. The ROM code protect is specified according to the ROM option data* in the mask file which is submitted at ordering. Note that the mask file which has nothing at the ROM option data* or has the data other than "0016", "FE16" and "FF16" can not be accepted.
- Set "FF16" to the ROM code protect address in ROM data regardless of the presence or absence of a protect. When data other than "FF16" is set, we may ask that the ROM data be submitted again.

* ROM option data: mask option noted in MM

Data Required For QzROM Writing Orders

The following are necessary when ordering a QzROM product shipped after writing:

1. QzROM Writing Confirmation Form*
2. Mark Specification Form*
3. ROM data.....Mask file

* For the QzROM writing confirmation form and the mark specification form, refer to the "Renesas Technology Corp." Homepage (<http://www.renesas.com/homepage.jsp>).

Note that we cannot deal with special font marking (customer's trademark etc.) in QzROM microcomputer.

QzROM Receive Flow

When writing to QzROM is performed by user side, the receiving inspection by the following flow is necessary.

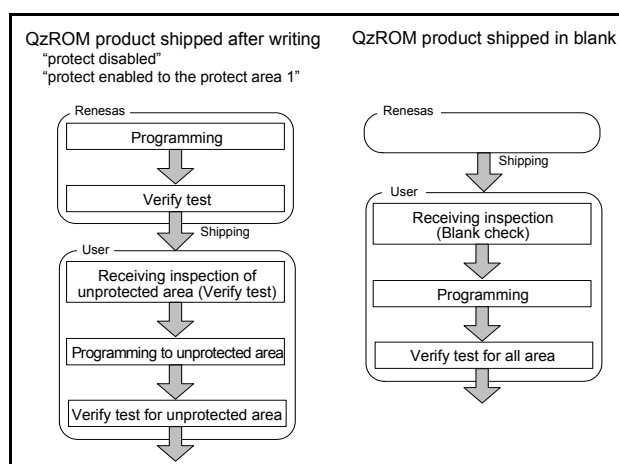


Fig. 88 QzROM receive flow

NOTES ON FLASH MEMORY VERSION**CPU Rewrite Mode****(1) Operation speed**

During CPU rewrite mode, set the system clock ϕ 4.0 MHz or less using the main clock division ratio selection bits (bits 6 and 7 of address 003B₁₆).

(2) Instructions inhibited against use

The instructions which refer to the internal data of the flash memory cannot be used during the CPU rewrite mode.

(3) Interrupts inhibited against use

The interrupts cannot be used during the CPU rewrite mode because they refer to the internal data of the flash memory.

(4) Watchdog timer

In case of the watchdog timer has been running already, the internal reset generated by watchdog timer underflow does not happen, because of watchdog timer is always clearing during program or erase operation.

(5) Reset

Reset is always valid. In case of CNVSS = "H" when reset is released, boot mode is active. So the program starts from the address contained in address FFFC₁₆ and FFFD₁₆ in boot ROM area.

CNVss Pin

The CNVss pin determines the flash memory mode. Connect the CNVss/Vpp pin the shortest possible to the GND pattern which is supplied to the Vss pin of the microcomputer. In addition connecting an approximately 5 k Ω resistor in series to the GND could improve noise immunity. In this case as well as the above mention, connect the pin the shortest possible to the GND pattern which is supplied to the Vss pin of the microcomputer.

Note. When the boot mode or the standard serial I/O mode is used, a switch of the input level to the CNVss pin is required.

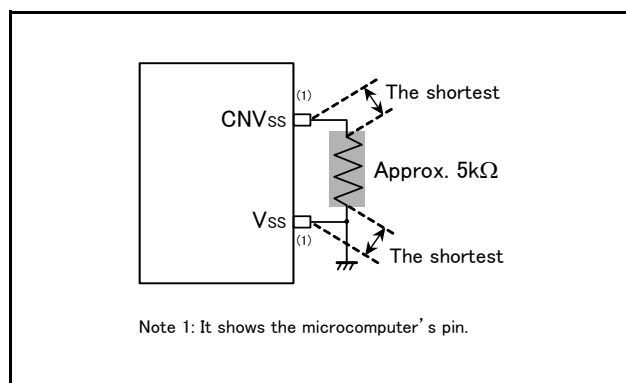


Fig 89. Wiring for the CNVss

NOTES ON DIFFERENCES BETWEEN QzROM VERSION AND FLASH MEMORY VERSION

The QzROM version and flash memory versions differ in their manufacturing processes, built-in ROM, and layout patterns. Because of these differences, characteristic values, operation margins, noise immunity, and noise radiation and oscillation circuit constants may vary within the specified range of electrical characteristics.

When switching to the QzROM version, implement system evaluations equivalent to those performed in the flash memory version.

Confirm page 11 about the differences of functions.

Countermeasures against noise

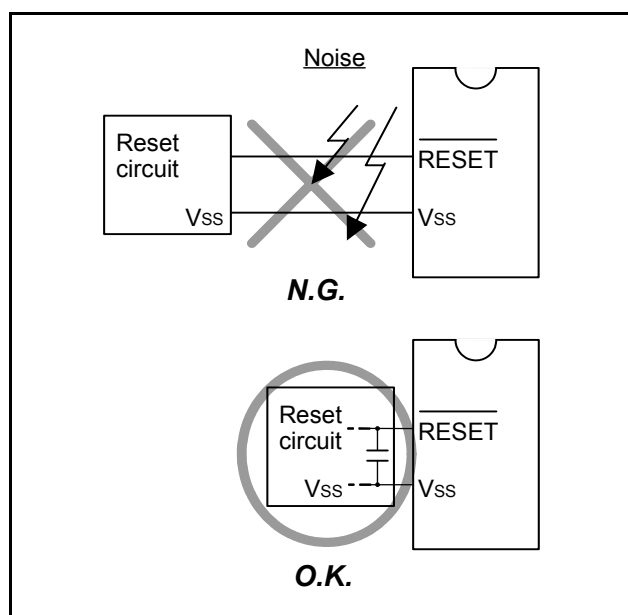
(1) Shortest wiring length

1. Wiring for $\overline{\text{RESET}}$ pin

Make the length of wiring which is connected to the $\overline{\text{RESET}}$ pin as short as possible. Especially, connect a capacitor across the $\overline{\text{RESET}}$ pin and the Vss pin with the shortest possible wiring (within 20 mm).

• Reason

The width of a pulse input into the $\overline{\text{RESET}}$ pin is determined by the timing necessary conditions. If noise having a shorter pulse width than the standard is input to the $\overline{\text{RESET}}$ pin, the reset is released before the internal state of the microcomputer is completely initialized. This may cause a program runaway.

Fig. 90 Wiring for the $\overline{\text{RESET}}$ pin

2. Wiring for clock input/output pins

- Make the length of wiring which is connected to clock I/O pins as short as possible.
- Make the length of wiring (within 20 mm) across the grounding lead of a capacitor which is connected to an oscillator and the Vss pin of a microcomputer as short as possible.
- Separate the Vss pattern only for oscillation from other Vss patterns.

• Reason

If noise enters clock I/O pins, clock waveforms may be deformed.

This may cause a program failure or program runaway. Also, if a potential difference is caused by the noise between the Vss level of a microcomputer and the Vss level of an oscillator, the correct clock will not be input in the microcomputer.

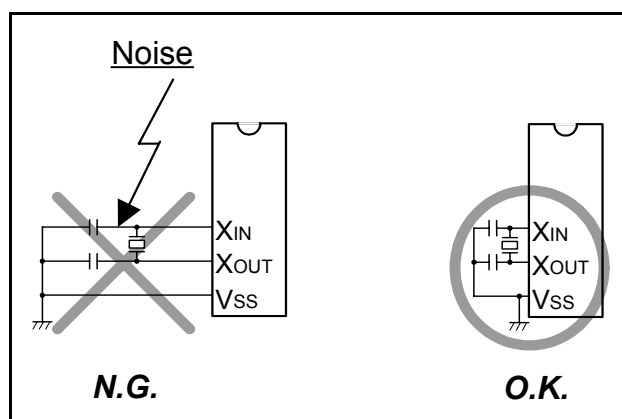


Fig. 91 Wiring for clock I/O pins

(2) Connection of bypass capacitor across Vss line and Vcc line

In order to stabilize the system operation and avoid the latch-up, connect an approximately 0.1 μF bypass capacitor across the Vss line and the Vcc line as follows:

- Connect a bypass capacitor across the Vss pin and the Vcc pin at equal length.
- Connect a bypass capacitor across the Vss pin and the Vcc pin with the shortest possible wiring.
- Use lines with a larger diameter than other signal lines for Vss line and Vcc line.
- Connect the power source wiring via a bypass capacitor to the Vss pin and the Vcc pin.

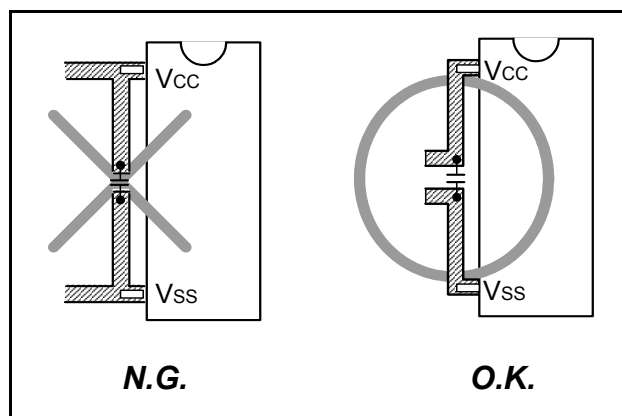


Fig. 92 Bypass capacitor across the Vss line and the Vcc line

(3) Oscillator concerns

In order to obtain the stabilized operation clock on the user system and its condition, contact the oscillator manufacturer and select the oscillator and oscillation circuit constants. Be careful especially when range of voltage and temperature is wide. Also, take care to prevent an oscillator that generates clocks for a microcomputer operation from being affected by other signals.

1. Keeping oscillator away from large current signal lines

Install a microcomputer (and especially an oscillator) as far as possible from signal lines where a current larger than the tolerance of current value flows.

• Reason

In the system using a microcomputer, there are signal lines for controlling motors, LEDs, and thermal heads or others. When a large current flows through those signal lines, strong noise occurs because of mutual inductance.

2. Installing oscillator away from signal lines where potential levels change frequently

Install an oscillator and a connecting pattern of an oscillator away from signal lines where potential levels change frequently. Also, do not cross such signal lines over the clock lines or the signal lines which are sensitive to noise.

• Reason

Signal lines where potential levels change frequently (such as the CNTR pin signal line) may affect other lines at signal rising edge or falling edge. If such lines cross over a clock line, clock waveforms may be deformed, which causes a microcomputer failure or a program runaway.

(4) Analog input

The analog input pin is connected to the capacitor of a voltage comparator. Accordingly, sufficient accuracy may not be obtained by the charge/discharge current at the time of A/D conversion when the analog signal source of high-impedance is connected to an analog input pin. In order to obtain the A/D conversion result stabilized more, please lower the impedance of an analog signal source, or add the smoothing capacitor to an analog input pin.

(5) Difference of memory size

When memory size differ in one group, actual values such as an electrical characteristics, A/D conversion accuracy, and the amount of proof of noise incorrect operation may differ from the ideal values.

When these products are used switching, perform system evaluation for each product of every after confirming product specification.

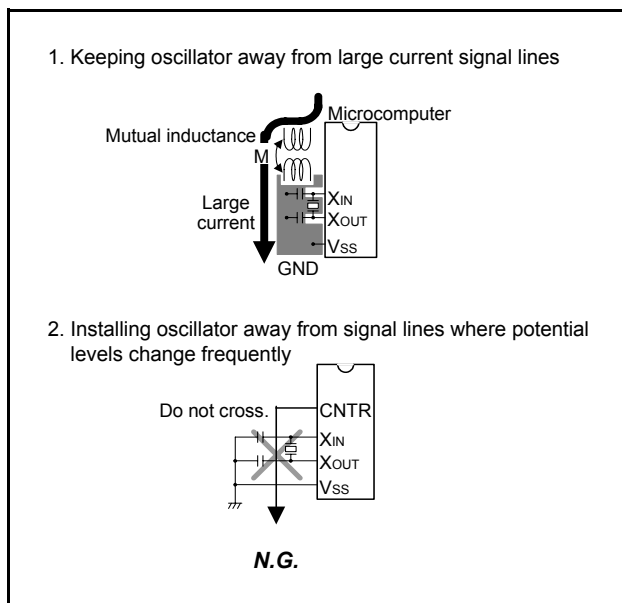


Fig. 93 Wiring for a large current signal line/Wiring of signal lines where potential levels change frequently

QzROM VERSION ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings

Table 21 Absolute maximum ratings

Symbol	Parameter		Conditions	Ratings	Unit
V _{CC}	Power source voltage		All voltages are based on V _{SS} . When an input voltage is measured, output transistors are cut off.	–0.3 to 6.5	V
V _I	Input voltage P00–P07, P10–P17, P20–P27, P30–P37, P40–P47, P50–P57, P60–P62			–0.3 to V _{CC} +0.3	V
V _I	Input voltage	V _{L1}		–0.3 to V _{L2}	V
V _I	Input voltage	V _{L2}		V _{L1} to V _{L3}	V
V _I	Input voltage	V _{L3}		V _{L2} to 6.5	V
V _I	Input voltage $\overline{\text{RESET}}$, X _{IN} , OSCSEL			–0.3 to V _{CC} +0.3	V
V _O	Output voltage P00–P07, P10–P17, P20–P27	at output port		–0.3 to V _{CC} +0.3	V
		at segment port		–0.3 to V _{L3} +0.3	V
V _O	Output voltage COM0–COM3			–0.3 to V _{L3} +0.3	V
V _O	Output voltage P30–P37, P40–P47, P50–P57, P60–P62			–0.3 to V _{CC} +0.3	V
V _O	Output voltage X _{OUT}			–0.3 to V _{CC} +0.3	V
P _d	Power dissipation		T _a = 25°C	300	mW
T _{opr}	Operating temperature		–	–20 to 85	°C
T _{stg}	Storage temperature		–	–40 to 125	°C

Recommended Operating Conditions

Table 22 Recommended operating conditions (1)
(V_{CC} = 1.8 to 5.5 V, V_{SS} = 0 V, T_a = -20 to 85°C unless otherwise noted)

Symbol	Parameter			Limits			Unit	
				Min.	Typ.	Max.		
VCC	Power source voltage ⁽¹⁾	Frequency/2 mode ⁽²⁾	f(XIN) ≤ 12.5MHz	4.5		5.5	V	
			f(XIN) ≤ 8.0MHz	4.0		5.5	V	
			f(XIN) ≤ 4.0MHz	2.0		5.5	V	
			f(XIN) ≤ 2.0MHz	1.8		5.5	V	
		Frequency/4 mode	f(XIN) ≤ 16MHz	4.5		5.5	V	
			f(XIN) ≤ 8.0MHz	2.0		5.5	V	
			f(XIN) ≤ 4.0MHz	1.8		5.5	V	
		Frequency/8 mode	f(XIN) ≤ 16MHz	4.5		5.5	V	
			f(XIN) ≤ 8.0MHz	2.0		5.5	V	
			f(XIN) ≤ 4.0MHz	1.8		5.5	V	
		Low-speed mode			1.8		5.5	V
		On-chip oscillator mode			1.8		5.5	V
		When start oscillating ⁽³⁾			0.05 × f + 1.9			V
VSS	Power source voltage				0		V	
VL3	LCD power source voltage			2.5		5.5	V	
VREF	A/D converter reference voltage			2.0		VCC	V	
AVSS	Analog power source voltage				0		V	
VIA	Analog input voltage AN0–AN7			AVSS		VCC	V	
VIH	“H” input voltage P04–P07, P10–P17, P20–P27, P30, P32, P35, P36, P40–P47, P52, P53, P62			0.7VCC		VCC	V	
VIH	“H” input voltage P00–P03, P31, P33, , P34, P37, P50, 51, P54–P57, P60, P61			0.8VCC		VCC	V	
VIH	“H” input voltage $\overline{\text{RESET}}$	2.2V < VCC ≤ 5.5V	0.8VCC		VCC	V		
		VCC ≤ 2.2V	$V_{CC} - \frac{65 \times V_{CC} - 99}{100}$		VCC	V		
VIH	“H” input voltage XIN			0.8VCC		VCC	V	
VIL	“L” input voltage P04–P07, P10–P17, P20–P27, P30, P32, P35, P36, P40–P47, P52, P53, P62			0		0.3VCC	V	
VIL	“L” input voltage P00–P03, P31, P33, P34, P37, P50, P51, P54–P57, P60, P61, OSCSEL			0		0.2VCC	V	
VIL	“L” input voltage $\overline{\text{RESET}}$	2.2V < VCC ≤ 5.5V	0		0.2VCC	V		
		VCC ≤ 2.2V	0		$\frac{65 \times V_{CC} - 99}{100}$	V		
VIL	“L” input voltage XIN			0		0.2VCC	V	

NOTES:

- When the A/D converter is used, refer to the recommended operating conditions of the A/D converter.
 - 12.5 MHz < f(X_{IN}) ≤ 16 MHz is not available in the frequency/2 mode.
 - The oscillation start voltage and the oscillation start time differ depending on factors such as the oscillator, circuit constants, and operating temperature range. Note that oscillation start may be particularly difficult at low voltage when using a high-frequency oscillator.
- f: Oscillation frequency (1 MHz ≤ f(X_{IN}) ≤ 8 MHz) of oscillator. When the 8 MHz oscillation is used, assign “8” to “f”.

Table 23 Recommended operating conditions (3)
(V_{CC} = 1.8 to 5.5 V, V_{SS} = 0 V, T_a = -20 to 85°C, unless otherwise noted)

Symbol	Parameter	Limits			Unit
		Min.	Typ.	Max.	
$\Sigma I_{OH(peak)}$	"H" total peak output current (1) P00-P07, P10-P17, P20-P27, P30-P37			-40	mA
$\Sigma I_{OH(peak)}$	"H" total peak output current (1) P40-P47, P50-P57, P60-P62			-40	mA
$\Sigma I_{OL(peak)}$	"L" total peak output current (1) P00-P07, P10-P17, P20-P27			40	mA
$\Sigma I_{OL(peak)}$	"L" total peak output current (1) P40-P47, P50, P51, P54-P57, P60-P62			40	mA
$\Sigma I_{OL(peak)}$	"L" total peak output current (1) P30-P37, P52, P53			110	mA
$\Sigma I_{OH(avg)}$	"H" total average output current (1) P00-P07, P10-P17, P20-P27, P30-P37			-20	mA
$\Sigma I_{OH(avg)}$	"H" total average output current (1) P40-P47, P50-P57, P60-P62			-20	mA
$\Sigma I_{OL(avg)}$	"L" total average output current (1) P00-P07, P10-P17, P20-P27			20	mA
$\Sigma I_{OL(avg)}$	"L" total average output current (1) P40-P47, P50, P51, P54-P57, P60-P62			20	mA
$\Sigma I_{OL(avg)}$	"L" total average output current (1) P30-P37, P52, P53			90	mA
$I_{OH(peak)}$	"H" peak output current (2) P00-P07, P10-P17, P20-P27			-2.0	mA
$I_{OH(peak)}$	"H" peak output current (2) P30-P37, P40-P47, P50-P57, P60-P62			-5.0	mA
$I_{OL(peak)}$	"L" peak output current (2) P00-P07, P10-P17, P20-P27			5.0	mA
$I_{OL(peak)}$	"L" peak output current (2) P40-P47, P50, P51, P54-P57, P60-P62			10	mA
$I_{OL(peak)}$	"L" peak output current (2) P30-P37, P52, P53			30	mA
$I_{OH(avg)}$	"H" average output current (3) P00-P07, P10-P17, P20-P27			-1.0	mA
$I_{OH(avg)}$	"H" average output current (3) P30-P37, P40-P47, P50-P57, P60-P62			-2.5	mA
$I_{OL(avg)}$	"L" average output current (3) P00-P07, P10-P17, P20-P27			2.5	mA
$I_{OL(avg)}$	"L" average output current (3) P40-P47, P50, P51, P54-P57, P60-P62			5.0	mA
$I_{OL(avg)}$	"L" average output current (3) P30-P37, P52, P53			15	mA

NOTES:

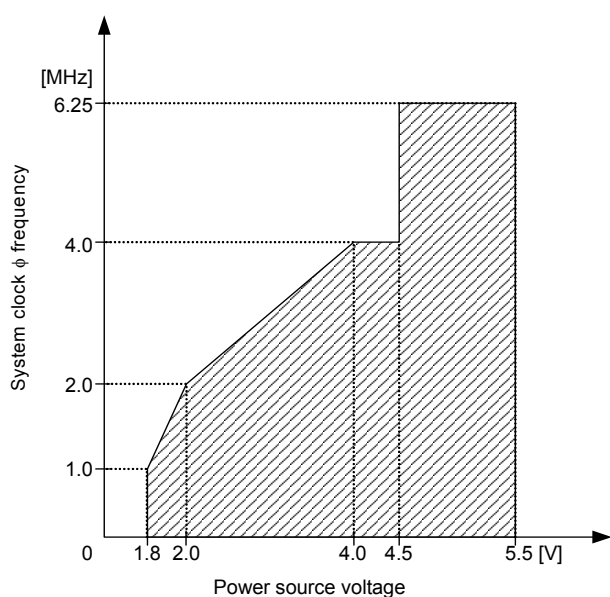
1. The total output current is the sum of all the currents flowing through all the applicable ports. The total average current is an average value measured over 100 ms. The total peak current is the peak value of all the currents.
2. The peak output current is the peak current flowing in each port.
3. The average output current is average value measured over 100 ms.

Table 24 Recommended operating conditions (4)
($V_{CC} = 1.8$ to 5.5 V, $V_{SS} = 0$ V, $T_a = -20$ to 85°C , unless otherwise noted)

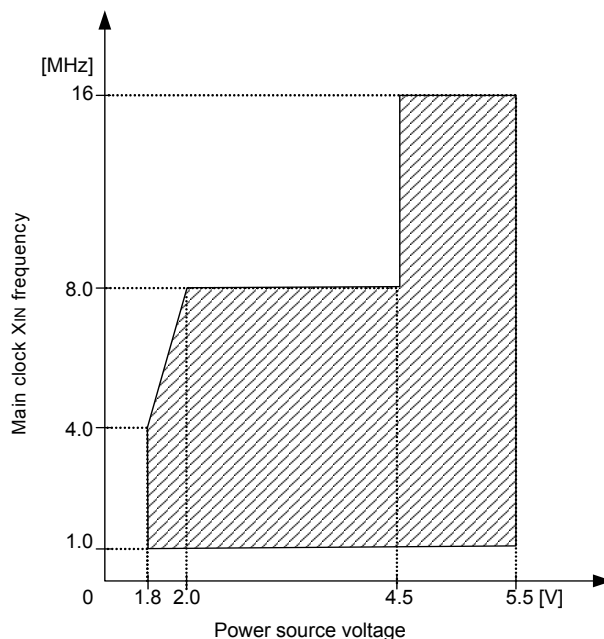
Symbol	Parameter	Conditions	Limits			Unit
			Min.	Typ.	Max.	
$f(\text{CNTR}_0)$ $f(\text{CNTR}_1)$	Timer X and Timer Y Input frequency (duty cycle 50%)	$4.5 \leq V_{CC} \leq 5.5\text{V}$			6.25	MHz
		$4.0 \leq V_{CC} < 4.5\text{V}$			$2 \times V_{CC} - 4$	MHz
		$2.0 \leq V_{CC} < 4.0\text{V}$			V_{CC}	MHz
		$V_{CC} < 2.0\text{V}$			$5 \times V_{CC} - 8$	MHz
$f(\text{Tclk})$	Timer X, Timer Y, Timer 1, Timer 2, Timer 3, Timer 4 clock input frequency (Count source frequency of each timer)	$4.5 \leq V_{CC} \leq 5.5\text{V}$			16	MHz
		$4.0 \leq V_{CC} < 4.5\text{V}$			$4 \times V_{CC} - 8$	MHz
		$2.0 \leq V_{CC} < 4.0\text{V}$			$2 \times V_{CC}$	MHz
		$V_{CC} < 2.0\text{V}$			$10 \times V_{CC} - 16$	MHz
$f(\phi)$	System clock ϕ frequency ⁽¹⁾	$4.5 \leq V_{CC} \leq 5.5\text{V}$			6.25	MHz
		$4.0 \leq V_{CC} < 4.5\text{V}$			4	MHz
		$2.0 \leq V_{CC} < 4.0\text{V}$			V_{CC}	MHz
		$V_{CC} < 2.0\text{V}$			$5 \times V_{CC} - 8$	MHz
$f(\text{XIN})$	Main clock input frequency (duty cycle 50%) ⁽²⁾⁽³⁾	$4.5 \leq V_{CC} \leq 5.5\text{V}$	1.0		16	MHz
		$2.0 \leq V_{CC} < 4.5\text{V}$	1.0		8.0	MHz
		$V_{CC} < 2.0\text{V}$	1.0		$20 \times V_{CC} - 32$	MHz
$f(\text{XCIN})$	Sub-clock oscillation frequency (duty cycle 50%) ⁽⁴⁾⁽⁵⁾			32.768	80	kHz

NOTES:

- Relationship between system clock ϕ frequency and power source voltage is shown in the graph below.
- When the A/D converter is used, refer to the recommended operating conditions of the A/D converter.
- $12.5\text{ MHz} < f(\text{XIN}) \leq 16\text{ MHz}$ is not available in the frequency/2 mode.
- The oscillation start voltage and the oscillation start time differ depending on factors such as the oscillator, circuit constants, and operation temperature range. Note that oscillation start may be particularly difficult at low voltage when using a high-frequency oscillator.
- When using the microcomputer in low-speed mode, set the clock input oscillation frequency on condition that $f(\text{XCIN}) < f(\text{XIN})/3$.

<System clock ϕ frequency>

<Main clock XIN frequency>



Electrical Characteristics

Table 25 Electrical characteristics (1)

(V_{CC} = 1.8 to 5.5 V, V_{SS} = 0 V, T_a = -20 to 85°C, unless otherwise noted)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V _{OH}	“H” output voltage P00–P07, P10–P17, P20–P27	I _{OH} = -2.5mA	V _{CC} -2.0			V
		I _{OH} = -0.6mA V _{CC} =2.5V	V _{CC} -1.0			
V _{OH}	“H” output voltage P30–P37, P40–P47, P50–P57, P60–P62 (1)	I _{OH} = -5mA	V _{CC} -2.0			V
		I _{OH} = -1.25mA	V _{CC} -0.5			
		I _{OH} = -1.25mA V _{CC} =2.5V	V _{CC} -1.0			
V _{OL}	“L” output voltage P00–P07, P10–P17, P20–P27	I _{OL} =5mA			2.0	V
		I _{OL} =1.25mA			0.5	
		I _{OL} =1.25mA V _{CC} =2.5V			1.0	
V _{OL}	“L” output voltage P40–P47, P50, P51, P54–P57, P60–P61 (1)	I _{OL} =10mA			2.0	V
		I _{OL} =2.5mA			0.5	
		I _{OL} =2.5mA V _{CC} =2.5V			1.0	
V _{OL}	“L” output voltage P30–P37, P52, P53	I _{OL} =15mA			2.0	V
		I _{OL} =3.0mA V _{CC} =2.5V			0.8	
V _{T+} – V _{T-}	Hysteresis CNTR0, CNTR1, INT0–INT2, KW0–KW7			0.5		V
V _{T+} – V _{T-}	Hysteresis RxD1, RxD2, SCLK1, SCLK2			0.5		V
V _{T+} – V _{T-}	Hysteresis RESET	V _{CC} = 2.0 V to 5.5 V on RESET		0.5		V
I _{IH}	“H” input current P00–P07, P10–P17, P20–P27	V _I =V _{CC}			5.0	μA
I _{IH}	“H” input current P30–P37, P40–P47, P50–P57, P60–P62	V _I =V _{CC}			5.0	μA
I _{IH}	“H” input current RESET, OSCSEL	V _I =V _{CC}			5.0	μA
I _{IH}	“H” input current X _{IN}	V _I =V _{CC}		4.0		μA
I _{IL}	“L” input current P00–P07, P10–P17, P20–P27	V _I =V _{SS} Pull-up “OFF”			-5.0	μA
		V _{CC} =5.0V, V _I =V _{SS} Pull-up “ON”	-60	-120	-240	μA
		V _{CC} =3.0V, V _I =V _{SS} Pull-up “ON”	-25	-50	-100	μA
I _{IL}	“L” input current P30–P37, P40–P47, P50–P57, P60– P62	V _I =V _{SS} Pull-up “OFF”			-5.0	μA
		V _{CC} =5.0V, V _I =V _{SS} Pull-up “ON”	-30	-70	-140	μA
		V _{CC} =3.0V, V _I =V _{SS} Pull-up “ON”	-6.5	-25	-45	μA
I _{IL}	“L” input current RESET, OSCSEL	V _I =V _{SS}			-5.0	μA
I _{IL}	“L” input current X _{IN}	V _I =V _{SS}		-4.0		μA
f(OCO)	On-chip oscillator frequency	V _{CC} =5.0V, T _a =25°C	2500	5000	7500	kHz

NOTE:

1. When the port Xc switch bit (bit 4 of address 003B16) of CPU mode register is “1”, the drivability of P62 is different from the above.

Table 26 Electrical characteristics (2)

(V_{CC} = 1.8 to 5.5 V, V_{SS} = 0 V, T_a = -20 to 85°C, f(X_{CIN}) = 32.768 kHz, output transistors in the cut-off state, A/D converter stopped, unless otherwise noted)

Symbol	Parameter	Test conditions			Limits			Unit	
					Min.	Typ.	Max.		
VRAM	RAM hold voltage	When clock is stopped			1.8		5.5	V	
ICC	Power source current	Frequency/2 mode	VCC=5.0V	f(XIN)=12.5MHz		6.4	13	mA	
				f(XIN)=12.5MHz (in WIT state)		1.5	3.0	mA	
				f(XIN)=4MHz		2.2	3.0	mA	
			VCC=2.5V	f(XIN)=4MHz		0.6	1.2	mA	
				f(XIN)=4MHz (in WIT state)		0.3	0.6	mA	
				f(XIN)=2MHz		0.4	0.8	mA	
			Frequency/4 mode	VCC=5.0V	f(XIN)=12.5MHz		3.5	10	mA
					f(XIN)=12.5MHz (in WIT state)		1.5	3.0	mA
					f(XIN)=4MHz		1.5	2.5	mA
		VCC=2.5V		f(XIN)=8MHz		0.8	2.5	mA	
				f(XIN)=8MHz (in WIT state)		0.3	0.6	mA	
				f(XIN)=4MHz		0.5	1.0	mA	
		Frequency/8 mode	VCC=5.0V	f(XIN)=12.5MHz		2.5	5.0	mA	
				f(XIN)=12.5MHz (in WIT state)		1.5	3.0	mA	
				f(XIN)=4MHz		1.2	1.6	mA	
			VCC=2.5V	f(XIN)=8MHz		0.5	1.0	mA	
				f(XIN)=8MHz (in WIT state)		0.3	0.6	mA	
				f(XIN)=4MHz		0.3	0.6	mA	
		Low-speed mode	VCC=5.0V	f(XIN)=stop		17	26	μA	
				in WIT state		5.5	11	μA	
			VCC=2.5V	f(XIN)=stop		7.0	14	μA	
				in WIT state		3.5	7.0	μA	
		On-chip oscillator mode f(XIN), f(XCIN) = stop			VCC=5.0V		270	540	μA
					VCC=2.5V		35	90	μA
					VCC=2.5V (in WIT state)		25	75	μA
		All oscillations stopped (in STP state)			Ta=25°C		0.1	1.0	μA
					Ta=85°C			10	μA
Current increased at A/D converter operating			f(XIN)=12.5 MHz, VCC=5 V in frequency/2, 4 or 8 mode		0.5		mA		
			f(XIN)= stop, VCC = 5 V in on-chip oscillator operating		0.5		mA		
			f(XIN) = stop, VCC = 5 V in low-speed mode		0.4		mA		

A/D Converter Characteristics

Table 27 A/D converter recommended operating condition

(V_{CC} = 2.0 to 5.5 V, V_{SS} = 0V, T_a = -20 to 85°C, output transistors in cut-off state, unless otherwise noted)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V _{CC}	Power source voltage		2.0	5.0	5.5	V
V _{IH}	"H" input voltage ADKEY		0.9V _{CC}		V _{CC}	V
V _{IL}	"L" input voltage ADKEY		0		0.7 × V _{CC} -0.5	V
f(φ _{AD})	AD converter clock frequency ⁽¹⁾ (Low-speed • on-chip oscillator mode excluded)	4.5V < V _{CC} ≤ 5.5V			6.25	MHz
		4.0V < V _{CC} ≤ 4.5V			4.0	MHz
		2.0V < V _{CC} ≤ 4.0V			V _{CC}	MHz

NOTE:

1. Confirm the recommended operating condition for main clock input frequency.

Table 28 A/D converter characteristics

($V_{CC} = 2.0$ to 5.5 V, $T_a = -20$ to 85°C , output transistors in cut-off state, low-speed • on-chip oscillator mode included, unless otherwise noted)

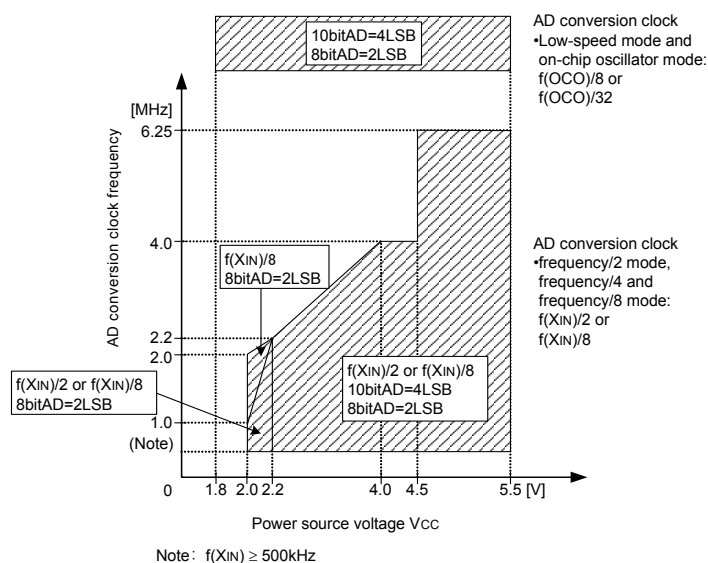
Symbol	Parameter	Test conditions		Limits			Unit							
				Min.	Typ.	Max.								
–	Resolution					10	Bits							
ABS	Absolute accuracy (quantification error excluded)	10bitAD mode	4.5V < V _{CC} ≤ 5.5V, AD conversion clock=f(X _{IN})/2, f(X _{IN})/8 ≤ 6.25MHz			4	LSB							
			4.0V < V _{CC} ≤ 4.5V, AD conversion clock=f(X _{IN})/2, f(X _{IN})/8 ≤ 4MHz											
			2.2V ≤ V _{CC} ≤ 4.0V, AD conversion clock=f(X _{IN})/2, f(X _{IN})/8 ≤ V _{CC} MHz											
			2.0V ≤ V _{CC} ≤ 5.5V, AD conversion clock=f(OCO)/8, f(OCO)/32											
		8bitAD mode	4.5V < V _{CC} ≤ 5.5V, AD conversion clock=f(X _{IN})/2, f(X _{IN})/8 ≤ 6.25MHz					2						
			4.0V < V _{CC} ≤ 4.5V, AD conversion clock=f(X _{IN})/2, f(X _{IN})/8 ≤ 4MHz											
			2.2V < V _{CC} ≤ 4.0V, AD conversion clock=f(X _{IN})/2, f(X _{IN})/8 ≤ V _{CC} MHz											
			2.0V ≤ V _{CC} ≤ 2.2V, AD conversion clock=f(X _{IN})/2, f(X _{IN})/8 ≤ (6V _{CC} –11)MHz											
			2.0V ≤ V _{CC} ≤ 2.2V, AD conversion clock=f(X _{IN})/8 ≤ V _{CC} MHz											
			2.0V ≤ V _{CC} ≤ 5.5V, AD conversion clock=f(OCO)/8, f(OCO)/32											
			t _{CONV}			Conversion time ⁽¹⁾			10bitAD mode	tc(φAD)×61		tc(φAD)×62	μs	
						8bitAD mode			tc(φAD)×49		tc(φAD)×50			
RLADDER	Ladder resistor			12	35	100	kΩ							
I _{VREF}	Reference input current	V _{REF} =5.0V		50	150	200	μA							
I _{IA}	Analog input current					5.0	μA							

NOTES:

1. tc(ϕ AD): one cycle of AD conversion clock. AD conversion clock can be selected from ϕ SOURCE/2 or ϕ SOURCE/8. ϕ SOURCE represents the X_{IN} input in the frequency/2, 4 or 8 mode and internal on-chip oscillator divided by 4 in the on-chip oscillator mode or the low-speed mode.

When the A/D conversion is executed in the frequency/2 mode, frequency/4 mode, or frequency/8 mode, set $f(X_{IN}) \geq 500$ kHz.

Relationship among AD conversion clock frequency, power source voltage, AD conversion mode and absolute accuracy.



LCD power supply characteristics

Table 29 LCD power supply characteristics (when connecting division resistors for LCD power supply)
(V_{CC} = 1.8 to 5.5 V, V_{SS} = 0 V, T_a = -20 to 85°C, unless otherwise noted)

Symbol	Parameter	Test conditions			Limits			Unit
					Min.	Typ.	Max.	
R _{LCD}	Division resistor for LCD power supply ⁽¹⁾	RSEL="10"				200		kΩ
		RSEL="11"				5		
		LCD drive timing A	LCD circuit division ratio = divided by 1	RSEL="01"		120		
				RSEL="00"		90		
			LCD circuit division ratio = divided by 2	RSEL="01"		150		
				RSEL="00"		120		
			LCD circuit division ratio = divided by 4	RSEL="01"		170		
				RSEL="00"		150		
			LCD circuit division ratio = divided by 8	RSEL="01"		190		
				RSEL="00"		170		
		LCD drive timing B	LCD circuit division ratio = divided by 1	RSEL="01"		150		
				RSEL="00"		120		
			LCD circuit division ratio = divided by 2	RSEL="01"		170		
				RSEL="00"		150		
			LCD circuit division ratio = divided by 4	RSEL="01"		190		
				RSEL="00"		170		
			LCD circuit division ratio = divided by 8	RSEL="01"		190		
				RSEL="00"		190		

NOTE:

1. The value is the average of each one division resistor.

Timing Requirements and Switching Characteristics

Table 30 Timing requirements (1)

(V_{CC} = 4.0 to 5.5 V, V_{SS} = 0 V, T_a = –20 to 85°C, unless otherwise noted)

Symbol	Parameter		Limits			Unit
			Min.	Typ.	Max.	
tw(RESET)	Reset input "L" pulse width		2			μs
tc(XIN)	Main clock input cycle time	4.5V ≤ V _{CC} ≤ 5.5V (1)	62.5			ns
		4.0V ≤ V _{CC} < 4.5V	125			ns
twh(XIN)	Main clock input "H" pulse width	4.5V ≤ V _{CC} ≤ 5.5V (2)	25			ns
		4.0V ≤ V _{CC} < 4.5V	50			ns
tWL(XIN)	Main clock input "L" pulse width	4.5V ≤ V _{CC} ≤ 5.5V (2)	25			ns
		4.0V ≤ V _{CC} < 4.5V	50			ns
tc(CNTR)	CNTR0, CNTR1 input cycle time		250			ns
twh(CNTR)	CNTR0, CNTR1 input "H" pulse width		105			ns
tWL(CNTR)	CNTR0, CNTR1 input "L" pulse width		105			ns
twh(INT)	INT0–INT2 input "H" pulse width		80			ns
tWL(INT)	INT0–INT2 input "L" pulse width		80			ns
tc(SCLK)	Serial I/O1, 2 clock input cycle time (3)		800			ns
twh(SCLK)	Serial I/O1, 2 clock input "H" pulse width (3)		370			ns
tWL(SCLK)	Serial I/O1, 2 clock input "L" pulse width (3)		370			ns
tsu(RxD–SCLK)	Serial I/O1, 2 input setup time		220			ns
th(SCLK–RxD)	Serial I/O1, 2 input hold time		100			ns

NOTES:

1. 80 ns in the frequency/2 mode.
2. 32 ns in the frequency/2 mode.
3. When bit 6 of address 001A₁₆, 001F₁₆ are "1" (clock synchronous).
Divide this value by four when bit 6 of address 001A₁₆, 001F₁₆ are "0" (UART).

Table 31 Timing requirements (2)

(V_{CC} = 1.8 to 4.0 V, V_{SS} = 0 V, T_a = –20 to 85°C, unless otherwise noted)

Symbol	Parameter		Limits			Unit
			Min.	Typ.	Max.	
tw(RESET)	Reset input "L" pulse width		2			μs
tc(XIN)	Main clock input cycle time (XIN input)	2.0V ≤ V _{CC} ≤ 4.0V	125			ns
		V _{CC} < 2.0V	166			ns
twh(XIN)	Main clock input "H" pulse width	2.0V ≤ V _{CC} ≤ 4.0V	50			ns
		V _{CC} < 2.0V	70			ns
tWL(XIN)	Main clock input "L" pulse width	2.0V ≤ V _{CC} ≤ 4.0V	50			ns
		V _{CC} < 2.0V	70			ns
tc(CNTR)	CNTR0, CNTR1 input cycle time	2.0V ≤ V _{CC} ≤ 4.0V	1000/V _{CC}			ns
		V _{CC} < 2.0V	1000/(5 × V _{CC} –8)			ns
twh(CNTR)	CNTR0, CNTR1 input "H" pulse width		tc(CNTR)/2–20			ns
tWL(CNTR)	CNTR0, CNTR1 input "L" pulse width		tc(CNTR)/2–20			ns
twh(INT)	INT0–INT2 input "H" pulse width		230			ns
tWL(INT)	INT0–INT2 input "L" pulse width		230			ns
tc(SCLK)	Serial I/O1, 2 clock input cycle time (1)		2000			ns
twh(SCLK)	Serial I/O1, 2 clock input "H" pulse width (1)		950			ns
tWL(SCLK)	Serial I/O1, 2 clock input "L" pulse width (1)		950			ns
tsu(RxD–SCLK)	Serial I/O1, 2 input setup time		400			ns
th(SCLK–RxD)	Serial I/O1, 2 input hold time		200			ns

NOTE:

1. When bit 6 of address 001A₁₆, 001F₁₆ are "1" (clock synchronous).
Divide this value by four when bit 6 of address 001A₁₆, 001F are "0" (UART).

Table 32 Switching characteristics (1)

(V_{CC} = 4.0 to 5.5 V, V_{SS} = 0 V, T_a = -20 to 85°C, unless otherwise noted)

Symbol	Parameter	Limits			Unit
		Min.	Typ	Max.	
t _{WH} (SCLK)	Serial I/O1, 2 clock output "H" pulse width	t _c (SCLK)/2-30			ns
t _{WL} (SCLK)	Serial I/O1, 2 clock output "L" pulse width	t _c (SCLK)/2-30			ns
t _d (SCLK-TxD)	Serial I/O1, 2 output delay time ⁽¹⁾			140	ns
t _v (SCLK-TxD)	Serial I/O1, 2 output valid time ⁽¹⁾	-30			ns
t _r (SCLK)	Serial I/O1, 2 clock output rising time			30	ns
t _f (SCLK)	Serial I/O1, 2 clock output falling time			30	ns

NOTE:

1. The P5₅/TxD₁ [P3₂/TxD₂] P-channel output disable bit (bit 4 of address 001B₁₆ [001F₁₆]) of UART control register is "0".

Table 33 Switching characteristics (2)

(V_{CC} = 1.8 to 4.0 V, V_{SS} = 0 V, T_a = -20 to 85°C, unless otherwise noted)

Symbol	Parameter	Limits			Unit
		Min.	Typ	Max.	
t _{WH} (SCLK)	Serial I/O1, 2 clock output "H" pulse width	t _c (SCLK)/2-80			ns
t _{WL} (SCLK)	Serial I/O1, 2 clock output "L" pulse width	t _c (SCLK)/2-80			ns
t _d (SCLK-TxD)	Serial I/O1, 2 output delay time ⁽¹⁾			350	ns
t _v (SCLK-TxD)	Serial I/O1, 2 output valid time ⁽¹⁾	-30			ns
t _r (SCLK)	Serial I/O1, 2 clock output rising time			80	ns
t _f (SCLK)	Serial I/O1, 2 clock output falling time			80	ns

NOTE:

1. The P5₅/TxD₁ [P3₂/TxD₂] P-channel output disable bit (bit 4 of address 001B₁₆ [001F₁₆]) of UART control register is "0".

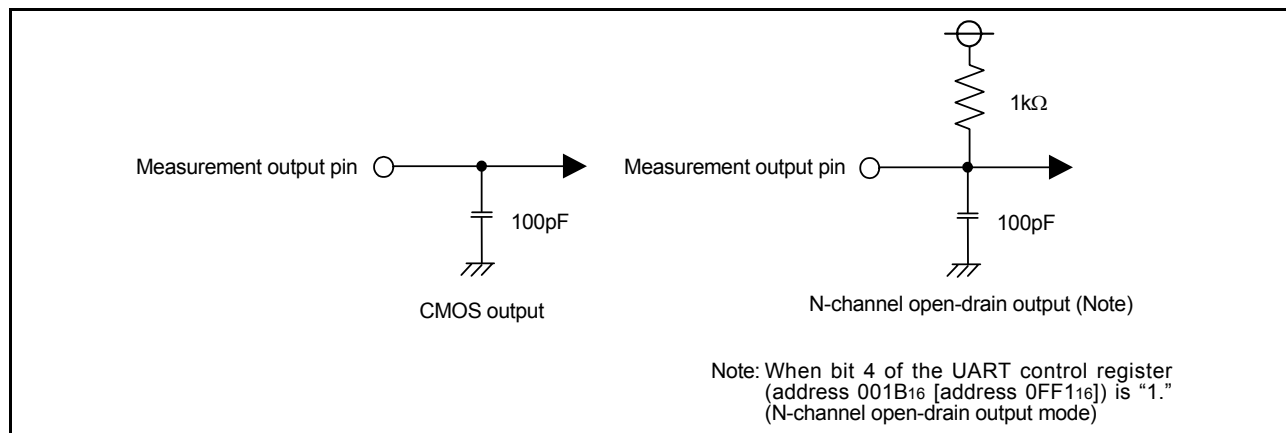


Fig 94. Circuit for measuring output switching characteristics

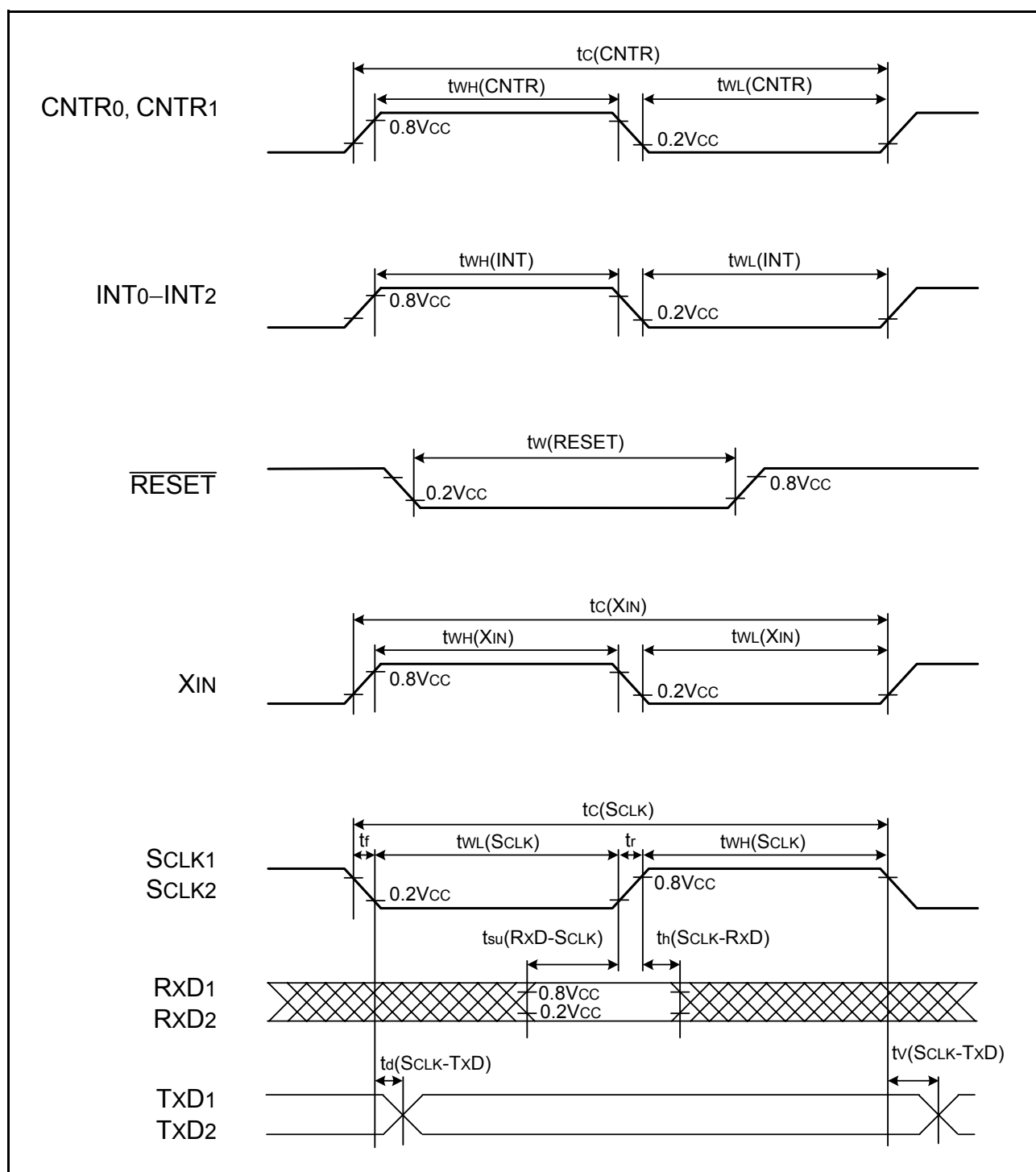


Fig 95. Timing diagram

FLASH MEMORY VERSION ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings

Table 34 Absolute maximum ratings

Symbol	Parameter		Conditions	Ratings	Unit
V _{CC}	Power source voltage		All voltages are based on V _{SS} . When an input voltage is measured, output transistors are cut off.	−0.3 to 6.5	V
V _I	Input voltage P00–P07, P10–P17, P20–P27, P30–P37, P40–P47, P50–P57, P60–P62			−0.3 to V _{CC} +0.3	V
V _I	Input voltage	V _{L1}		−0.3 to V _{L2}	V
V _I	Input voltage	V _{L2}		V _{L1} to V _{L3}	V
V _I	Input voltage	V _{L3}		V _{L2} to 6.5	V
V _I	Input voltage	<u>RESET</u> , X _{IN} , CNV _{SS}		−0.3 to V _{CC} +0.3	V
V _O	Output voltage P00–P07, P10–P17, P20–P27	At output port		−0.3 to V _{CC} +0.3	V
		At segment output		−0.3 to V _{L3} +0.3	V
V _O	Output voltage COM0–COM3			−0.3 to V _{L3} +0.3	V
V _O	Output voltage P30–P37, P40–P47, P50–P57, P60–P62			−0.3 to V _{CC} +0.3	V
V _O	Output voltage X _{OUT}			−0.3 to V _{CC} +0.3	V
P _d	Power dissipation		T _a =25°C	300	mW
T _{opr}	Operating temperature		–	−20 to 85	°C
T _{stg}	Storage temperature		-	−40 to 125	°C

Recommended Operating Conditions

Table 35 Recommended operating conditions (1)
 (V_{CC} = 2.7 to 5.5 V, V_{SS} = 0 V, T_a = -20 to 85°C unless otherwise noted)

Symbol	Parameter			Limits			Unit
				Min.	Typ.	Max.	
VCC	Power source voltage ⁽¹⁾	Frequency/2 mode ⁽²⁾	f(X _{IN}) ≤ 12.5MHz	4.5		5.5	V
			f(X _{IN}) ≤ 8MHz	4.0		5.5	V
			f(X _{IN}) ≤ 4MHz	2.7		5.5	V
		Frequency/4 mode	f(X _{IN}) ≤ 16MHz	4.5		5.5	V
			f(X _{IN}) ≤ 8MHz	2.7		5.5	V
		Frequency/8 mode	f(X _{IN}) ≤ 16MHz	4.5		5.5	V
			f(X _{IN}) ≤ 8MHz	2.7		5.5	V
		Low-speed mode		2.7		5.5	V
		On-chip oscillator mode		2.7		5.5	V
VSS	Power source voltage				0		V
VL3	LCD power source voltage			2.5		5.5	V
VREF	A/D converter reference voltage			2.7		Vcc	V
AVSS	Analog power source voltage				0		V
VIA	Analog input voltage AN0–AN7			AVss		Vcc	V
VIH	“H” input voltage	P04–P07, P10–P17, P20–P27, P30, P32, P35, P36, P40–P47, P52, P53, P62		0.7Vcc		Vcc	V
VIH	“H” input voltage	P00–P03, P31, P33, P34, P37, P50, P51, P54–P57, P60, P61		0.8Vcc		Vcc	V
VIH	“H” input voltage	$\overline{\text{RESET}}$		0.8Vcc		Vcc	V
VIH	“H” input voltage	XIN		0.8Vcc		Vcc	V
VIL	“L” input voltage	P04–P07, P10–P17, P20–P27, P30, P32, P35, P36, P40–P47, P52, P53, P62		0		0.3Vcc	V
VIL	“L” input voltage	P00–P03, P31, P33, P34, P37, P50, P51, P54–P57, P60, P61, CNVss		0		0.2Vcc	V
VIL	“L” input voltage	$\overline{\text{RESET}}$		0		0.2Vcc	V
VIL	“L” input voltage	XIN		0		0.2Vcc	V

NOTES:

1. When the A/D converter is used, refer to the recommended operating conditions of the A/D converter.
2. 12.5 MHz < f(X_{IN}) ≤ 16 MHz is not available in the frequency/2 mode.

Table 36 Recommended operating conditions (3)
(V_{CC} = 2.7 to 5.5 V, V_{SS} = 0 V, T_a = –20 to 85°C, unless otherwise noted)

Symbol	Parameter	Limits			Unit
		Min.	Typ.	Max.	
$\Sigma I_{OH(peak)}$	“H” total peak output current (1) P00–P07, P10–P17, P20–P27, P30–P37			–40	mA
$\Sigma I_{OH(peak)}$	“H” total peak output current (1) P40–P47, P50–P57, P60–P62			–40	mA
$\Sigma I_{OL(peak)}$	“L” total peak output current (1) P00–P07, P10–P17, P20–P27			40	mA
$\Sigma I_{OL(peak)}$	“L” total peak output current (1) P40–P47, P50, P51, P54–P57, P60–P62			40	mA
$\Sigma I_{OL(peak)}$	“L” total peak output current (1) P30–P37, P52, P53			110	mA
$\Sigma I_{OH(avg)}$	“H” total average output current (1) P00–P07, P10–P17, P20–P27, P30–P37			–20	mA
$\Sigma I_{OH(avg)}$	“H” total average output current (1) P40–P47, P50–P57, P60–P62			–20	mA
$\Sigma I_{OL(avg)}$	“L” total average output current (1) P00–P07, P10–P17, P20–P27			20	mA
$\Sigma I_{OL(avg)}$	“L” total average output current (1) P40–P47, P50, P51, P54–P57, P60–P61			20	mA
$\Sigma I_{OL(avg)}$	“L” total average output current (1) P30–P37, P52, P53			90	mA
$I_{OH(peak)}$	“H” peak output current (2) P00–P07, P10–P17, P20–P27			–2.0	mA
$I_{OH(peak)}$	“H” peak output current (2) P30–P37, P40–P47, P50–P57, P62–P62			–5.0	mA
$I_{OL(peak)}$	“L” peak output current (2) P00–P07, P10–P17, P20–P27			5.0	mA
$I_{OL(peak)}$	“L” peak output current (2) P40–P47, P50, P51, P54–P57, P60–P62			10	mA
$I_{OL(peak)}$	“L” peak output current (2) P30–P37, P52, P53			30	mA
$I_{OH(avg)}$	“H” average output current (3) P00–P07, P10–P17, P20–P27			–1.0	mA
$I_{OH(avg)}$	“H” average output current (3) P30–P37, P40–P47, P50–P57, P60–P62			–2.5	mA
$I_{OL(avg)}$	“L” average output current (3) P00–P07, P10–P17, P20–P27			2.5	mA
$I_{OL(avg)}$	“L” average output current (3) P40–P47, P50, P51, P54–P57, P60–P62			5.0	mA
$I_{OL(avg)}$	“L” average output current (3) P30–P37, P52, P53			15	mA

NOTES:

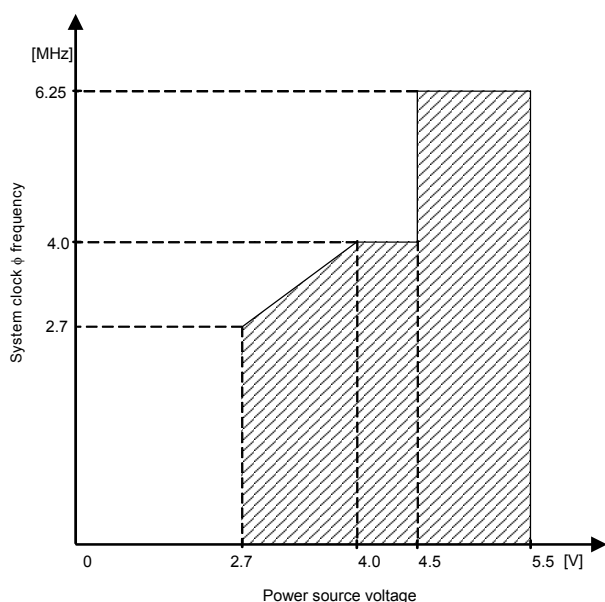
1. The total output current is the sum of all the currents flowing through all the applicable ports. The total average current is an average value measured over 100 ms. The total peak current is the peak value of all the currents.
2. The peak output current is the peak current flowing in each port.
3. The average output current is average value measured over 100 ms.

Table 37 Recommended operating conditions (4)
 ($V_{CC} = 2.7$ to 5.5 V, $V_{SS} = 0$ V, $T_a = -20$ to 85°C , unless otherwise noted)

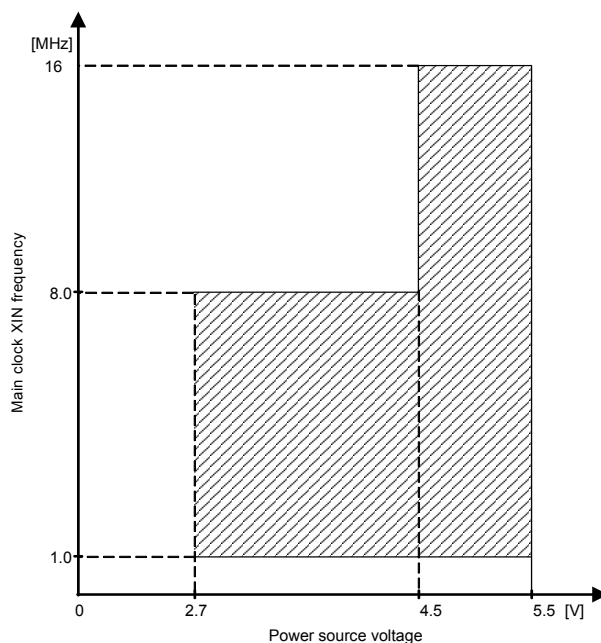
Symbol	Parameter	Conditions	Limits			Unit
			Min.	Typ.	Max.	
$f(\text{CNTR0})$ $f(\text{CNTR1})$	Timer X and Timer Y Input frequency (duty cycle 50%)	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$			6.25	MHz
		$4.0\text{V} \leq V_{CC} < 4.5\text{V}$			$2 \times V_{CC} - 4$	MHz
		$2.7\text{V} \leq V_{CC} < 4.0\text{V}$			V_{CC}	MHz
$f(\text{Tclk})$	Timer X, Timer Y, Timer 1, Timer 2, Timer 3, Timer 4 clock input frequency (Count source frequency of each timer)	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$			16	MHz
		$4.0\text{V} \leq V_{CC} < 4.5\text{V}$			$4 \times V_{CC} - 8$	MHz
		$2.7\text{V} \leq V_{CC} < 4.0\text{V}$			$2 \times V_{CC}$	MHz
$f(\phi)$	System clock ϕ frequency (1)	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$			6.25	MHz
		$4.0\text{V} \leq V_{CC} < 4.5\text{V}$			4	MHz
		$2.7\text{V} \leq V_{CC} < 4.0\text{V}$			V_{CC}	MHz
$f(\text{XIN})$	Main clock input frequency (duty cycle 50%) (2)(3)	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$	1.0		16	MHz
		$2.7\text{V} \leq V_{CC} < 4.5\text{V}$	1.0		8.0	MHz
$f(\text{XCIN})$	Sub-clock oscillation frequency (duty cycle 50%) (4)(5)			32.768	80	kHz

NOTES:

- Relationship between system clock ϕ frequency and power source voltage is shown in the graph below.
- When the A/D converter is used, refer to the recommended operating conditions of the A/D converter.
- $12.5\text{ MHz} < f(\text{XIN}) \leq 16\text{ MHz}$ is not available in the frequency/2 mode.
- The oscillation start voltage and the oscillation start time differ depending on factors such as the oscillator, circuit constants, and operating temperature range. Note that oscillation start may be particularly difficult at low voltage when using a high-frequency oscillator.
- When using the microcomputer in low-speed mode, set the clock input oscillation frequency on condition that $f(\text{XCIN}) < f(\text{XIN})/3$.

<System clock ϕ frequency>

<Main clock XIN frequency>



Electrical Characteristics

Table 38 Electrical characteristics (1)

(V_{CC} = 2.7 to 5.5 V, V_{SS} = 0 V, T_a = -20 to 85°C, unless otherwise noted)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V _{OH}	"H" output voltage P00–P07, P10–P17, P20–P27	I _{OH} = -2.5mA	V _{CC} -2.0			V
V _{OH}	"H" output voltage P30–P37, P40–P47, P50–P57, P60–P62 ⁽¹⁾	I _{OH} = -5mA	V _{CC} -2.0			V
		I _{OH} = -1.25mA	V _{CC} -0.5			V
V _{OL}	"L" output voltage P00–P07, P10–P17, P20–P27	I _{OL} = 5mA			2.0	V
		I _{OL} = 1.25mA			0.5	V
V _{OL}	"L" output voltage P40–P47, P50, P51, P54–P57, P60–P62 ⁽¹⁾	I _{OL} = 10mA			2.0	V
		I _{OL} = 2.5mA			0.5	V
V _{OL}	"L" output voltage P30–P37, P52, P53	I _{OL} = 15mA			2.0	V
V _{T+} –V _{T–}	Hysteresis CNTR0, CNTR1, INT0–INT2, KW0–KW7			0.5		V
V _{T+} –V _{T–}	Hysteresis RxD1, RxD2, SCLK1, SCLK2			0.5		V
V _{T+} –V _{T–}	Hysteresis $\overline{\text{RESET}}$			0.5		V
I _{IH}	"H" input current P00–P07, P10–P17, P20–P27	V _I = V _{CC}			5.0	μA
I _{IH}	"H" input current P30–P37, P40–P47, P50–P57, P60–P62	V _I = V _{CC}			5.0	μA
I _{IH}	"H" input current $\overline{\text{RESET}}$, CNV _{SS}	V _I = V _{CC}			5.0	μA
I _{IH}	"H" input current X _{IN}	V _I = V _{CC}		4.0		μA
I _{IL}	"L" input current P00–P07, P10–P17, P20–P27	V _I = V _{SS} Pull-up "OFF"			-5.0	μA
		V _{CC} = 5.0V, V _I = V _{SS} Pull-up "ON"	-60	-120	-240	μA
		V _{CC} = 3.0V, V _I = V _{SS} Pull-up "ON"	-25	-50	-100	μA
I _{IL}	"L" input current P30–P37, P40–P47, P50–P57, P60–P67	V _I = V _{SS} Pull-up "OFF"			-5.0	μA
		V _{CC} = 5.0V, V _I = V _{SS} Pull-up "ON"	-30	-70	-140	μA
		V _{CC} = 3.0V, V _I = V _{SS} Pull-up "ON"	-6.5	-25	-45	μA
I _{IL}	"L" input current $\overline{\text{RESET}}$, CNV _{SS}	V _I = V _{SS}			-5.0	μA
I _{IL}	"L" input current X _{IN}	V _I = V _{SS}		-4.0		μA
f(OCO)	On-chip oscillator frequency	V _{CC} = 5V, T _a = 25°C	2500	5000	7500	kHz

NOTE:

- When the port Xc switch bit (bit 4 of address 003B16) of CPU mode register is "1", the drivability of P62 is different from the above.

Table 39 Electrical characteristics (2)

($V_{CC} = 2.7$ to 5.5 V, $V_{SS} = 0$ V, $T_a = -20$ to 85°C , $f(X_{CIN}) = 32.768$ kHz, output transistors in the cut-off state, A/D converter stopped, unless otherwise noted)

Symbol	Parameter	Test conditions				Limits			Unit	
						Min.	Typ.	Max.		
VRAM	RAM hold voltage	When clock is stopped				2.2		5.5	V	
ICC	Power source current	Frequency/2 mode	Vcc=5.0V	f(XIN)=12.5MHz			4.0	7.0	mA	
				f(XIN)=12.5MHz (in WIT state)			2.0	3.5	mA	
				f(XIN)=4MHz			2.0	3.5	mA	
			Vcc=2.7V	f(XIN)=4MHz			1.5	3	mA	
				f(XIN)=4MHz (in WIT state)			1.0	2.5	mA	
				f(XIN)=2MHz			1.0	2.5	mA	
		Frequency/4 mode	Vcc=5.0V	f(XIN)=12.5MHz			3.2	5.6	mA	
				f(XIN)=12.5MHz (in WIT state)			1.6	3.2	mA	
				f(XIN)=4MHz			1.6	3.2	mA	
			Vcc=2.7V	f(XIN)=8MHz			1.6	3.2	mA	
				f(XIN)=8MHz (in WIT state)			1.0	2.5	mA	
				f(XIN)=4MHz			1.0	2.5	mA	
		Frequency/8 mode	Vcc=5.0V	f(XIN)=12.5MHz			2.5	5	mA	
				f(XIN)=12.5MHz (in WIT state)			1.5	3	mA	
				f(XIN)=4MHz			1.5	3	mA	
			Vcc=2.7V	f(XIN)=8MHz			1.5	3	mA	
				f(XIN)=8MHz (in WIT state)			1.0	2.5	mA	
				f(XIN)=4MHz			1.0	2.5	mA	
		Low-speed mode	Vcc=5.0V	f(XIN)=stop			400	800	μA	
				in WIT state	Ta=25°C		4.0	10	μA	
					Ta=85°C			20		
			Vcc=2.7V	f(XIN)=stop			300	600	μA	
				in WIT state	Ta=25°C		3.7	9	μA	
					Ta=85°C			18		
		On-chip oscillator mode f(XIN), f(XCIN): stop			Vcc=5.0V			600	1200	μA
					Vcc=2.7V			500	1000	μA
					Vcc=2.7V (in WIT state)			500	1000	μA
		All oscillations are stopped (in STP state)			Ta=25°C			0.6	3.0	μA
					Ta=85°C			1.0		μA
		Current increased at A/D converter operating			f(XIN)=12.5MHz, Vcc=5V in frequency/2, 4 or 8 mode			1.0		mA
					f(XIN)=stop, Vcc=5V in on-chip oscillator operating			1.0		mA
					f(XIN)=stop, Vcc=5V in low-speed mode			0.8		mA

A/D Converter Characteristics

Table 40 A/D converter recommended operating condition

($V_{CC} = 2.7$ to 5.5 V, $T_a = -20$ to 85°C , output transistors in cut-off state, unless otherwise noted)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V_{CC}	Power source voltage		2.7	5.0	5.5	V
V_{IH}	"H" input voltage ADKEY		$0.9V_{CC}$		V_{CC}	V
V_{IL}	"L" input voltage ADKEY		0		$0.7 \times V_{CC} - 0.5$	V
$f(\phi_{AD})$	AD converter clock frequency ⁽¹⁾ (Low-speed • on-chip oscillator mode excluded)	$4.5\text{V} < V_{CC} \leq 5.5\text{V}$			6.25	MHz
		$4.0\text{V} < V_{CC} \leq 4.5\text{V}$			4.0	MHz
		$2.7\text{V} < V_{CC} \leq 4.0\text{V}$			V_{CC}	MHz

NOTE:

1. Confirm the recommended operating condition for main clock input frequency.

Table 41 A/D converter characteristics

(V_{CC} = 2.7 to 5.5 V, T_a = –20 to 85°C, output transistors in cut-off state, low-speed • on-chip oscillator mode included, unless otherwise noted)

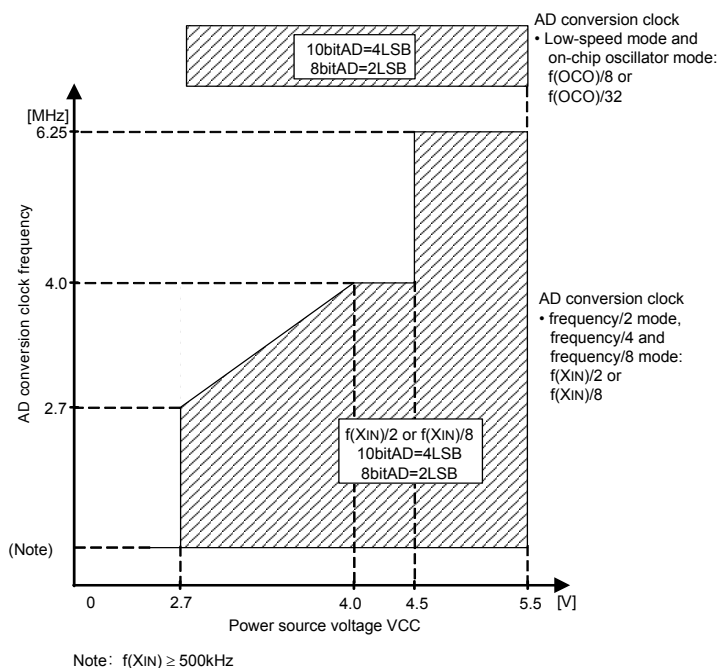
Symbol	Parameter	Test conditions		Limits			Unit	
				Min.	Typ.	Max.		
–	Resolution					10	Bits	
ABS	Absolute accuracy (quantification error excluded)	10bitAD mode	4.5V < V _{CC} ≤ 5.5V, AD conversion clock=f(X _{IN})/2, f(X _{IN})/8≤6.25MHz			4	LSB	
			4.0V < V _{CC} ≤ 4.5V, AD conversion clock=f(X _{IN})/2, f(X _{IN})/8≤4MHz					
			2.7V ≤ V _{CC} ≤ 4.0V, AD conversion clock=f(X _{IN})/2, f(X _{IN})/8≤V _{CC} MHz					
			2.7V ≤ V _{CC} ≤ 5.5V, f(OCO)/8, f(OCO)/32					
		8bitAD mode	4.5V < V _{CC} ≤ 5.5V, AD conversion clock=f(X _{IN})/2, f(X _{IN})/8≤6.25MHz			2		
			4.0V < V _{CC} ≤ 4.5V, AD conversion clock=f(X _{IN})/2, f(X _{IN})/8≤4MHz					
			2.7V ≤ V _{CC} ≤ 4.0V, AD conversion clock=f(X _{IN})/2, f(X _{IN})/8≤V _{CC} MHz					
			2.7V ≤ V _{CC} ≤ 5.5V, f(OCO)/8, f(OCO)/32					
		t _{CONV}	Conversion time ⁽¹⁾	10bitAD mode	tc(φAD) × 61		tc(φAD) × 62	μs
				8bitAD mode	tc(φAD) × 49		tc(φAD) × 50	
RLADDER	Ladder resistor			12	35	100	kΩ	
I _{VREF}	Reference input current	V _{REF} =5V		50	150	200	μA	
I _{IA}	Analog input current					5.0	μA	

NOTES:

1. tc(φAD): one cycle of AD conversion clock. AD conversion clock can be selected from φSOURCE/2 or φSOURCE/8. φSOURCE represents the X_{IN} input in the frequency/2, 4 or 8 mode and internal on-chip oscillator divided by 4 in the on-chip oscillator mode or the low-speed mode.

When the A/D conversion is executed in the frequency/2 mode, frequency/4 mode, or frequency/8 mode, set f(X_{IN}) ≥ 500 kHz.

Relationship among AD conversion clock frequency, power source voltage, AD conversion mode and absolute accuracy.



LCD power supply characteristics

Table 42 LCD power supply characteristics (when connecting division resistors for LCD power supply)
(V_{CC} = 2.7 to 5.5 V, V_{SS} = 0 V, T_a = –20 to 85°C, unless otherwise noted)

Symbol	Parameter	Test conditions			Limits			Unit
					Min.	Typ.	Max.	
R _{LCD}	Division resistor for LCD power supply ⁽¹⁾	RSEL="10"				200		kΩ
		RSEL="11"				5		
		LCD drive timing A	LCD circuit division ratio = divided by 1	RSEL="01"		120		
				RSEL="00"		90		
			LCD circuit division ratio = divided by 2	RSEL="01"		150		
				RSEL="00"		120		
			LCD circuit division ratio = divided by 4	RSEL="01"		170		
				RSEL="00"		150		
			LCD circuit division ratio = divided by 8	RSEL="01"		190		
				RSEL="00"		170		
		LCD drive timing B	LCD circuit division ratio = divided by 1	RSEL="01"		150		
				RSEL="00"		120		
			LCD circuit division ratio = divided by 2	RSEL="01"		170		
				RSEL="00"		150		
			LCD circuit division ratio = divided by 4	RSEL="01"		190		
				RSEL="00"		170		
			LCD circuit division ratio = divided by 8	RSEL="01"		190		
				RSEL="00"		190		

NOTE:

1. The value is the average of each one division resistor.

Timing Requirements And Switching Characteristics

Table 43 Power supply circuit characteristics
($V_{CC} = 2.7$ to 5.5 V, $V_{SS} = 0$ V, $T_a = -20$ to 85°C , unless otherwise noted)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
td(P-R)	Internal power source voltage stabilizes time at power-on	$2.7 \leq V_{CC} \leq 5.5\text{V}$	2			ms

Table 44 Timing requirements (1)
($V_{CC} = 4.0$ to 5.5 V, $V_{SS} = 0$ V, $T_a = -20$ to 85°C , unless otherwise noted)

Symbol	Parameter		Limits			Unit
			Min.	Typ.	Max.	
tw(RESET)	Reset input "L" pulse width		2			μs
tc(XIN)	Main clock input cycle time	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$ (1)	62.5			ns
		$4.0\text{V} \leq V_{CC} < 4.5\text{V}$	125			ns
twh(XIN)	Main clock input "H" pulse width	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$ (2)	25			ns
		$4.0\text{V} \leq V_{CC} < 4.5\text{V}$	50			ns
twl(XIN)	Main clock input "L" pulse width	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$ (2)	25			ns
		$4.0\text{V} \leq V_{CC} < 4.5\text{V}$	50			ns
tc(CNTR)	CNTR0, CNTR1 input cycle time		250			ns
twh(CNTR)	CNTR0, CNTR1 input "H" pulse width		105			ns
twl(CNTR)	CNTR0, CNTR1 input "L" pulse width		105			ns
twh(INT)	INT0–INT2 input "H" pulse width		80			ns
twl(INT)	INT0–INT2 input "L" pulse width		80			ns
tc(SCLK)	Serial I/O1, 2 clock input cycle time (3)		800			ns
twh(SCLK)	Serial I/O1, 2 clock input "H" pulse width (3)		370			ns
twl(SCLK)	Serial I/O1, 2 clock input "L" pulse width (3)		370			ns
tsu(RxD-SCLK)	Serial I/O1, 2 input setup time		220			ns
th(SCLK-RxD)	Serial I/O1, 2 input hold time		100			ns

NOTES:

- 80 ns in the frequency/2 mode.
- 32 ns in the frequency/2 mode.
- When bit 6 of address 001A₁₆, 001F₁₆ are "1" (clock synchronous).
Divide this value by four when bit 6 of address 001A₁₆, 001F₁₆ are "0" (UART).

Table 45 Timing requirements (2)
($V_{CC} = 2.7$ to 4.0 V, $V_{SS} = 0$ V, $T_a = -20$ to 85°C , unless otherwise noted)

Symbol	Parameter	Limits			Unit
		Min.	Typ.	Max.	
tw(RESET)	Reset input "L" pulse width	2			μs
tc(XIN)	Main clock input cycle time (XIN input)	125			ns
twh(XIN)	Main clock input "H" pulse width	50			ns
twl(XIN)	Main clock input "L" pulse width	50			ns
tc(CNTR)	CNTR0, CNTR1 input cycle time	$1000/V_{CC}$			ns
twh(CNTR)	CNTR0, CNTR1 input "H" pulse width	$tc(CNTR)/2 - 20$			ns
twl(CNTR)	CNTR0, CNTR1 input "L" pulse width	$tc(CNTR)/2 - 20$			ns
twh(INT)	INT0–INT2 input "H" pulse width	230			ns
twl(INT)	INT0–INT2 input "L" pulse width	230			ns
tc(SCLK)	Serial I/O1, 2 clock input cycle time	2000			ns
twh(SCLK)	Serial I/O1, 2 clock input "H" pulse width	950			ns
twl(SCLK)	Serial I/O1, 2 clock input "L" pulse width	950			ns
tsu(RxD-SCLK)	Serial I/O1, 2 input setup time	400			ns
th(SCLK-RxD)	Serial I/O1, 2 input hold time	200			ns

NOTE:

- When bit 6 of address 001A₁₆, 001F₁₆ are "1" (clock synchronous).
Divide this value by four when bit 6 of address 001A₁₆, 001F₁₆ are "0" (UART).

Table 46 Switching characteristics (1)

(V_{CC} = 4.0 to 5.5 V, V_{SS} = 0 V, T_a = -20 to 85°C, unless otherwise noted)

Symbol	Parameter	Limits			Unit
		Min.	Typ	Max.	
t _{WH} (SCLK)	Serial I/O1, 2 clock output "H" pulse width	t _c (SCLK)/2-30			ns
t _{WL} (SCLK)	Serial I/O1, 2 clock output "L" pulse width	t _c (SCLK)/2-30			ns
t _d (SCLK-TxD)	Serial I/O1, 2 output delay time ⁽¹⁾			140	ns
t _v (SCLK-TxD)	Serial I/O1, 2 output valid time ⁽¹⁾	-30			ns
t _r (SCLK)	Serial I/O1, 2 clock output rising time			30	ns
t _f (SCLK)	Serial I/O1, 2 clock output falling time			30	ns

NOTE:

1. The P5s/TxD1 [P32/TxD2] P-channel output disable bit (bit 4 of address 001B16 [0FF116]) of UART control register is "0".

Table 47 Switching characteristics (2)

(V_{CC} = 2.7 to 4.0 V, V_{SS} = 0 V, T_a = -20 to 85°C, unless otherwise noted)

Symbol	Parameter	Limits			Unit
		Min.	Typ	Max.	
t _{WH} (SCLK)	Serial I/O1, 2 clock output "H" pulse width	t _c (SCLK)/2-80			ns
t _{WL} (SCLK)	Serial I/O1, 2 clock output "L" pulse width	t _c (SCLK)/2-80			ns
t _d (SCLK-TxD)	Serial I/O1, 2 output delay time ⁽¹⁾			350	ns
t _v (SCLK-TxD)	Serial I/O1, 2 output valid time ⁽¹⁾	-30			ns
t _r (SCLK)	Serial I/O1, 2 clock output rising time			80	ns
t _f (SCLK)	Serial I/O1, 2 clock output falling time			80	ns

NOTE:

1. The P5s/TxD1 [P32/TxD2] P-channel output disable bit (bit 4 of address 001B16 [0FF116]) of UART control register is "0".

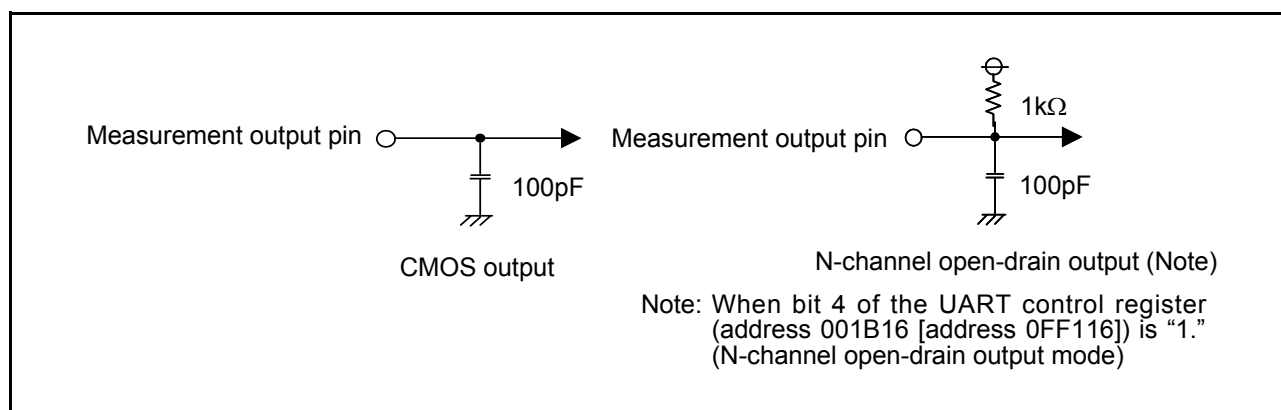


Fig 96. Circuit for measuring output switching characteristics

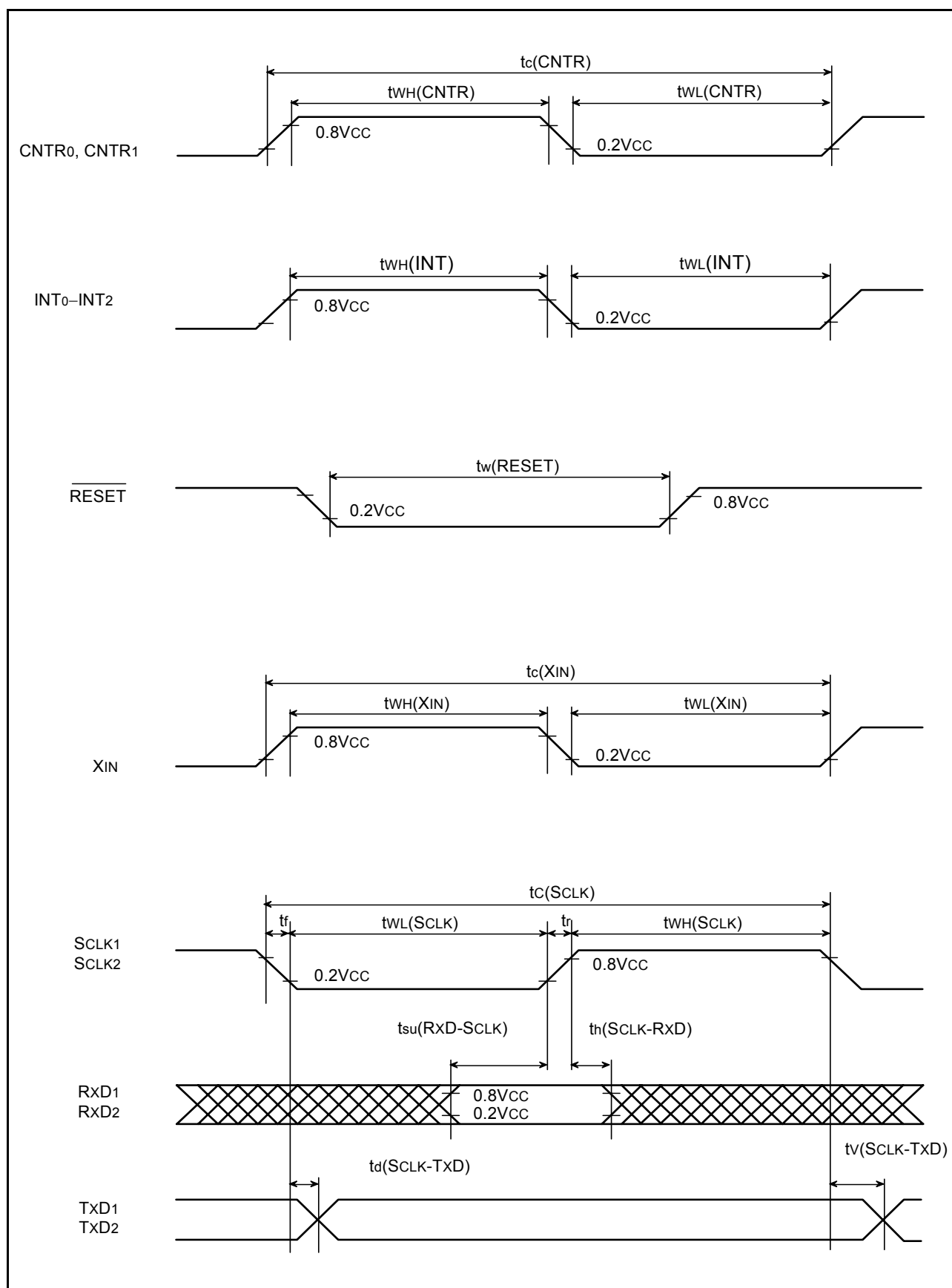
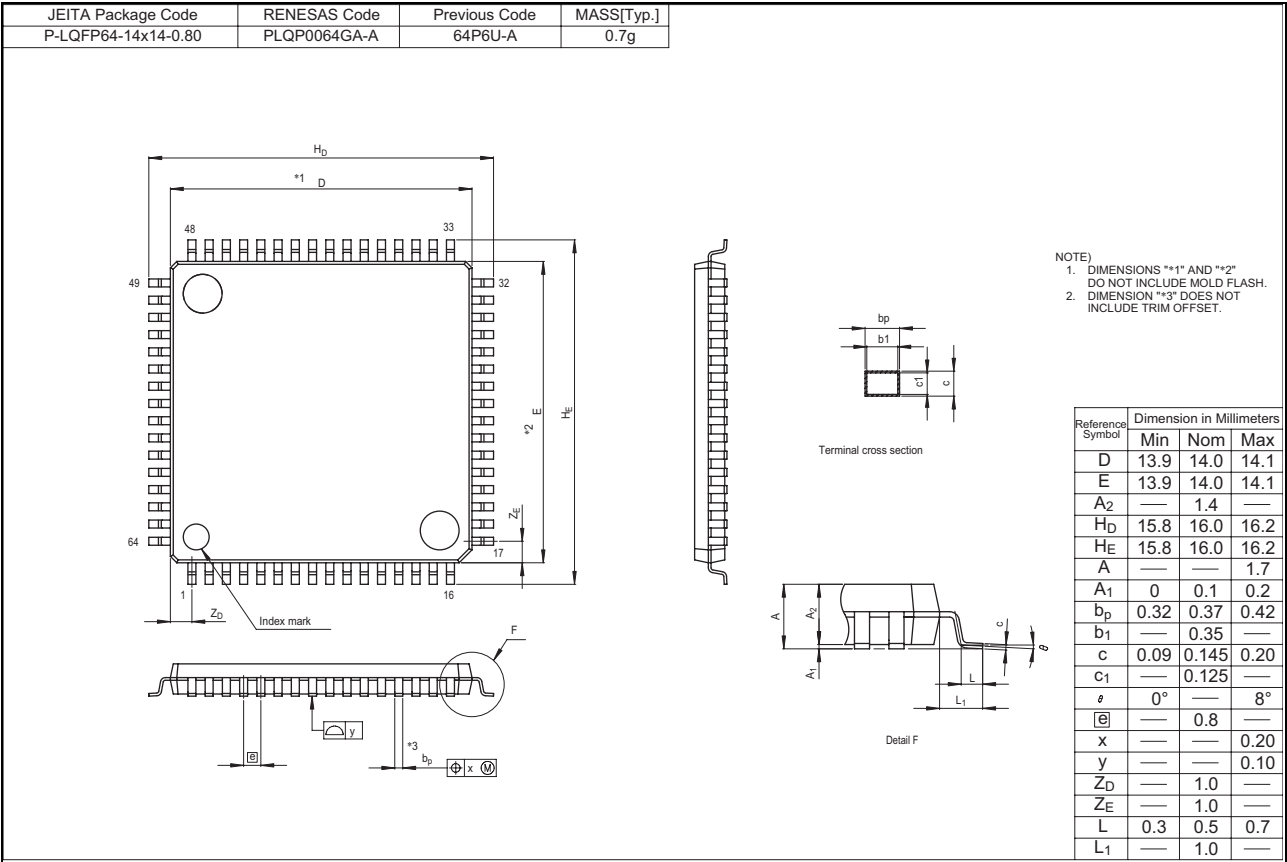
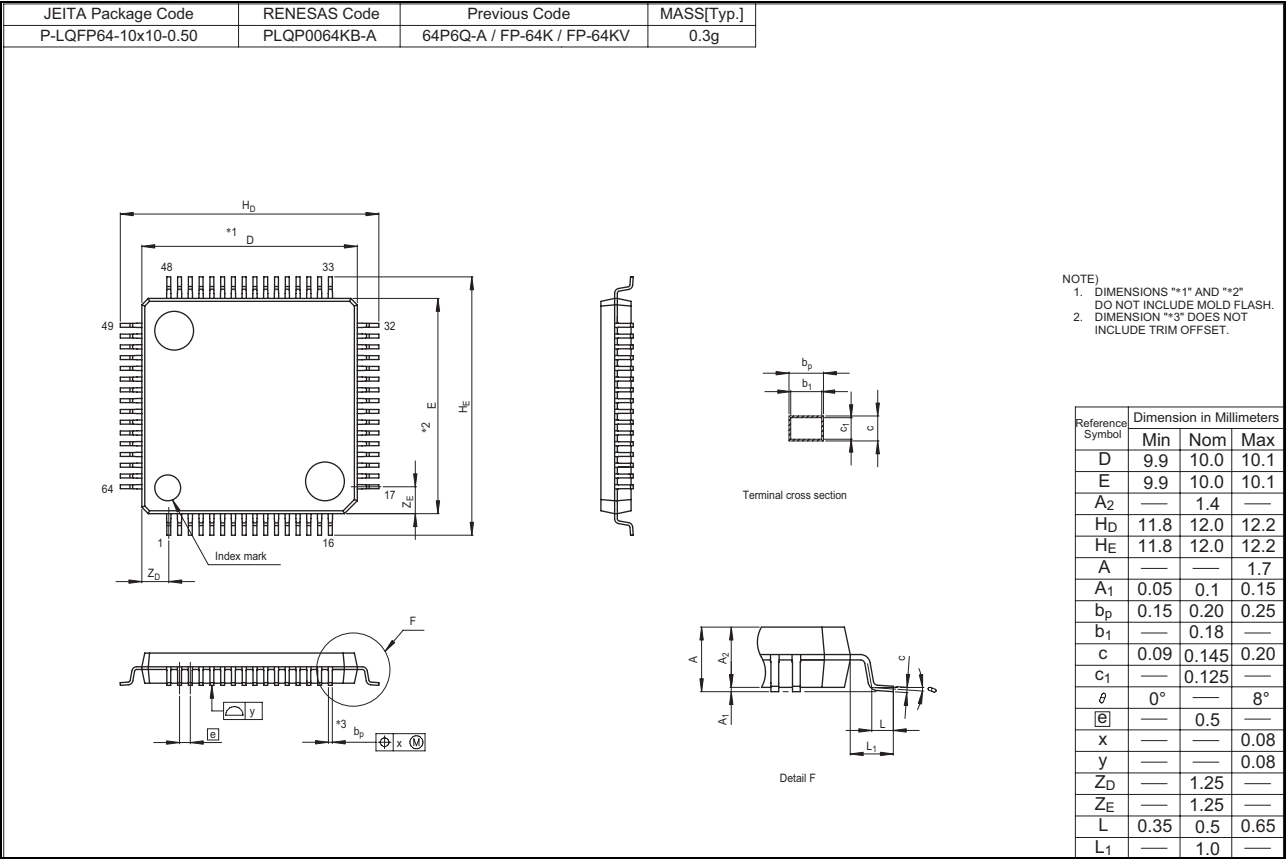


Fig 97. Timing diagram (in single-chip mode)

PACKAGE OUTLINE

Diagrams showing the latest package dimensions and mounting information are available in the “Packages” section of the Renesas Technology website.





APPENDIX

Note on Programming

1. Processor Status Register

(1) Initialization of the processor status register

It is required to initialize the processor status register (PS) flags which affect program execution. It is particularly essential to initialize the T and D flags because of their effect on calculations. Initialize these flags at the beginning of the program.

<Reason>

At a reset, the contents of the processor status register (PS) are undefined except for the I flag which is "1".

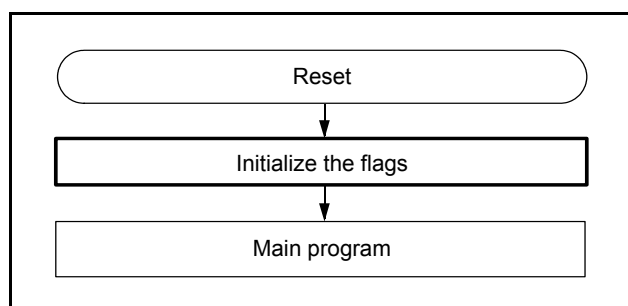


Fig. 98 Initialization of processor status register flags

(2) How to refer the processor status register

To refer the contents of the processor status register (PS), execute the PHP instruction once and then read the contents of (S+1). If necessary, execute the PLP instruction to return the stored PS to its original status.

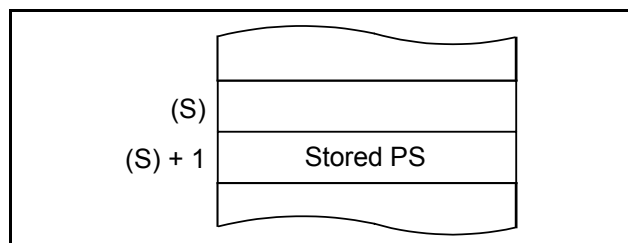


Fig. 99 Stack memory contents after PHP instruction execution

2. Decimal Calculations

(1) Instructions for decimal calculations

To perform decimal calculations, set the decimal mode (D) flag to "1" with the SED instruction and execute the ADC or SBC instruction. In that case, after the ADC or SBC instruction, execute another instruction before the SEC, CLC, or CLD instruction.

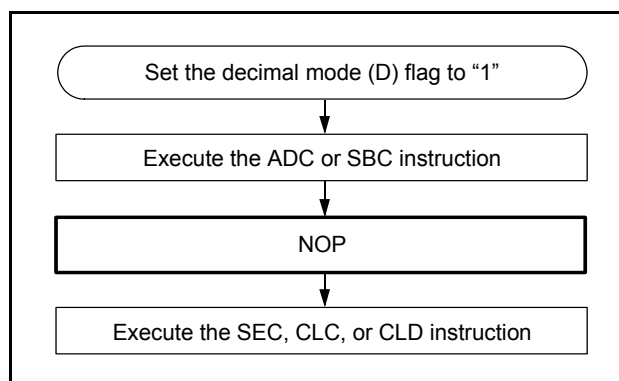


Fig. 100 Instructions for decimal calculations

(2) Status flag at decimal calculations

When the ADC or SBC instruction is executed in decimal mode (D flag = "1"), three of the status flags (N, V, and Z) are disabled. The carry (C) flag is set to "1" if a carry is generated and is cleared to "0" if a borrow is generated as a result of a calculation, so it can be used to determine whether the calculation has generated a carry or borrow.

Initialize the C flag before each calculation.

3. JMP Instruction

When using the JMP instruction (indirect addressing mode), do not specify the address where “FF16” is allocated to the low-order 8 bits as the operand.

4. Multiplication and Division Instructions

- (1) The MUL and DIV instructions are not affected by the T and D flags.
- (2) Executing these instructions does not change the contents of the processor status register.

5. Read-Modify-Write Instruction

Do not execute any read-modify-write instruction to the read invalid (address) SFR.

The read-modify-write instruction reads 1-byte of data from memory, modifies the data, and writes 1-byte the data to the original memory.

In the 740 Family, the read-modify-write instructions are the following:

- (1) Bit handling instructions:
CLB, SEB
- (2) Shift and rotate instructions:
ASL, LSR, ROL, ROR, RRF
- (3) Add and subtract instructions:
DEC, INC
- (4) Logical operation instructions (1's complement):
COM

Although not the read-modify-write instructions, add and subtract/logical operation instructions (ADC, SBC, AND, EOR, and ORA) when T flag = “1” operate in the way as the read-modify-write instruction. Do not execute them to the read invalid SFR.

<Reason>

When the read-modify-write instruction is executed to the read invalid SFR, the following may result:

As reading is invalid, the read value is undefined. The instruction modifies this undefined value and writes it back, so the written value will be indeterminate.

Notes on Peripheral Functions

Notes on I/O Ports

1. Use in Stand-By State

When using the MCU in stand-by state*¹ for low-power consumption, do not leave the input level of an I/O port undefined. Be especially careful to the I/O ports for the N-channel open-drain.

In this case, pull-up (connect to Vcc) or pull-down (connect to Vss) these ports through a resistor.

When determining a resistance value, note the following:

- External circuit
- Variation in the output level during ordinary operation

When using a built-in pull-up resistor, note variations in current values:

- When setting as an input port: Fix the input level
- When setting as an output port: Prevent current from flowing out externally.

<Reason>

Even if a port is set to output by the direction register, when the content of the port latch is “1”, the transistor becomes the OFF state, which allows the port to be in the high-impedance state. This may cause the level to be undefined depending on external circuits.

As described above, if the input level of an I/O port is left undefined, the power source current may flow because the potential applied to the input buffer in the MCU will be unstable.

*¹ Stand-by state: Stop mode by executing the STP instruction
Wait mode by executing the WIT instruction

2. Modifying Output Data with Bit Handling Instruction

When the port latch of an I/O port is modified with the bit handling instruction*¹, the value of an unspecified bit may change.

<Reason>

I/O ports can be set to input mode or output mode in byte units.

When the port register is read or written, the following will be operated:

- Port as input mode
Read: Read the pin level
Write: Write to the port latch
- Port as output mode
Read: Read the port latch or peripheral function output (specifications vary depending on the port)
Write: Write to the port latch (output the content of the port latch from the pin)

Meanwhile, the bit handling instructions are the read-modify-write instructions*². Executing the bit handling instruction to the port register allows reading and writing a bit unspecified with the instruction at the same time.

If an unspecified bit is set to input mode, the pin level is read and the value is written to the port latch. At this time, if the original content of the port latch and the pin level do not match, the content of the port latch changes.

If an unspecified bit is set to output mode, the port latch is normally read, but the peripheral function output is read in some ports and the value is written to the port latch. At this time, if the original content of the port latch and the peripheral function output do not match, the content of the port latch changes.

*¹ Bit handling instructions: CLB, SEB

*² Read-modify-write instruction: Reads 1-byte of data from memory, modifies the data, and writes 1-byte of the data to the original memory.

3. Direction Registers

The values of the port direction registers cannot be read. This means, it is impossible to use the LDA instruction, memory operation instruction when the T flag is "1", addressing mode using direction register values as qualifiers, and bit test instructions such as BBC and BBS. It is also impossible to use bit operation instructions such as CLB and SEB, and read-modify-write instructions to direction registers, including calculations such as ROR. To set the direction registers, use instructions such as LDM or STA.

4. Pull-Up Control

Only for the pin set to input mode, pull-up is controlled by the PULL register and the segment output disable register.

Notes on Termination of Unused Pins

1. Termination of Unused Pins

Perform the following at the shortest possible distance (20 mm or less) from the MCU pins.

(1) I/O ports

Set the ports to input mode and connect each pin to VCC or VSS through a resistor of 1 k to 10 k Ω . An internal pull-up resistor can also be used for the port where the internal pull-up resistor is selectable.

To set the ports to output mode, leave open at "L" or "H" output.

- When setting the ports to output mode and leave open, input mode in the initial state remains until the mode of the ports are switched to output mode by a program after a reset. This may cause the voltage level of the pins to be undefined and the power source current to increase while the ports remains in input mode. For any effects on the system, careful system evaluations should be implemented on the user side.
- The direction registers may be changed due to a program runaway or noise, so reset the registers periodically by a program to increase the program reliability.

2. Termination Concerns

(1) When setting I/O ports to input mode

[1] Do not leave open

<Reason>

- The power source current may increase depending on the first-stage circuit.
- The ports are more likely affected by noise when compared with the termination shown on the above "1. (1) I/O ports"

[2] Do not connect to VCC or VSS directly

<Reason>

If the direction registers are changed to output mode due to a program runaway or noise, a short circuit may occur.

[3] Do not connect multiple ports in a lump to VCC or VSS through a resistor.

<Reason>

If the direction registers are changed to output mode due to a program runaway or noise, a short circuit may occur between the ports.

Notes on Interrupts

1. Changing Related Register Settings

If the interrupt occurrence synchronized with the following settings is not required, take the sequence shown below.

- When selecting the external interrupt active edge
- When selecting the interrupt source of the interrupt vector address where two or more interrupt sources are allocated

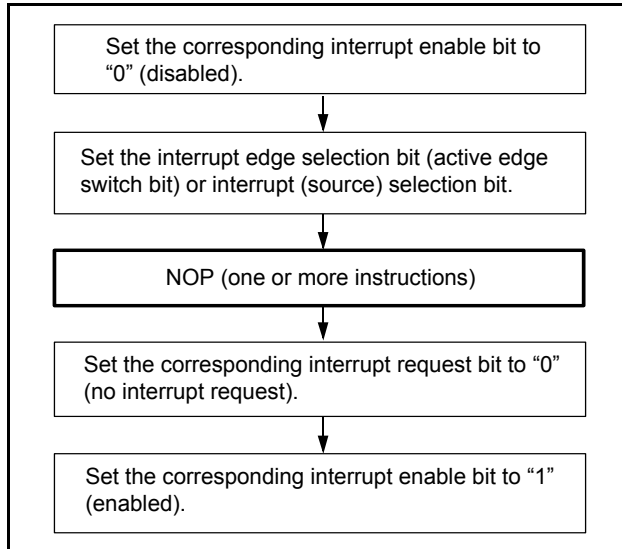


Fig. 101 Sequence for setting related register

<Reason>

In the following cases, the interrupt request bit of the corresponding interrupt may be set to "1".

<When switching the external interrupt active edge>

- INT0 interrupt edge selection bit
(bit 0 of interrupt edge selection register (address 003A16))
- INT1 interrupt edge selection bit
(bit 1 of interrupt edge selection register)
- INT2 interrupt edge selection bit
(bit 2 of interrupt edge selection register)
- CNTR0 active edge switch bits
(bits 6 and 7 of timer X control register 1 (address 002E16))
- CNTR1 active edge switch bit
(bits 6 of timer Y mode register (address 003816))

<When switching the interrupt source of the interrupt vector address where two or more interrupt sources are allocated>

- INT2/Key input interrupt switch bit
(bit 3 of interrupt edge selection register)
- Timer Y/CNTR1 interrupt switch bit
(bit 4 of interrupt edge selection register)

2. Checking Interrupt Request Bit

To check the interrupt request bit with the BBC or BBS instruction immediately after this bit is set to "0", take the following sequence.

<Reason>

If the BBC or BBS instruction is executed immediately after the interrupt request bit is set to "0", the bit value before being set to "0" is read.

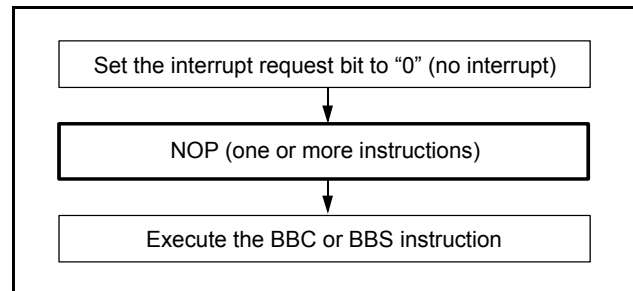


Fig. 102 Sequence for setting interrupt request bit

3. Setting Unused Interrupts

Set the interrupt enable bit of the unused interrupt to "0" (disabled).

Notes on Timers

1. Frequency Divider

All timers share one circuit for the frequency divider to generate the count source.

Thus the frequency divider is not initialized when each individual timer is activated. When the frequency divider is selected as the count source, a one-cycle delay of the maximum count source will result between when the timer is activated and when it starts counting or outputs the waveform. The count source cannot be observed externally.

2. Division Ratio for Timer 1 to 4

The division ratio is $1/(n+1)$ when the value n (0 to 255) is written to the timer latch.

3. Switching Frequency and Count Source for Timer 1 to 4, X, and Y

Switch the frequency division or count source* while the timer count is stopped.

*This also applies when the frequency divider output is selected as the timer count source and the count source is switched in conjunction with a transition between operating modes (on-chip oscillator mode, XIN mode, or low-speed mode). Be careful when changing settings in the CPU mode register.

4. Setting Timer 1 and 2 When STP Instruction Executed

Before executing the STP instruction, first set the wait time at return.

5. Setting Order to Timer 1 to 4

When switching the count source of timer 1 to timer 4, a narrow pulse may be generated at the count input, which causes the timer count value to be undefined. Also, if the timers are used in cascade connection, a narrow pulse may be generated at the output when writing to the previous timer, which causes the next timer count value to be undefined.

Thus set the value from timer 1 in order after setting the count source of timer 1 to timer 4.

6. Write to Timer 2, 3, and 4

When writing to the latch only, if the write timing to the reload latch and the underflow timing are almost the same, the value is set into the timer and the timer latch at the same time. At this time, count is stopped during write operation to the reload latch.

7. Timer 3 PWM0 Mode, Timer 4 PWM1 Mode

- (1) When PWM output is suspended once it starts, the time to resume outputting may be delayed one section ($256 \times t_s$) of the short interval depending on the level of the output pulse at that time:
 Stop at "H": No output delay
 Stop at "L": Output is delayed time of $256 \times t_s$
- (2) When PWM mode is used, the interrupt requests and values of timer 3 and timer 4 are updated every cycle of the long interval ($4 \times 256 \times t_s$).

8. Write Order to Timer X

- (1) When timer mode, pulse output mode, event counter mode, or pulse width measurement mode is set, write to the following registers in the order below:

The timer X register (extension)

The timer X register (low-order)

The timer X register (high-order)

Writing to only one of these registers cannot be performed.

When either of the above modes is set and timer X operates as a 16-bit counter, if the timer X register (extension) is never set after a reset release, setting the timer X register (extension) is not required. In that case, write the timer X register (low-order) first and the timer X register (high-order) next. However, once the timer X register (extension) is written, note that the value is retained in the reload latch.

- (2) Write to the timer X register by the 16-bit unit. Do not read the timer X register while write operation is performed. If the write operation is not completed, normal operation will not be performed.
- (3) When IGBT output mode or PWM mode is set, do not write "1" to the timer X register (extension). If "1" has been already written to the timer X register, be sure to write "0" to the register before use.

Write to the following registers in the order below:

The compare registers 1, 2, 3 (high- and low-order)

The timer X register (extension)

The timer X register (low-order)

The timer X register (high-order)

The compare registers (high- and low-order) can be written in either order. However, be sure to write both the compare registers 1, 2, 3 and the timer X register at the same time.

9. Read Order to Timer X

- (1) In all modes, read the following registers in the order below:
 The timer X register (extension)
 The timer X register (high-order)
 The timer X register (low-order)
 When reading the timer X register (extension) is not required, read the timer X register (high-order) first and the timer X register (low-order) next.
 The read order to the compare registers 1, 2, 3 is not specified.
- (2) Read the timer X register in 16-bit units. Do not write to it during read operation. If read operation is terminated in progress, normal operation will not be performed.

10. Write to Timer X

- (1) Timer X can select either writing data to both the latch and the timer at the same time or writing data only by the timer X write control bit (b3) in the timer X mode register (address 002D16). When writing to the latch only, if a value is written to the timer X address, the value is set into the reload latch and the timer is updated at the next underflow. After a reset release, if a value is written to the timer X address, the value is set into the timer and the timer latch at the same time, because they are written simultaneously. When writing to the latch only, if the write timing to the high-order reload latch and the underflow timing are almost the same, the value is set into the timer and the timer latch at the same time. At this time, count is stopped during write operation to the high-order reload latch.
- (2) Switch the frequency division or count source* while the timer count is stopped.

*This also applies when the frequency divider output is selected as the timer count source and the count source is switched in conjunction with a transition between operating modes (on-chip oscillator mode, XIN mode, or low-speed mode). Be careful when changing settings in the CPU mode register.

11. Setting Timer X Mode Register

When PWM mode or IGBT output mode is set, be sure to set the write control bit in the timer X mode register to "1" (writing to latch only). After writing to the timer X register (high-order), the contents of both registers are simultaneously reflected in the output waveform at the next underflow.

12. Timer X Output Control Functions

To use the output control functions (INT1 and INT2), set the levels of INT1 and INT2 to "H" for the falling edge active or to "L" for the rising edge active before switching to IGBT output mode.

13. CNTR0 Active Edge Selection

- (1) Setting the CNTR0 active edge switch bits also affects the interrupt active edge at the same time.
- (2) When the pulse width is measured, set bit 7 of the CNTR0 active edge switch bits to "0".

14. When Timer X Pulse Width Measurement Mode Used

When timer X pulse mode measurement mode is used, enable the event counter window control data (bit 5 of timer X mode register (address 002D16)) by setting to "0".

<Reason>

If the event counter window control data (bit 5 of timer X mode register (address 002D16)) is set to "1" (disabled) to enable/disable the CNTR0 input, the input is not accepted after the timer 1 underflow.

15. CNTR1 Active Edge Selection

Setting the CNTR1 active edge switch bits also affects the interrupt active edge at the same time.

However, in pulse width HL continuous HL measurement mode, the CNTR1 interrupt request is generated at both rising and falling edges of the pin regardless of the settings of the CNTR1 active edge switch bits.

16. Read from/Write to Timer Y

- (1) When reading from/writing to timer Y, read from/write to both the high-order and low-order bytes of timer Y. To read the value, read the high-order bytes first and the low-order bytes next. To write the value, write the low-order bytes first and the high-order bytes next. Writing/reading should be preformed in 16-bit units. If write/read operation is changed in progress, normal operation will not be performed.
- (2) Timer Y can select either writing data to both the latch and the timer at the same time or writing data only by the timer Y write control bit (b0) in the timer Y control register (address 003916). When writing to the latch only, if a value is written to the timer Y address, the value is set into the reload latch and the timer is updated at the next underflow. After a reset release, if a value is written to the timer Y address, the value is set into the timer and the timer latch at the same time, because they are written simultaneously. When writing to the latch only, if the write timing to the high-order reload latch and the underflow timing are almost the same, the value is set into the timer and the timer latch at the same time. At this time, count is stopped during write operation to the high-order reload latch.
- (3) Switch the frequency division or count source* while the timer count is stopped.

*This also applies when the frequency divider output is selected as the timer count source and the count source is switched in conjunction with a transition between operating modes (on-chip oscillator mode, XIN mode, or low-speed mode). Be careful when changing settings in the CPU mode register.

17. Real time port control

When switching the setting of the real time port control bits between valid and invalid, write to the timer Y mode register in byte units with the LDM or STA instruction so that both bits are switched at the same time. Also, before using this function, set the P46 and P47 port direction registers to output.

Notes on Serial I/O1

Because the operation of the serial I/O2 is as same as serial I/O1, the following notes are written about the serial I/O1.

1. Write to Baud Rate Generator

Write to the baud rate generator while transmission/reception is stopped.

2. Setting Sequence When Serial I/O1 Transmit Interrupt Used

To use the serial I/O1 transmit interrupt, if the interrupt occurrence synchronized with settings is not required, take the following sequence:

- (1) Set the serial I/O1 transmit interrupt enable bit (bit 2 of interrupt control register 2 (address 003F16)) to "0" (disabled).
- (2) Set the transmit enable bit to "1".
- (3) After one or more instructions have been executed, set the serial I/O1 transmit interrupt request bit (bit 2 of interrupt request register 2 (address 003D16)) to "0" (no interrupt).
- (4) Set the serial I/O1 transmit interrupt enable bit to "1" (enabled).

<Reason>

When the transmit enable bit is set to "1", the transmit buffer empty flag (bit 0 of serial I/O1 status register) and the transmit shift completion flag are set to "1".

This allows an interrupt request to be generated regardless of which interrupt occurrence source has been selected by the transmit interrupt source selection bit (bit 3 of serial I/O1 control register) and the serial I/O1 transmit interrupt request bit is set to "1".

3. Data Transmission Control Using Transmit Shift Completion Flag

After transmit data is written to the transmit buffer register, the transmit shift completion flag (bit 2 of serial I/O1 status register (address 001916)) changes from "1" to "0" after a delay of 0.5 to 1.5 cycles of the system clock. Thus, after transmit data is written to the transmit buffer register, note this delay when controlling data transmission by referencing the transmit shift completion flag.

4. Setting Serial I/O1 Control Register

Before setting the serial I/O1 control register again, first set both the transmit enable bit and the receive enable bit to "0" and initialize the transmission and reception circuits.

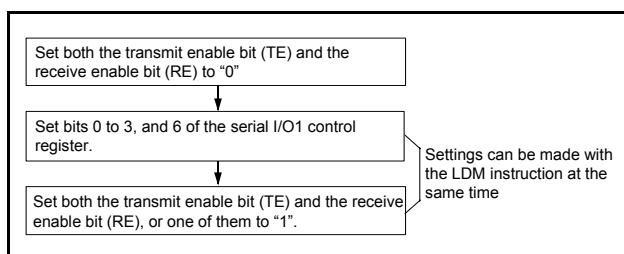


Fig. 103 Sequence of setting serial I/O1 control register

5. Pin Status After Transmission Completed

After transmission is completed, the TxD pin retains the level when transmission is completed.

When the internal clock is selected in clock synchronous serial I/O mode, the SCLK1 pin is set to "H".

6. Serial I/O1 Enable Bit during Transmit Operation

During transmission, if the serial I/O1 enable bit (bit 7 of serial I/O1 control register (address 001A16)) is set to "0", the pin function is set to an I/O port and the internal transmit operation continues even though transmit data is not output externally. Also, if the transmit buffer register is written in this state, transmit operation starts internally. If the serial I/O1 enable bit is set to "1" at this time, transmit data is output to the TxD pin from that point.

7. Transmission Control When External Clock Selected

During data transmission, if the external clock is selected as the synchronous clock, set the transmit enable bit to "1" while SCLK1 is set to "H". Also, write to the transmit buffer register while SCLK1 is set to "H".

8. Receive Operation in Clock Synchronous Serial I/O Mode

During reception in clock synchronous serial I/O mode, set both the transmit enable bit and the receive enable bit to "1". Then write dummy data to the transmit buffer register. When the internal clock is selected as the synchronous clock, the synchronous clock is output at this point and receive operation starts. When the external clock is selected, reception is enabled at this point and inputting the external clock starts transmit operation.

The P55/TxD1 [P32/TxD2] pin outputs dummy data written in the transmit buffer register.

9. Transmit/Receive Operation in Clock Synchronous Serial I/O Mode

In clock synchronous serial I/O mode, set the transmit enable bit and the receive enable bit to "0" simultaneously to stop transmit/receive operations. If only one of the operations is stopped, transmission and reception cannot be synchronized, which will cause a bit error.

Notes on A/D Conversion

1. Analog Input Pin

Set the signal source impedance for analog input low, or equip an analog input pin with an external capacitor of 0.01 μF to 1 μF . In addition, operations of application products should be verified thoroughly on the user side.

<Reason>

An analog input pin has a built-in capacitor for analog voltage comparison. Thus if a signal from the high impedance signal source is input to the analog input pin, charge and discharge noise will be generated. This may cause the A/D conversion/comparison accuracy to drop.

2. Clock Frequency during A/D Conversion

The comparator input consists of a capacity coupling. If the conversion rate is too low, the A/D conversion accuracy may deteriorate due to a charge lost, so set $f(\text{XIN})$ 500 kHz or more for A/D conversion in XIN mode. Also, do not execute the STP or WIT instruction during A/D conversion.

In low-speed mode (when on-chip oscillator is selected), as A/D conversion is performed using the internal on-chip oscillator, there is no limit on the minimum frequency for $f(\text{XIN})$.

3. ADKEY Function

When the ADKEY enable bit is set to "1", the analog input pin selection bits are disabled. Do not execute the A/D conversion by a program while ADKEY is enabled. Enabling ADKEY does not change bits 0 to 2 of ADCON.

4. A/D Conversion Immediately After ADKEY Function Started

In the ADKEY function, A/D conversion is not performed to the analog input voltage immediately after starting the function. This causes the A/D conversion result immediately after starting the function to be undefined. If the A/D conversion result of the analog input voltage applied to the ADKEY pin is required, select the analog input pin corresponding to ADKEY before performing A/D conversion.

5. Input Voltage Applied to ADKEY Pin

Set the input to the ADKEY pin into a steep falling waveform and stabilize the input voltage within eight cycles (1 μs when $f(\text{XIN}) = 8 \text{ MHz}$) from the moment the input voltage reaches V_{IL} or lower.

The actual threshold voltage for the ADKEY pin is between V_{IH} and V_{IL} .

To prevent unnecessary ADKEY operation due to noise or other factors, set the ADKEY pin voltage to V_{IH} (0.9 V_{CC}) or more while the input is waited.

6. Register Operation during A/D Conversion

The A/D conversion operation is not guaranteed if the following are preformed:

- The CPU mode register is operated during A/D conversion operation
- The AD control register is operated during A/D conversion operation
- The STP or WIT instruction is executed during A/D conversion operation

7. A/D Converter Power Source Pin

Connect to the A/D converter power source pin to AVSS or VSS whether the A/D conversion function is used or not.

<Reason>

If the AVSS pin is left open, the MCU may operate incorrectly because the pin will be affected by noise or other factors.

Notes on LCD Drive Control Circuit

1. Setting Data to LCD Display RAM

To write data to the LCD display RAM when the LCD enable bit is set to "1" and while LCD is turned on, set fixed data. Rewriting with temporary data may cause LCD to flicker. The following shows a processing example to write data to the LCD display RAM while LCD is turned on.

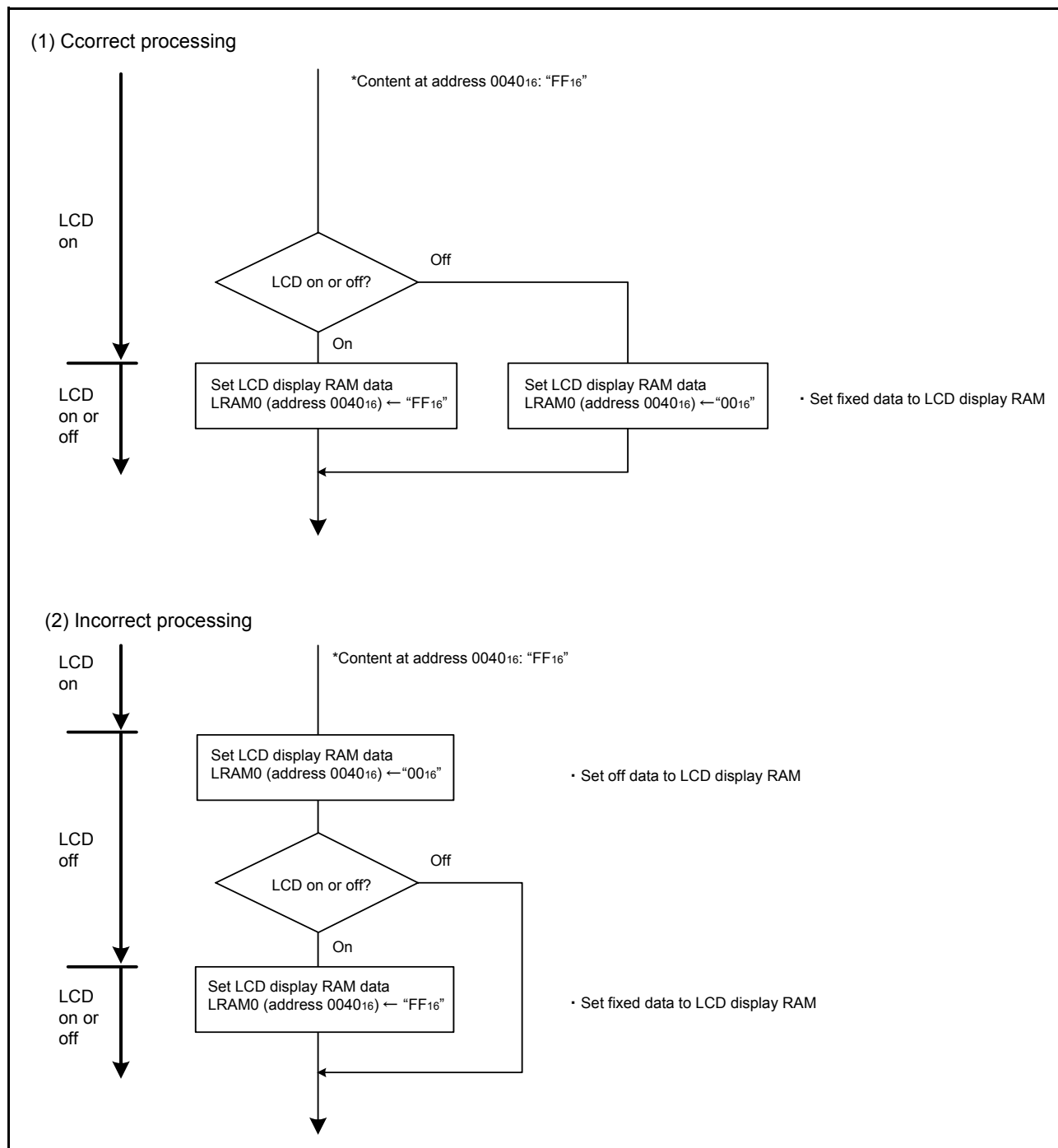


Fig. 104 Processing example when writing data to LCD display RAM While LCD Turned On

2. Executing STP Instruction

Execution of the STP instruction sets the LCD enable bit (bit 3 of the LCD mode register) and bits 0 to 5 and bit 7 of the LCD power control register to “0” and the LCD panel turns off. To make the LCD panel turn on after returning from the stop mode, set these bits to “1”.

3. VL3 Pin

To use the LCD drive control circuit while VL3 is set to the voltage equal to VCC, apply the VCC voltage to the VL3 pin and write “1” to the VL3 connection bit of LCD power control register (address 003816)).

4. LCD Drive Power Supply

Power supply capacitor may be insufficient with the division resistance for LCD power supply, and the characteristic of the LCD panel. In this case, there is the method of connecting the bypass capacitor about 0.1–0.33 μ F to VL1–VL3 pins. The example of a strengthening measure of the LCD drive power supply is shown below.

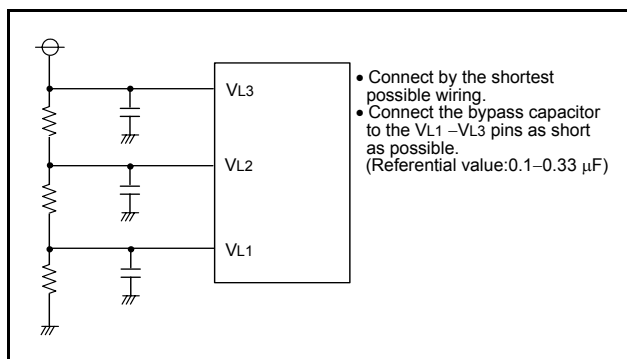


Fig. 105 Strengthening measure example of LCD drive power supply

Notes on ROM Correction Function

1. Returning to Main Program

To return to the main program from the correction program, use the JMP instruction (3-byte instruction).

2. Using ROM Correction Function

If the ROM correction function is used, be sure to enable the ROM correction enable bit after setting the ROM correction register.

3. Address

Do not set addresses other than the ROM area in the ROM correction address registers. Also, do not set the same address in the ROM correction address 1 register and the ROM correction address 2 register.

4. ROM Correction Process

Include the ROM correction process in the program beforehand.

5. Using No ROM Correction Function

If the ROM correction function is not used, the ROM correction vector can be used as normal RAM/ROM. When using as normal RAM/ROM, be sure to set bits 1 and 0 of the ROM correction enable register to “0” (disabled).

Notes on Clock Generating Circuit

1. Oscillation Circuit Constants

The oscillation circuit constants vary depending on the resonator. Use values recommended by the oscillator manufacturer.

A feed-back resistor is implemented between the XIN and XOUT pins (an external feed-back resistor may be required depending on conditions). As no feed-back resistor is implemented between XCIN and XCOUT, add a feedback resistor of about 10 M Ω .

2. Transition between Modes

When the MCU transits between on-chip oscillator mode, XIN mode, or low-speed mode, both the XIN and XCIN oscillations must be stabilized. Be especially careful when turning the power on and returning from stop mode. Refer to the clock state transition diagram for a transition between each mode. Also, set the frequency in the condition that $f(XIN) \geq 3 \times (XCIN)$.

When XIN mode is not used (the XIN-XOUT oscillation or external clock input to XIN is not performed), connect XIN to VCC through a resistor.

3. Oscillation Stabilization

Before executing the STP instruction, set the values * to generate the wait time required for oscillation stabilization to timer 1 latch and timer 2 latch (low-order 8 bits of timer 1 and high-order 8 bits of timer 2).

*Referential values

(Set values according to your oscillator and system)

- OSCSEL = “L” in the flash memory and QzROM versions:
.....000516 or more
- OSCSEL = “H” in the QzROM version:
.....01FF16 or more

4. Low-Speed Mode, XIN Mode

To use low-speed mode or XIN mode, wait until oscillation stabilizes after enabling the XIN-XOUT and XCIN-XCOUT oscillation, then switch to the mode.

Notes on Flash Memory Mode

• CPU Rewrite Mode

(1) Operating Speed

During CPU rewrite mode, set the system clock ϕ to 4.0 MHz or less using the main clock division ratio selection bits (bits 6 and 7 of address 003B16).

(2) Prohibited Instructions

During CPU rewrite mode, the instructions which reference data in the flash memory cannot be used.

(3) Interrupts

During CPU rewrite mode, interrupts cannot be used because they reference data in the flash memory.

(4) Watchdog Timer

If the watchdog timer has been running already, the internal reset by underflow will not occur because the watchdog timer is continuously cleared during program or erase operation.

(5) Reset

Reset is always valid. If CNVSS = "H" when a reset is released, boot mode is active. The program starts from the address stored in addresses FFFC16 and FFFD16 in boot ROM area.

Notes on Watchdog Timer**1. Watchdog Timer Underflow**

The watchdog timer does not operate in stop mode, but it continues counting during the wait time to release the stop state and in wait mode. Write to the watchdog timer control register so that the watchdog timer will not underflow during these periods.

2. Stopping On-Chip Oscillator Oscillation

When the on-chip oscillator is selected by the watchdog timer count source selection bit 2, the on-chip oscillator forcibly oscillates and it cannot be stopped. Also, in this time, set the STP instruction function selection bit to "1" at this time. Select "0" (ϕ SOURCE) for the watchdog timer count source selection bit 2 at the system which on-chip oscillator is stopped.

3. Watchdog Timer Control Register

Bits 7 to 5 can be rewritten only once after a reset. After writing, rewriting is disabled because they are locked. These bits are set to "0" after a reset.

Notes on Differences between QzROM Version and Flash Memory Version

The flash memory and QzROM versions differ in their manufacturing processes, built-in ROM, memory size, and layout patterns. Because of these differences, characteristic values, operation margins, noise immunity, and noise radiation and oscillation circuit constants may vary within the specified range of electrical characteristics.

When switching to the QzROM version, implement system evaluations equivalent to those performed in the flash memory version.

Confirm page 11 about the differences of functions.

Notes on Power Source Voltage

When the power supply voltage value of the MCU is less than the value indicated in the recommended operating conditions, the MCU may not operate normally and perform unstable operation. In a system where the power source voltage drops slowly when the power source voltage drops or the power is turned off, reset the MCU when the power source voltage is less than the recommended operating conditions, and design the system so that this unstable operation does not cause errors to it.

Notes on Handling Power Source Pins

Before using the MCU, connect a capacitor suitable for high frequencies as a bypass capacitor between the following:

The power source pin (VCC pin) and the GND pin (VSS pin)

The power source pin (VCC pin) and the analog power source input pin (AVSS pin). As a bypass capacitor, a ceramic capacitor of 0.01 μ F to 0.1 μ F is recommended.

Also, use the shortest possible wiring to connect a bypass capacitor between the power source pin and the GND pin and between the power source pin and the analog power source pin.

Notes on Memory**1. RAM**

The RAM content is undefined at a reset. Be sure to set the initial value before use.

Notes on QzROM Version

Wiring to OSCSEL pin

(1) OSCSEL = L

Connect the OSCSEL pin the shortest possible to the GND pattern which is supplied to the VSS pin of the microcomputer. In addition connecting an approximately 5 kΩ resistor in series to the GND could improve noise immunity. In this case as well as the above mention, connect the pin the shortest possible to the GND pattern which is supplied to the VSS pin of the microcomputer.

(2) OSCSEL = H

Connect the OSCSEL pin the shortest possible to the VCC pattern which is supplied to the VCC pin of the microcomputer. In addition connecting an approximately 5 kΩ resistor in series to the VCC could improve noise immunity. In this case as well as the above mention, connect the pin the shortest possible to the VCC pattern which is supplied to the VCC pin of the microcomputer.

<Reason>

The OSCSEL pin is the power source input pin for the built-in QzROM.

When programming in the QzROM, the impedance of the OSCSEL pin is low to allow the electric current for writing to flow into the built-in QzROM. Because of this, noise can enter easily. If noise enters the OSCSEL pin, abnormal instruction codes or data are read from the QzROM, which may cause a program runaway.

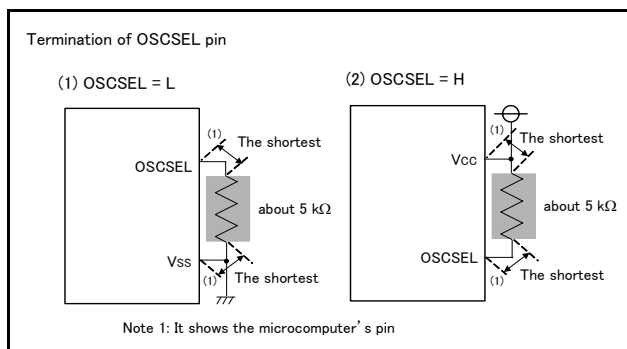


Fig. 106 Wiring for OSCSEL pin

Overvoltage in QzROM Version

Make sure that voltage exceeding the VCC pin voltage is not applied to other pins. In particular, ensure that the state indicated by bold lines in figure below does not occur for pin OSCSEL pin (VPP power source pin for QzROM) during power-on or power-off. Otherwise the contents of QzROM could be rewritten.

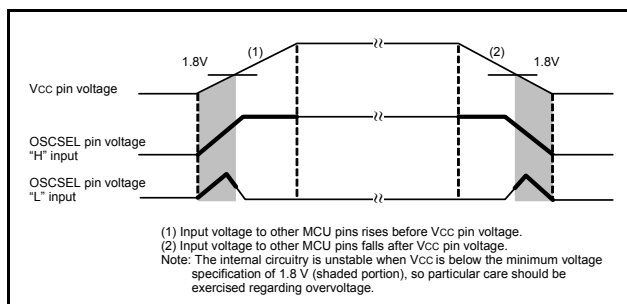


Fig. 107 Timing Diagram (Bold-lined periods are applicable)

QzROM Version Product Shipped in Blank

As for the product shipped in blank, Renesas does not perform the writing test to user ROM area after the assembly process though the QzROM writing test is performed enough before the assembly process. Therefore, a writing error of approximate 0.1% may occur.

Moreover, please note the contact of cables and foreign bodies on a socket, etc. because a writing environment may cause some writing errors.

Ordering QzROM Writing

1. Notes On QzROM Writing Orders

When ordering the QzROM product shipped after writing, submit the mask file (extension: .msk) which is made by the mask file converter MM.

- Be sure to set the ROM option data* setup when making the mask file by using the mask file converter MM.. The ROM code protect is specified according to the ROM option data* in the mask file which is submitted at ordering. Note that the mask file which has nothing at the ROM option data* or has the data other than "0016", "FE16" and "FF16" can not be accepted.
- Set "FF16" to the ROM code protect address in ROM data regardless of the presence or absence of a protect. When data other than "FF16" is set, we may ask that the ROM data be submitted again.

* ROM option data: mask option noted in MM

2. Data Required for QzROM Ordering

The following are necessary when ordering a QzROM product shipped after writing:

- QzROM Writing Confirmation Form*
- Mark Specification Form*
- ROM data: Mask file

* For the QzROM writing confirmation form and the mark specification form, refer to the "Renesas Technology Corp." Homepage (<http://www.renesas.com/homepage.jsp>).

Note that we cannot deal with special font marking (customer's trademark etc.) in QzROM microcomputer.

3. QzROM Product Receiving Procedure

When writing to QzROM is performed by user side, the receiving inspection by the following flow is necessary.

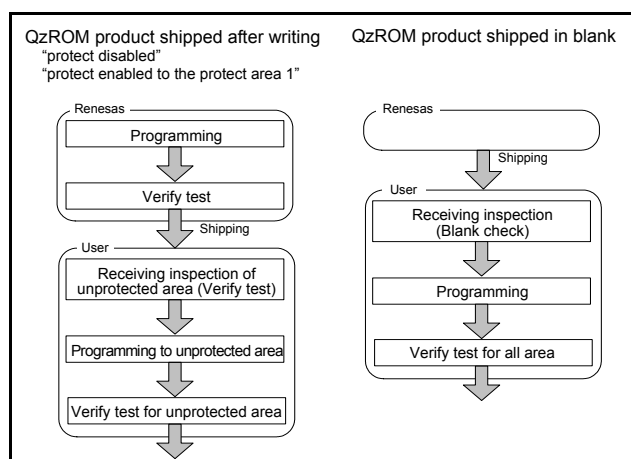


Fig. 108 QzROM receiving procedure

During CPU rewrite mode, set the system clock ϕ 4.0 MHz or less using the main clock division ratio selection bits (bits 6 and 7 of address 003B₁₆).

2. Prohibited Instructions

The instructions which refer to the internal data of the flash memory cannot be used during the CPU rewrite mode.

3. Interrupts

The interrupts cannot be used during the CPU rewrite mode because they refer to the internal data of the flash memory.

4. Watchdog Timer

In case of the watchdog timer has been running already, the internal reset generated by watchdog timer underflow does not happen, because of watchdog timer is always clearing during program or erase operation.

5. Reset

Reset is always valid. In case of CNVSS = "H" when reset is released, boot mode is active. So the program starts from the address contained in address FFFC₁₆ and FFFD₁₆ in boot ROM area.

CNVss Pin

The CNVss pin determines the flash memory mode.

Connect the CNVss pin the shortest possible to the GND pattern which is supplied to the Vss pin of the microcomputer.

In addition connecting an approximately 5 k Ω resistor in series to the GND could improve noise immunity. In this case as well as the above mention, connect the pin the shortest possible to the GND pattern which is supplied to the Vss pin of the microcomputer.

Note. When the boot mode or the standard serial I/O mode is used, a switch of the input level to the CNVss pin is required.

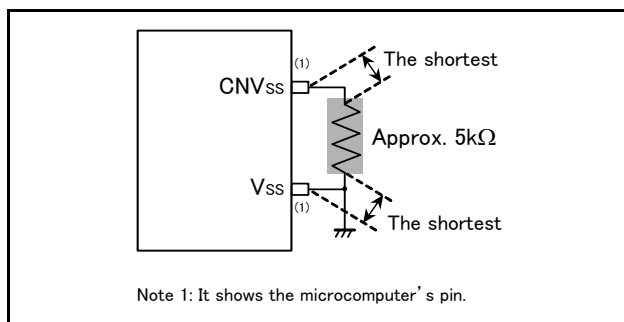


Fig. 109 Wiring for CNVss pin

REVISION HISTORY	38D2 Group Datasheet
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Rev.	Date	Description	
		Page	Summary
1.00	Jan. 23, 2006	–	First edition issued
2.00	Mar. 24, 2006	1	FEATURES : Description of reset circuit eliminated and Power source voltage revised.
		3	Performance overview: Oscillation frequency and Power source voltage revised.
		4	FUNCTIONAL BLOCK DIAGRAM : Description of reset circuit eliminated.
		7	Fig. 4 and Table 3 38D29GC, 38D29G8 added.
		12	Fig. 9 Memory map diagram revised.
		15	Table 7 Non-port function of port P54–P57 revised. Related SFRs of port P40 and P41 revised.
		18	Fig. 15 (18) Port P61 revised.
		26	Fig. 22 Timer 12 mode register revised.
		29	Notes on Timer X: (1), (2) revised.
		32	• Real Time Port Control revised.
		36	Fig. 32 UART control register revised.
		38	Fig. 34 Note 1 revised.
		42	Fig. 38 Note 2 revised.
		48	Fig. 46 Memory map revised.
		49	Note 1 revised.
		50	Clock output function revised.
		51	Reset circuit revised.
		53	(1)Stop mode: Description revised.
		54	Fig. 58 ϕ SOURCE added.
		55	Fig. 60 State transitions of system clock: Note 3 revised.
2.01	Nov. 15, 2006	56	Address of oscillation output control register revised.
		60	Fig. 64 Connection of XIN and XOUT revised.
		65-75	Electrical characteristics added.
		1	DESCRIPTION revised Power dissipation described.
		3	Main clock / Sub-clock generating circuits: Built-in feed back resistor → Built-in Power dissipation described.
		5	AVss: GND input pin → Analog power source input pin
		12	ROM and ROM Code Protect Address : Description revised. Fig. 9 is revised.
		15	Table 7 : As for CKOUT, non-port function and related SFRs are added.
		19	Termination of unused pins : As for I/O ports, description added. VL3 : Terminations 1 and 2 revised.
		25	Timer 1, Timer 2 : Description revised.
		28	Timer X : Description revised.
		29	Fig. 24 : TXCON1 bit 5 = 1 → TXCON1 bit 5 = 0
		31	Timer Y : Description revised. Fig. 26 : Note added.
		37	Fig. 33 : Note and ϕ source added.

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Rev.	Date	Description	
		Page	Summary
2.01	Nov. 15, 2006	42	LCD Power Circuit • Description added • Fig. 38 : Note 3 eliminated • Fig. 39 : Bit name described
		48	Fig. 46 : Reserved ROM area address revised. ROM CORRECTION FUNCTION : Description added.
		49	Fig. 48 : On-chip oscillator → On-chip oscillator/4 Note added. Fig. 49 : On-chip oscillator → On-chip oscillator/4 ϕ source/1024 → Count source/1024 ϕ source/4 → Count source/4
		53	(5) Low-speed Mode : Description added
		54	Fig. 58 : Note added and circuit expression is revised.
		56	Fig. 61 : Circuit expression is revised.
		57	Table 12: As for VREF and AVSS, function revised.
		59 to 62	Fig. 63 to Fig. 66 added and revised.
		71	Table 17 I _{IH} and I _{IL} : OSCSEL added.
		75	Table 23: Note revised.
3.01	Sep.18, 2007	–	Flash memory version function: added
		1	DESCRIPTION: flash memory version contents added FEATURES: flash memory version contents added Power source voltages: flash memory version contents added Power dissipation: flash memory version contents added Flash memory mode: added
		2	Fig. 1: Note is added
		3	Table 1: Power source voltage: revised and flash memory version contents added Power dissipation: flash memory version contents added
		5	Table 2: LED ₀ to 7 and KW ₀ to 3 are added to pin name
		6	Pin description table is divided (to Table 2 and Table 3) Table 3: CNVss pin is added
		7	Fig. 3: F (Flash memory) is added to memory type
		8	Flash memory size is added Fig. 4: Some “Under developing” are erased
		9	Table 3: Flash memory version products are added
		10	Table 5 “Differences between QzROM and flash memory versions” and “Notes on Differences between QzROM and Flash Memory Versions” are added
		12	Fig. 6: “Push contents of processor status register on stack” position is moved
		14	CPU mode register explanation is revised Fig. 7: Some notes are added
		15	Fig. 8: Flash memory version flow is added
		16	Fig. 9: Flash memory version SRF is added
		17	Fig. 10: Flash memory version SRF and notes are added
		19	Table 2: LED ₀ to 7 and KW ₀ to 3 are added to pin name
		24-28	“Interrupt” is wholly revised
		32	“Frequency Divider for Timer” is revised
		35	“Frequency Divider for Timer” is revised

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Rev.	Date	Description	
		Page	Summary
3.01	Sep.18, 2007	35	"(6) Pulse Width Measurement Mode" is revised
		36	"(3) Write To Timer X" is revised
		37	"(7) When Timer X Pulse Width Measurement Mode Used"
		38	"(5) Real Time Port Control" is added
		39	"Notes on Timer Y" is revised
		44	"Comparator and Control Circuit" is revised
		45	Fig. 37: Revised "ADKEY Control Circuit" is revised
		56	"Initial value of watchdog timer" is revised "Bit 6 of Watchdog Timer Control Register" and "<Notes>" are revised Fig. 51: Revised Fig. 52: Revised
		57	Fig. 54: Revised "[RRF register (RRFR)]" is added
		58	Explanation is revised Fig. 56: revised Fig. 57: Notes are added
		59	Fig. 58: Revised
		60	Explanation is revised
		62	Fig. 61: Revised
		63	Fig. 62: Revised
		65	Table 14: Revised
		71-88	"Flash Memory Mode" is added
		89	Revised to "Notes on Use" from "Notes on Programming" contents
		90	Added "NOTES on QzROM VERSION"
		91	Added "NOTES on FLASH MEMORY VERSION" and "NOTES ON DIFFERENCES BETWEEN QzROM VERSION AND FLASH MEMORY VERSION"
		94	Table 21: Revised
		95-101	Table 22 to 29: "Vss=0V" are added to condition
		95	Table 22: VIL of XCIN is deleted
		98	Table 25: "VCC = 4.0 t o 5.0 V" → "VCC = 1.8 to 5.5 V"
		100	Table 28: • ABS of 10bitAD mode "2.2V ≤ VCC ≤ 4.0V" → "2.2V ≤ VCC ≤ 4.0V" "1.8V ≤ VCC ≤ 5.5V" → "2.0V ≤ VCC ≤ 5.5V" • ABS of 8bitAD mode "2.2V ≤ VCC ≤ 4.0V" → "2.2V ≤ VCC ≤ 4.0V" "1.8V ≤ VCC ≤ 5.5V" → "2.0V ≤ VCC ≤ 5.5V" • tCONV is separated to 10bitAD mode and 8bitADmode, and note is added
		102	Table 30: TC, TWH, and TWL of XIN "4.5 V to 5.5 V" → "4.5V ≤ VCC ≤ 5.5V" "4.0 V to 5.5 V" → "4.0V ≤ VCC ≤ 5.5V" Table 31: TC of XIN and CNTR, and TWH and TWL of XIN "2.0V ≤ VCC ≤ 4.0V" → "2.0V ≤ VCC ≤ 4.0V" "VCC ≤ 2.0V" → "VCC ≤ 2.0V"
		104	Fig. 95: XCIN timing is deleted
		105-115	Flash memory version electrical characteristics is added

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Rev.	Date	Description	
		Page	Summary
3.01	Sep.18, 2007	118-131	Appendix is added
3.02	Apr. 09, 2008	2	Fig. 1: Revised
		3	Table 1: Revised
		5	Table 2: Revised
		18	"Direction Registers": Peripheral output name is added and deleted
		21	Fig. 14: Revised
		23	Table 9: Revised
		25	"External Interrupt Pin Selection" is deleted
		26	Fig. 17: Revised
		29	Port name is revised
		34	Fig. 26: Revised
		38	"Timer Y" is revised
		44	Fig. 36: Revised
		49	Fig. 41: Revised
		57	Fig. 53 and 54 are revised
		58	Fig. 56: Revised
		63	Fig. 63: Revised
		64	Fig. 63: Revised
		65	Table 14: Revised
		66	Fig. 65: Revised
		74	Fig. 73: Revised
		85	Fig. 80: Revised
		86	Fig. 81: Revised
		90	Notes On ROM Code Protect is revised
		95	Table 22: Revised
		99	Table 27: Revised
		102	Table 30: Revised
		109	NOTE of Table 38: Revised
		110	Table 40: Revised
		129	Notes On ROM Code Protect is revised

Notes:

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